

Based on Arm® Cortex®-M4F single

General description

CYT2B7 is a family of TRAVEO™ T2G microcontrollers targeted at automotive systems such as body control units. CYT2B7 has an Arm® Cortex®-M4F CPU for primary processing, and an Arm® Cortex®-M0+ CPU for peripheral and security processing. These devices contain embedded peripherals supporting Controller Area Network with Flexible Data rate (CAN FD), and Local Interconnect Network (LIN). TRAVEO™ T2G devices are manufactured on an advanced 40-nm process. CYT2B7 incorporates a low-power flash memory, multiple high-performance analog and digital peripherals, and enables the creation of a secure computing platform.

Features

Dual CPU subsystem

- 160-MHz (max) 32-bit Arm® Cortex®-M4F CPU with
 - Single-cycle multiply
 - Single-precision floating point unit (FPU)
 - Memory protection unit (MPU)
- 100-MHz (max) 32-bit Arm® Cortex® M0+ CPU with
 - · Single-cycle multiply
 - Memory Protection Unit
- Inter-processor communication in hardware
- Three DMA controllers
 - Peripheral DMA controller #0 (P-DMA0) with 89 channels
 - Peripheral DMA controller #1 (P-DMA1) with 33 channels
 - Memory DMA controller #0 (M-DMA0) with 4 channels

· Integrated memories

- 1088 KB of code-flash with an additional 96 KB of work-flash
 - Read-While-Write (RWW) allows updating the code-flash/work-flash while executing from it
 - Single- and dual-bank modes (specifically for Firmware update Over The Air [FOTA])
 - Flash programming through SWD/JTAG interface
- 128 KB of SRAM with selectable retention granularity

Crypto engine^[1]

- Supports enhanced Secure Hardware Extension (eSHE) and Hardware Security Module (HSM)
- Secure boot and authentication
 - · Using digital signature verification
 - · Using fast secure boot
- AES: 128-bit blocks, 128-/192-/256-bit keys
- 3DES^[2]: 64-bit blocks, 64-bit key
- Vector unit^[2] supporting asymmetric key cryptography such as Rivest-Shamir-Adleman (RSA) and Elliptic Curve (ECC)
- SHA-1/2/3^[2]: SHA-512, SHA-256, SHA-160 with variable length input data
- CRC^[2]: supports CCITT CRC16 and IEEE-802.3 CRC32
- True random number generator (TRNG) and pseudo random number generator (PRNG)
- Galois/Counter Mode (GCM)

Functional safety for ASIL-B

- Memory protection unit (MPU)
- Shared memory protection unit (SMPU)
- Peripheral protection unit (PPU)

Notes

- 1. The Crypto engine features are available on select MPNs.
- 2. This feature is not available in "eSHE only" parts; for more information, refer to **Ordering information**.

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Features



- Watchdog timer (WDT)
- Multi-counter watchdog timer (MCWDT)
- Low-voltage detector (LVD)
- Brown-out detector (BOD)
- Overvoltage detection (OVD)
- Clock supervisor (CSV)
- Hardware error correction (SECDED ECC) on all safety-critical memories (SRAM, flash)

• Low-power 2.7-v to 5.5-v operation

- Low-power Active, Sleep, Low-power Sleep, DeepSleep, and Hibernate modes for fine-grained power management
- Configurable options for robust BOD
 - \bullet Two threshold levels (2.7 V and 3.0 V) for BOD on V_{DDD} and V_{DDA}
 - One threshold level (1.1 V) for BOD on V_{CCD}

· Wakeup support

- Up to two pins to wakeup from Hibernate mode
- Up to 152 GPIO pins to wakeup from Sleep modes
- Event Generator, SCB, Watchdog Timer, RTC alarms to wake from DeepSleep modes

Clock sources

- Internal main oscillator (IMO)
- Internal low-speed oscillator (ILO)
- External crystal oscillator (ECO)
- Watch crystal oscillator (WCO)
- Phase-locked loop (PLL)
- Frequency-locked loop (FLL)

· Communication interfaces

- Up to six CAN FD channels
 - Increased data rate (up to 8 Mbps) compared to classic CAN, limited by physical layer topology and transceivers
 - Compliant to ISO 11898-1:2015
 - Supports all the requirements of Bosch CAN FD Specification V1.0 for non-ISO CAN FD
 - ISO 16845:2015 certificate available
- Up to eight runtime-reconfigurable SCB (serial communication block) channels, each configurable as I²C, SPI, or UART
- Up to eight independent LIN channels
 - LIN protocol compliant with ISO 17987

Timers

- Up to 75 16-bit and four 32-bit timer/counter pulse-width modulator (TCPWM) blocks
 - Up to 12 16-bit counters for motor control
 - Up to 63 16-bit counters and four 32-bit counters for regular operations
 - Supports timer, capture, quadrature decoding, pulse-width modulation (PWM), PWM with dead time (PW-M_DT), pseudo-random PWM (PWM_PR), and shift-register (SR) modes
- Up to 11 Event Generation (EVTGEN) timers supporting cyclic wakeup from DeepSleep
 - Events trigger a specific device operation (such as execution of an interrupt handler, a SAR ADC conversion, and so on)

Real time clock (RTC)

- Year/Month/Date, Day-of-week, Hour:Minute:Second fields
- 12- and 24-hour formats
- Automatic leap-year correction

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Features



· I/O

- Up to 152 Programmable I/Os
- Two I/O types
 - GPIO Standard (GPIO_STD)
 - GPIO Enhanced (GPIO_ENH)

Regulators

- Generates 1.1-V nominal core supply from a 2.7-V to 5.5-V input supply
- Two types of regulators
 - DeepSleep
 - Core internal

Programmable analog

- Three SAR A/D converters with up to 67 external channels (64 I/Os + 3 I/Os for motor control)
 - ADC0 supports 24 logical channels, with 24 + 1 physical connections
 - ADC1 supports 32 logical channels, with 32 + 1 physical connections
 - ADC2 supports 8 logical channels, with 8 + 1 physical connections
 - Any external channel can be connected to any logical channel in the respective SAR
- Each ADC supports 12-bit resolution and sampling rates of up to 1 Msps
- Each ADC also supports up to six internal analog inputs like
 - Bandgap reference to establish absolute voltage levels
 - Calibrated diode for junction temperature calculations
 - Two AMUXBUS inputs and two direct connections to monitor supply levels
- Each ADC supports addressing of external multiplexers
- Each ADC has a sequencer supporting autonomous scanning of configured channels
- Synchronized sampling of all ADCs for motor-sense applications

Smart I/O™

- Up to five Smart I/O blocks, which can perform Boolean operations on signals going to and from I/Os
- Up to 36 I/Os (GPIO_STD) supported

Debug interface

- JTAG controller and interface compliant to IEEE-1149.1-2001
- Arm® SWD (Serial Wire Debug) port
- Supports Arm® Embedded Trace Macrocell (ETM) Trace
 - Data trace using SWD
 - Instruction and data trace using JTAG

· Compatible with industry-standard tools

GHS/MULTI or IAR EWARM for code development and debugging

Packages

- 64-LQFP, 10 × 10 × 1.7 mm (max), 0.5-mm lead pitch
- 80-LQFP, 12 × 12 × 1.7 mm (max). 0.5-mm lead pitch
- 100-LQFP, 14 × 14 × 1.7 mm (max), 0.5-mm lead pitch
- 144-LQFP, 20 × 20 × 1.7 mm (max), 0.5-mm lead pitch
- 176-LQFP, 24 × 24 × 1.7 mm (max), 0.5-mm lead pitch

Certification

Qualified for automotive application according to AEC-Q100

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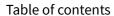




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Features list



1 Features list

Table 1-1 CYT2B7 feature list for all packages

Conturas	Packages						
Features	64-LQFP	80-LQFP	100-LQFP	144-LQFP	176-LQFP		
CPU							
Core	32-bit Arn	n® Cortex®-M4	F CPU and 32-I	oit Arm® Cortex	® M0+ CPU		
Functional safety			ASIL-B				
Operating voltage			2.7 V to 5.5 V	,			
Core voltage			1.05 V to 1.15	V			
Operating frequency	Arm® Cortex®-M4F 160 MHz (max) and Arm® Cortex®-M0+ 100 MHz (max), related by integer frequency ratio (that is, 1:1, 1:2, 1:3, and so on						
MPU, PPU	Supported						
FPU		Sin	gle precision (3	32-bit)			
DSP-MUL/DIV/MAC		Supported	d by Arm® Corte	ex®-M4F CPU			
Memory							
Code-flash		1088	3 KB (960 KB + 1	28 KB)			
Work-flash	96 KB (72 KB + 24 KB)						
SRAM (configurable for retention)	128 KB						
ROM	32 KB						
Communication Interfaces	!						
CANO (CAN FD: Up to 8 Mbps)	3 ch						
CAN1 (CAN FD: Up to 8 Mbps)	2 ch		3	ch			
CAN RAM		24 KB per i	nstance (3 ch),	48 KB in total			
Serial communication block (SCB/UART)	7 ch		8	ch			
Serial communication block (SCB/I2C)	6	ch		8 ch			
Serial communication block (SCB/SPI)	3 ch	6 ch		8 ch			
LINO	6 ch	7	ch	8 (ch		
Timers							
RTC			1 ch				
TCPWM (16-bit) (Motor Control)			12 ch				
TCPWM (16-bit)			63 ch				
TCPWM (32-bit)			4 ch				
External Interrupts	49	63	78	122	152		
Analog							
	3 Ur	nits (SAR0/24,	SAR1/32, SAR2	2/8 logical chan	nels)		
12-bit, 1 Msps SAR ADC	27 external channels (SAR0 11 ch, SAR1 9 ch, SAR2 7 ch)	34 external channels (SAR0 12 ch, SAR1 14 ch, SAR2 8 ch)	39 external channels (SAR0 14 ch, SAR1 17 ch, SAR2 8 ch)	54 external channels (SAR0 21 ch, SAR1 25 ch, SAR2 8 ch)	64 external channels (SAR0 24 ch, SAR1 32 ch, SAR2 8 ch)		
		18 ch (6 p	oer ADC) Intern	al sampling			

Note

^{3.} Enhanced Secure Hardware Extension (eSHE) and Hardware Security Module (HSM) support are enabled by third-party firmware.

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Features list



Table 1-1 CYT2B7 feature list for all packages (continued)

Fastures			Packages			
Features	64-LQFP	80-LQFP	100-LQFP	144-LQFP	176-LQFP	
Motor Control Input	3 ch (synch	ronous samp	ling of one cha	nnel on each of	the 3 ADCs)	
Security	l.					
Flash Security (program/work read protection)			Supported			
Flash Chip erase enable			Configurable	<u> </u>		
eSHE/HSM		Ву	separate firmw	are ^[3]		
System						
DMA Controller	P-DMA0 w channe	vith 89 channe ls (8 general p	els (16 general ourpose), and M	purpose), P-DM 1-DMA0 with 4 o	A1 with 33 channels	
Internal main oscillator			8 MHz			
Internal low-speed oscillator	32.768 kHz (nominal)					
PLL	Input frequency: 3.988 to 33.34 MHz, PLL output frequency: up to 160 MHz					
FLL	Input freque	ncy: 0.25 to 80) MHz, FLL outp	out frequency:	up to 100 MH	
Watchdog timer and multi-counter watchdog timer			orted (WDT + 2× 0 tied to CM0+, MCW			
Clock supervisor			Supported			
Cyclic wakeup from DeepSleep			Supported			
GPIO_STD	45	59	74	118	148	
GPIO_ENH			4	1	l	
Smart I/O (Blocks)	3 blocks, 9 I/Os	3 blocks, 14 I/Os	4 blocks, 20 I/Os	5 blocks, 29 I/Os	5 blocks, 36 I/Os	
Low-voltage detect	Two, 26 selectable levels					
Maximum ambient temperature	105 °C for S-grade and 125 °C for E-grade					
Debug interface			SWD/JTAG			
Debug trace	Arm® Cortex®		e of 8 KB, Arm®	Cortex® M0+ M	TB size of 4 K	

1.1 Communication peripheral instance list

The following table lists the instances supported under each package for communication peripherals, based on the minimum pins needed for the functionality.

Table 1-2 Peripheral instance list

Module	64-LQFP	80-LQFP	100-LQFP	144-LQFP	176-LQFP	Minimum pin functions
CAN0	0/1/2	0/1/2	0/1/2	0/1/2	0/1/2	TX, RX
CAN1	0/2	0/1/2	0/1/2	0/1/2	0/1/2	TX, RX
LIN0	0/1/2/3/4/7	0/1/2/3/4/6/7	0/1/2/3/4/6/7	0/1/2/3/4/5/6/7	0/1/2/3/4/5/6/7	TX, RX
SCB/UART	0/1/2/3/4/5/7	0/1/2/3/4/5/6/7	0/1/2/3/4/5/6/7	0/1/2/3/4/5/6/7	0/1/2/3/4/5/6/7	TX, RX
SCB/I2C	0/2/3/4/5/7	0/1/3/4/5/7	0/1/2/3/4/5/6/7	0/1/2/3/4/5/6/7	0/1/2/3/4/5/6/7	SCL, SDA
SCB/SPI	0/3/4	0/1/3/4/5/7	0/1/2/3/4/5/6/7	0/1/2/3/4/5/6/7	0/1/2/3/4/5/6/7	MISO, MOSI, SCK, SELECTO

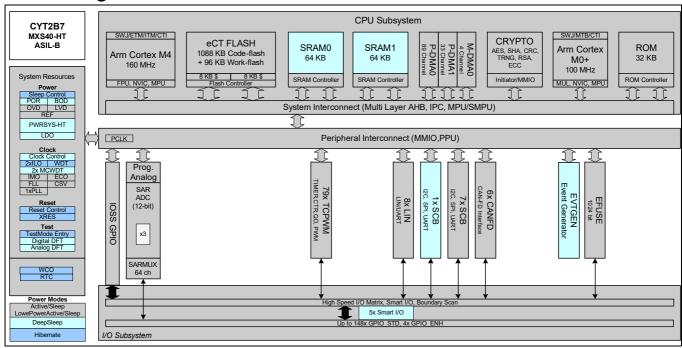
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Blocks and functionality



Blocks and functionality 2

Block diagram



The **Block diagram** shows the CYT2B7 architecture, giving a simplified view of the interconnection between subsystems and blocks. CYT2B7 has four major subsystems: CPU, system resources, peripherals, and $I/O^{[4,5]}$. The color-coding shows the lowest power mode where the particular block is still functional.

CYT2B7 provides extensive support for programming, testing, debugging, and tracing of both hardware and firmware.

Debug-on-chip functionality enables in-system debugging using the production device. It does not require special interfaces, debugging pods, simulators, or emulators.

The JTAG interface is fully compatible with industry-standard third-party probes such as I-jet, J-Link, and GHS.

The debug circuits are enabled by default.

CYT2B7 provides a high level of security with robust flash protection and the ability to disable features such as debug.

Additionally, each device interface can be permanently disabled for applications concerned with phishing attacks from a maliciously reprogrammed device or attempts to defeat security by starting and interrupting flash programming sequences. All programming, debug, and test interfaces are disabled when maximum device security is enabled.

Notes

GPIO_STD supporting 2.7 V to 5.5 V V_{DDIO} range.
 GPIO_ENH supporting 2.7 V to 5.5 V V_{DDIO} range with higher currents at lower voltages.

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Functional description



3 Functional description

3.1 CPU subsystem

3.1.1 CPU

The CYT2B7 CPU subsystem contains a 32-bit Arm® Cortex®-M0+ CPU with MPU, and a 32-bit Arm® Cortex®-M4F CPU with MPU, and single-precision FPU. This subsystem also includes P-/M-DMA controllers, a cryptographic accelerator, 1088 KB of code-flash, 96 KB of work-flash, 128 KB of SRAM, and 32 KB of ROM.

The Cortex®-M0+ CPU provides a secure, un-interruptible boot function. This guarantees that, following completion of the boot function, system integrity is valid and privileges are enforced. Shared resources (flash, SRAM, peripherals, and so on) can be accessed through bus arbitration, and exclusive accesses are supported by an inter-processor communication (IPC) mechanism using hardware semaphores.

3.1.2 DMA controllers

CYT2B7 has three DMA controllers: P-DMA0 with 16 general-purpose and 73 dedicated channels, P-DMA1 with 8 general-purpose and 25 dedicated channels, and M-DMA0 with four channels. P-DMA is used for peripheral-to-memory and memory-to-peripheral data transfers and provides low latency for a large number of channels. Each P-DMA controller uses a single data-transfer engine that is shared by the associated channels. General purpose channels have a rich interconnect matrix including P-DMA cross triggering which enables demanding data-transfer scenarios. Dedicated channels have a single triggering input (such as an ADC channel) to handle common transfer needs. M-DMA is used for memory-to-memory data transfers and provides high memory bandwidth for a small number of channels. M-DMA uses a dedicated data-transfer engine for each channel. They support independent accesses to peripherals using the AHB multi-layer bus.

3.1.3 Flash

CYT2B7 has 1088 KB (960 KB with a 32-KB sector size, and 128 KB with an 8-KB sector size) of code-flash with an additional work-flash of up to 96 KB (72 KB with 2-KB sector size, and 24 KB with 128-B sectors size). Work-flash is optimized for reprogramming many more times than code-flash. Code-flash supports Read-While-Write (RWW) operation allowing flash to be updated while the CPU is active. Both the code-flash and work-flash areas support dual-bank operation for over-the-air (OTA) programming.

3.1.4 SRAM

CYT2B7 has 128 KB of SRAM with two independent controllers. The first controller, SRAM0, provides DeepSleep retention in 32-KB increments, while SRAM1 is selectable between fully retained and not retained.

3.1.5 ROM

CYT2B7 has 32-KB ROM that contains boot and configuration routines. This ROM enables secure boot and authentication of user flash to guarantee a secure system.

3.1.6 Cryptography accelerator for security

The cryptography accelerator implements (3)DES block cipher, AES block cipher, SHA hash, cyclic redundancy check, pseudo random number generation, true random number generation, galois/counter mode, and a vector unit to support asymmetric key cryptography such as RSA and ECC.

Depending on the part number, this block is either completely or partially available or not available at all. See **Ordering information** for more details.

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Functional description



3.2 System resources

3.2.1 Power system

The power system ensures that the supply voltage levels meet the requirements of each power mode, and provides a full-system reset when these levels are not valid. Internal power-on reset (POR) guarantees full-chip reset during the initial power ramp.

Three Brown-Out Detection (BOD) circuits monitor the external supply voltages (V_{DDD} , V_{DDA} , V_{CCD}). The BOD on V_{DDD} and V_{CCD} are initially enabled and cannot be disabled. The BOD on V_{DDA} is initially disabled and can be enabled by the user. For the external supplies V_{DDD} and V_{DDA} , BOD circuits are software configurable with two settings; a 2.7-V minimum voltage that is robust for all internal signaling and a 3.0-V minimum voltage, which is also robust for all I/O specifications (which are guaranteed at 2.7 V). The BOD on V_{CCD} is provided as a safety measure and is not a robust detector.

Three overvoltage detection (OVD) circuits are provided for monitoring external supplies (V_{DDD} , V_{DDA} , V_{CCD}), and overcurrent detection circuits (OCD) for monitoring internal and external regulators. OVD thresholds on V_{DDD} and V_{DDA} are configurable with two settings; a 5.0-V and 5.5-V maximum voltage. Two voltage-detection circuits are provided to monitor the external supply voltage (V_{DDD}) for falling and rising levels, each configurable for one of the 26 selectable levels.

All BOD, OVD, and OCD circuits on V_{DDD} and V_{CCD} generate a reset, because these protect the CPUs and fault logic. The BOD and OVD circuits on V_{DDA} can be configured to generate either a reset, or a fault.

3.2.2 Regulators

CYT2B7 contains two regulators that provide power to the low-voltage core transistors: DeepSleep and core internal. These regulators accept a 2.7–5.5-V V_{DDD} supply and provide a low-noise 1.1-V supply to various parts of the device. These regulators are automatically enabled and disabled by hardware and firmware when switching between power modes. The core internal and core external regulators operate in active mode, and provide power to the CPU subsystem and associated peripherals.

3.2.2.1 DeepSleep

The DeepSleep regulator is used to maintain power to a small number of blocks when in DeepSleep mode. These blocks include the ILO and WDT timers, BOD detector, SCB0, SRAM memories, Smart I/O, and other configuration memories. The DeepSleep regulator is enabled when in DeepSleep mode, and the core internal regulator is disabled. It is disabled when XRES_L is asserted (LOW) and when the core internal regulator is disabled.

3.2.2.2 Core internal

The core internal regulator supports load currents up to 150 mA, and is operational during the device start-up (boot process), and in Active/Sleep modes.

3.2.3 Clock system

The CYT2B7 clock system provides clocks to all subsystems that require them, and glitch-free switching between different clock sources. In addition, the clock system ensures that no metastable conditions occur.

The clock system for CYT2B7 consists of the 8-MHz IMO, two ILOs, three watchdog timers, a PLL, an FLL, five clock supervisors (CSV), a 3.988- to 33.34 MHz ECO, and a 32.768-kHz WCO.

The clock system supports two main clock domains: CLK_HF, and CLK_LF.

- CLK_HFx are the Active mode clocks. Each can use any of the high frequency clock sources including IMO, EXT_CLK, ECO, FLL, or PLL
- CLK_LF is a DeepSleep domain clock and provides a reference clock for the MCWDT or RTC modules. The reference clock for the CLK_LF domain is either disabled or selectable from ILO0, ILO1, or WCO

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Table 3-1 CLK_HF destinations

Name	Description
CLK_HF0	CPUSS clocks, PERI, and AHB infrastructure
CLK_HF1	Event Generator, also available in HSIOM as an output

3.2.3.3 IMO clock source

The IMO is the frequency reference in CYT2B7 when no external reference is available or enabled. The IMO operates at a frequency of around 8 MHz.

3.2.3.4 ILO clock source

An ILO is a low-power oscillator, nominally 32.768 kHz, which generates clocks for a watchdog timer when in DeepSleep mode. There are two ILOs to ensure clock supervisor (CSV) capability in DeepSleep mode. ILO-driven counters can be calibrated to the IMO, WCO, or ECO to improve their accuracy. ILO1 is also used for clock supervision.

3.2.3.5 PLL and FLL

A PLL or FLL may be used to generate high-speed clocks from the IMO, the ECO, or EXT_CLK. The FLL provides a much faster lock than the PLL (5 μ s instead of 35 μ s) in exchange for a small amount (±2%) of frequency error^[6].

3.2.3.6 Clock supervisor (CSV)

Each CSV allows one clock (reference) to supervise the behavior of another clock (monitored). Each CSV has counters for both the monitored and reference clocks. Parameters for each counter determine the frequency of the reference clock as well as the upper and lower frequency limits of the monitored clock. If the frequency range comparator detects a stopped clock or a clock outside the specified frequency range, an abnormal state is signaled and either a reset or an interrupt is generated.

3.2.3.7 **EXT_CLK**

One of the two GPIO_STD I/Os can be used to provide an external clock input of up to 80 MHz. This clock can be used as the source clock for either the PLL or FLL, or can be used directly by the CLK_HF domain.

3.2.3.8 ECO

The ECO provides high-frequency clocking using an external crystal connected to the ECO_IN and ECO_OUT pins. It supports fundamental mode (non-overtone) quartz crystals, in the range of 3.988 to 33.34 MHz. When used in conjunction with the PLL, it generates CPU and peripheral clocks up to device's maximum frequency. ECO accuracy depends on the selected crystal. If the ECO is disabled, the associated pins can be used for any of the available I/O functions.

3.2.3.9 WCO

The WCO is a low-power, watch-crystal oscillator intended for real-time-clock applications. It requires an external 32.768-kHz crystal connected to the WCO_IN and WCO_OUT pins. The WCO can also be configured as a clock reference for CLK_LF, which is the clock source for the MCWDT and RTC.

3.2.4 Reset

CYT2B7 can be reset from a variety of sources, including software. Reset events are asynchronous and guarantee reversion to a known state. The reset cause (POR, BOD, OVD, overcurrent, XRES_L, WDT, MCWDT, software reset, fault, CSV, Hibernate wakeup, debug) is recorded in a register, which is sticky through reset and allows software to determine the cause of the reset. An XRES_L pin is available for external reset.

Note

6. Operation of reference-timed peripherals (like a UART) with an FLL-based reference is not recommended due the allowed frequency

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3.2.5 Watchdog timers

CYT2B7 has one watchdog timer (WDT) and two multi-counter watchdog timers (MCWDT).

The WDT is a free-running counter clocked only by ILO0, which allows it to be used as a wakeup source from Hibernate. Watchdog operation is possible during all power modes. To prevent a device reset from a WDT timeout, the WDT must be serviced during a configured window. A watchdog reset is recorded in the reset cause register.

An MCWDT is available for each of the CPU cores. These timers provide more capabilities than the WDT, and are only available in Active, Sleep, and DeepSleep modes. These timers have multiple counters that can be used separately or cascaded to trigger interrupts and/or resets. They are clocked from ILO0 or the WCO.

3.2.6 Power modes

CYT2B7 has the following six power modes:

- Active all peripherals are available
- Low-Power Active (LPACTIVE) Low-power profile of Active mode where all peripherals and the CPUs are available, but with limited capability
- Sleep all peripherals except the CPUs are available
- Low-Power Sleep (LPSLEEP) Low-power profile of Sleep mode where all peripherals except the CPUs are available, but with limited capability
- DeepSleep only peripherals which work with CLK_LF are available
- Hibernate the device and I/O states are frozen, the device resets on wakeup

3.3 Peripherals

3.3.1 Peripheral clock dividers

Integer and fractional clock dividers are provided for peripheral and timing purposes.

Table 3-1 Clock dividers

Divider	Count	Description
div_8	32	Integer divider, 8 bits
div_16	16	Integer divider, 16 bits
div_24_5	8	Fractional divider, 24.5 bits (24 integer bits, 5 fractional bits)

3.3.2 Peripheral protection unit

The Peripheral Protection Unit (PPU) controls and monitors unauthorized access from all masters (CPU, P-/M-DMA, Crypto, and any enabled debug interface) to the peripherals. It allows or restricts data transfers on the bus infrastructure. The access rules are enforced based on specific properties of a transfer, such as an address range for the transfer and access attributes (such as read/write, user/privilege, and secure/non-secure).

Note

^{7.} VREF_L prevents IR drops in the VSSIO and VSSA paths from impacting the measurements. VREF_L, when properly connected, reduces or removes the impact of IR drops in the VSSIO and VSSA paths from measurements.

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Functional description



3.3.3 12-bit SAR ADC

CYT2B7 contains three 1-Msps SAR ADCs. These ADCs can be clocked at up to 26.67 MHz and provide a 12-bit result in 26 clock cycles.

The references for all three SAR ADCs come from a dedicated pair of inputs: VREFH and VREFL^[7].

CYT2B7 devices support up to 85 logical ADC channels, and external inputs from up to 67 I/Os. Each ADC also supports six internal connections for diagnostic and monitoring purposes. The number of ADC channels (per ADC and package type) are listed in **Table 1-1**.

Each ADC has a sequencer, which autonomously cycles through the configured channels (sequencer scan) with zero-switching overhead (that is, the aggregate sampling bandwidth, when clocked at 26.67 MHz, is equal to 1 Msps whether it is for a single channel or distributed over several channels). The sequencer switching is controlled through a state machine or firmware. The sequencer prioritizes trigger requests, enables the appropriate analog channel, controls ADC sampling, initiates ADC data conversion, manages results, and initiates subsequent conversions for repetitive or group conversions without CPU intervention.

Each SAR ADC has an analog multiplexer used to connect the signals to be measured to the ADC. It has 32 GPIO_STD inputs, one special GPIO_STD input for motor-sense, and six additional inputs to measure internal signals such as a band-gap reference, a temperature sensor, and power supplies. The device supports synchronous sampling of one motor-sense channel on each of the three ADCs.

CYT2B7 has one temperature sensor that is shared by all three ADCs. The temperature sensor must only be sampled by one ADC at a time. Software post processing is required to convert the temperature sensor reading into kelvin or Celsius values.

To accommodate signals with varying source impedances and frequencies, it is possible to have different sample times programmed for each channel. Each ADC also supports range comparison, which allows fast detection of out-of-range values without having to wait for a sequencer scan to complete and for the CPU firmware to evaluate the measurement for out-of-range values.

The ADCs are not usable in DeepSleep and Hibernate modes as they require a high-speed clock. The ADC input reference voltage VREFH range is 2.7 V to V_{DDA} and VREFL is V_{SSA} .

3.3.4 Timer/counter/PWM block (TCPWM)

The TCPWM block consists of 16-bit (75 channels) and 32-bit (four channels) counters with a user-programmable period. Twelve of the 16-bit counters include extra features to support motor control operations. Each TCPWM counter contains a capture register to record the count at the time of an event, a period register (used to either stop or auto-reload the counter when its count is equal to the period register), and compare registers to generate signals that are used as PWM duty-cycle outputs.

Each counter within the TCPWM block supports several functional modes such as timer, capture, quadrature, PWM, PWM with dead-time insertion (PWM_DT, 8-bit), pseudo-random PWM (PWM_PR), and shift-register.

In motor-control applications, the counter within the TCPWM block supports enhanced quadrature mode with features such as asymmetric PWM generation, dead-time insertion (16-bit), and association of different dead times for PWM output signals.

The TCPWM block also provides true and complement outputs, with programmable offset between them, to allow their use as deadband complementary PWM outputs. The TCPWM block also has a kill input (only for the PWM mode) to force outputs to a predetermined state; for example, this may be used in motor-drive systems when an overcurrent state is detected and the PWMs driving the FETs need to be shut off immediately (no time for software intervention).

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Functional description



3.3.5 Serial communication blocks (SCB)

CYT2B7 contains eight serial communication blocks, each configurable to support I²C, UART, or SPI.

I²C interface 3.3.5.10

An SCB can be configured to implement a full I²C master (capable of multi-master arbitration) or slave interface. Each SCB configured for I²C can operate at speeds of up to 1 Mbps (Fast-mode Plus^[8]) and has flexible buffering options to reduce the interrupt overhead and latency of the CPU. In addition, each SCB supports FIFO buffering for receive and transmit data, which, by increasing the time for the CPU to read the data, reduces the need for clock stretching. The I²C interface is compatible with Standard, Fast-mode, and Fast-mode Plus devices as specified in the NXP I²C-bus specification and user manual (UM10204). The I²C-bus I/O is implemented with GPIO in open-drain modes [9, 10]

3.3.5.11 **UART** interface

When configured as a UART, each SCB provides a full-featured UART with maximum signaling rate determined by the configured peripheral-clock frequency and over-sampling rate. It supports infrared interface (IrDA) and SmartCard (ISO 7816) protocols, which are minor variants of the UART protocol. It also supports the 9-bit multiprocessor mode that allows the addressing of peripherals connected over common Rx and Tx lines. Common UART functions such as parity, number of stop bits, break detect, and frame error are supported. FIFO buffering of transmit and receive data allows greater CPU service latencies to be tolerated.

The LIN protocol is supported by the UART. LIN is based on a single-master multi-slave topology. There is one master node and multiple slave nodes on the LIN bus. The SCB UART supports only LIN slave functionality. Compared to the dedicated LIN blocks, an SCB/UART used for LIN requires a higher level of software interaction and increased CPU load.

3.3.5.12 **SPI** interface

The SPI configuration supports full Motorola SPI, TI Synchronous Serial Protocol (SSP, essentially adds a start pulse that is used to synchronize SPI-based codecs), and National Microwire (a half-duplex form of SPI). The SPI interface can use the FIFO. The SPI interface operates with up to a 12.5-MHz SPI Clock. SCB also supports FZSPI^[11] mode.

SCB0 supports the following additional features:

- Operable as a slave in DeepSleep mode
- I²C slave EZ (EZI2C^[12]) mode with up to 256-B data buffer for multi-byte communication without CPU
- I²C slave externally-clocked operations
- Command/response mode with a 512-B data buffer for multi-byte communication without CPU intervention

3.3.6 **CAN FD**

CYT2B7 supports two CAN FD controller blocks, each supporting three CAN FD channels. All CAN FD controllers are compliant with the ISO 11898-1:2015 standard; an ISO 16845:2015 certificate is available. It also implements the time-triggered CAN (TTCAN) protocol specified in ISO 11898-4 (TTCAN protocol levels 1 and 2) completely in

All functions concerning the handling of messages are implemented by the Rx and Tx handlers. The Rx handler manages message acceptance filtering, transfer of received messages from the CAN core to a message RAM, and provides receive-message status. The Tx handler is responsible for the transfer of transmit messages from the message RAM, to the CAN core, and provides transmit-message status.

- 8. I/Os drive level does not support the full bus capacitance in Fast-mode Plus speeds.
 9. This is not 100% compliant with the I²C-bus specification; I/Os are not over-voltage tolerant, do not support the 20-mA sink requirement of Fast-mode Plus, and violate the leakage specification when no power is applied.
- 10.Only Port 0 with the slew rate control enabled meets the minimum fall time requirement.

 11.The Easy SPI (EZSPI) protocol is based on the Motorola SPI operating in any mode (0, 1, 2, or 3). It allows communication between master and slave reduces the need for CPU intervention.
- 12. The Easy I²C (EZI2C) protocol is a unique communication scheme built on top of the I²C protocol by Infineon. It uses a meta protocol around the standard I²C protocol to communicate to an I²C slave using indexed memory transfers. This reduces the need for CPU intervention.

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Functional description



3.3.7 Local interconnect network (LIN)

CYT2B7 contains up to eight LIN channels. Each channel supports transmission/reception of data following the LIN protocol according to ISO standard 17987. Each LIN channel connects to an external transceiver through a 3-pin interface (including an enable function) and supports master and slave functionality. Each channel also supports classic and enhanced checksum, along with break detection during message reception and wake-up signaling. Break detection, sync field, checksum calculations, and error interrupts are handled in hardware.

3.3.8 One-time-programmable (OTP) eFuse

CYT2B7 contains a 1024-bit OTP eFuse memory that can be used to store and access a unique and unalterable identifier or serial number for each device. eFuses are also used to control the device life-cycle (manufacturing, programming, normal operation, end-of-life, and so on) and the security state. Of the 1024 bits, 192 are available for user purposes.

3.3.9 Event generator

The event generator supports generation of interrupts and triggers in Active mode and interrupts in DeepSleep mode. The event generators are used to trigger a specific device operation (execution of an interrupt handler, a SAR ADC conversion, and so on) and to provide a cyclic wakeup mechanism from DeepSleep mode. They provide CPU-free triggers for device functions, and reduce CPU involvement in triggering device functions, thus reducing overall power consumption and processing overhead.

3.3.10 Trigger multiplexer

CYT2B7 supports connecting various peripherals using trigger signals. Triggers are used to inform a peripheral of the occurrence of an event or change of state. These triggers are used to affect or initiate some action in other peripherals. The trigger multiplexer is used to route triggers from a source peripheral to a destination. Triggers provide active logic functionality and are typically supported in Active mode.

3.4 I/Os

CYT2B7 has up to 152 programmable I/Os.

The I/Os are organized as logical entities called ports, which are a maximum of 8 bits wide. During power-on, and reset, the I/Os are forced to the High-Z state. During the Hibernate mode, I/Os are frozen.

Every I/O can generate an interrupt (if enabled) and each port has an interrupt request (IRQ) and interrupt service routine (ISR) associated with it.

I/O port power source mapping is listed in **Table 3-1**. The associated supply determines the V_{OH} , V_{OL} , V_{IH} , and V_{IL} levels when configured for CMOS and Automotive thresholds.

Table 3-1 I/O port power source

Supply	Ports
VDDD	P0, P1, P2, P3, P4, P5, P16, P17, P18, P19, P20, P21, P22, P23
VDDIO_1	P6, P7, P8, P9 ^[13]
VDDIO_2	P10, P11, P12, P13, P14, P15

Note

13. The I/Os in VDDIO_1 domain are referred to the VDDD domain in 64-LQFP package.

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Functional description



3.4.1 Port nomenclature

Px.y describes a particular bit "y" available within an I/O port "x."

For example, P4.2 reads "port 4, bit 2".

Each I/O implements the following:

- Programmable drive mode
 - High impedance
 - Resistive pull-up
 - Resistive pull-down
 - Open drain with strong pull-down
 - Open drain with strong pull-up
 - Strong pull-up or pull-down
 - Weak pull-up or pull-down

CYT2B7 has two types of programmable I/Os: GPIO standard and GPIO Enhanced.

GPIO Standard (GPIO_STD)

Supports standard automotive signaling across the 2.7-V to 5.5-V V_{DDIO} range. GPIO Standard I/Os have multiple configurable drive levels, drive modes, and selectable input levels.

GPIO Enhanced (GPIO_ENH)

Supports extended functionality automotive signaling across the 2.7-V to 5.5-V V_{DDIO} range with higher currents at lower voltages (full I²C timing support, slew-rate control).

Both GPIO_STD and GPIO_ENH implement the following:

- Configurable input threshold (CMOS, TTL, or Automotive)
- Hold mode for latching previous state (used for retaining the I/O state in DeepSleep mode)
- Analog input mode (input and output buffers disabled)

3.4.2 Smart I/O

Smart I/O allows Boolean operations on signals going to the I/O from the subsystems of the chip or on signals coming into the chip. CYT2B7 has five Smart I/O blocks. Operation can be synchronous or asynchronous and the blocks operate in all device power modes except for the Hibernate mode.

TRAVEO™ T2G 32-bit Automotive MCU Based on Arm® Cortex®-M4F single

CYT2B7 address map



4 CYT2B7 address map

The CYT2B7 microcontroller supports the memory spaces shown in Figure 4-1.

- 1088KB (960KB + 128KB) of code-flash, used in the single- or dual-bank mode based on the associated bit in the flash control register
 - Single-bank mode 1088KB
 - Dual-bank mode 544KB per bank
- 96KB (72KB + 24KB) of work-flash, used in the single- or dual-bank mode based on the associated bit in the flash control register
 - Single-bank mode 96KB
 - Dual-bank mode 48KB per bank
- 32KB of secure ROM
- 128KB of SRAM (First 2 KB is reserved for internal usage)

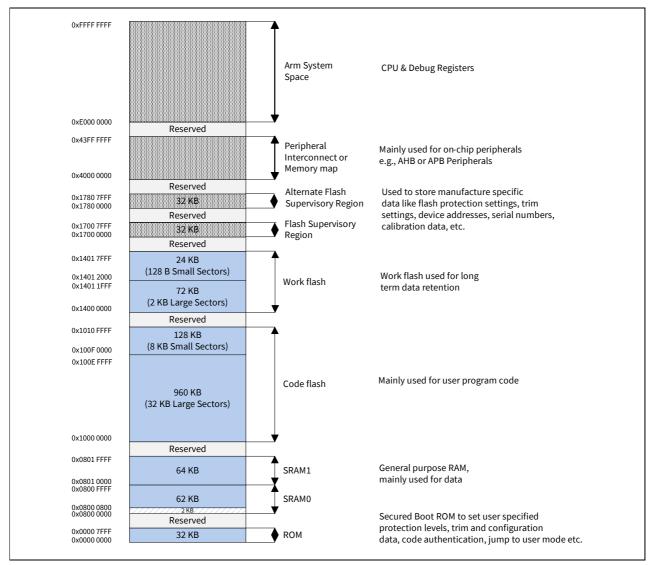


Figure 4-1 CYT2B7 address map^[14, 15]

Notes

14.The size representation is not up to scale.

15. First 2 KB of SRAM is reserved, not available for users. User must keep the power of first 32KB block of SRAM0 in enabled or retained in all Active, LP Active, Sleep, LP Sleep, DeepSleep modes.

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Flash base address map



5 Flash base address map

Table 5-1 through **Table 5-6** give information about the sector mapping of the code- and work-flash regions along with their respective base addresses.

Table 5-1 Code-flash Address Mapping in Single Bank Mode

Code-flash Size (KB)	Large Sectors (LS)	Small Sectors (SS)	Large Sector Base Address	Small Sector Base Address
1088	32KB × 30	8KB × 16	0x1000 0000	0x100F 0000

Table 5-2 Work-flash Address Mapping in Single Bank Mode

Work-flash Size (KB)	Large Sectors	Small Sectors	Large Sector Base Address	Small Sector Base Address
96	2KB × 36	128 B × 192	0x1400 0000	0x1401 2000

Table 5-3 Code-flash Address Mapping in Dual Bank Mode (Mapping A)

Code-flash Size (KB)	First Half LS	First Half SS	Second Half LS	Second Half SS	First Half LS Base Address	First Half SS Base Address	Second Half LS Base Address	Second Half SS Base Address
1088	32KB × 15	8KB × 8	32KB × 15	8KB × 8	0x1000 0000	0x1007 8000	0x1200 0000	0x1207 8000

Table 5-4 Code-flash Address Mapping in Dual Bank Mode (Mapping B)

Code-flash Size (KB)	First Half LS	First Half SS	Second Half LS	Second Half SS	First Half LS Base Address	First Half SS Base Address	Second Half LS Base Address	Second Half SS Base Address
1088	32KB × 15	8KB × 8	32KB × 15	8KB × 8	0x1200 0000	0x1207 8000	0x1000 0000	0x1007 8000

Table 5-5 Work-flash Address Mapping in Dual Bank Mode (Mapping A)

Work-flash Size (KB)	First Half LS	First Half SS	Second Half LS	Second Half SS	First Half LS Base Address	First Half SS Base Address	Second Half LS Base Address	Second Half SS Base Address
96	2KB × 18	128 B × 96	2KB × 18	128 B × 96	0x1400 0000	0x1400 9000	0x1500 0000	0x1500 9000

Table 5-6 Work-flash Address Mapping in Dual Bank Mode (Mapping B)

Work-flash Size (KB)	First Half LS	First Half SS	Second Half LS	Second Half SS	First Half LS Base Address	First Half SS Base Address	Second Half LS Base Address	Second Half SS Base Address
96	2KB × 18	128 B × 96	2KB × 18	128 B × 96	0x1500 0000	0x1500 9000	0x1400 0000	0x1400 9000

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Peripheral I/O map



6 Peripheral I/O map

Table 6-1 CYT2B7 peripheral I/O map

Section	Description	Base Address	Instances	Instance Size	Group	Slave	
	Peripheral interconnect	0x4000 0000			0 0 1 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2		
PERI	Peripheral group (0, 1, 2, 3, 5, 6, 9)	0x4000 4000	7	0x20	1 ,	0	
PERI	Peripheral trigger group	0x4000 8000	11	11 0x400		0	
	Peripheral 1:1 trigger group	0x4000 C000	11	0x400	1		
	Peripheral interconnect, master interface	0x4001 0000			_	_	
PERI_MS	PERI Programmable PPU	0x4001 0000	6 ^[16]	0x40	0	1	
	PERI Fixed PPU	0x4001 0800	458	0x40	1		
Crypto	Cryptography component	0x4010 0000			1	0	
CPUSS	CPU subsystem (CPUSS)	0x4020 0000			2	0	
	Fault structure subsystem	0x4021 0000			2	1	
FAULI	Fault structures	0x4021 0000	4	0x100		1	
	Inter process communication	0x4022 0000					
IPC	IPC structures	0x4022 0000	8	0x20	2	2	
	IPC interrupt structures	0x4022 1000	8	0x20	1		
	Protection	0x4023 0000			0		
Crypto CPUSS FAULT IPC PROT FLASHC SRSS	Shared memory protection unit structures	0x4023 2000	16 0x40		2	3	
	Memory protection unit structures	0x4023 4000	16	0x400	2 2 2 2 2 2 2 2		
FLASHC	Flash controller	0x4024 0000			2	4	
Peripheral interconnect, master interface PERI Programmable PPU 0x4001 0000 6 16 0x40	0x4026 0000						
	0x10						
			_				
SRSS	Clock Supervision Low Frequency	0x4026 1720	1		2	5	
		0x4026 1730	1		0		
	Multi Counter WDT	0x4026 8000	2	0x100			
	Free Running WDT	0x4026 C000	1				
DACKLID	SRSS Backup Domain/RTC	0x4027 0000			2	c	
BACKUP	Backup Register	0x4027 1000	4	0x04		6	
	P-DMA0 Controller	0x4028 0000			2	7	
D DMA	P-DMA0 channel structures	0x4028 8000	89	0x40	2	7	
P-DIMA	P-DMA1 Controller	0x4029 0000			2	0	
	P-DMA1 channel structures	0x4029 8000	33	0x40	2	8	
M DMA	M-DMA0 Controller	0x402A 0000			_		
м-имА	M-DMA0 channels	0x402A 1000	4	0x100	2	9	
eFUSE	eFUSE Customer Data (192 bits)	0x402C 0868	6	0x04	2	10	

Note

^{16.} These six Programmable PPUs are configured by the Boot ROM and are available for the user based on the access rights. Refer to the device specific TRM to know more about the configuration of these programmable PPUs.

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Peripheral I/O map



Table 6-1 CYT2B7 peripheral I/O map (continued)

Section	Description	Base Address	Instances	Instance Size	Group	Slave
HSIOM	High-Speed I/O Matrix (HSIOM)	0x4030 0000	24	0x10	3	0
GPIO	GPIO port control/configuration	0x4031 0000	24	0x80	3	1
SMADTIO	Programmable I/O configuration	0x4030 0000 24 0x10 3 0x4031 0000 24 0x80 3 0x4032 0000 5 0x100 3 0x4038 0000 63 0x80 3 0x4038 8000 12 0x80 3 0x4039 0000 4 0x80 3 0x403F 0000 4 0x20 3 1xuc- 0x403F 0800 11 0x20 3 1xuc- 0x4050 0000 8 0x100 3 0x4052 0000 3 0x200 3 0x4053 0000 0x4053 0000 0x6000 3	2	2		
SMAKTIO	SMARTIO port configuration	0x4032 0C00	5	0x100	3	Z
	Timer/Counter/PWM 0 (TCPWM0)	0x4038 0000				
TCPWM	TCPWM0 Group #0 (16-bit)	0x4038 0000	63	0x80		
TCPWM	TCPWM0 Group #1 (16-bit, Motor control)	bit, Motor 0x4038 8000 12 0x		0x80	3	3
	TCPWM0 Group #2 (32-bit)	0x4039 0000	4	0x80		
	Event generator 0 (EVTGEN0)	0x403F 0000			3 3 - 3	
EVTGEN	Event generator 0 comparator structures	0x403F 0800	11	0x20	3	4
LINI	Local Interconnect Network 0 (LIN0)	0x4050 0000			5 (0
LIIN	LIN0 Channels	0x4050 8000	8	0x100	3	U
	CAN0 controller	0x4052 0000	3	0x200	5	1
TTCANED	Message RAM CAN0	0x4053 0000		0x6000		1
TICANED	CAN1 controller	0x4054 0000	3	0x200	5	2
	Message RAM CAN1	0x4055 0000		0x6000		Z
SCB	Serial Communications Block (SPI/UART/I ² C)	0x4060 0000	8	0x10000	6	0-7
	Programmable Analog Subsystem (PASS0)	0x4090 0000			0x20 0x100 0x200 0x6000 0x6000 0x10000 6 0x10000	
SMARTIO S T TCPWM Ti CC TT EVTGEN E E T T T T T T T T T T T	SAR0 channel controller	0x4090 0000			1	
	SAR1 channel controller	0x4090 1000			1	
PASSO SAR	High-Speed I/O Matrix (HSIOM)	9	0			
	SAR0 channel structures	0x4090 0800	24	0x40	1	
	SAR1 channel structures	0x4090 1800	32	0x40	1	
	SAR2 channel structures	0x4090 2800	8	0x40		

CYT2B7 clock diagram



7 CYT2B7 clock diagram

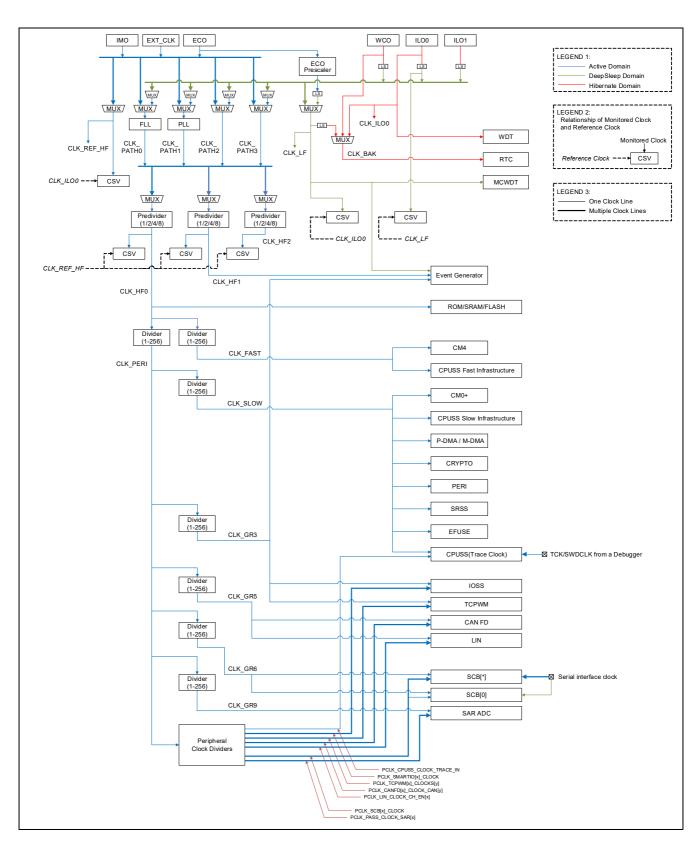


Figure 7-1 CYT2B7 clock diagram

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CYT2B7 CPU start-up sequence



8 CYT2B7 CPU start-up sequence

The start-up sequence is described in the following steps:

1. System Reset (@0x0000 0000)

2.CM0+ executes ROM boot (@0x0000 0004)

- i. Applies trims
- ii. Applies Debug Access port (DAP) access restrictions and system protection from eFuse and supervisory flash
- iii. Authenticates flash boot (only in SECURE life-cycle stage) and transfers control to it

3. CM0+ executes flash boot (from Supervisory flash @0x1700 2000)

- i. Debug pins are configured as per the SWD/JTAG spec^[17]
- ii. Sets CM0+ vector offset register (CM0_VTOR part of the Arm® system space) to the beginning of flash (@0x1000 0000)
- iii.CM0+ branches to its Reset handler

4. CM0+ starts execution

- i. Moves CM0+ vector table to SRAM (updates CM0+ vector table base)
- ii. Sets CM4_VECTOR_TABLE_BASE (@0x0000 0200) to the location of CM4 vector table mentioned in flash (specified in CM4 linker definition file)
- iii.Releases CM4 from reset
- iv.Continues execution of CM0+ user application

5. CM4 executes directly from either code-flash or SRAM

- i. CM4 branches to its Reset handler
- ii. Continues execution of CM4 user application

Note

17. Port configuration of SWD/JTAG pins will be changed from the default GPIO mode to support debugging after the boot process, refer to **Table 11-1** for pin assignments.

Pin assignment



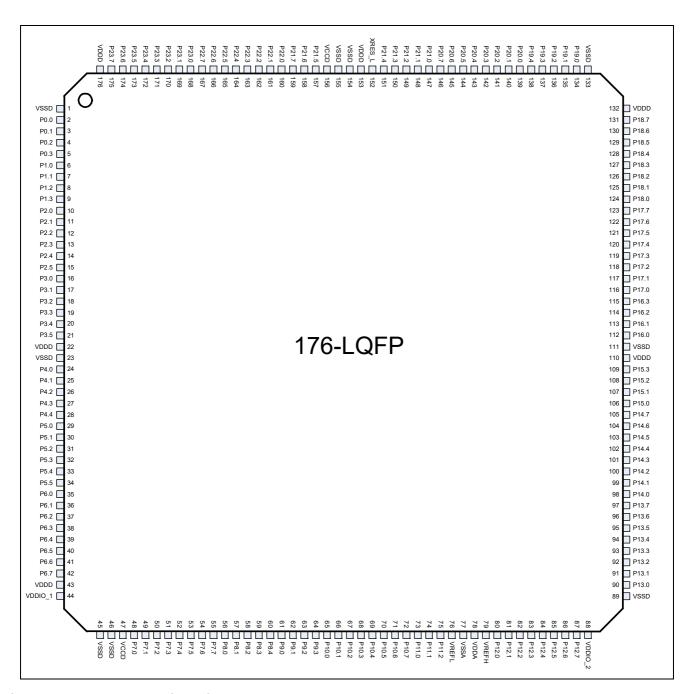


Figure 9-1 176-LQFP pin assignment



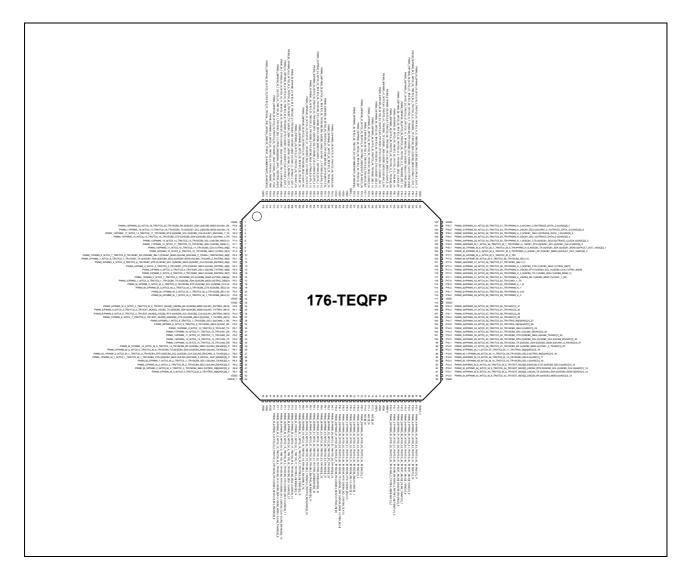


Figure 9-2 176-LQFP pin assignment with alternate functions

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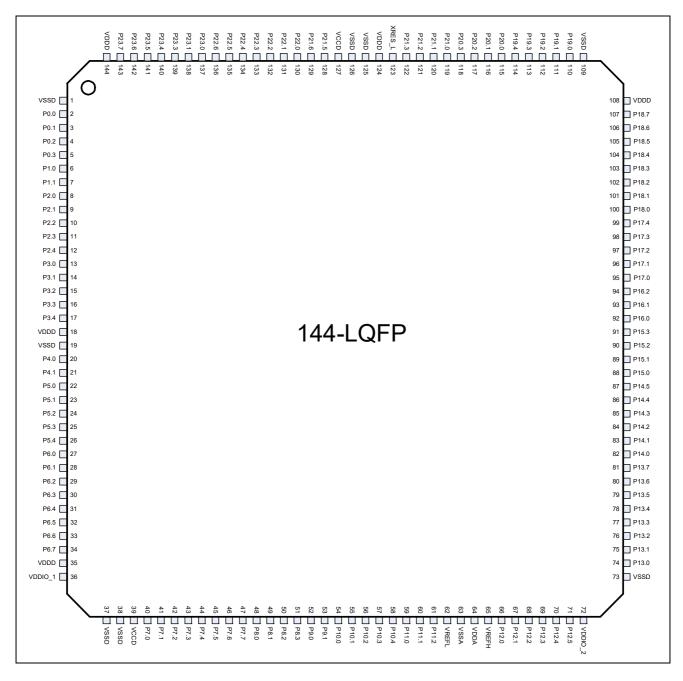


Figure 9-3 144-LQFP pin assignment





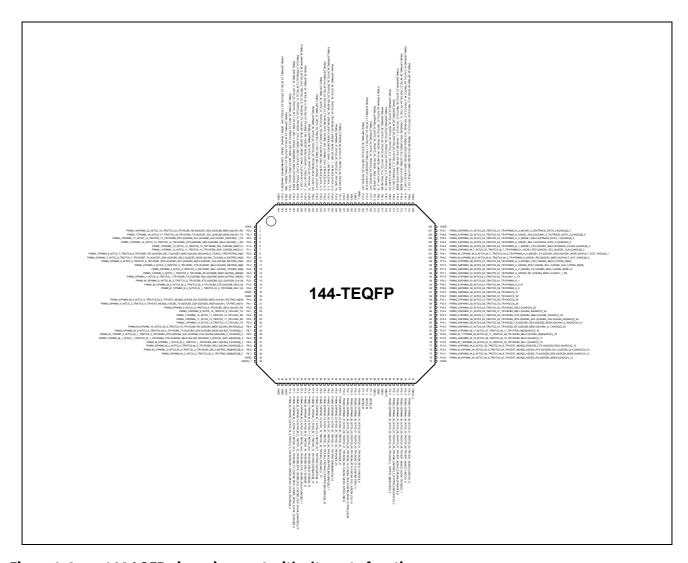


Figure 9-4 144-LQFP pin assignment with alternate functions



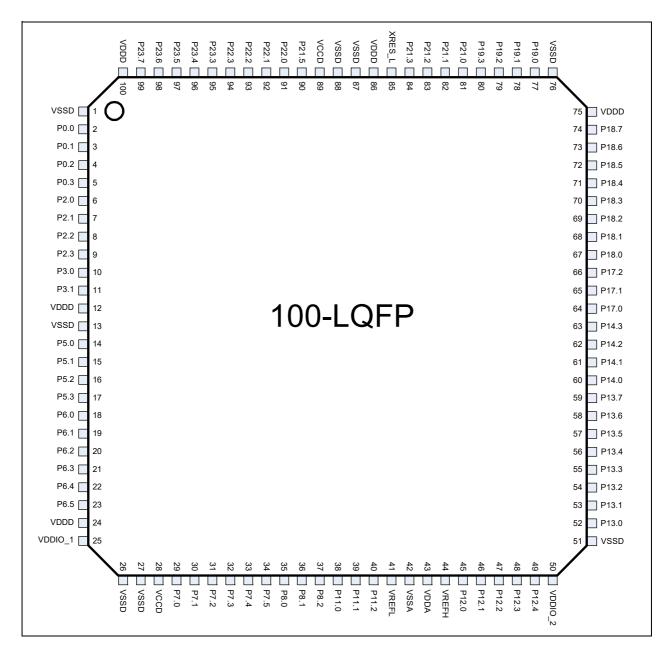
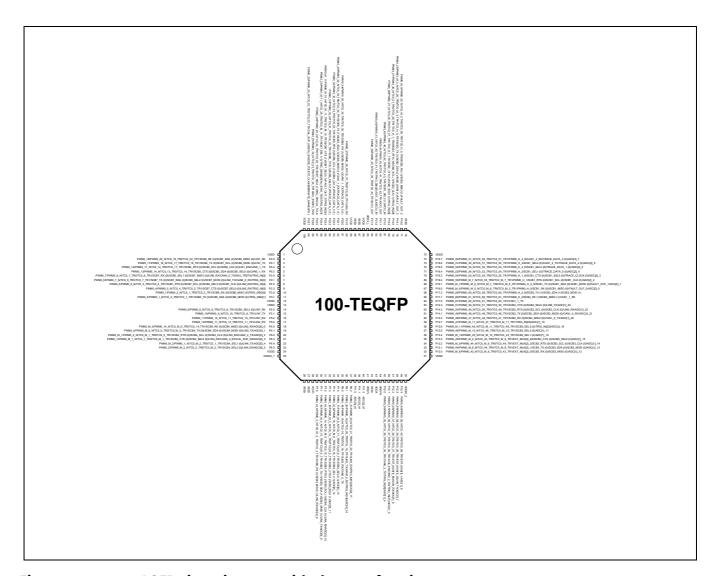


Figure 9-5 100-LQFP pin assignment

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100-LQFP pin assignment with alternate functions Figure 9-6



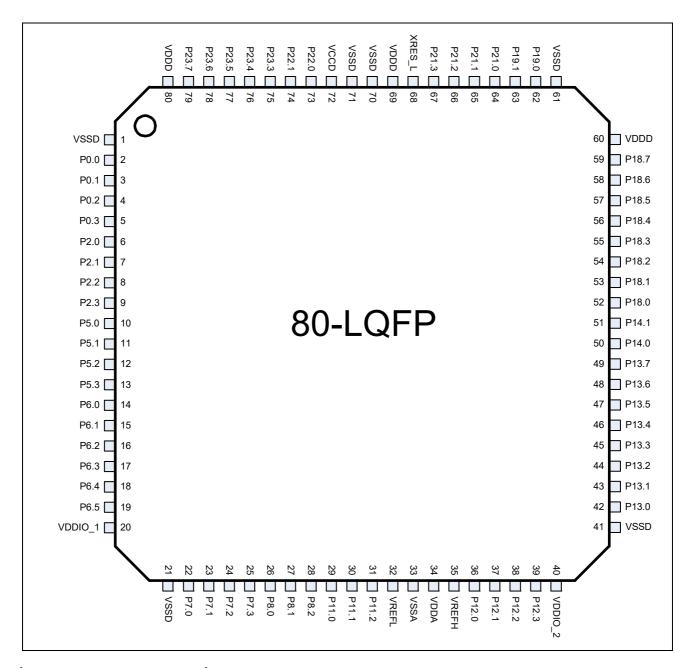


Figure 9-7 80-LQFP pin assignment

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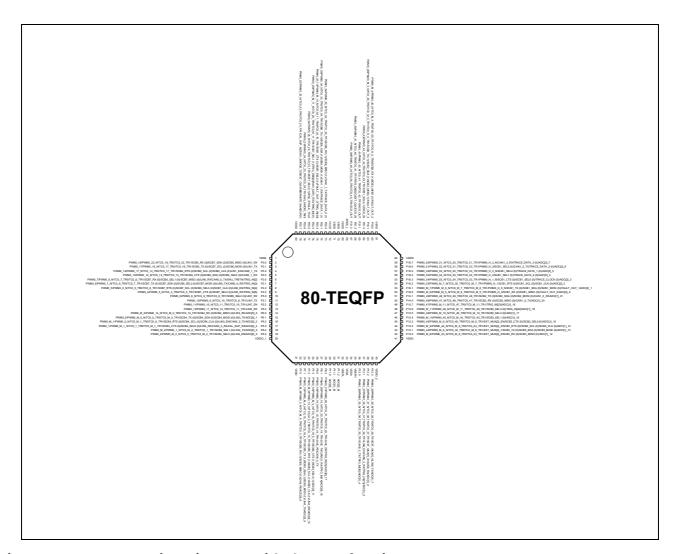


Figure 9-8 80-LQFP pin assignment with alternate functions



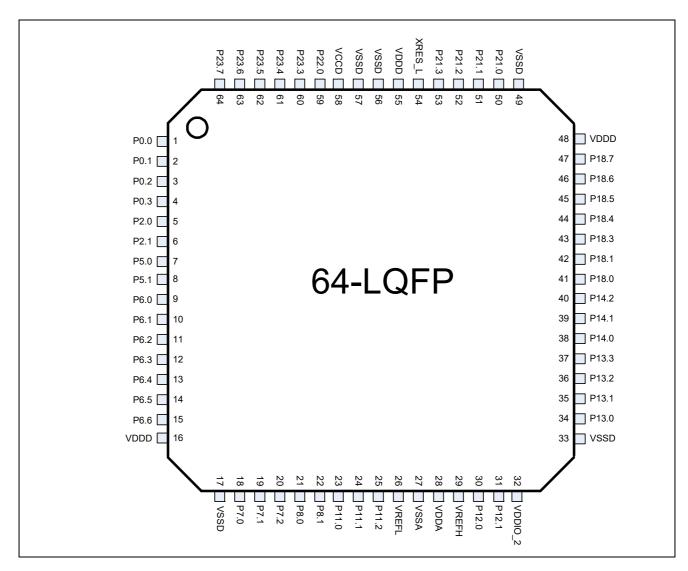
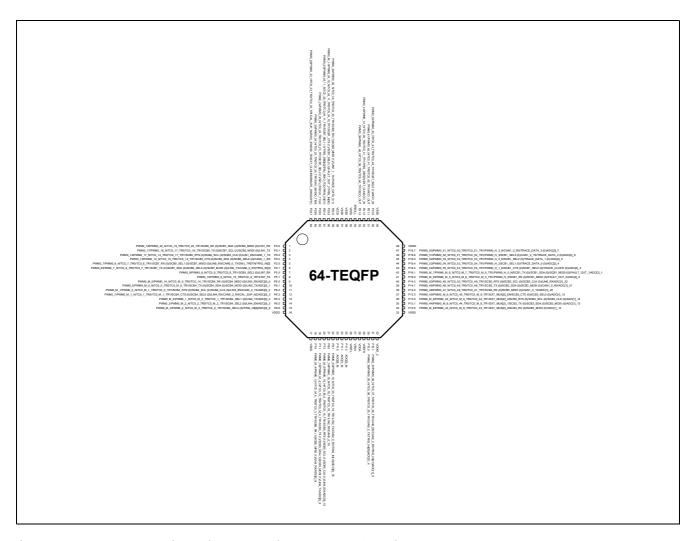


Figure 9-9 64-LQFP pin assignment

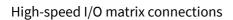
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64-LQFP pin assignment with alternate functions Figure 9-10

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High-speed I/O matrix connections 10

HSIOM connections reference **Table 10-1**

Name	Number	Description
HSIOM_SEL_GPIO	0	GPIO controls 'out'
HSIOM_SEL_GPIO_DSI	1	
HSIOM_SEL_DSI_DSI	2	
HSIOM_SEL_DSI_GPIO	3	
HSIOM_SEL_AMUXA	4	Reserved
HSIOM_SEL_AMUXB	5	
HSIOM_SEL_AMUXA_DSI	6	
HSIOM_SEL_AMUXB_DSI	7	
HSIOM_SEL_ACT_0	8	Active functionality 0
HSIOM_SEL_ACT_1	9	Active functionality 1
HSIOM_SEL_ACT_2	10	Active functionality 2
HSIOM_SEL_ACT_3	11	Active functionality 3
HSIOM_SEL_DS_0	12	DeepSleep functionality 0
HSIOM_SEL_DS_1	13	DeepSleep functionality 1
HSIOM_SEL_DS_2	14	DeepSleep functionality 2
HSIOM_SEL_DS_3	15	DeepSleep functionality 3
HSIOM_SEL_ACT_4	16	Active functionality 4
HSIOM_SEL_ACT_5	17	Active functionality 5
HSIOM_SEL_ACT_6	18	Active functionality 6
HSIOM_SEL_ACT_7	19	Active functionality 7
HSIOM_SEL_ACT_8	20	Active functionality 8
HSIOM_SEL_ACT_9	21	Active functionality 9
HSIOM_SEL_ACT_10	22	Active functionality 10
HSIOM_SEL_ACT_11	23	Active functionality 11
HSIOM_SEL_ACT_12	24	Active functionality 12
HSIOM_SEL_ACT_13	25	Active functionality 13
HSIOM_SEL_ACT_14	26	Active functionality 14
HSIOM_SEL_ACT_15	27	Active functionality 15
HSIOM_SEL_DS_4	28	DeepSleep functionality 4
HSIOM_SEL_DS_5	29	DeepSleep functionality 5
HSIOM_SEL_DS_6	30	DeepSleep functionality 6
HSIOM_SEL_DS_7	31	DeepSleep functionality 7

Package pin list and alternate functions

11 Package pin list and alternate functions

Most pins have alternate functionality, as specified in **Table 11-1**.

Port 11 has the following additional features,

- Ability to pass full-level analog signals to the SAR without clipping to V_{DDD} in cases where V_{DDD} < V_{DDA}
- Ability to simultaneously capture all three ADC signals with highest priority (ADC[0:2]_M)
- Lower noise, for the most sensitive sensors

Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O^[21, 22]

				Package				DeepSleep Mapping			
Name	HCon#0 ^[18]	176-LQFP	144-LQFP	100-LQFP	80-LQFP	64-LQFP	HCon#14	HCon#29	HCon#30	Analog	SMARTIO
	I/O Type	Pin	Pin	Pin	Pin	Pin	DS #0 ^[19]	DS #1	DS #2		
P0.0	GPIO_ENH	2	2	2	2	1			SCB0_MISO (0)		
P0.1	GPIO_ENH	3	3	3	3	2			SCB0_MOSI (0)		
P0.2	GPIO_ENH	4	4	4	4	3	SCB0_SCL (0)		SCB0_CLK (0)		
P0.3	GPIO_ENH	5	5	5	5	4	SCB0_SDA (0)		SCB0_SEL0 (0)		
P1.0	GPIO_STD	6	6	NA	NA	NA	SCB0_SCL (1)		SCB0_MISO (1)		
P1.1	GPIO_STD	7	7	NA	NA	NA	SCB0_SDA (1)		SCB0_MOSI (1)		
P1.2	GPIO_STD	8	NA	NA	NA	NA			SCB0_CLK (1)		
P1.3	GPIO_STD	9	NA	NA	NA	NA			SCB0_SEL0 (1)		
P2.0	GPIO_STD	10	8	6	6	5		SWJ_TRSTN	SCB0_SEL1 (0)		
P2.1	GPIO_STD	11	9	7	7	6			SCB0_SEL2 (0)		
P2.2	GPIO_STD	12	10	8	8	NA			SCB0_SEL3 (0)		
P2.3	GPIO_STD	13	11	9	9	NA					
P2.4	GPIO_STD	14	12	NA	NA	NA					
P2.5	GPIO_STD	15	NA	NA	NA	NA					
P3.0	GPIO_STD	16	13	10	NA	NA					
P3.1	GPIO_STD	17	14	11	NA	NA					
P3.2	GPIO_STD	18	15	NA	NA	NA					

Notes

- 18.HCon refers to High Speed I/O matrix connection reference as per **Table 10-1**.
- 19.DeepSleep ordering (DS #0, DS #1, DS #2) does not have any impact on choosing any alternate functions; the HSIOM module handles the individual alternate function assignment.
- 20.All port pin functions available in DeepSleep mode are also available in Active mode.
- 21. Refer to **Table 13-2** for more information on pin multiplexer abbreviations used.
- 22. For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group "n".



Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O^[21, 22] (continued)

				Package				DeepSleep Mapping ^{[2}	0]		
Name	HCon#0 ^[18]	176-LQFP	144-LQFP	100-LQFP	80-LQFP	64-LQFP	HCon#14	HCon#29	HCon#30	Analog	SMARTIO
	I/O Type	Pin	Pin	Pin	Pin	Pin	DS #0 ^[19]	DS #1	DS #2		
P3.3	GPIO_STD	19	16	NA	NA	NA					
P3.4	GPIO_STD	20	17	NA	NA	NA					
P3.5	GPIO_STD	21	NA	NA	NA	NA					
P4.0	GPIO_STD	24	20	NA	NA	NA					
P4.1	GPIO_STD	25	21	NA	NA	NA					
P4.2	GPIO_STD	26	NA	NA	NA	NA					
P4.3	GPIO_STD	27	NA	NA	NA	NA					
P4.4	GPIO_STD	28	NA	NA	NA	NA					
P5.0	GPIO_STD	29	22	14	10	7					
P5.1	GPIO_STD	30	23	15	11	8					
P5.2	GPIO_STD	31	24	16	12	NA					
P5.3	GPIO_STD	32	25	17	13	NA					
P5.4	GPIO_STD	33	26	NA	NA	NA					
P5.5	GPIO_STD	34	NA	NA	NA	NA					
P6.0	GPIO_STD	35	27	18	14	9				ADC[0]_0	
P6.1	GPIO_STD	36	28	19	15	10				ADC[0]_1	
P6.2	GPIO_STD	37	29	20	16	11				ADC[0]_2	
P6.3	GPIO_STD	38	30	21	17	12				ADC[0]_3	
P6.4	GPIO_STD	39	31	22	18	13				ADC[0]_4	
P6.5	GPIO_STD	40	32	23	19	14				ADC[0]_5	
P6.6	GPIO_STD	41	33	NA	NA	15				ADC[0]_6	
P6.7	GPIO_STD	42	34	NA	NA	NA				ADC[0]_7	
P7.0	GPIO_STD	48	40	29	22	18				ADC[0]_8	
P7.1	GPIO_STD	49	41	30	23	19				ADC[0]_9	
P7.2	GPIO_STD	50	42	31	24	20				ADC[0]_10	
P7.3	GPIO_STD	51	43	32	25	NA				ADC[0]_11	
P7.4	GPIO_STD	52	44	33	NA	NA				ADC[0]_12	
P7.5	GPIO_STD	53	45	34	NA	NA				ADC[0]_13	
P7.6	GPIO_STD	54	46	NA	NA	NA				ADC[0]_14	
P7.7	GPIO_STD	55	47	NA	NA	NA				ADC[0]_15	
P8.0	GPIO_STD	56	48	35	26	21					



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Package pin list and alternate functions

Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O^[21, 22] (continued)

				Package				DeepSleep Mapping ^[20]			
Name	HCon#0 ^[18]	176-LQFP	144-LQFP	100-LQFP	80-LQFP	64-LQFP	HCon#14	HCon#29	HCon#30	Analog	SMARTIO
	I/O Type	Pin	Pin	Pin	Pin	Pin	DS #0 ^[19]	DS #1	DS #2		
P8.1	GPIO_STD	57	49	36	27	22				ADC[0]_16	
P8.2	GPIO_STD	58	50	37	28	NA				ADC[0]_17	
P8.3	GPIO_STD	59	51	NA	NA	NA				ADC[0]_18	
P8.4	GPIO_STD	60	NA	NA	NA	NA				ADC[0]_19	
P9.0	GPIO_STD	61	52	NA	NA	NA				ADC[0]_20	
P9.1	GPIO_STD	62	53	NA	NA	NA				ADC[0]_21	
P9.2	GPIO_STD	63	NA	NA	NA	NA				ADC[0]_22	
P9.3	GPIO_STD	64	NA	NA	NA	NA				ADC[0]_23	
P10.0	GPIO_STD	65	54	NA	NA	NA					
P10.1	GPIO_STD	66	55	NA	NA	NA					
P10.2	GPIO_STD	67	56	NA	NA	NA					
P10.3	GPIO_STD	68	57	NA	NA	NA					
P10.4	GPIO_STD	69	58	NA	NA	NA				ADC[1]_0	
P10.5	GPIO_STD	70	NA	NA	NA	NA				ADC[1]_1	
P10.6	GPIO_STD	71	NA	NA	NA	NA				ADC[1]_2	
P10.7	GPIO_STD	72	NA	NA	NA	NA				ADC[1]_3	
P11.0	GPIO_STD	73	59	38	29	23				ADC[0]_M	
P11.1	GPIO_STD	74	60	39	30	24				ADC[1]_M	
P11.2	GPIO_STD	75	61	40	31	25				ADC[2]_M	
P12.0	GPIO_STD	80	66	45	36	30				ADC[1]_4	SMARTIO12_0
P12.1	GPIO_STD	81	67	46	37	31				ADC[1]_5	SMARTIO12_1
P12.2	GPIO_STD	82	68	47	38	NA				ADC[1]_6	SMARTIO12_2
P12.3	GPIO_STD	83	69	48	39	NA				ADC[1]_7	SMARTIO12_3
P12.4	GPIO_STD	84	70	49	NA	NA				ADC[1]_8	SMARTIO12_4
P12.5	GPIO_STD	85	71	NA	NA	NA				ADC[1]_9	SMARTIO12_5
P12.6	GPIO_STD	86	NA	NA	NA	NA				ADC[1]_10	SMARTIO12_6
P12.7	GPIO_STD	87	NA	NA	NA	NA				ADC[1]_11	SMARTIO12_7
P13.0	GPIO_STD	90	74	52	42	34				ADC[1]_12	SMARTIO13_0
P13.1	GPIO_STD	91	75	53	43	35				ADC[1]_13	SMARTIO13_1
P13.2	GPIO_STD	92	76	54	44	36				ADC[1]_14	SMARTIO13_2
P13.3	GPIO_STD	93	77	55	45	37				ADC[1]_15	SMARTIO13_3



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Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O^[21, 22] (continued)

				Package				DeepSleep Mapping ^[20]]		
Name	HCon#0 ^[18]	176-LQFP	144-LQFP	100-LQFP	80-LQFP	64-LQFP	HCon#14	HCon#29	HCon#30	Analog	SMARTIO
	I/O Type	Pin	Pin	Pin	Pin	Pin	DS #0 ^[19]	DS #1	DS #2		
P13.4	GPIO_STD	94	78	56	46	NA				ADC[1]_16	SMARTIO13_4
P13.5	GPIO_STD	95	79	57	47	NA				ADC[1]_17	SMARTIO13_5
P13.6	GPIO_STD	96	80	58	48	NA				ADC[1]_18	SMARTIO13_6
P13.7	GPIO_STD	97	81	59	49	NA				ADC[1]_19	SMARTIO13_7
P14.0	GPIO_STD	98	82	60	50	38				ADC[1]_20	SMARTIO14_0
P14.1	GPIO_STD	99	83	61	51	39				ADC[1]_21	SMARTIO14_1
P14.2	GPIO_STD	100	84	62	NA	40				ADC[1]_22	SMARTIO14_2
P14.3	GPIO_STD	101	85	63	NA	NA				ADC[1]_23	SMARTIO14_3
P14.4	GPIO_STD	102	86	NA	NA	NA				ADC[1]_24	SMARTIO14_4
P14.5	GPIO_STD	103	87	NA	NA	NA				ADC[1]_25	SMARTIO14_5
P14.6	GPIO_STD	104	NA	NA	NA	NA				ADC[1]_26	SMARTIO14_6
P14.7	GPIO_STD	105	NA	NA	NA	NA				ADC[1]_27	SMARTIO14_7
P15.0	GPIO_STD	106	88	NA	NA	NA				ADC[1]_28	SMARTIO15_0
P15.1	GPIO_STD	107	89	NA	NA	NA				ADC[1]_29	SMARTIO15_1
P15.2	GPIO_STD	108	90	NA	NA	NA				ADC[1]_30	SMARTIO15_2
P15.3	GPIO_STD	109	91	NA	NA	NA				ADC[1]_31	SMARTIO15_3
P16.0	GPIO_STD	112	92	NA	NA	NA					
P16.1	GPIO_STD	113	93	NA	NA	NA					
P16.2	GPIO_STD	114	94	NA	NA	NA					
P16.3	GPIO_STD	115	NA	NA	NA	NA					
P17.0	GPIO_STD	116	95	64	NA	NA					SMARTIO17_0
P17.1	GPIO_STD	117	96	65	NA	NA					SMARTIO17_1
P17.2	GPIO_STD	118	97	66	NA	NA					SMARTIO17_2
P17.3	GPIO_STD	119	98	NA	NA	NA					SMARTIO17_3
P17.4	GPIO_STD	120	99	NA	NA	NA					SMARTIO17_4
P17.5	GPIO_STD	121	NA	NA	NA	NA					SMARTIO17_5
P17.6	GPIO_STD	122	NA	NA	NA	NA					SMARTIO17_6
P17.7	GPIO_STD	123	NA	NA	NA	NA					SMARTIO17_7
P18.0	GPIO_STD	124	100	67	52	41				ADC[2]_0	
P18.1	GPIO_STD	125	101	68	53	42				ADC[2]_1	
P18.2	GPIO_STD	126	102	69	54	NA				ADC[2]_2	



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Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O^[21, 22] (continued)

		Package DeepSleep Mapping ^[20]				20]					
Name	HCon#0 ^[18]	176-LQFP	144-LQFP	100-LQFP	80-LQFP	64-LQFP	HCon#14	HCon#29	HCon#30	Analog	SMARTIO
	I/O Type	Pin	Pin	Pin	Pin	Pin	DS #0 ^[19]	DS #1	DS #2		
P18.3	GPIO_STD	127	103	70	55	43				ADC[2]_3	
P18.4	GPIO_STD	128	104	71	56	44				ADC[2]_4	
P18.5	GPIO_STD	129	105	72	57	45				ADC[2]_5	
P18.6	GPIO_STD	130	106	73	58	46				ADC[2]_6	
P18.7	GPIO_STD	131	107	74	59	47				ADC[2]_7	
P19.0	GPIO_STD	134	110	77	62	NA					
P19.1	GPIO_STD	135	111	78	63	NA					
P19.2	GPIO_STD	136	112	79	NA	NA					
P19.3	GPIO_STD	137	113	80	NA	NA					
P19.4	GPIO_STD	138	114	NA	NA	NA					
P20.0	GPIO_STD	139	115	NA	NA	NA					
P20.1	GPIO_STD	140	116	NA	NA	NA					
P20.2	GPIO_STD	141	117	NA	NA	NA					
P20.3	GPIO_STD	142	118	NA	NA	NA					
P20.4	GPIO_STD	143	NA	NA	NA	NA					
P20.5	GPIO_STD	144	NA	NA	NA	NA					
P20.6	GPIO_STD	145	NA	NA	NA	NA					
P20.7	GPIO_STD	146	NA	NA	NA	NA					
P21.0	GPIO_STD	147	119	81	64	50				WCO_IN ^[23]	
P21.1	GPIO_STD	148	120	82	65	51				WCO_OUT ^[23]	
P21.2	GPIO_STD	149	121	83	66	52				ECO_IN ^[23]	
P21.3	GPIO_STD	150	122	84	67	53				ECO_OUT ^[23]	
P21.4 ^[24]	GPIO_STD	151	NA	NA	NA	NA				HIBERNATE_WAKEUP[0]	
P21.5	GPIO_STD	157	128	90	NA	NA					
P21.6	GPIO_STD	158	129	NA	NA	NA					
P21.7	GPIO_STD	159	NA	NA	NA	NA		RTC_CAL			
P22.0	GPIO_STD	160	130	91	73	59					
P22.1	GPIO_STD	161	131	92	74	NA					
P22.2	GPIO_STD	162	132	93	NA	NA					
P22.3	GPIO_STD	163	133	94	NA	NA					
P22.4	GPIO_STD	164	134	NA	NA	NA					



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Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O^[21, 22] (continued)

				Package				DeepSleep Mapping ^{[20}]		
Name	HCon#0 ^[18]	176-LQFP	144-LQFP	100-LQFP	80-LQFP	64-LQFP	HCon#14	HCon#29	HCon#30	Analog	SMARTIO
	I/O Type	Pin	Pin	Pin	Pin	Pin	DS #0 ^[19]	DS #1	DS #2		
P22.5	GPIO_STD	165	135	NA	NA	NA					
P22.6	GPIO_STD	166	136	NA	NA	NA					
P22.7	GPIO_STD	167	NA	NA	NA	NA					
P23.0	GPIO_STD	168	137	NA	NA	NA					
P23.1	GPIO_STD	169	138	NA	NA	NA					
P23.2	GPIO_STD	170	NA	NA	NA	NA					
P23.3	GPIO_STD	171	139	95	75	60					
P23.4	GPIO_STD	172	140	96	76	61		SWJ_SWO_TDO			
P23.5	GPIO_STD	173	141	97	77	62		SWJ_SWCLK_TCLK			
P23.6	GPIO_STD	174	142	98	78	63		SWJ_SWDIO_TMS			
P23.7	GPIO_STD	175	143	99	79	64		SWJ_SWDOE_TDI		HIBERNATE_WAKEUP[1]	
XRES_L		152	123	85	68	54					

Notes

23.I/O pins that support an oscillator function (WCO or ECO) must be configured for high-impedance if the oscillator is enabled. 24.This I/O has increased leakage to ground when the V_{DDD} supply is below the POR threshold.



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Power pin assignments

Power pin assignments 12

Table 12-1 Power pin assignments

Nama			Pac	kage		Remarks
Name	64-LQFP	80-LQFP	100-LQFP	144-LQFP	176-LQFP	Remarks
VDDD	55, 48, 16	80, 69, 60	100, 86, 75, 24, 12	144, 124, 108, 35, 18	176, 153, 132, 110, 43, 22	Main digital supply
VSSD	57, 56, 49, 33, 17	71, 70, 61, 41, 21, 1	88, 87, 76, 51, 27, 26, 13, 1	126, 125, 109, 73, 38, 37, 19, 1	155, 154, 133, 111, 89, 46, 45, 23, 1	Main digital ground
VDDIO_1	NA	20	25	36	44	I/O supply for analog I/Os (except analog I/Os on V _{DDA})
VDDIO_2	32	40	50	72	88	I/O supply for analog I/Os (except analog I/Os on V _{DDA}), P11
VCCD ^[25]	58	72	89, 28	127, 39	156, 47	Main regulated supply. Driven by LDO regulator (either internal LDO or external LDO/PMIC)
VREFH	29	35	44	65	79	High reference voltage for SAR ADCs
VREFL	26	32	41	62	76	Low reference voltage for SAR ADCs
VDDA	28	34	43	64	78	Main analog supply for SAR ADCs
VSSA	27	33	42	63	77	Main analog ground

Note
25.The V_{CCD} pins must be connected together to ensure a low-impedance connection. (see the requirement in **Figure 26-2**)



Alternate function pin assignments

Alternate function pin assignments 13

Alternate pin functions in Active Mode^[28, 29] **Table 13-1**

						Active Map	ping					
Name	HCon#8 ^[26]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#19	HCon#20	HCon#21	HCon#26	HCon#27
	ACT#0 ^[27]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#7	ACT#8	ACT#9	ACT#14	ACT#15
P0.0	PWM0_18	PWM0_22_N	TC0_18_TR0	TC0_22_TR1		SCB0_RX (0)	SCB7_SDA (2)		LIN1_RX			
P0.1	PWM0_17	PWM0_18_N	TC0_17_TR0	TC0_18_TR1		SCB0_TX (0)	SCB7_SCL (2)		LIN1_TX			
P0.2	PWM0_14	PWM0_17_N	TC0_14_TR0	TC0_17_TR1		SCB0_RTS (0)			LIN1_EN	CAN0_1_TX		
P0.3	PWM0_13	PWM0_14_N	TC0_13_TR0	TC0_14_TR1		SCB0_CTS (0)				CAN0_1_RX		
P1.0	PWM0_12	PWM0_13_N	TC0_12_TR0	TC0_13_TR1								
P1.1	PWM0_11	PWM0_12_N	TC0_11_TR0	TC0_12_TR1								
P1.2	PWM0_10	PWM0_11_N	TC0_10_TR0	TC0_11_TR1							TRIG_IN[0]	
P1.3	PWM0_8	PWM0_10_N	TC0_8_TR0	TC0_10_TR1							TRIG_IN[1]	
P2.0	PWM0_7	PWM0_8_N	TC0_7_TR0	TC0_8_TR1		SCB7_RX (0)		SCB7_MISO (0)	LIN0_RX	CAN0_0_TX	TRIG_IN[2]	
2.1	PWM0_6	PWM0_7_N	TC0_6_TR0	TC0_7_TR1		SCB7_TX (0)	SCB7_SDA (0)	SCB7_MOSI (0)	LIN0_TX	CAN0_0_RX	TRIG_IN[3]	
2.2	PWM0_5	PWM0_6_N	TC0_5_TR0	TC0_6_TR1		SCB7_RTS (0)	SCB7_SCL (0)	SCB7_CLK (0)	LIN0_EN		TRIG_IN[4]	
2.3	PWM0_4	PWM0_5_N	TC0_4_TR0	TC0_5_TR1		SCB7_CTS (0)		SCB7_SEL0 (0)	LIN5_RX		TRIG_IN[5]	
P2.4	PWM0_3	PWM0_4_N	TC0_3_TR0	TC0_4_TR1				SCB7_SEL1 (0)	LIN5_TX		TRIG_IN[6]	
2.5	PWM0_2	PWM0_3_N	TC0_2_TR0	TC0_3_TR1				SCB7_SEL2 (0)	LIN5_EN		TRIG_IN[7]	
23.0	PWM0_1	PWM0_2_N	TC0_1_TR0	TC0_2_TR1		SCB6_RX (0)		SCB6_MISO (0)				TRIG_DBG[0]
23.1	PWM0_0	PWM0_1_N	TC0_0_TR0	TC0_1_TR1		SCB6_TX (0)	SCB6_SDA (0)	SCB6_MOSI (0)				TRIG_DBG[1]
23.2	PWM0_M_3	PWM0_0_N	TC0_M_3_TR0	TC0_0_TR1		SCB6_RTS (0)	SCB6_SCL (0)	SCB6_CLK (0)				
23.3	PWM0_M_2	PWM0_M_3_N	TC0_M_2_TR0	TC0_M_3_TR1		SCB6_CTS (0)		SCB6_SEL0 (0)				
P3.4	PWM0_M_1	PWM0_M_2_N	TC0_M_1_TR0	TC0_M_2_TR1				SCB6_SEL1 (0)				
P3.5	PWM0_M_0	PWM0_M_1_N	TC0_M_0_TR0	TC0_M_1_TR1				SCB6_SEL2 (0)				
P4.0	PWM0_4	PWM0_M_0_N	TC0_4_TR0	TC0_M_0_TR1	EXT_MUX[0]_0	SCB5_RX (0)		SCB5_MISO (0)	LIN1_RX		TRIG_IN[10]	
P4.1	PWM0_5	PWM0_4_N	TC0_5_TR0	TC0_4_TR1	EXT_MUX[0]_1	SCB5_TX (0)	SCB5_SDA (0)	SCB5_MOSI (0)	LIN1_TX		TRIG_IN[11]	
P4.2	PWM0_6	PWM0_5_N	TC0_6_TR0	TC0_5_TR1	EXT_MUX[0]_2	SCB5_RTS (0)	SCB5_SCL (0)	SCB5_CLK (0)	LIN1_EN		TRIG_IN[12]	
P4.3	PWM0_7	PWM0_6_N	TC0_7_TR0	TC0_6_TR1	EXT_MUX[0]_EN	SCB5_CTS (0)		SCB5_SEL0 (0)		CAN0_1_TX	TRIG_IN[13]	

Notes

26.High Speed I/O matrix connection (HCon) reference as per **Table 10-1**.
27.Active Mode ordering (ACT#0, ACT#1, and so on) does not have any impact on configuring alternate functions; the HSIOM module handles the alternate function assignments.
28.Refer to **Table 13-2** for more information on pin multiplexer abbreviations used.
29.For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group "n".



Datasheet

Alternate pin functions in Active $\mathsf{Mode}^{[28,\,29]}$ **Table 13-1**

						Active Map	ping					
Name	HCon#8 ^[26]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#19	HCon#20	HCon#21	HCon#26	HCon#27
	ACT#0 ^[27]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#7	ACT#8	ACT#9	ACT#14	ACT#15
4.4	PWM0_8	PWM0_7_N	TC0_8_TR0	TC0_7_TR1				SCB5_SEL1 (0)		CAN0_1_RX		
5.0	PWM0_9	PWM0_8_N	TC0_9_TR0	TC0_8_TR1				SCB5_SEL2 (0)	LIN7_RX			
5.1	PWM0_10	PWM0_9_N	TC0_10_TR0	TC0_9_TR1					LIN7_TX			
5.2	PWM0_11	PWM0_10_N	TC0_11_TR0	TC0_10_TR1					LIN7_EN			
5.3	PWM0_12	PWM0_11_N	TC0_12_TR0	TC0_11_TR1					LIN2_RX			
5.4	PWM0_13	PWM0_12_N	TC0_13_TR0	TC0_12_TR1					LIN2_TX			
5.5	PWM0_14	PWM0_13_N	TC0_14_TR0	TC0_13_TR1					LIN2_EN			
6.0	PWM0_M_0	PWM0_14_N	TC0_M_0_TR0	TC0_14_TR1		SCB4_RX (0)		SCB4_MISO (0)	LIN3_RX			
6.1	PWM0_0	PWM0_M_0_N	TC0_0_TR0	TC0_M_0_TR1		SCB4_TX (0)	SCB4_SDA (0)	SCB4_MOSI (0)	LIN3_TX			
6.2	PWM0_M_1	PWM0_0_N	TC0_M_1_TR0	TC0_0_TR1		SCB4_RTS (0)	SCB4_SCL (0)	SCB4_CLK (0)	LIN3_EN	CAN0_2_TX		
6.3	PWM0_1	PWM0_M_1_N	TC0_1_TR0	TC0_M_1_TR1		SCB4_CTS (0)		SCB4_SEL0 (0)	LIN4_RX	CAN0_2_RX		CAL_SUP_NZ
6.4	PWM0_M_2	PWM0_1_N	TC0_M_2_TR0	TC0_1_TR1				SCB4_SEL1 (0)	LIN4_TX			
6.5	PWM0_2	PWM0_M_2_N	TC0_2_TR0	TC0_M_2_TR1				SCB4_SEL2 (0)	LIN4_EN			
6.6	PWM0_M_3	PWM0_2_N	TC0_M_3_TR0	TC0_2_TR1				SCB4_SEL3 (0)			TRIG_IN[8]	
6.7	PWM0_3	PWM0_M_3_N	TC0_3_TR0	TC0_M_3_TR1							TRIG_IN[9]	
7.0	PWM0_M_4	PWM0_3_N	TC0_M_4_TR0	TC0_3_TR1		SCB5_RX (1)		SCB5_MISO (1)	LIN4_RX			
7.1	PWM0_15	PWM0_M_4_N	TC0_15_TR0	TC0_M_4_TR1		SCB5_TX (1)	SCB5_SDA (1)	SCB5_MOSI (1)	LIN4_TX			
7.2	PWM0_M_5	PWM0_15_N	TC0_M_5_TR0	TC0_15_TR1		SCB5_RTS (1)	SCB5_SCL (1)	SCB5_CLK (1)	LIN4_EN			
7.3	PWM0_16	PWM0_M_5_N	TC0_16_TR0	TC0_M_5_TR1		SCB5_CTS (1)		SCB5_SEL0 (1)				
7.4	PWM0_M_6	PWM0_16_N	TC0_M_6_TR0	TC0_16_TR1				SCB5_SEL1 (1)				
7.5	PWM0_17	PWM0_M_6_N	TC0_17_TR0	TC0_M_6_TR1				SCB5_SEL2 (1)				
7.6	PWM0_M_7	PWM0_17_N	TC0_M_7_TR0	TC0_17_TR1							TRIG_IN[16]	
7.7	PWM0_18	PWM0_M_7_N	TC0_18_TR0	TC0_M_7_TR1							TRIG_IN[17]	
98.0	PWM0_19	PWM0_18_N	TC0_19_TR0	TC0_18_TR1					LIN2_RX	CAN0_0_TX		
8.1	PWM0_20	PWM0_19_N	TC0_20_TR0	TC0_19_TR1					LIN2_TX	CAN0_0_RX	TRIG_IN[14]	
8.2	PWM0_21	PWM0_20_N	TC0_21_TR0	TC0_20_TR1					LIN2_EN		TRIG_IN[15]	
8.3	PWM0_22	PWM0_21_N	TC0_22_TR0	TC0_21_TR1								TRIG_DBG[0]
8.4	PWM0_23	PWM0_22_N	TC0_23_TR0	TC0_22_TR1								TRIG_DBG[1]
9.0	PWM0_24	PWM0_23_N	TC0_24_TR0	TC0_23_TR1								
9.1	PWM0_25	PWM0_24_N	TC0_25_TR0	TC0_24_TR1								
P9.2	PWM0_26	PWM0_25_N	TC0_26_TR0	TC0_25_TR1								



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Alternate function pin assignments

Alternate pin functions in Active $\mathsf{Mode}^{[28,\,29]}$ **Table 13-1**

						Active Map	ping					
Name	HCon#8 ^[26]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#19	HCon#20	HCon#21	HCon#26	HCon#27
	ACT#0 ^[27]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#7	ACT#8	ACT#9	ACT#14	ACT#15
P9.3	PWM0_27	PWM0_26_N	TC0_27_TR0	TC0_26_TR1								
P10.0	PWM0_28	PWM0_27_N	TC0_28_TR0	TC0_27_TR1		SCB4_RX (1)		SCB4_MISO (1)			TRIG_IN[18]	
P10.1	PWM0_29	PWM0_28_N	TC0_29_TR0	TC0_28_TR1		SCB4_TX (1)	SCB4_SDA (1)	SCB4_MOSI (1)			TRIG_IN[19]	
P10.2	PWM0_30	PWM0_29_N	TC0_30_TR0	TC0_29_TR1		SCB4_RTS (1)	SCB4_SCL (1)	SCB4_CLK (1)				
P10.3	PWM0_31	PWM0_30_N	TC0_31_TR0	TC0_30_TR1		SCB4_CTS (1)		SCB4_SEL0 (1)				
P10.4	PWM0_32	PWM0_31_N	TC0_32_TR0	TC0_31_TR1				SCB4_SEL1 (1)				
P10.5	PWM0_33	PWM0_32_N	TC0_33_TR0	TC0_32_TR1				SCB4_SEL2 (1)				
P10.6	PWM0_34	PWM0_33_N	TC0_34_TR0	TC0_33_TR1								
P10.7	PWM0_35	PWM0_34_N	TC0_35_TR0	TC0_34_TR1								
P11.0												
P11.1												
P11.2												
P12.0	PWM0_36	PWM0_35_N	TC0_36_TR0	TC0_35_TR1						CAN0_2_TX	TRIG_IN[20]	
P12.1	PWM0_37	PWM0_36_N	TC0_37_TR0	TC0_36_TR1					LIN6_EN	CAN0_2_RX	TRIG_IN[21]	
P12.2	PWM0_38	PWM0_37_N	TC0_38_TR0	TC0_37_TR1	EXT_MUX[1]_EN				LIN6_RX			
P12.3	PWM0_39	PWM0_38_N	TC0_39_TR0	TC0_38_TR1	EXT_MUX[1]_0				LIN6_TX			
P12.4	PWM0_40	PWM0_39_N	TC0_40_TR0	TC0_39_TR1	EXT_MUX[1]_1							
P12.5	PWM0_41	PWM0_40_N	TC0_41_TR0	TC0_40_TR1	EXT_MUX[1]_2							
P12.6	PWM0_42	PWM0_41_N	TC0_42_TR0	TC0_41_TR1								
P12.7	PWM0_43	PWM0_42_N	TC0_43_TR0	TC0_42_TR1								
P13.0	PWM0_M_8	PWM0_43_N	TC0_M_8_TR0	TC0_43_TR1	EXT_MUX[2]_0	SCB3_RX (0)		SCB3_MISO (0)				
P13.1	PWM0_44	PWM0_M_8_N	TC0_44_TR0	TC0_M_8_TR1	EXT_MUX[2]_1	SCB3_TX (0)	SCB3_SDA (0)	SCB3_MOSI (0)				
P13.2	PWM0_M_9	PWM0_44_N	TC0_M_9_TR0	TC0_44_TR1	EXT_MUX[2]_2	SCB3_RTS (0)	SCB3_SCL (0)	SCB3_CLK (0)				
P13.3	PWM0_45	PWM0_M_9_N	TC0_45_TR0	TC0_M_9_TR1	EXT_MUX[2]_EN	SCB3_CTS (0)		SCB3_SEL0 (0)				
P13.4	PWM0_M_10	PWM0_45_N	TC0_M_10_TR0	TC0_45_TR1				SCB3_SEL1 (0)				
P13.5	PWM0_46	PWM0_M_10_N	TC0_46_TR0	TC0_M_10_TR1				SCB3_SEL2 (0)				
P13.6	PWM0_M_11	PWM0_46_N	TC0_M_11_TR0	TC0_46_TR1				SCB3_SEL3 (0)			TRIG_IN[22]	
P13.7	PWM0_47	PWM0_M_11_N	TC0_47_TR0	TC0_M_11_TR1							TRIG_IN[23]	
P14.0	PWM0_48	PWM0_47_N	TC0_48_TR0	TC0_47_TR1		SCB2_RX (0)		SCB2_MISO (0)		CAN1_0_TX		
P14.1	PWM0_49	PWM0_48_N	TC0_49_TR0	TC0_48_TR1		SCB2_TX (0)	SCB2_SDA (0)	SCB2_MOSI (0)		CAN1_0_RX		
P14.2	PWM0_50	PWM0_49_N	TC0_50_TR0	TC0_49_TR1		SCB2_RTS (0)	SCB2_SCL (0)	SCB2_CLK (0)	LIN6_RX			



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Alternate function pin assignments

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Datasheet

Alternate pin functions in Active $\mathsf{Mode}^{[28,\,29]}$ **Table 13-1**

						Active Map	ping					
Name	HCon#8 ^[26]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#19	HCon#20	HCon#21	HCon#26	HCon#27
	ACT#0 ^[27]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#7	ACT#8	ACT#9	ACT#14	ACT#15
P19.2	PWM0_27	PWM0_26_N	TC0_27_TR0	TC0_26_TR1	TC0_H_1_TR0	SCB2_RTS (1)	SCB2_SCL (1)	SCB2_CLK (1)			TRIG_IN[28]	
P19.3	PWM0_28	PWM0_27_N	TC0_28_TR0	TC0_27_TR1	TC0_H_1_TR1	SCB2_CTS (1)		SCB2_SEL0 (1)			TRIG_IN[29]	
P19.4	PWM0_29	PWM0_28_N	TC0_29_TR0	TC0_28_TR1	TC0_H_2_TR0			SCB2_SEL1 (1)				
P20.0	PWM0_30	PWM0_29_N	TC0_30_TR0	TC0_29_TR1	TC0_H_2_TR1			SCB2_SEL2 (1)	LIN5_RX			
P20.1	PWM0_49	PWM0_30_N	TC0_49_TR0	TC0_30_TR1	TC0_H_3_TR0				LIN5_TX			
P20.2	PWM0_48	PWM0_49_N	TC0_48_TR0	TC0_49_TR1	TC0_H_3_TR1				LIN5_EN			
P20.3	PWM0_47	PWM0_48_N	TC0_47_TR0	TC0_48_TR1		SCB1_RX (1)		SCB1_MISO (1)		CAN1_2_TX		
P20.4	PWM0_46	PWM0_47_N	TC0_46_TR0	TC0_47_TR1		SCB1_TX (1)	SCB1_SDA (1)	SCB1_MOSI (1)		CAN1_2_RX		
P20.5	PWM0_45	PWM0_46_N	TC0_45_TR0	TC0_46_TR1		SCB1_RTS (1)	SCB1_SCL (1)	SCB1_CLK (1)				
P20.6	PWM0_44	PWM0_45_N	TC0_44_TR0	TC0_45_TR1		SCB1_CTS (1)		SCB1_SEL0 (1)				
P20.7	PWM0_43	PWM0_44_N	TC0_43_TR0	TC0_44_TR1				SCB1_SEL1 (1)				
P21.0	PWM0_42	PWM0_43_N	TC0_42_TR0	TC0_43_TR1				SCB1_SEL2 (1)				
P21.1	PWM0_41	PWM0_42_N	TC0_41_TR0	TC0_42_TR1								
P21.2	PWM0_40	PWM0_41_N	TC0_40_TR0	TC0_41_TR1							EXT_CLK	TRIG_DBG[1]
P21.3	PWM0_39	PWM0_40_N	TC0_39_TR0	TC0_40_TR1								
P21.4	PWM0_38	PWM0_39_N	TC0_38_TR0	TC0_39_TR1								
P21.5	PWM0_37	PWM0_38_N	TC0_37_TR0	TC0_38_TR1					LIN0_RX			
P21.6	PWM0_36	PWM0_37_N	TC0_36_TR0	TC0_37_TR1					LIN0_TX			
P21.7	PWM0_35	PWM0_36_N	TC0_35_TR0	TC0_36_TR1					LIN0_EN			CAL_SUP_NZ
P22.0	PWM0_34	PWM0_35_N	TC0_34_TR0	TC0_35_TR1		SCB6_RX (1)		SCB6_MISO (1)		CAN1_1_TX		TRACE_DATA_0 (1)
P22.1	PWM0_33	PWM0_34_N	TC0_33_TR0	TC0_34_TR1		SCB6_TX (1)	SCB6_SDA (1)	SCB6_MOSI (1)		CAN1_1_RX		TRACE_DATA_1 (1)
P22.2	PWM0_32	PWM0_33_N	TC0_32_TR0	TC0_33_TR1		SCB6_RTS (1)	SCB6_SCL (1)	SCB6_CLK (1)				TRACE_DATA_2 (1)
P22.3	PWM0_31	PWM0_32_N	TC0_31_TR0	TC0_32_TR1		SCB6_CTS (1)		SCB6_SEL0 (1)				TRACE_DATA_3 (1)
P22.4	PWM0_30	PWM0_31_N	TC0_30_TR0	TC0_31_TR1				SCB6_SEL1 (1)				TRACE_CLOCK (1)
P22.5	PWM0_29	PWM0_30_N	TC0_29_TR0	TC0_30_TR1				SCB6_SEL2 (1)	LIN7_RX			
P22.6	PWM0_28	PWM0_29_N	TC0_28_TR0	TC0_29_TR1					LIN7_TX			
P22.7	PWM0_27	PWM0_28_N	TC0_27_TR0	TC0_28_TR1					LIN7_EN			
P23.0	PWM0_M_8	PWM0_27_N	TC0_M_8_TR0	TC0_27_TR1		SCB7_RX (1)		SCB7_MISO (1)		CAN1_0_TX		FAULT_OUT_0
P23.1	PWM0_M_9	PWM0_M_8_N	TC0_M_9_TR0	TC0_M_8_TR1		SCB7_TX (1)	SCB7_SDA (1)	SCB7_MOSI (1)		CAN1_0_RX		FAULT_OUT_1
P23.2	PWM0_M_10	PWM0_M_9_N	TC0_M_10_TR0	TC0_M_9_TR1		SCB7_RTS (1)	SCB7_SCL (1)	SCB7_CLK (1)				FAULT_OUT_2
P23.3	PWM0_M_11	PWM0_M_10_N	TC0_M_11_TR0	TC0_M_10_TR1		SCB7_CTS (1)		SCB7_SEL0 (1)			TRIG_IN[30]	FAULT_OUT_3



Alternate pin functions in Active Mode^[28, 29] **Table 13-1**

		Active Mapping										
Name	HCon#8 ^[26]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#19	HCon#20	HCon#21	HCon#26	HCon#27
	ACT#0 ^[27]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#7	ACT#8	ACT#9	ACT#14	ACT#15
P23.4	PWM0_25	PWM0_M_11_N	TC0_25_TR0	TC0_M_11_TR1				SCB7_SEL1 (1)			TRIG_IN[31]	TRIG_DBG[0]
P23.5	PWM0_24	PWM0_25_N	TC0_24_TR0	TC0_25_TR1				SCB7_SEL2 (1)				
P23.6	PWM0_23	PWM0_24_N	TC0_23_TR0	TC0_24_TR1								
P23.7	PWM0_22	PWM0_23_N	TC0_22_TR0	TC0_23_TR1							EXT_CLK	CAL_SUP_NZ

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Pin Mux descriptions Table 13-2

Sl. No.	Pin	Module	Description
1	PWMx_y	TCPWM	TCPWM 16-bit PWM (no motor control), PWM_DT and PWM_PR line out, x-TCPWM block, y-counter number
2	PWMx_y_N	TCPWM	TCPWM 16-bit PWM (no motor control), PWM_DT and PWM_PR complementary line out (N), x-TCPWM block, y-counter number
3	PWMx_M_y	TCPWM	TCPWM 16-bit PWM with motor control line out, x-TCPWM block, y-counter number
4	PWMx_M_y_N	TCPWM	TCPWM 16-bit PWM with motor control complementary line out (N), x-TCPWM block, y-counter number
5	PWMx_H_y	TCPWM	TCPWM 32-bit PWM, PWM_DT and PWM_PR line out, x-TCPWM block, y-counter number
6	PWMx_H_y_N	TCPWM	TCPWM 32-bit PWM, PWM_DT and PWM_PR complementary line out (N), x-TCPWM block, y-counter number
7	TCx_y_TRz	TCPWM	TCPWM 16-bit dedicated counter input triggers, x-TCPWM block, y-counter number, z-trigger number
8	TCx_M_y_TRz	TCPWM	TCPWM 16-bit dedicated counter input triggers with motor control, x-TCPWM block, y-counter number, z-trigger number
9	TCx_H_y_TRz	TCPWM	TCPWM 32-bit dedicated counter input triggers, x-TCPWM block, y-counter number, z-trigger number
10	SCBx_RX	SCB	UART Receive, x-SCB block
11	SCBx_TX	SCB	UART Transmit, x-SCB block
12	SCBx_RTS	SCB	UART Request to Send (Handshake), x-SCB block
13	SCBx_CTS	SCB	UART Clear to Send (Handshake), x-SCB block
14	SCBx_SDA	SCB	I2C Data line, x-SCB block
15	SCBx_SCL	SCB	I2C Clock line, x-SCB block
16	SCBx_MISO	SCB	SPI Master Input Slave Output, x-SCB block
17	SCBx_MOSI	SCB	SPI Master Output Slave Input, x-SCB block
18	SCBx_CLK	SCB	SPI Serial Clock, x-SCB block
19	SCBx_SELy	SCB	SPI Slave Select, x-SCB block, y-select line
20	LINx_RX	LIN	LIN Receive line, x-LIN block
21	LINx_TX	LIN	LIN Transmit line, x-LIN block
22	LINx_EN	LIN	LIN Enable line, x-LIN block
23	CANx_y_TX	CANFD	CAN Transmit line, x-CAN block, y-channel number
24	CANx_y_RX	CANFD	CAN Receive line, x-CAN block, y-channel number
25	CAL_SUP_NZ	CPUSS	ETAS Calibration support line
26	FAULT_OUT_x	SRSS	Fault output line x-0 to 3
27	TRACE_DATA_x	SRSS	Trace dataout line x-0 to 3
28	TRACE_CLOCK	SRSS	Trace clock line
29	RTC_CAL	SRSS RTC	RTC calibration clock input
30	SWJ_TRSTN	SRSS	JTAG Test reset line (Active low)
31	SWJ_SWO_TDO	SRSS	JTAG Test data output/SWO (Serial Wire Output)
32	SWJ_SWCLK_TCLK	SRSS	JTAG Test clock/SWD clock (Serial Wire Clock)

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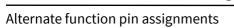




 Table 13-2
 Pin Mux descriptions (continued)

Sl. No.	Pin	Module	Description
33	SWJ_SWDIO_TMS	SRSS	JTAG Test mode select/SWD data (Serial Wire Data Input/Output)
34	SWJ_SWDOE_TDI	SRSS	JTAG Test data input
35	HIBERNATE_WAKEUP[x]	SRSS	Hibernate wakeup line x-0 to 1
36	ADC[x]_y	PASS SAR	SAR, channel, x-SAR number, y-channel number
37	ADC[x]_M	PASS SAR	SAR motor control input, x-SAR number
38	EXT_MUX[x]_y	PASS SAR	External SAR MUX inputs, x-MUX number, y-MUX input 0 to 2
39	EXT_MUX[x]_EN	PASS SAR	External SAR MUX enable line
40	EXT_CLK	SRSS	External clock input or output
41	TRIG_IN[x]	HSIOM	HSIOM_IO_INPUT[x] of trigger inputs, x-0 to 47
42	TRIG_DBG[x]	HSIOM	HSIOM_IO_OUTPUT[x] of trigger outputs, x-0 to 1
43	WCO_IN	SRSS	Watch crystal oscillator input
44	WCO_OUT	SRSS	Watch crystal oscillator output
45	ECO_IN	SRSS	External crystal oscillator input
46	ECO_OUT	SRSS	External crystal oscillator output

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Interrupts and wake-up assignments



Peripheral interrupt assignments and wake-up sources **Table 14-1**

Interrupt	Source	Power Mode	Description
0	cpuss_interrupts_ipc_0_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #0
1	cpuss_interrupts_ipc_1_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #1
2	cpuss_interrupts_ipc_2_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #2
3	cpuss_interrupts_ipc_3_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #3
4	cpuss_interrupts_ipc_4_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #4
5	cpuss_interrupts_ipc_5_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #5
6	cpuss_interrupts_ipc_6_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #6
7	cpuss_interrupts_ipc_7_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #7
8	cpuss_interrupts_fault_0_IRQn	DeepSleep	CPUSS Fault Structure #0 Interrupt
9	cpuss_interrupts_fault_1_IRQn	DeepSleep	CPUSS Fault Structure #1 Interrupt
10	cpuss_interrupts_fault_2_IRQn	DeepSleep	CPUSS Fault Structure #2 Interrupt
11	cpuss_interrupts_fault_3_IRQn	DeepSleep	CPUSS Fault Structure #3 Interrupt
12	srss_interrupt_backup_IRQn	DeepSleep	BACKUP domain Interrupt
13	srss_interrupt_mcwdt_0_IRQn	DeepSleep	Multi Counter Watchdog Timer #0 interrupt
14	srss_interrupt_mcwdt_1_IRQn	DeepSleep	Multi Counter Watchdog Timer #1 interrupt
15	srss_interrupt_wdt_IRQn	DeepSleep	Hardware Watchdog Timer interrupt
16	srss_interrupt_IRQn	DeepSleep	Other combined Interrupts for SRSS (LVD, CLKCAL)
17	scb_0_interrupt_IRQn	DeepSleep	SCB0 interrupt (DeepSleep capable)
18	evtgen_0_interrupt_dpslp_IRQn	DeepSleep	Event gen DeepSleep domain interrupt
19	ioss_interrupt_vdd_IRQn	DeepSleep	I/O Supply (V _{DDIO} , V _{DDA} , V _{DDD}) state change Interrupt
20	ioss_interrupt_gpio_IRQn	DeepSleep	Consolidated Interrupt for GPIO_STD and GPIO_ENH, All Ports
21	ioss_interrupts_gpio_0_IRQn	DeepSleep	GPIO_ENH Port #0 Interrupt
22	ioss_interrupts_gpio_1_IRQn	DeepSleep	GPIO_STD Port #1 Interrupt
23	ioss_interrupts_gpio_2_IRQn	DeepSleep	GPIO_STD Port #2 Interrupt
24	ioss_interrupts_gpio_3_IRQn	DeepSleep	GPIO_STD Port #3 Interrupt
25	ioss_interrupts_gpio_4_IRQn	DeepSleep	GPIO_STD Port #4 Interrupt
26	ioss_interrupts_gpio_5_IRQn	DeepSleep	GPIO_STD Port #5 Interrupt
27	ioss_interrupts_gpio_6_IRQn	DeepSleep	GPIO_STD Port #6 Interrupt
28	ioss_interrupts_gpio_7_IRQn	DeepSleep	GPIO_STD Port #7 Interrupt
29	ioss_interrupts_gpio_8_IRQn	DeepSleep	GPIO_STD Port #8 Interrupt
30	ioss_interrupts_gpio_9_IRQn	DeepSleep	GPIO_STD Port #9 Interrupt
31	ioss_interrupts_gpio_10_IRQn	DeepSleep	GPIO_STD Port #10 Interrupt
32	ioss_interrupts_gpio_11_IRQn	DeepSleep	GPIO_STD Port #11 Interrupt
33	ioss_interrupts_gpio_12_IRQn	DeepSleep	GPIO_STD Port #12 Interrupt
34	ioss_interrupts_gpio_13_IRQn	DeepSleep	GPIO_STD Port #13 Interrupt
35	ioss_interrupts_gpio_14_IRQn	DeepSleep	GPIO_STD Port #14 Interrupt
36	ioss_interrupts_gpio_15_IRQn	DeepSleep	GPIO_STD Port #15 Interrupt
37	ioss_interrupts_gpio_16_IRQn	DeepSleep	GPIO_STD Port #16 Interrupt
38	ioss_interrupts_gpio_17_IRQn	DeepSleep	GPIO_STD Port #17 Interrupt
39	ioss_interrupts_gpio_18_IRQn	DeepSleep	GPIO_STD Port #18 Interrupt

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Peripheral interrupt assignments and wake-up sources (continued) **Table 14-1**

Interrupt	Source	Power Mode	Description
40	ioss_interrupts_gpio_19_IRQn	DeepSleep	GPIO_STD Port #19 Interrupt
41	ioss_interrupts_gpio_20_IRQn	DeepSleep	GPIO_STD Port #20 Interrupt
42	ioss_interrupts_gpio_21_IRQn	DeepSleep	GPIO_STD Port #21 Interrupt
43	ioss_interrupts_gpio_22_IRQn	DeepSleep	GPIO_STD Port #22 Interrupt
44	ioss_interrupts_gpio_23_IRQn	DeepSleep	GPIO_STD Port #23 Interrupt
45	cpuss_interrupt_crypto_IRQn	Active	Crypto Accelerator Interrupt
46	cpuss_interrupt_fm_IRQn	Active	FLASH Macro Interrupt
47	cpuss_interrupts_cm4_fp_IRQn	Active	CM4 Floating Point operation fault
48	cpuss_interrupts_cm0_cti_0_IRQn	Active	CM0+ CTI (Cross Trigger Interface) #0
49	cpuss_interrupts_cm0_cti_1_IRQn	Active	CM0+ CTI #1
50	cpuss_interrupts_cm4_cti_0_IRQn	Active	CM4 CTI #0
51	cpuss_interrupts_cm4_cti_1_IRQn	Active	CM4 CTI #1
52	evtgen_0_interrupt_IRQn	Active	Event gen Active domain interrupt
53	canfd_0_interrupt0_IRQn	Active	CANO, Consolidated Interrupt #0 for all three channels
54	canfd_0_interrupt1_IRQn	Active	CANO, Consolidated Interrupt #1 for all three channels
55	canfd_1_interrupt0_IRQn	Active	CAN1, Consolidated Interrupt #0 for all three channels
56	canfd_1_interrupt1_IRQn	Active	CAN1, Consolidated Interrupt #1 for all three channels
57	canfd_0_interrupts0_0_IRQn	Active	CAN0, Interrupt #0, Channel #0
58	canfd_0_interrupts0_1_IRQn	Active	CAN0, Interrupt #0, Channel #1
59	canfd_0_interrupts0_2_IRQn	Active	CAN0, Interrupt #0, Channel #2
60	canfd_0_interrupts1_0_IRQn	Active	CAN0, Interrupt #1, Channel #0
61	canfd_0_interrupts1_1_IRQn	Active	CAN0, Interrupt #1, Channel #1
62	canfd_0_interrupts1_2_IRQn	Active	CAN0, Interrupt #1, Channel #2
63	canfd_1_interrupts0_0_IRQn	Active	CAN1, Interrupt #0, Channel #0
64	canfd_1_interrupts0_1_IRQn	Active	CAN1, Interrupt #0, Channel #1
65	canfd_1_interrupts0_2_IRQn	Active	CAN1, Interrupt #0, Channel #2
66	canfd_1_interrupts1_0_IRQn	Active	CAN1, Interrupt #1, Channel #0
67	canfd_1_interrupts1_1_IRQn	Active	CAN1, Interrupt #1, Channel #1
68	canfd_1_interrupts1_2_IRQn	Active	CAN1, Interrupt #1, Channel #2
69	lin_0_interrupts_0_IRQn	Active	LINO, Channel #0 Interrupt
70	lin_0_interrupts_1_IRQn	Active	LINO, Channel #1 Interrupt
71	lin_0_interrupts_2_IRQn	Active	LINO, Channel #2 Interrupt
72	lin_0_interrupts_3_IRQn	Active	LINO, Channel #3 Interrupt
73	lin_0_interrupts_4_IRQn	Active	LINO, Channel #4 Interrupt
74	lin_0_interrupts_5_IRQn	Active	LINO, Channel #5 Interrupt
75	lin_0_interrupts_6_IRQn	Active	LINO, Channel #6 Interrupt
76	lin_0_interrupts_7_IRQn	Active	LINO, Channel #7 Interrupt
77	scb_1_interrupt_IRQn	Active	SCB1 Interrupt
78	scb_2_interrupt_IRQn	Active	SCB2 Interrupt

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 Table 14-1
 Peripheral interrupt assignments and wake-up sources (continued)

Interrupt	Source	Power Mode	Description
79	scb_3_interrupt_IRQn	Active	SCB3 Interrupt
80	scb_4_interrupt_IRQn	Active	SCB4 Interrupt
81	scb_5_interrupt_IRQn	Active	SCB5 Interrupt
82	scb_6_interrupt_IRQn	Active	SCB6 Interrupt
83	scb_7_interrupt_IRQn	Active	SCB7 Interrupt
84	pass_0_interrupts_sar_0_IRQn	Active	SAR0, Logical Channel #0 Interrupt
85	pass_0_interrupts_sar_1_IRQn	Active	SAR0, Logical Channel #1 Interrupt
86	pass_0_interrupts_sar_2_IRQn	Active	SAR0, Logical Channel #2 Interrupt
87	pass_0_interrupts_sar_3_IRQn	Active	SAR0, Logical Channel #3 Interrupt
88	pass_0_interrupts_sar_4_IRQn	Active	SAR0, Logical Channel #4 Interrupt
89	pass_0_interrupts_sar_5_IRQn	Active	SAR0, Logical Channel #5 Interrupt
90	pass_0_interrupts_sar_6_IRQn	Active	SAR0, Logical Channel #6 Interrupt
91	pass_0_interrupts_sar_7_IRQn	Active	SAR0, Logical Channel #7 Interrupt
92	pass_0_interrupts_sar_8_IRQn	Active	SAR0, Logical Channel #8 Interrupt
93	pass_0_interrupts_sar_9_IRQn	Active	SAR0, Logical Channel #9 Interrupt
94	pass_0_interrupts_sar_10_IRQn	Active	SAR0, Logical Channel #10 Interrupt
95	pass_0_interrupts_sar_11_IRQn	Active	SAR0, Logical Channel #11 Interrupt
96	pass_0_interrupts_sar_12_IRQn	Active	SAR0, Logical Channel #12 Interrupt
97	pass_0_interrupts_sar_13_IRQn	Active	SAR0, Logical Channel #13 Interrupt
98	pass_0_interrupts_sar_14_IRQn	Active	SAR0, Logical Channel #14 Interrupt
99	pass_0_interrupts_sar_15_IRQn	Active	SAR0, Logical Channel #15 Interrupt
100	pass_0_interrupts_sar_16_IRQn	Active	SAR0, Logical Channel #16 Interrupt
101	pass_0_interrupts_sar_17_IRQn	Active	SAR0, Logical Channel #17 Interrupt
102	pass_0_interrupts_sar_18_IRQn	Active	SAR0, Logical Channel #18 Interrupt
103	pass_0_interrupts_sar_19_IRQn	Active	SAR0, Logical Channel #19 Interrupt
104	pass_0_interrupts_sar_20_IRQn	Active	SAR0, Logical Channel #20 Interrupt
105	pass_0_interrupts_sar_21_IRQn	Active	SAR0, Logical Channel #21 Interrupt
106	pass_0_interrupts_sar_22_IRQn	Active	SAR0, Logical Channel #22 Interrupt
107	pass_0_interrupts_sar_23_IRQn	Active	SAR0, Logical Channel #23 Interrupt
108	pass_0_interrupts_sar_32_IRQn	Active	SAR1, Logical Channel #0 Interrupt
109	pass_0_interrupts_sar_33_IRQn	Active	SAR1, Logical Channel #1 Interrupt
110	pass_0_interrupts_sar_34_IRQn	Active	SAR1, Logical Channel #2 Interrupt
111	pass_0_interrupts_sar_35_IRQn	Active	SAR1, Logical Channel #3 Interrupt
112	pass_0_interrupts_sar_36_IRQn	Active	SAR1, Logical Channel #4 Interrupt
113	pass_0_interrupts_sar_37_IRQn	Active	SAR1, Logical Channel #5 Interrupt
114	pass_0_interrupts_sar_38_IRQn	Active	SAR1, Logical Channel #6 Interrupt
115	pass_0_interrupts_sar_39_IRQn	Active	SAR1, Logical Channel #7 Interrupt
116	pass_0_interrupts_sar_40_IRQn	Active	SAR1, Logical Channel #8 Interrupt
117	pass_0_interrupts_sar_41_IRQn	Active	SAR1, Logical Channel #9 Interrupt
118	pass_0_interrupts_sar_42_IRQn	Active	SAR1, Logical Channel #10 Interrupt
119	pass_0_interrupts_sar_43_IRQn	Active	SAR1, Logical Channel #11 Interrupt
120	pass_0_interrupts_sar_44_IRQn	Active	SAR1, Logical Channel #12 Interrupt

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 Table 14-1
 Peripheral interrupt assignments and wake-up sources (continued)

Interrupt	Source	Power Mode	Description
121	pass_0_interrupts_sar_45_IRQn	Active	SAR1, Logical Channel #13 Interrupt
122	pass_0_interrupts_sar_46_IRQn	Active	SAR1, Logical Channel #14 Interrupt
123	pass_0_interrupts_sar_47_IRQn	Active	SAR1, Logical Channel #15 Interrupt
124	pass_0_interrupts_sar_48_IRQn	Active	SAR1, Logical Channel #16 Interrupt
125	pass_0_interrupts_sar_49_IRQn	Active	SAR1, Logical Channel #17 Interrupt
126	pass_0_interrupts_sar_50_IRQn	Active	SAR1, Logical Channel #18 Interrupt
127	pass_0_interrupts_sar_51_IRQn	Active	SAR1, Logical Channel #19 Interrupt
128	pass_0_interrupts_sar_52_IRQn	Active	SAR1, Logical Channel #20 Interrupt
129	pass_0_interrupts_sar_53_IRQn	Active	SAR1, Logical Channel #21 Interrupt
130	pass_0_interrupts_sar_54_IRQn	Active	SAR1, Logical Channel #22 Interrupt
131	pass_0_interrupts_sar_55_IRQn	Active	SAR1, Logical Channel #23 Interrupt
132	pass_0_interrupts_sar_56_IRQn	Active	SAR1, Logical Channel #24 Interrupt
133	pass_0_interrupts_sar_57_IRQn	Active	SAR1, Logical Channel #25 Interrupt
134	pass_0_interrupts_sar_58_IRQn	Active	SAR1, Logical Channel #26 Interrupt
135	pass_0_interrupts_sar_59_IRQn	Active	SAR1, Logical Channel #27 Interrupt
136	pass_0_interrupts_sar_60_IRQn	Active	SAR1, Logical Channel #28 Interrupt
137	pass_0_interrupts_sar_61_IRQn	Active	SAR1, Logical Channel #29 Interrupt
138	pass_0_interrupts_sar_62_IRQn	Active	SAR1, Logical Channel #30 Interrupt
139	pass_0_interrupts_sar_63_IRQn	Active	SAR1, Logical Channel #31 Interrupt
140	pass_0_interrupts_sar_64_IRQn	Active	SAR2, Logical Channel #0 Interrupt
141	pass_0_interrupts_sar_65_IRQn	Active	SAR2, Logical Channel #1 Interrupt
142	pass_0_interrupts_sar_66_IRQn	Active	SAR2, Logical Channel #2 Interrupt
143	pass_0_interrupts_sar_67_IRQn	Active	SAR2, Logical Channel #3 Interrupt
144	pass_0_interrupts_sar_68_IRQn	Active	SAR2, Logical Channel #4 Interrupt
145	pass_0_interrupts_sar_69_IRQn	Active	SAR2, Logical Channel #5 Interrupt
146	pass_0_interrupts_sar_70_IRQn	Active	SAR2, Logical Channel #6 Interrupt
147	pass_0_interrupts_sar_71_IRQn	Active	SAR2, Logical Channel #7 Interrupt
148	cpuss_interrupts_dmac_0_IRQn	Active	CPUSS M-DMA0, Channel #0 Interrupt
149	cpuss_interrupts_dmac_1_IRQn	Active	CPUSS M-DMA0, Channel #1 Interrupt
150	cpuss_interrupts_dmac_2_IRQn	Active	CPUSS M-DMA0, Channel #2 Interrupt
151	cpuss_interrupts_dmac_3_IRQn	Active	CPUSS M-DMA0, Channel #3 Interrupt
152	cpuss_interrupts_dw0_0_IRQn	Active	CPUSS P-DMA0, Channel #0 Interrupt
153	cpuss_interrupts_dw0_1_IRQn	Active	CPUSS P-DMA0, Channel #1 Interrupt
154	cpuss_interrupts_dw0_2_IRQn	Active	CPUSS P-DMA0, Channel #2 Interrupt
155	cpuss_interrupts_dw0_3_IRQn	Active	CPUSS P-DMA0, Channel #3 Interrupt
156	cpuss_interrupts_dw0_4_IRQn	Active	CPUSS P-DMA0, Channel #4 Interrupt
157	cpuss_interrupts_dw0_5_IRQn	Active	CPUSS P-DMA0, Channel #5 Interrupt
158	cpuss_interrupts_dw0_6_IRQn	Active	CPUSS P-DMA0, Channel #6 Interrupt
159	cpuss_interrupts_dw0_7_IRQn	Active	CPUSS P-DMA0, Channel #7 Interrupt
160	cpuss_interrupts_dw0_8_IRQn	Active	CPUSS P-DMA0, Channel #8 Interrupt
161	cpuss_interrupts_dw0_9_IRQn	Active	CPUSS P-DMA0, Channel #9 Interrupt
162	cpuss_interrupts_dw0_10_IRQn	Active	CPUSS P-DMA0, Channel #10 Interrupt

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Peripheral interrupt assignments and wake-up sources (continued) Table 14-1

Interrupt	Source	Power Mode	Description
163	cpuss_interrupts_dw0_11_IRQn	Active	CPUSS P-DMA0, Channel #11 Interrupt
164	cpuss_interrupts_dw0_12_IRQn	Active	CPUSS P-DMA0, Channel #12 Interrupt
165	cpuss_interrupts_dw0_13_IRQn	Active	CPUSS P-DMA0, Channel #13 Interrupt
166	cpuss_interrupts_dw0_14_IRQn	Active	CPUSS P-DMA0, Channel #14 Interrupt
167	cpuss_interrupts_dw0_15_IRQn	Active	CPUSS P-DMA0, Channel #15 Interrupt
168	cpuss_interrupts_dw0_16_IRQn	Active	CPUSS P-DMA0, Channel #16 Interrupt
169	cpuss_interrupts_dw0_17_IRQn	Active	CPUSS P-DMA0, Channel #17 Interrupt
170	cpuss_interrupts_dw0_18_IRQn	Active	CPUSS P-DMA0, Channel #18 Interrupt
171	cpuss_interrupts_dw0_19_IRQn	Active	CPUSS P-DMA0, Channel #19 Interrupt
172	cpuss_interrupts_dw0_20_IRQn	Active	CPUSS P-DMA0, Channel #20 Interrupt
173	cpuss_interrupts_dw0_21_IRQn	Active	CPUSS P-DMA0, Channel #21 Interrupt
174	cpuss_interrupts_dw0_22_IRQn	Active	CPUSS P-DMA0, Channel #22 Interrupt
175	cpuss_interrupts_dw0_23_IRQn	Active	CPUSS P-DMA0, Channel #23 Interrupt
176	cpuss_interrupts_dw0_24_IRQn	Active	CPUSS P-DMA0, Channel #24 Interrupt
177	cpuss_interrupts_dw0_25_IRQn	Active	CPUSS P-DMA0, Channel #25 Interrupt
178	cpuss_interrupts_dw0_26_IRQn	Active	CPUSS P-DMA0, Channel #26 Interrupt
179	cpuss_interrupts_dw0_27_IRQn	Active	CPUSS P-DMA0, Channel #27 Interrupt
180	cpuss_interrupts_dw0_28_IRQn	Active	CPUSS P-DMA0, Channel #28 Interrupt
181	cpuss_interrupts_dw0_29_IRQn	Active	CPUSS P-DMA0, Channel #29 Interrupt
182	cpuss_interrupts_dw0_30_IRQn	Active	CPUSS P-DMA0, Channel #30 Interrupt
183	cpuss_interrupts_dw0_31_IRQn	Active	CPUSS P-DMA0, Channel #31 Interrupt
184	cpuss_interrupts_dw0_32_IRQn	Active	CPUSS P-DMA0, Channel #32 Interrupt
185	cpuss_interrupts_dw0_33_IRQn	Active	CPUSS P-DMA0, Channel #33 Interrupt
186	cpuss_interrupts_dw0_34_IRQn	Active	CPUSS P-DMA0, Channel #34 Interrupt
187	cpuss_interrupts_dw0_35_IRQn	Active	CPUSS P-DMA0, Channel #35 Interrupt
188	cpuss_interrupts_dw0_36_IRQn	Active	CPUSS P-DMA0, Channel #36 Interrupt
189	cpuss_interrupts_dw0_37_IRQn	Active	CPUSS P-DMA0, Channel #37 Interrupt
190	cpuss_interrupts_dw0_38_IRQn	Active	CPUSS P-DMA0, Channel #38 Interrupt
191	cpuss_interrupts_dw0_39_IRQn	Active	CPUSS P-DMA0, Channel #39 Interrupt
192	cpuss_interrupts_dw0_40_IRQn	Active	CPUSS P-DMA0, Channel #40 Interrupt
193	cpuss_interrupts_dw0_41_IRQn	Active	CPUSS P-DMA0, Channel #41 Interrupt
194	cpuss_interrupts_dw0_42_IRQn	Active	CPUSS P-DMA0, Channel #42 Interrupt
195	cpuss_interrupts_dw0_43_IRQn	Active	CPUSS P-DMA0, Channel #43 Interrupt
196	cpuss_interrupts_dw0_44_IRQn	Active	CPUSS P-DMA0, Channel #44 Interrupt
197	cpuss_interrupts_dw0_45_IRQn	Active	CPUSS P-DMA0, Channel #45 Interrupt
198	cpuss_interrupts_dw0_46_IRQn	Active	CPUSS P-DMA0, Channel #46 Interrupt
199	cpuss_interrupts_dw0_47_IRQn	Active	CPUSS P-DMA0, Channel #47 Interrupt
200	cpuss_interrupts_dw0_48_IRQn	Active	CPUSS P-DMA0, Channel #48 Interrupt
201	cpuss_interrupts_dw0_49_IRQn	Active	CPUSS P-DMA0, Channel #49 Interrupt
202	cpuss_interrupts_dw0_50_IRQn	Active	CPUSS P-DMA0, Channel #50 Interrupt
203	cpuss_interrupts_dw0_51_IRQn	Active	CPUSS P-DMA0, Channel #51 Interrupt
204	cpuss_interrupts_dw0_52_IRQn	Active	CPUSS P-DMA0, Channel #52 Interrupt

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 Table 14-1
 Peripheral interrupt assignments and wake-up sources (continued)

Interrupt	Source	Power Mode	Description
205	cpuss_interrupts_dw0_53_IRQn	Active	CPUSS P-DMA0, Channel #53 Interrupt
206	cpuss_interrupts_dw0_54_IRQn	Active	CPUSS P-DMA0, Channel #54 Interrupt
207	cpuss_interrupts_dw0_55_IRQn	Active	CPUSS P-DMA0, Channel #55 Interrupt
208	cpuss_interrupts_dw0_56_IRQn	Active	CPUSS P-DMA0, Channel #56 Interrupt
209	cpuss_interrupts_dw0_57_IRQn	Active	CPUSS P-DMA0, Channel #57 Interrupt
210	cpuss_interrupts_dw0_58_IRQn	Active	CPUSS P-DMA0, Channel #58 Interrupt
211	cpuss_interrupts_dw0_59_IRQn	Active	CPUSS P-DMA0, Channel #59 Interrupt
212	cpuss_interrupts_dw0_60_IRQn	Active	CPUSS P-DMA0, Channel #60 Interrupt
213	cpuss_interrupts_dw0_61_IRQn	Active	CPUSS P-DMA0, Channel #61 Interrupt
214	cpuss_interrupts_dw0_62_IRQn	Active	CPUSS P-DMA0, Channel #62 Interrupt
215	cpuss_interrupts_dw0_63_IRQn	Active	CPUSS P-DMA0, Channel #63 Interrupt
216	cpuss_interrupts_dw0_64_IRQn	Active	CPUSS P-DMA0, Channel #64 Interrupt
217	cpuss_interrupts_dw0_65_IRQn	Active	CPUSS P-DMA0, Channel #65 Interrupt
218	cpuss_interrupts_dw0_66_IRQn	Active	CPUSS P-DMA0, Channel #66 Interrupt
219	cpuss_interrupts_dw0_67_IRQn	Active	CPUSS P-DMA0, Channel #67 Interrupt
220	cpuss_interrupts_dw0_68_IRQn	Active	CPUSS P-DMA0, Channel #68 Interrupt
221	cpuss_interrupts_dw0_69_IRQn	Active	CPUSS P-DMA0, Channel #69 Interrupt
222	cpuss_interrupts_dw0_70_IRQn	Active	CPUSS P-DMA0, Channel #70 Interrupt
223	cpuss_interrupts_dw0_71_IRQn	Active	CPUSS P-DMA0, Channel #71 Interrupt
224	cpuss_interrupts_dw0_72_IRQn	Active	CPUSS P-DMA0, Channel #72 Interrupt
225	cpuss_interrupts_dw0_73_IRQn	Active	CPUSS P-DMA0, Channel #73 Interrupt
226	cpuss_interrupts_dw0_74_IRQn	Active	CPUSS P-DMA0, Channel #74 Interrupt
227	cpuss_interrupts_dw0_75_IRQn	Active	CPUSS P-DMA0, Channel #75 Interrupt
228	cpuss_interrupts_dw0_76_IRQn	Active	CPUSS P-DMA0, Channel #76 Interrupt
229	cpuss_interrupts_dw0_77_IRQn	Active	CPUSS P-DMA0, Channel #77 Interrupt
230	cpuss_interrupts_dw0_78_IRQn	Active	CPUSS P-DMA0, Channel #78 Interrupt
231	cpuss_interrupts_dw0_79_IRQn	Active	CPUSS P-DMA0, Channel #79 Interrupt
232	cpuss_interrupts_dw0_80_IRQn	Active	CPUSS P-DMA0, Channel #80 Interrupt
233	cpuss_interrupts_dw0_81_IRQn	Active	CPUSS P-DMA0, Channel #81 Interrupt
234	cpuss_interrupts_dw0_82_IRQn	Active	CPUSS P-DMA0, Channel #82 Interrupt
235	cpuss_interrupts_dw0_83_IRQn	Active	CPUSS P-DMA0, Channel #83 Interrupt
236	cpuss_interrupts_dw0_84_IRQn	Active	CPUSS P-DMA0, Channel #84 Interrupt
237	cpuss_interrupts_dw0_85_IRQn	Active	CPUSS P-DMA0, Channel #85 Interrupt
238	cpuss_interrupts_dw0_86_IRQn	Active	CPUSS P-DMA0, Channel #86 Interrupt
239	cpuss_interrupts_dw0_87_IRQn	Active	CPUSS P-DMA0, Channel #87 Interrupt
240	cpuss_interrupts_dw0_88_IRQn	Active	CPUSS P-DMA0, Channel #88 Interrupt
241	cpuss_interrupts_dw1_0_IRQn	Active	CPUSS P-DMA1, Channel #0 Interrupt
242	cpuss_interrupts_dw1_1_IRQn	Active	CPUSS P-DMA1, Channel #1 Interrupt
243	cpuss_interrupts_dw1_2_IRQn	Active	CPUSS P-DMA1, Channel #2 Interrupt
244	cpuss_interrupts_dw1_3_IRQn	Active	CPUSS P-DMA1, Channel #3 Interrupt
245	cpuss_interrupts_dw1_4_IRQn	Active	CPUSS P-DMA1, Channel #4 Interrupt
246	cpuss_interrupts_dw1_5_IRQn	Active	CPUSS P-DMA1, Channel #5 Interrupt

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 Table 14-1
 Peripheral interrupt assignments and wake-up sources (continued)

Interrupt	Source	Power Mode	Description
247	cpuss_interrupts_dw1_6_IRQn	Active	CPUSS P-DMA1, Channel #6 Interrupt
248	cpuss_interrupts_dw1_7_IRQn	Active	CPUSS P-DMA1, Channel #7 Interrupt
249	cpuss_interrupts_dw1_8_IRQn	Active	CPUSS P-DMA1, Channel #8 Interrupt
250	cpuss_interrupts_dw1_9_IRQn	Active	CPUSS P-DMA1, Channel #9 Interrupt
251	cpuss_interrupts_dw1_10_IRQn	Active	CPUSS P-DMA1, Channel #10 Interrupt
252	cpuss_interrupts_dw1_11_IRQn	Active	CPUSS P-DMA1, Channel #11 Interrupt
253	cpuss_interrupts_dw1_12_IRQn	Active	CPUSS P-DMA1, Channel #12 Interrupt
254	cpuss_interrupts_dw1_13_IRQn	Active	CPUSS P-DMA1, Channel #13 Interrupt
255	cpuss_interrupts_dw1_14_IRQn	Active	CPUSS P-DMA1, Channel #14 Interrupt
256	cpuss_interrupts_dw1_15_IRQn	Active	CPUSS P-DMA1, Channel #15 Interrupt
257	cpuss_interrupts_dw1_16_IRQn	Active	CPUSS P-DMA1, Channel #16 Interrupt
258	cpuss_interrupts_dw1_17_IRQn	Active	CPUSS P-DMA1, Channel #17 Interrupt
259	cpuss_interrupts_dw1_18_IRQn	Active	CPUSS P-DMA1, Channel #18 Interrupt
260	cpuss_interrupts_dw1_19_IRQn	Active	CPUSS P-DMA1, Channel #19 Interrupt
261	cpuss_interrupts_dw1_20_IRQn	Active	CPUSS P-DMA1, Channel #20 Interrupt
262	cpuss_interrupts_dw1_21_IRQn	Active	CPUSS P-DMA1, Channel #21 Interrupt
263	cpuss_interrupts_dw1_22_IRQn	Active	CPUSS P-DMA1, Channel #22 Interrupt
264	cpuss_interrupts_dw1_23_IRQn	Active	CPUSS P-DMA1, Channel #23 Interrupt
265	cpuss_interrupts_dw1_24_IRQn	Active	CPUSS P-DMA1, Channel #24 Interrupt
266	cpuss_interrupts_dw1_25_IRQn	Active	CPUSS P-DMA1, Channel #25 Interrupt
267	cpuss_interrupts_dw1_26_IRQn	Active	CPUSS P-DMA1, Channel #26 Interrupt
268	cpuss_interrupts_dw1_27_IRQn	Active	CPUSS P-DMA1, Channel #27 Interrupt
269	cpuss_interrupts_dw1_28_IRQn	Active	CPUSS P-DMA1, Channel #28 Interrupt
270	cpuss_interrupts_dw1_29_IRQn	Active	CPUSS P-DMA1, Channel #29 Interrupt
271	cpuss_interrupts_dw1_30_IRQn	Active	CPUSS P-DMA1, Channel #30 Interrupt
272	cpuss_interrupts_dw1_31_IRQn	Active	CPUSS P-DMA1, Channel #31 Interrupt
273	cpuss_interrupts_dw1_32_IRQn	Active	CPUSS P-DMA1, Channel #32 Interrupt
274	tcpwm_0_interrupts_0_IRQn	Active	TCPWM0 Group #0, Counter #0 Interrupt
275	tcpwm_0_interrupts_1_IRQn	Active	TCPWM0 Group #0, Counter #1 Interrupt
276	tcpwm_0_interrupts_2_IRQn	Active	TCPWM0 Group #0, Counter #2 Interrupt
277	tcpwm_0_interrupts_3_IRQn	Active	TCPWM0 Group #0, Counter #3 Interrupt
278	tcpwm_0_interrupts_4_IRQn	Active	TCPWM0 Group #0, Counter #4 Interrupt
279	tcpwm_0_interrupts_5_IRQn	Active	TCPWM0 Group #0, Counter #5 Interrupt
280	tcpwm_0_interrupts_6_IRQn	Active	TCPWM0 Group #0, Counter #6 Interrupt
281	tcpwm_0_interrupts_7_IRQn	Active	TCPWM0 Group #0, Counter #7 Interrupt
282	tcpwm_0_interrupts_8_IRQn	Active	TCPWM0 Group #0, Counter #8 Interrupt
283	tcpwm_0_interrupts_9_IRQn	Active	TCPWM0 Group #0, Counter #9 Interrupt
284	tcpwm_0_interrupts_10_IRQn	Active	TCPWM0 Group #0, Counter #10 Interrupt
285	tcpwm_0_interrupts_11_IRQn	Active	TCPWM0 Group #0, Counter #11 Interrupt
286	tcpwm_0_interrupts_12_IRQn	Active	TCPWM0 Group #0, Counter #12 Interrupt
287	tcpwm_0_interrupts_13_IRQn	Active	TCPWM0 Group #0, Counter #13 Interrupt
288	tcpwm_0_interrupts_14_IRQn	Active	TCPWM0 Group #0, Counter #14 Interrupt

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Table 14-1 Peripheral interrupt assignments and wake-up sources (continued)

Interrupt	Source	Power Mode	Description
289	tcpwm_0_interrupts_15_IRQn	Active	TCPWM0 Group #0, Counter #15 Interrupt
290	tcpwm_0_interrupts_16_IRQn	Active	TCPWM0 Group #0, Counter #16 Interrupt
291	tcpwm_0_interrupts_17_IRQn	Active	TCPWM0 Group #0, Counter #17 Interrupt
292	tcpwm_0_interrupts_18_IRQn	Active	TCPWM0 Group #0, Counter #18 Interrupt
293	tcpwm_0_interrupts_19_IRQn	Active	TCPWM0 Group #0, Counter #19 Interrupt
294	tcpwm_0_interrupts_20_IRQn	Active	TCPWM0 Group #0, Counter #20 Interrupt
295	tcpwm_0_interrupts_21_IRQn	Active	TCPWM0 Group #0, Counter #21 Interrupt
296	tcpwm_0_interrupts_22_IRQn	Active	TCPWM0 Group #0, Counter #22 Interrupt
297	tcpwm_0_interrupts_23_IRQn	Active	TCPWM0 Group #0, Counter #23 Interrupt
298	tcpwm_0_interrupts_24_IRQn	Active	TCPWM0 Group #0, Counter #24 Interrupt
299	tcpwm_0_interrupts_25_IRQn	Active	TCPWM0 Group #0, Counter #25 Interrupt
300	tcpwm_0_interrupts_26_IRQn	Active	TCPWM0 Group #0, Counter #26 Interrupt
301	tcpwm_0_interrupts_27_IRQn	Active	TCPWM0 Group #0, Counter #27 Interrupt
302	tcpwm_0_interrupts_28_IRQn	Active	TCPWM0 Group #0, Counter #28 Interrupt
303	tcpwm_0_interrupts_29_IRQn	Active	TCPWM0 Group #0, Counter #29 Interrupt
304	tcpwm_0_interrupts_30_IRQn	Active	TCPWM0 Group #0, Counter #30 Interrupt
305	tcpwm_0_interrupts_31_IRQn	Active	TCPWM0 Group #0, Counter #31 Interrupt
306	tcpwm_0_interrupts_32_IRQn	Active	TCPWM0 Group #0, Counter #32 Interrupt
307	tcpwm_0_interrupts_33_IRQn	Active	TCPWM0 Group #0, Counter #33 Interrupt
308	tcpwm_0_interrupts_34_IRQn	Active	TCPWM0 Group #0, Counter #34 Interrupt
309	tcpwm_0_interrupts_35_IRQn	Active	TCPWM0 Group #0, Counter #35 Interrupt
310	tcpwm_0_interrupts_36_IRQn	Active	TCPWM0 Group #0, Counter #36 Interrupt
311	tcpwm_0_interrupts_37_IRQn	Active	TCPWM0 Group #0, Counter #37 Interrupt
312	tcpwm_0_interrupts_38_IRQn	Active	TCPWM0 Group #0, Counter #38 Interrupt
313	tcpwm_0_interrupts_39_IRQn	Active	TCPWM0 Group #0, Counter #39 Interrupt
314	tcpwm_0_interrupts_40_IRQn	Active	TCPWM0 Group #0, Counter #40 Interrupt
315	tcpwm_0_interrupts_41_IRQn	Active	TCPWM0 Group #0, Counter #41 Interrupt
316	tcpwm_0_interrupts_42_IRQn	Active	TCPWM0 Group #0, Counter #42 Interrupt
317	tcpwm_0_interrupts_43_IRQn	Active	TCPWM0 Group #0, Counter #43 Interrupt
318	tcpwm_0_interrupts_44_IRQn	Active	TCPWM0 Group #0, Counter #44 Interrupt
319	tcpwm_0_interrupts_45_IRQn	Active	TCPWM0 Group #0, Counter #45 Interrupt
320	tcpwm_0_interrupts_46_IRQn	Active	TCPWM0 Group #0, Counter #46 Interrupt
321	tcpwm_0_interrupts_47_IRQn	Active	TCPWM0 Group #0, Counter #47 Interrupt
322	tcpwm_0_interrupts_48_IRQn	Active	TCPWM0 Group #0, Counter #48 Interrupt
323	tcpwm_0_interrupts_49_IRQn	Active	TCPWM0 Group #0, Counter #49 Interrupt
324	tcpwm_0_interrupts_50_IRQn	Active	TCPWM0 Group #0, Counter #50 Interrupt
325	tcpwm_0_interrupts_51_IRQn	Active	TCPWM0 Group #0, Counter #51 Interrupt
326	tcpwm_0_interrupts_52_IRQn	Active	TCPWM0 Group #0, Counter #52 Interrupt
327	tcpwm_0_interrupts_53_IRQn	Active	TCPWM0 Group #0, Counter #53 Interrupt
328	tcpwm_0_interrupts_54_IRQn	Active	TCPWM0 Group #0, Counter #54 Interrupt
329	tcpwm_0_interrupts_55_IRQn	Active	TCPWM0 Group #0, Counter #55 Interrupt
330	tcpwm_0_interrupts_56_IRQn	Active	TCPWM0 Group #0, Counter #56 Interrupt

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 Table 14-1
 Peripheral interrupt assignments and wake-up sources (continued)

Interrupt	Source	Power Mode	Description
331	tcpwm_0_interrupts_57_IRQn	Active	TCPWM0 Group #0, Counter #57 Interrupt
332	tcpwm_0_interrupts_58_IRQn	Active	TCPWM0 Group #0, Counter #58 Interrupt
333	tcpwm_0_interrupts_59_IRQn	Active	TCPWM0 Group #0, Counter #59 Interrupt
334	tcpwm_0_interrupts_60_IRQn	Active	TCPWM0 Group #0, Counter #60 Interrupt
335	tcpwm_0_interrupts_61_IRQn	Active	TCPWM0 Group #0, Counter #61 Interrupt
336	tcpwm_0_interrupts_62_IRQn	Active	TCPWM0 Group #0, Counter #62 Interrupt
337	tcpwm_0_interrupts_256_IRQn	Active	TCPWM0 Group #1, Counter #0 Interrupt
338	tcpwm_0_interrupts_257_IRQn	Active	TCPWM0 Group #1, Counter #1 Interrupt
339	tcpwm_0_interrupts_258_IRQn	Active	TCPWM0 Group #1, Counter #2 Interrupt
340	tcpwm_0_interrupts_259_IRQn	Active	TCPWM0 Group #1, Counter #3 Interrupt
341	tcpwm_0_interrupts_260_IRQn	Active	TCPWM0 Group #1, Counter #4 Interrupt
342	tcpwm_0_interrupts_261_IRQn	Active	TCPWM0 Group #1, Counter #5 Interrupt
343	tcpwm_0_interrupts_262_IRQn	Active	TCPWM0 Group #1, Counter #6 Interrupt
344	tcpwm_0_interrupts_263_IRQn	Active	TCPWM0 Group #1, Counter #7 Interrupt
345	tcpwm_0_interrupts_264_IRQn	Active	TCPWM0 Group #1, Counter #8 Interrupt
346	tcpwm_0_interrupts_265_IRQn	Active	TCPWM0 Group #1, Counter #9 Interrupt
347	tcpwm_0_interrupts_266_IRQn	Active	TCPWM0 Group #1, Counter #10 Interrupt
348	tcpwm_0_interrupts_267_IRQn	Active	TCPWM0 Group #1, Counter #11 Interrupt
349	tcpwm_0_interrupts_512_IRQn	Active	TCPWM0 Group #2, Counter #0 Interrupt
350	tcpwm_0_interrupts_513_IRQn	Active	TCPWM0 Group #2, Counter #1 Interrupt
351	tcpwm_0_interrupts_514_IRQn	Active	TCPWM0 Group #2, Counter #2 Interrupt
352	tcpwm_0_interrupts_515_IRQn	Active	TCPWM0 Group #2, Counter #3 Interrupt

Based on Arm® Cortex®-M4F single

Core interrupt types



15 Core interrupt types

Table 15-1 Core interrupt types

Interrupt	Source	Power Mode	Description
0	CPUIntIdx0_IRQn ^[30]	DeepSleep	CPU User Interrupt #0
1	CPUIntIdx1_IRQn ^[30]	DeepSleep	CPU User Interrupt #1
2	CPUIntIdx2_IRQn	DeepSleep	CPU User Interrupt #2
3	CPUIntIdx3_IRQn	DeepSleep	CPU User Interrupt #3
4	CPUIntIdx4_IRQn	DeepSleep	CPU User Interrupt #4
5	CPUIntIdx5_IRQn	DeepSleep	CPU User Interrupt #5
6	CPUIntIdx6_IRQn	DeepSleep	CPU User Interrupt #6
7	CPUIntIdx7_IRQn	DeepSleep	CPU User Interrupt #7
8	Internal0_IRQn	Active	Internal Software Interrupt #0
9	Internal1_IRQn	Active	Internal Software Interrupt #1
10	Internal2_IRQn	Active	Internal Software Interrupt #2
11	Internal3_IRQn	Active	Internal Software Interrupt #3
12	Internal4_IRQn	Active	Internal Software Interrupt #4
13	Internal5_IRQn	Active	Internal Software Interrupt #5
14	Internal6_IRQn	Active	Internal Software Interrupt #6
15	Internal7_IRQn	Active	Internal Software Interrupt #7

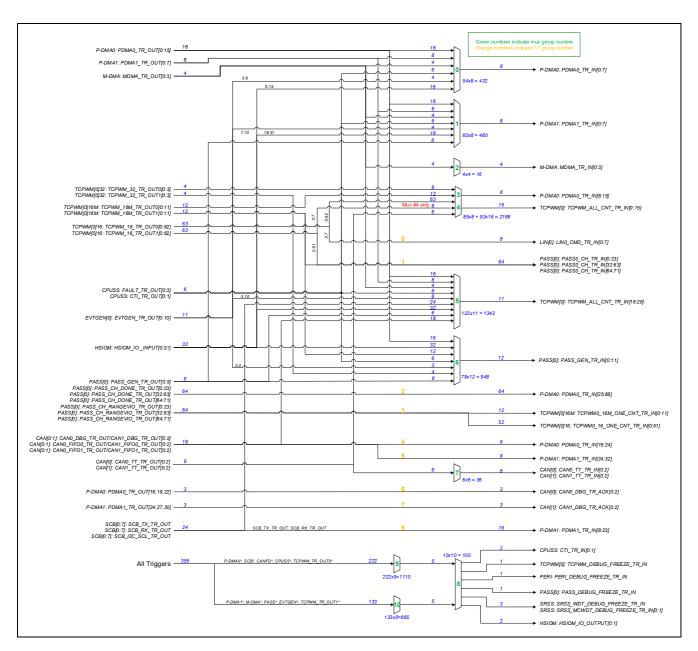
Note

30. User interrupt cannot be used for CM0+ application, as it is used internally by system calls. Note, this does not impact CM4 application.

Trigger multiplexer



Trigger multiplexer 16



Trigger multiplexer^[31] Figure 16-1

Note

^{31.} The diagram shows only the TRIG_LABEL, final trigger formation is based on the formula TRIG_{PREFIX(IN/OUT)}_{MUX_x}_{TRIG_LABEL} And Table 17-1, Table 18-1, and Table 19-1.

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Triggers group inputs



17 Triggers group inputs

Table 17-1 Trigger inputs

Input	Trigger Label (TRIG_LABEL)	Description
MUX Group 0	: PDMA0_TR (P-DMA0_0_15 trigg	er multiplexer)
1:16 ^[32]	PDMA0_TR_OUT[0:15]	Allow P-DMA0 to chain to itself, useful for triggering once per row for 2D transfer
17:24	PDMA1_TR_OUT[0:7]	Cross connections from P-DMA1 to P-DMA0, Channels 0-7 are used
25:28	MDMA_TR_OUT[0:3]	Cross connections from M-DMA0 to P-DMA0
29:32	FAULT_TR_OUT[0:3]	Allow faults to initiate data transfer for debug purposes
33:34	CTI_TR_OUT[0:1]	Trace events
35:38	EVTGEN_TR_OUT[3:6]	EVTGEN triggers
39:54	HSIOM_IO_INPUT[0:15]	I/O inputs
MUX Group 1	: PDMA1_TR (P-DMA1 trigger mu	ltiplexer)
1:16	PDMA0_TR_OUT[0:15]	Allow P-DMA0 to trigger P-DMA1
17:24	PDMA1_TR_OUT[0:7]	Allow P-DMA1 to chain to itself, useful for triggering once per row for 2D transfer
25:28	MDMA_TR_OUT[0:3]	Allow M-DMA0 to trigger P-DMA0
29:32	FAULT_TR_OUT[0:3]	Allow faults to initiate data transfer for debug purposes
33:34	CTI_TR_OUT[0:1]	Trace events
35:38	EVTGEN_TR_OUT[7:10]	EVTGEN triggers
39:54	HSIOM_IO_INPUT[16:31]	I/O inputs
55:60	PASS_GEN_TR_OUT[0:5]	PASS SAR events
MUX Group 2	: MDMA (M-DMA0 trigger multiple	exer)
1:4	MDMA_TR_OUT[0:3]	Allow M-DMA0 to trigger itself
MUX Group 3	: TCPWM_TO_PDMA0 (TCPWM0 t	o P-DMA0 trigger multiplexer)
1:4	TCPWM_32_TR_OUT0[0:3]	32-bit TCPWM0 counters
5:16	TCPWM_16M_TR_OUT0[0:11	16-bit Motor enhanced TCPWM0 counters
17:79	TCPWM_16_TR_OUT0[0:62]	16-bit TCPWM0 counters
80:82	CAN0_TT_TR_OUT[0:2]	CAN0 TT Sync Outputs
83:85	CAN1_TT_TR_OUT[0:2]	CAN1 TT Sync Outputs
MUX Group 4	: TCPWM_OUT (TCPWM0 loop ba	ck multiplexer)
1:4	TCPWM_32_TR_OUT0[0:3]	32-bit TCPWM0 counters
5:16	TCPWM_16M_TR_OUT0[0:11	16-bit Motor enhanced TCPWM0 counters
17:79	TCPWM_16_TR_OUT0[0:62]	16-bit TCPWM0 counters
80:87	TCPWM_16_TR_OUT1[0:7]	Allows feedback of two signals from same counters
88:90	CAN0_TT_TR_OUT[0:2]	CAN0 TT Sync Outputs
91:93	CAN1_TT_TR_OUT[0:2]	CAN1 TT Sync Outputs
MUX Group 5	: TCPWM_IN (TCPWM0 Trigger M	ultiplexer)
1:16	PDMA0_TR_OUT[0:15]	General purpose P-DMA0 triggers
	1	<u> </u>

Note

^{32. &}quot;a:b" depicts a range starting from 'a' through 'b'.

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Triggers group inputs



Table 17-1 Trigger inputs (continued)

Input	Trigger Label (TRIG_LABEL)	Description
17:24	PDMA1_TR_OUT[0:7]	General purpose P-DMA1 triggers
25:28	MDMA_TR_OUT[0:3]	M-DMA0 triggers
29:30	CTI_TR_OUT[0:1]	Trace events
31:34	FAULT_TR_OUT[0:3]	Fault events
35:40	PASS_GEN_TR_OUT[0:5]	PASS SAR events
41:72	HSIOM_IO_INPUT[0:31]	I/O inputs
73	SCB_TX_TR_OUT[0]	SCB0 TX trigger
74	SCB_RX_TR_OUT[0]	SCB0 RX trigger
75	SCB_I2C_SCL_TR_OUT[0]	SCB0 I ² C trigger
76	SCB_TX_TR_OUT[1]	SCB1 TX trigger
77	SCB_RX_TR_OUT[1]	SCB1 RX trigger
78	SCB_I2C_SCL_TR_OUT[1]	SCB1 I ² C trigger
79	SCB_TX_TR_OUT[2]	SCB2 TX trigger
80	SCB_RX_TR_OUT[2]	SCB2 RX trigger
81	SCB_I2C_SCL_TR_OUT[2]	SCB2 I ² C trigger
82	SCB_TX_TR_OUT[3]	SCB3 TX trigger
83	SCB_RX_TR_OUT[3]	SCB3 RX trigger
84	SCB_I2C_SCL_TR_OUT[3]	SCB3 I ² C trigger
85	SCB_TX_TR_OUT[4]	SCB4 TX trigger
86	SCB_RX_TR_OUT[4]	SCB4 RX trigger
87	SCB_I2C_SCL_TR_OUT[4]	SCB4 I ² C trigger
88	SCB_TX_TR_OUT[5]	SCB5 TX trigger
89	SCB_RX_TR_OUT[5]	SCB5 RX trigger
90	SCB_I2C_SCL_TR_OUT[5]	SCB5 I ² C trigger
91	SCB_TX_TR_OUT[6]	SCB6 TX trigger
92	SCB_RX_TR_OUT[6]	SCB6 RX trigger
93	SCB_I2C_SCL_TR_OUT[6]	SCB6 I ² C trigger
94	SCB_TX_TR_OUT[7]	SCB7 TX trigger
95	SCB_RX_TR_OUT[7]	SCB7 RX trigger
96	SCB_I2C_SCL_TR_OUT[7]	SCB7 I ² C trigger
97:99	CAN0_DBG_TR_OUT[0:2]	CANO M-DMA0 events
100:102	CAN0_FIFO0_TR_OUT[0:2]	CAN0 FIFO0 events
103:105	CAN0_FIFO1_TR_OUT[0:2]	CAN0 FIFO1 events
106:108	CAN1_DBG_TR_OUT[0:2]	CAN1 M-DMA0 events
109:111	CAN1_FIFO0_TR_OUT[0:2]	CAN1 FIFO0 events
112:114	CAN1_FIFO1_TR_OUT[0:2]	CAN1 FIFO1 events
115:122	EVTGEN_TR_OUT[3:10]	EVTGEN triggers
	ASS (PASS SAR trigger multiple	· · · · · · · · · · · · · · · · · · ·
1:16	PDMA0_TR_OUT[0:15]	General purpose P-DMA0 triggers
17:18	CTI_TR_OUT[0:1]	Trace events
19:22	FAULT_TR_OUT[0:3]	Fault events

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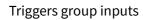
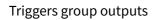




Table 17-1 Trigger inputs (continued)

Input	Trigger Label (TRIG_LABEL)	Description	
23:25	EVTGEN_TR_OUT[0:2]	EVTGEN triggers	
26:31	PASS_GEN_TR_OUT[0:5]	PASS SAR done signals	
32:63	HSIOM_IO_INPUT[0:31]	I/O inputs	
64:67	TCPWM_32_TR_OUT1[0:3]	32-bit TCPWM0 counters	
68:79	TCPWM_16M_TR_OUT1[0:11	16-bit Motor enhanced TCPWM0 counters	
MUX Group 7:	CAN TT sync triggers	<u> </u>	
1:3	CAN0_TT_TR_OUT[0:2]	CAN0 TT Sync Outputs	
4:6	CAN1_TT_TR_OUT[0:2]	CAN1 TT Sync Outputs	
MUX Group 8:	DebugMain (Debug Multiplexer)		
1:5	TR_GROUP9_OUTPUT[0:4]	Output from debug reduction multiplexer #1	
6:10	TR_GROUP10_OUTPUT[0:4]	Output from debug reduction multiplexer #2	
MUX Group 9:	DebugReduction1 (Debug Redu	iction #1)	
1:89	PDMA0_TR_OUT[0:88]	P-DMA0 triggers	
90:97	SCB_TX_TR_OUT[0:7]	SCB TTCAN tx Triggers	
98:105	SCB_RX_TR_OUT[0:7]	SCB TTCAN rx Triggers	
106:113	SCB_I2C_SCL_TR_OUT[0:7]	SCB I ² C triggers	
114:116	CAN0_DBG_TR_OUT[0:2]	CANO P-DMA	
117:119	CAN0_FIFO0_TR_OUT[0:2]	CAN0 FIFO0	
120:122	CAN0_FIFO1_TR_OUT[0:2]	CAN0 FIFO1	
123:125	CAN0_TT_TR_OUT[0:2]	CAN TT Sync Outputs	
126:128	CAN1_DBG_TR_OUT[0:2]	CAN1 P-DMA	
129:131	CAN1_FIFO0_TR_OUT[0:2]	CAN1 FIFO0	
132:134	CAN1_FIFO1_TR_OUT[0:2]	CAN1 FIFO1	
135:137	CAN1_TT_TR_OUT[0:2]	CAN TT Sync Outputs	
138:139	CTI_TR_OUT[0:1]	Trace events	
140:143	FAULT_TR_OUT[0:3]	Fault events	
144:147	TCPWM_32_TR_OUT0[0:3]	32-bit TCPWM0 counters	
148:159	TCPWM_16M_TR_OUT0[0:11	16-bit Motor enhanced TCPWM0 counters	
160:222	TCPWM_16_TR_OUT0[0:62]	16-bit TCPWM0 counters	
MUX Group 10): DebugReduction2 (Debug Red	luction #2)	
1:33	PDMA1_TR_OUT[0:32]	16-bit Motor enhanced TCPWM0 counters	
34:37	MDMA_TR_OUT[0:3]	16-bit TCPWM0 counters	
38:41	TCPWM_32_TR_OUT1[0:3]	32-bit TCPWM0 counters	
42:53	TCPWM_16M_TR_OUT1[0:11	16-bit Motor enhanced TCPWM0 counters	
54:116	TCPWM_16_TR_OUT1[0:62]	16-bit TCPWM0 counters	
117:122	PASS_GEN_TR_OUT[0:5]	PASS SAR conversion complete events	
123:133	EVTGEN_TR_OUT[0:10]	EVTGEN Triggers	

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Triggers group outputs 18

Trigger outputs Table 18-1

Output	Trigger Label (TRIG_LABEL)	Description
MUX Group 0: PDMA0_T	R (P-DMA0 trigger multiplexer)	
0:7	PDMA0_TR_IN[0:7]	Triggers to P-DMA0[0:7]
MUX Group 1: PDMA1_T	R (P-DMA1 trigger multiplexer)	
0:7	PDMA1_TR_IN[0:7]	Triggers to P-DMA1[0:7]
MUX Group 2: MDMA (M-	DMA0 trigger multiplexer)	
0:3	MDMA_TR_IN[0:3]	Triggers to M-DMA0
MUX Group 3: TCPWM_T	O_PDMA0 (TCPWM0 to P-DMA0 trigger mult	iplexer)
0:7	PDMA0_TR_IN[8:15]	Triggers to P-DMA0[8:15]
MUX Group 4: TCPWM_C	OUT (TCPWM0 loop back multiplexer)	
0:15	TCPWM_ALL_CNT_TR_IN[0:15]	All counters trigger input
MUX Group 5: TCPWM_II	N (TCPWM0 Trigger Multiplexer)	
0:10	TCPWM_ALL_CNT_TR_IN[16:26]	Triggers to TCPWM0
MUX Group 6: PASS (PAS	S SAR trigger multiplexer)	
0:11	PASS_GEN_TR_IN[0:11]	Triggers to SAR ADCs
MUX Group 7: CANTT (CA	AN TT Sync)	
0:2	CAN0_TT_TR_IN[0:2]	CAN0 TT Sync Inputs
3:5	CAN1_TT_TR_IN[0:2]	CAN1 TT Sync Inputs
MUX Group 8: DebugMai	n (Debug Multiplexer)	
0:1	HSIOM_IO_OUTPUT[0:1]	To HSIOM as an output
2:3	CTI_TR_IN[0:1]	To CPU Cross Trigger system
4	PERI_DEBUG_FREEZE_TR_IN	Signal to Freeze PERI operation
5	PASS_DEBUG_FREEZE_TR_IN	Signal to Freeze SAR ADC operation
6	SRSS_WDT_DEBUG_FREEZE_TR_IN	Signal to Freeze WDT operation
7:8	SRSS_MCWDT_DEBUG FREEZE_TR_IN[0:1]	Signal to Freeze MCWDT operation
9	TCPWM_DEBUG_FREEZE_TR_IN	Signal to Freeze TCPWM0 operation
MUX Group 9: DebugRed	luction1 (Debug Reduction #1)	
0:4	TR_GROUP8_INPUT[1:5]	To main debug multiplexer
MUX Group 10: DebugRe	eduction2 (Debug Reduction #2)	•
0:4	TR_GROUP8_INPUT[6:10]	To main debug multiplexer

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Triggers one-to-one



19 Triggers one-to-one

Table 19-1 Triggers 1:1

Input	Trigger In	Trigger Out	Description
MUX Group	0: TCPWM0 to LIN0 Triggers	•	•
0:7	TCPWM0_16_TR_OUT0[0:7]	LIN0_CMD_TR_IN[0:7]	TCPWM0 (Group #0 Counter #00 to #07) to LIN0
MUX Group	1: TCPWM0 to PASS SARx direct connect		
0	TCPWM0_16M_TR_OUT1[0]	PASS0_CH_TR_IN[0]	TCPWM0 Group #1 Counter #00 (PWM0_M_0) to SAR0 ch#0
1	TCPWM0_16M_TR_OUT1[1]	PASS0_CH_TR_IN[1]	TCPWM0 Group #1 Counter #03 (PWM0_M_3) to SAR0 ch#1
2	TCPWM0_16M_TR_OUT1[2]	PASS0_CH_TR_IN[2]	TCPWM0 Group #1 Counter #06 (PWM0_M_6) to SAR0 ch#2
3	TCPWM0_16M_TR_OUT1[3]	PASS0_CH_TR_IN[3]	TCPWM0 Group #1 Counter #09 (PWM0_M_9) to SAR0 ch#3
4:23	TCPWM0_16_TR_OUT1[0:19]	PASS0_CH_TR_IN[4:23]	TCPWM0 Group #0 Counter #00 through 19 (PWM0_0 to PWM0_19) to SAR0 ch#4 through SAR0 ch#23
24	TCPWM0_16M_TR_OUT1[4]	PASS0_CH_TR_IN[32]	TCPWM0 Group #1 Counter #01 (PWM0_M_1) to SAR1 ch#0
25	TCPWM0_16M_TR_OUT1[5]	PASS0_CH_TR_IN[33]	TCPWM0 Group #1 Counter #04 (PWM0_M_4) to SAR1 ch#1
26	TCPWM0_16M_TR_OUT1[6]	PASS0_CH_TR_IN[34]	TCPWM0 Group #1 Counter #07 (PWM0_M_7) to SAR1 ch#2
27	TCPWM0_16M_TR_OUT1[7]	PASS0_CH_TR_IN[35]	TCPWM0 Group #1 Counter #10 (PWM0_M_10) to SAR1 ch#3
28:55	TCPWM0_16_TR_OUT1[20:47]	PASS0_CH_TR_IN[36:63]	TCPWM0 Group #0 Counter #20 through 47 (PWM0_20 to PWM0_47) to SAR1 ch#4 through SAR1 ch#31
56	TCPWM0_16M_TR_OUT1[8]	PASS0_CH_TR_IN[64]	TCPWM0 Group #1 Counter #02 (PWM0_M_2) to SAR2 ch#0
57	TCPWM0_16M_TR_OUT1[9]	PASS0_CH_TR_IN[65]	TCPWM0 Group #1 Counter #05 (PWM0_M_5) to SAR2 ch#1
58	TCPWM0_16M_TR_OUT1[10]	PASS0_CH_TR_IN[66]	TCPWM0 Group #1 Counter #08 (PWM0_M_8) to SAR2 ch#2
59	TCPWM0_16M_TR_OUT1[11]	PASS0_CH_TR_IN[67]	TCPWM0 Group #1 Counter #11 (PWM0_M_11) to SAR2 ch#3
60:63	TCPWM0_16_TR_OUT1[48:51]	PASSO_CH_TR_IN[68:71]	TCPWM0 Group #0 Counter #48 through 51 (PWM0_48 to PWM0_51) to SAR2 ch#4 through SAR2 ch#7
MUX Group	2: PASS SARx to P-DMA0 direct connect		
0:23	PASSO_CH_DONE_TR_OUT[0:23]	PDMA0_TR_IN[25:48]	PASS SAR0 [0:23] to P-DMA0 direct connect
24:55	PASS0_CH_DONE_TR_OUT[32:63]	PDMA0_TR_IN[49:80]	PASS SAR1 [0:31] to P-DMA0 direct connect
56:63	PASS0_CH_DONE_TR_OUT[64:71]	PDMA0_TR_IN[81:88]	PASS SAR2 [0:7] to P-DMA0 direct connect
MUX Group	3: PASS SARx to TCPWM0 direct connect		•
0	PASS0_CH_RANGEVIO_TR_OUT[0]	TCPWM0_16M_ONE_CNT_TR_IN[0]	SAR0 ch#0 ^[33] , range violation to TCPWM0 Group #1 Counter #00 trig=4
1	PASSO_CH_RANGEVIO_TR_OUT[1]	TCPWM0_16M_ONE_CNT_TR_IN[3]	SAR0 ch#1, range violation to TCPWM0 Group #1 Counter #03 trig=4
2	PASS0_CH_RANGEVIO_TR_OUT[2]	TCPWM0_16M_ONE_CNT_TR_IN[6]	SAR0 ch#2, range violation to TCPWM0 Group #1 Counter #06 trig=4
3	PASS0_CH_RANGEVIO_TR_OUT[3]	TCPWM0_16M_ONE_CNT_TR_IN[9]	SAR0 ch#3, range violation to TCPWM0 Group #1 Counter #09 trig=4
4	PASS0_CH_RANGEVIO_TR_OUT[4]	TCPWM0_16_ONE_CNT_TR_IN[0]	SAR0 ch#4, range violation to TCPWM0 Group #0 Counter #00 trig=4
5	PASS0_CH_RANGEVIO_TR_OUT[5]	TCPWM0_16_ONE_CNT_TR_IN[1]	SAR0 ch#5, range violation to TCPWM0 Group #0 Counter #01 trig=4
6	PASSO_CH_RANGEVIO_TR_OUT[6]	TCPWM0_16_ONE_CNT_TR_IN[2]	SAR0 ch#6, range violation to TCPWM0 Group #0 Counter #02 trig=4
7	PASSO_CH_RANGEVIO_TR_OUT[7]	TCPWM0_16_ONE_CNT_TR_IN[3]	SAR0 ch#7, range violation to TCPWM0 Group #0 Counter #03 trig=4
8	PASSO_CH_RANGEVIO_TR_OUT[8]	TCPWM0_16_ONE_CNT_TR_IN[4]	SAR0 ch#8, range violation to TCPWM0 Group #0 Counter #04 trig=4
9	PASS0_CH_RANGEVIO_TR_OUT[9]	TCPWM0_16_ONE_CNT_TR_IN[5]	SAR0 ch#9, range violation to TCPWM0 Group #0 Counter #05 trig=4
10	PASSO_CH_RANGEVIO_TR_OUT[10]	TCPWM0_16_ONE_CNT_TR_IN[6]	SAR0 ch#10, range violation to TCPWM0 Group #0 Counter #06 trig=4
11	PASSO_CH_RANGEVIO_TR_OUT[11]	TCPWM0_16_ONE_CNT_TR_IN[7]	SAR0 ch#11, range violation to TCPWM0 Group #0 Counter #07 trig=4
12	PASSO_CH_RANGEVIO_TR_OUT[12]	TCPWM0_16_ONE_CNT_TR_IN[8]	SAR0 ch#12, range violation to TCPWM0 Group #0 Counter #08 trig=4
13	PASSO_CH_RANGEVIO_TR_OUT[13]	TCPWM0_16_ONE_CNT_TR_IN[9]	SAR0 ch#13, range violation to TCPWM0 Group #0 Counter #09 trig=4
14	PASSO_CH_RANGEVIO_TR_OUT[14]	TCPWM0_16_ONE_CNT_TR_IN[10]	SAR0 ch#14, range violation to TCPWM0 Group #0 Counter #10 trig=4
15	PASSO_CH_RANGEVIO_TR_OUT[15]	TCPWM0_16_ONE_CNT_TR_IN[11]	SAR0 ch#15, range violation to TCPWM0 Group #0 Counter #11 trig=4
16	PASSO_CH_RANGEVIO_TR_OUT[16]	TCPWM0_16_ONE_CNT_TR_IN[12]	SAR0 ch#16, range violation to TCPWM0 Group #0 Counter #12 trig=4
17	PASSO_CH_RANGEVIO_TR_OUT[17]	TCPWM0_16_ONE_CNT_TR_IN[13]	SAR0 ch#17, range violation to TCPWM0 Group #0 Counter #13 trig=4
18	PASS0_CH_RANGEVIO_TR_OUT[18]	TCPWM0_16_ONE_CNT_TR_IN[14]	SAR0 ch#18, range violation to TCPWM0 Group #0 Counter #14 trig=4
19	PASS0_CH_RANGEVIO_TR_OUT[19]	TCPWM0_16_ONE_CNT_TR_IN[15]	SAR0 ch#19, range violation to TCPWM0 Group #0 Counter #15 trig=4
20	PASSO_CH_RANGEVIO_TR_OUT[20]	TCPWM0_16_ONE_CNT_TR_IN[16]	SAR0 ch#20, range violation to TCPWM0 Group #0 Counter #16 trig=4
21	PASSO_CH_RANGEVIO_TR_OUT[21]	TCPWM0_16_ONE_CNT_TR_IN[17]	SAR0 ch#21, range violation to TCPWM0 Group #0 Counter #17 trig=4
		TCPWM0_16_ONE_CNT_TR_IN[18]	SAR0 ch#22, range violation to TCPWM0 Group #0 Counter #18 trig=4
22	PASSO CH RANGEVIO IR OUTIZZI		1 3ANO CH#22, larige violation to 1Cr wind Gloub #0 Counter #18 H18=4
22 23	PASSO_CH_RANGEVIO_TR_OUT[22] PASSO_CH_RANGEVIO_TR_OUT[23]	TCPWM0_16_ONE_CNT_TR_IN[19]	SARO ch#23, range violation to TCPWM0 Group #0 Counter #19 trig=4

Note

33. Each logical channel of SAR ADC[x] can be connected to any of the SAR ADC[x]_y external pin. (x = 0, or 1, or, 2 and y = 0 to max 31)

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Triggers one-to-one



Table 19-1 Triggers 1:1 (continued)

Input	Trigger In	Trigger Out	Description
25	PASS0_CH_RANGEVIO_TR_OUT[33]	TCPWM0_16M_ONE_CNT_TR_IN[4]	SAR1 ch#1, range violation to TCPWM0 Group #1 Counter #04 trig=4
26	PASSO_CH_RANGEVIO_TR_OUT[34]	TCPWM0_16M_ONE_CNT_TR_IN[7]	SAR1 ch#2, range violation to TCPWM0 Group #1 Counter #07 trig=4
27	PASS0_CH_RANGEVIO_TR_OUT[35]	TCPWM0_16M_ONE_CNT_TR_IN[10]	SAR1 ch#3, range violation to TCPWM0 Group #1 Counter #10 trig=4
28	PASS0_CH_RANGEVIO_TR_OUT[36]	TCPWM0_16_ONE_CNT_TR_IN[20]	SAR1 ch#4, range violation to TCPWM0 Group #0 Counter #20 trig=4
29	PASS0_CH_RANGEVIO_TR_OUT[37]	TCPWM0_16_ONE_CNT_TR_IN[21]	SAR1 ch#5, range violation to TCPWM0 Group #0 Counter #21 trig=4
30	PASS0_CH_RANGEVIO_TR_OUT[38]	TCPWM0_16_ONE_CNT_TR_IN[22]	SAR1 ch#6, range violation to TCPWM0 Group #0 Counter #22 trig=4
31	PASSO_CH_RANGEVIO_TR_OUT[39]	TCPWM0_16_ONE_CNT_TR_IN[23]	SAR1 ch#7, range violation to TCPWM0 Group #0 Counter #23 trig=4
32	PASSO_CH_RANGEVIO_TR_OUT[40]	TCPWM0_16_ONE_CNT_TR_IN[24]	SAR1 ch#8, range violation to TCPWM0 Group #0 Counter #24 trig=4
33	PASSO_CH_RANGEVIO_TR_OUT[41]	TCPWM0_16_ONE_CNT_TR_IN[25]	SAR1 ch#9, range violation to TCPWM0 Group #0 Counter #25 trig=4
34	PASS0_CH_RANGEVIO_TR_OUT[42]	TCPWM0_16_ONE_CNT_TR_IN[26]	SAR1 ch#10, range violation to TCPWM0 Group #0 Counter #26 trig=
35	PASSO_CH_RANGEVIO_TR_OUT[43]	TCPWM0_16_ONE_CNT_TR_IN[27]	SAR1 ch#11, range violation to TCPWM0 Group #0 Counter #27 trig=
36	PASSO_CH_RANGEVIO_TR_OUT[44]	TCPWM0_16_ONE_CNT_TR_IN[28]	SAR1 ch#12, range violation to TCPWM0 Group #0 Counter #28 trig=
37	PASSO_CH_RANGEVIO_TR_OUT[45]	TCPWM0_16_ONE_CNT_TR_IN[29]	SAR1 ch#13, range violation to TCPWM0 Group #0 Counter #29 trig=
38	PASSO_CH_RANGEVIO_TR_OUT[46]	TCPWM0_16_ONE_CNT_TR_IN[30]	SAR1 ch#14, range violation to TCPWM0 Group #0 Counter #30 trig=
39	PASSO_CH_RANGEVIO_TR_OUT[47]	TCPWM0_16_ONE_CNT_TR_IN[31]	SAR1 ch#15, range violation to TCPWM0 Group #0 Counter #31 trig=
40			
	PASSO_CH_RANGEVIO_TR_OUT[48]	TCPWM0_16_ONE_CNT_TR_IN[32]	SAR1 ch#16, range violation to TCPWM0 Group #0 Counter #32 trig=
41	PASSO_CH_RANGEVIO_TR_OUT[49]	TCPWM0_16_ONE_CNT_TR_IN[33]	SAR1 ch#17, range violation to TCPWM0 Group #0 Counter #33 trig=
42	PASSO_CH_RANGEVIO_TR_OUT[50]	TCPWM0_16_ONE_CNT_TR_IN[34]	SAR1 ch#18, range violation to TCPWM0 Group #0 Counter #34 trig=
43	PASSO_CH_RANGEVIO_TR_OUT[51]	TCPWM0_16_ONE_CNT_TR_IN[35]	SAR1 ch#19, range violation to TCPWM0 Group #0 Counter #35 trig=
44	PASSO_CH_RANGEVIO_TR_OUT[52]	TCPWM0_16_ONE_CNT_TR_IN[36]	SAR1 ch#20, range violation to TCPWM0 Group #0 Counter #36 trig=
45	PASS0_CH_RANGEVIO_TR_OUT[53]	TCPWM0_16_ONE_CNT_TR_IN[37]	SAR1 ch#21, range violation to TCPWM0 Group #0 Counter #37 trig=
46	PASS0_CH_RANGEVIO_TR_OUT[54]	TCPWM0_16_ONE_CNT_TR_IN[38]	SAR1 ch#22, range violation to TCPWM0 Group #0 Counter #38 trig-
47	PASS0_CH_RANGEVIO_TR_OUT[55]	TCPWM0_16_ONE_CNT_TR_IN[39]	SAR1 ch#23, range violation to TCPWM0 Group #0 Counter #39 trig=
48	PASS0_CH_RANGEVIO_TR_OUT[56]	TCPWM0_16_ONE_CNT_TR_IN[40]	SAR1 ch#24, range violation to TCPWM0 Group #0 Counter #40 trig
49	PASS0_CH_RANGEVIO_TR_OUT[57]	TCPWM0_16_ONE_CNT_TR_IN[41]	SAR1 ch#25, range violation to TCPWM0 Group #0 Counter #41 trig
50	PASS0_CH_RANGEVIO_TR_OUT[58]	TCPWM0_16_ONE_CNT_TR_IN[42]	SAR1 ch#26, range violation to TCPWM0 Group #0 Counter #42 trig
51	PASS0_CH_RANGEVIO_TR_OUT[59]	TCPWM0_16_ONE_CNT_TR_IN[43]	SAR1 ch#27, range violation to TCPWM0 Group #0 Counter #43 trig-
52	PASSO_CH_RANGEVIO_TR_OUT[60]	TCPWM0_16_ONE_CNT_TR_IN[44]	SAR1 ch#28, range violation to TCPWM0 Group #0 Counter #44 trig=
53	PASSO_CH_RANGEVIO_TR_OUT[61]	TCPWM0_16_ONE_CNT_TR_IN[45]	SAR1 ch#29, range violation to TCPWM0 Group #0 Counter #45 trig=
54	PASSO_CH_RANGEVIO_TR_OUT[62]	TCPWM0_16_ONE_CNT_TR_IN[46]	SAR1 ch#30, range violation to TCPWM0 Group #0 Counter #46 trig=
55	PASSO_CH_RANGEVIO_TR_OUT[63]	TCPWM0_16_ONE_CNT_TR_IN[47]	SAR1 ch#31, range violation to TCPWM0 Group #0 Counter #47 trig
56	PASS0_CH_RANGEVIO_TR_OUT[64]	TCPWM0_16M_ONE_CNT_TR_IN[2]	SAR2 ch#0, range violation to TCPWM0 Group #1 Counter #02 trig=4
57	PASS0_CH_RANGEVIO_TR_OUT[65]	TCPWM0_16M_ONE_CNT_TR_IN[5]	SAR2 ch#1, range violation to TCPWM0 Group #1 Counter #05 trig=4
58	PASSO_CH_RANGEVIO_TR_OUT[66]	TCPWM0_16M_ONE_CNT_TR_IN[8]	SAR2 ch#2, range violation to TCPWM0 Group #1 Counter #08 trig=4
59	PASSO_CH_RANGEVIO_TR_OUT[67]	TCPWM0_16M_ONE_CNT_TR_IN[11]	SAR2 ch#3, range violation to TCPWM0 Group #1 Counter #11 trig=4
60	PASSO_CH_RANGEVIO_TR_OUT[68]	TCPWM0_16_ONE_CNT_TR_IN[48]	SAR2 ch#4, range violation to TCPWM0 Group #0 Counter #48 trig=4
61	PASSO_CH_RANGEVIO_TR_OUT[69]	TCPWM0_16_ONE_CNT_TR_IN[49]	SAR2 ch#5, range violation to TCPWM0 Group #0 Counter #40 trig=
62		TCPWM0_16_ONE_CNT_TR_IN[49]	
	PASSO_CH_RANGEVIO_TR_OUT[70]		SAR2 ch#6, range violation to TCPWM0 Group #0 Counter #50 trig=
63	PASSO_CH_RANGEVIO_TR_OUT[71]	TCPWM0_16_ONE_CNT_TR_IN[51]	SAR2 ch#7, range violation to TCPWM0 Group #0 Counter #51 trig=4
	4: CANO to P-DMAO Triggers	T	Tana at the action of
0	CAN0_DBG_TR_OUT[0]	PDMA0_TR_IN[16]	CANO, Channel #0 P-DMA0 trigger
1	CAN0_FIFO0_TR_OUT[0]	PDMA0_TR_IN[17]	CANO, Channel #0 FIFO0 trigger
2	CAN0_FIFO1_TR_OUT[0]	PDMA0_TR_IN[18]	CANO, Channel #0 FIFO1 trigger
3	CAN0_DBG_TR_OUT[1]	PDMA0_TR_IN[19]	CANO, Channel #1 P-DMA0 trigger
4	CAN0_FIFO0_TR_OUT[1]	PDMA0_TR_IN[20]	CANO, Channel #1 FIFO0 trigger
5	CAN0_FIFO1_TR_OUT[1]	PDMA0_TR_IN[21]	CANO, Channel #1 FIFO1 trigger
6	CAN0_DBG_TR_OUT[2]	PDMA0_TR_IN[22]	CANO, Channel #2 P-DMA0 trigger
7	CAN0_FIFO0_TR_OUT[2]	PDMA0_TR_IN[23]	CAN0, Channel #2 FIFO0 trigger
8	CAN0_FIFO1_TR_OUT[2]	PDMA0_TR_IN[24]	CAN0, Channel #2 FIFO1 trigger
JX Group	5: CAN1 to P-DMA1 triggers	•	
0	CAN1_DBG_TR_OUT[0]	PDMA1_TR_IN[24]	CAN1, Channel #0 P-DMA01 trigger
1	CAN1_FIFO0_TR_OUT[0]	PDMA1_TR_IN[25]	CAN1, Channel #0 FIFO0 trigger
		PDMA1_TR_IN[26]	CAN1, Channel #0 FIF01 trigger
2	I CANT FIFUL IR OUTIO		
3	CAN1_FIFO1_TR_OUT[0] CAN1_DBG_TR_OUT[1]	PDMA1_TR_IN[27]	CAN1, Channel #1 P-DMA1 trigger

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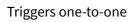




Table 19-1 Triggers 1:1 (continued)

Input	Trigger In	Trigger Out	Description
5	CAN1_FIFO1_TR_OUT[1]	PDMA1_TR_IN[29]	CAN1, Channel #1 FIFO1 trigger
6	CAN1_DBG_TR_OUT[2]	PDMA1_TR_IN[30]	CAN1, Channel #2 P-DMA1 trigger
7	CAN1_FIFO0_TR_OUT[2]	PDMA1_TR_IN[31]	CAN1, Channel #2 FIFO0 trigger
8	CAN1_FIFO1_TR_OUT[2]	PDMA1_TR_IN[32]	CAN1, Channel #2 FIFO1 trigger
MUX Group	6 :Acknowledge triggers from P-DMA0 to CANC)	
0	PDMA0_TR_OUT[16]	CAN0_DBG_TR_ACK[0]	CAN0, Channel #0 P-DMA0 acknowledge
1	PDMA0_TR_OUT[19]	CAN0_DBG_TR_ACK[1]	CAN0, Channel #1 P-DMA0 acknowledge
2	PDMA0_TR_OUT[22]	CAN0_DBG_TR_ACK[2]	CAN0, Channel #2 P-DMA0 acknowledge
MUX Group	7: Acknowledge triggers from P-DMA1 to CAN	1	
0	PDMA1_TR_OUT[24]	CAN1_DBG_TR_ACK[0]	CAN1, Channel #0 P-DMA1 acknowledge
1	PDMA1_TR_OUT[27]	CAN1_DBG_TR_ACK[1]	CAN1, Channel #1 P-DMA1 acknowledge
2	PDMA1_TR_OUT[30]	CAN1_DBG_TR_ACK[2]	CAN1, Channel #2 P-DMA1 acknowledge
MUX Group	8: SCBx to P-DMA1 Triggers		
0	SCB0_TX_TR_OUT	PDMA1_TR_IN[8]	SCB0 TX to P-DMA1 Trigger
1	SCB0_RX_TR_OUT	PDMA1_TR_IN[9]	SCB0 RX to P-DMA1 Trigger
2	SCB1_TX_TR_OUT	PDMA1_TR_IN[10]	SCB1 TX to P-DMA1 Trigger
3	SCB1_RX_TR_OUT	PDMA1_TR_IN[11]	SCB1 RX to P-DMA1 Trigger
4	SCB2_TX_TR_OUT	PDMA1_TR_IN[12]	SCB2 TX to P-DMA1 Trigger
5	SCB2_RX_TR_OUT	PDMA1_TR_IN[13]	SCB2 RX to P-DMA1 Trigger
6	SCB3_TX_TR_OUT	PDMA1_TR_IN[14]	SCB3 TX to P-DMA1 Trigger
7	SCB3_RX_TR_OUT	PDMA1_TR_IN[15]	SCB3 RX to P-DMA1 Trigger
8	SCB4_TX_TR_OUT	PDMA1_TR_IN[16]	SCB4 TX to P-DMA1 Trigger
9	SCB4_RX_TR_OUT	PDMA1_TR_IN[17]	SCB4 RX to P-DMA1 Trigger
10	SCB5_TX_TR_OUT	PDMA1_TR_IN[18]	SCB5 TX to P-DMA1 Trigger
11	SCB5_RX_TR_OUT	PDMA1_TR_IN[19]	SCB5 RX to P-DMA1 Trigger
12	SCB6_TX_TR_OUT	PDMA1_TR_IN[20]	SCB6 TX to P-DMA1 Trigger
13	SCB6_RX_TR_OUT	PDMA1_TR_IN[21]	SCB6 RX to P-DMA1 Trigger
14	SCB7_TX_TR_OUT	PDMA1_TR_IN[22]	SCB7 TX to P-DMA1 Trigger
15	SCB7_RX_TR_OUT	PDMA1_TR_IN[23]	SCB7 RX to P-DMA1 Trigger

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Peripheral clocks



20 Peripheral clocks

Table 20-1 Peripheral clock assignments

Output	Destination	Description
0	PCLK_CPUSS_CLOCK_TRACE_IN	Trace clock
1	PCLK_SMARTIO12_CLOCK	SMART I/O #12
2	PCLK_SMARTIO13_CLOCK	SMART I/O #13
3	PCLK_SMARTIO14_CLOCK	SMART I/O #14
4	PCLK_SMARTIO15_CLOCK	SMART I/O #15
5	PCLK_SMARTIO16_CLOCK	SMART I/O #16
6	PCLK_CANFD0_CLOCK_CAN0	CAN0, Channel #0
7	PCLK_CANFD0_CLOCK_CAN1	CAN0, Channel #1
8	PCLK_CANFD0_CLOCK_CAN2	CAN0, Channel #2
9	PCLK_CANFD1_CLOCK_CAN0	CAN1, Channel #0
10	PCLK_CANFD1_CLOCK_CAN1	CAN1, Channel #1
11	PCLK_CANFD1_CLOCK_CAN2	CAN1, Channel #2
12	PCLK_LIN0_CLOCK_CH_EN0	LIN0, Channel #0
13	PCLK_LIN0_CLOCK_CH_EN1	LIN0, Channel #1
14	PCLK_LIN0_CLOCK_CH_EN2	LIN0, Channel #2
15	PCLK_LIN0_CLOCK_CH_EN3	LIN0, Channel #3
16	PCLK_LIN0_CLOCK_CH_EN4	LIN0, Channel #4
17	PCLK_LIN0_CLOCK_CH_EN5	LIN0, Channel #5
18	PCLK_LIN0_CLOCK_CH_EN6	LIN0, Channel #6
19	PCLK_LIN0_CLOCK_CH_EN7	LIN0, Channel #7
20	PCLK_SCB0_CLOCK	SCB0
21	PCLK_SCB1_CLOCK	SCB1
22	PCLK_SCB2_CLOCK	SCB2
23	PCLK_SCB3_CLOCK	SCB3
24	PCLK_SCB4_CLOCK	SCB4
25	PCLK_SCB5_CLOCK	SCB5
26	PCLK_SCB6_CLOCK	SCB6
27	PCLK_SCB7_CLOCK	SCB7
28	PCLK_PASS0_CLOCK_SAR0	SAR0
29	PCLK_PASS0_CLOCK_SAR1	SAR1
30	PCLK_PASS0_CLOCK_SAR2	SAR2
31	PCLK_TCPWM0_CLOCKS0	TCPWM0 Group #0, Counter #0
32	PCLK_TCPWM0_CLOCKS1	TCPWM0 Group #0, Counter #1
33	PCLK_TCPWM0_CLOCKS2	TCPWM0 Group #0, Counter #2
34	PCLK_TCPWM0_CLOCKS3	TCPWM0 Group #0, Counter #3
35	PCLK_TCPWM0_CLOCKS4	TCPWM0 Group #0, Counter #4
36	PCLK_TCPWM0_CLOCKS5	TCPWM0 Group #0, Counter #5
37	PCLK_TCPWM0_CLOCKS6	TCPWM0 Group #0, Counter #6
38	PCLK_TCPWM0_CLOCKS7	TCPWM0 Group #0, Counter #7

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Peripheral clocks



Table 20-1 Peripheral clock assignments (continued)

Output	Destination	Description
39	PCLK_TCPWM0_CLOCKS8	TCPWM0 Group #0, Counter #8
40	PCLK_TCPWM0_CLOCKS9	TCPWM0 Group #0, Counter #9
41	PCLK_TCPWM0_CLOCKS10	TCPWM0 Group #0, Counter #10
42	PCLK_TCPWM0_CLOCKS11	TCPWM0 Group #0, Counter #11
43	PCLK_TCPWM0_CLOCKS12	TCPWM0 Group #0, Counter #12
44	PCLK_TCPWM0_CLOCKS13	TCPWM0 Group #0, Counter #13
45	PCLK_TCPWM0_CLOCKS14	TCPWM0 Group #0, Counter #14
46	PCLK_TCPWM0_CLOCKS15	TCPWM0 Group #0, Counter #15
47	PCLK_TCPWM0_CLOCKS16	TCPWM0 Group #0, Counter #16
48	PCLK_TCPWM0_CLOCKS17	TCPWM0 Group #0, Counter #17
49	PCLK_TCPWM0_CLOCKS18	TCPWM0 Group #0, Counter #18
50	PCLK_TCPWM0_CLOCKS19	TCPWM0 Group #0, Counter #19
51	PCLK_TCPWM0_CLOCKS20	TCPWM0 Group #0, Counter #20
52	PCLK_TCPWM0_CLOCKS21	TCPWM0 Group #0, Counter #21
53	PCLK_TCPWM0_CLOCKS22	TCPWM0 Group #0, Counter #22
54	PCLK_TCPWM0_CLOCKS23	TCPWM0 Group #0, Counter #23
55	PCLK_TCPWM0_CLOCKS24	TCPWM0 Group #0, Counter #24
56	PCLK_TCPWM0_CLOCKS25	TCPWM0 Group #0, Counter #25
57	PCLK_TCPWM0_CLOCKS26	TCPWM0 Group #0, Counter #26
58	PCLK_TCPWM0_CLOCKS27	TCPWM0 Group #0, Counter #27
59	PCLK_TCPWM0_CLOCKS28	TCPWM0 Group #0, Counter #28
60	PCLK_TCPWM0_CLOCKS29	TCPWM0 Group #0, Counter #29
61	PCLK_TCPWM0_CLOCKS30	TCPWM0 Group #0, Counter #30
62	PCLK_TCPWM0_CLOCKS31	TCPWM0 Group #0, Counter #31
63	PCLK_TCPWM0_CLOCKS32	TCPWM0 Group #0, Counter #32
64	PCLK_TCPWM0_CLOCKS33	TCPWM0 Group #0, Counter #33
65	PCLK_TCPWM0_CLOCKS34	TCPWM0 Group #0, Counter #34
66	PCLK_TCPWM0_CLOCKS35	TCPWM0 Group #0, Counter #35
67	PCLK_TCPWM0_CLOCKS36	TCPWM0 Group #0, Counter #36
68	PCLK_TCPWM0_CLOCKS37	TCPWM0 Group #0, Counter #37
69	PCLK_TCPWM0_CLOCKS38	TCPWM0 Group #0, Counter #38
70	PCLK_TCPWM0_CLOCKS39	TCPWM0 Group #0, Counter #39
71	PCLK_TCPWM0_CLOCKS40	TCPWM0 Group #0, Counter #40
72	PCLK_TCPWM0_CLOCKS41	TCPWM0 Group #0, Counter #41
73	PCLK_TCPWM0_CLOCKS42	TCPWM0 Group #0, Counter #42
74	PCLK_TCPWM0_CLOCKS43	TCPWM0 Group #0, Counter #43
75	PCLK_TCPWM0_CLOCKS44	TCPWM0 Group #0, Counter #44
76	PCLK_TCPWM0_CLOCKS45	TCPWM0 Group #0, Counter #45
77	PCLK_TCPWM0_CLOCKS46	TCPWM0 Group #0, Counter #46
78	PCLK_TCPWM0_CLOCKS47	TCPWM0 Group #0, Counter #47
79	PCLK_TCPWM0_CLOCKS48	TCPWM0 Group #0, Counter #48

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Peripheral clocks



Table 20-1 Peripheral clock assignments (continued)

Output	Destination	Description
80	PCLK_TCPWM0_CLOCKS49	TCPWM0 Group #0, Counter #49
81	PCLK_TCPWM0_CLOCKS50	TCPWM0 Group #0, Counter #50
82	PCLK_TCPWM0_CLOCKS51	TCPWM0 Group #0, Counter #51
83	PCLK_TCPWM0_CLOCKS52	TCPWM0 Group #0, Counter #52
84	PCLK_TCPWM0_CLOCKS53	TCPWM0 Group #0, Counter #53
85	PCLK_TCPWM0_CLOCKS54	TCPWM0 Group #0, Counter #54
86	PCLK_TCPWM0_CLOCKS55	TCPWM0 Group #0, Counter #55
87	PCLK_TCPWM0_CLOCKS56	TCPWM0 Group #0, Counter #56
88	PCLK_TCPWM0_CLOCKS57	TCPWM0 Group #0, Counter #57
89	PCLK_TCPWM0_CLOCKS58	TCPWM0 Group #0, Counter #58
90	PCLK_TCPWM0_CLOCKS59	TCPWM0 Group #0, Counter #59
91	PCLK_TCPWM0_CLOCKS60	TCPWM0 Group #0, Counter #60
92	PCLK_TCPWM0_CLOCKS61	TCPWM0 Group #0, Counter #61
93	PCLK_TCPWM0_CLOCKS62	TCPWM0 Group #0, Counter #62
94	PCLK_TCPWM0_CLOCKS256	TCPWM0 Group #1, Counter #0
95	PCLK_TCPWM0_CLOCKS257	TCPWM0 Group #1, Counter #1
96	PCLK_TCPWM0_CLOCKS258	TCPWM0 Group #1, Counter #2
97	PCLK_TCPWM0_CLOCKS259	TCPWM0 Group #1, Counter #3
98	PCLK_TCPWM0_CLOCKS260	TCPWM0 Group #1, Counter #4
99	PCLK_TCPWM0_CLOCKS261	TCPWM0 Group #1, Counter #5
100	PCLK_TCPWM0_CLOCKS262	TCPWM0 Group #1, Counter #6
101	PCLK_TCPWM0_CLOCKS263	TCPWM0 Group #1, Counter #7
102	PCLK_TCPWM0_CLOCKS264	TCPWM0 Group #1, Counter #8
103	PCLK_TCPWM0_CLOCKS265	TCPWM0 Group #1, Counter #9
104	PCLK_TCPWM0_CLOCKS266	TCPWM0 Group #1, Counter #10
105	PCLK_TCPWM0_CLOCKS267	TCPWM0 Group #1, Counter #11
106	PCLK_TCPWM0_CLOCKS512	TCPWM0 Group #2, Counter #0
107	PCLK_TCPWM0_CLOCKS513	TCPWM0 Group #2, Counter #1
108	PCLK_TCPWM0_CLOCKS514	TCPWM0 Group #2, Counter #2
109	PCLK_TCPWM0_CLOCKS515	TCPWM0 Group #2, Counter #3

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Faults



21 **Faults**

Fault Assignments Table 21-1

Fault	Source	Description
0	CPUSS_MPU_VIO_0	CM0+ SMPU violation DATA0[31:0]: Violating address. DATA1[0]: User read. DATA1[1]: User write. DATA1[2]: User execute. DATA1[3]: Privileged read. DATA1[4]: Privileged write. DATA1[5]: Privileged execute. DATA1[6]: Non-secure. DATA1[6]: Non-secure. DATA1[11:8]: Master identifier. DATA1[31: '0' MPU violation; '1': SMPU violation.
1	CPUSS_MPU_VIO_1	Crypto SMPU violation. See CPUSS_MPU_VIO_0 description.
2	CPUSS_MPU_VIO_2	P-DMA0 MPU/SMPU violation. See CPUSS_MPU_VIO_0 description.
3	CPUSS_MPU_VIO_3	P-DMA1 MPU/SMPU violation. See CPUSS_MPU_VIO_0 description.
4	CPUSS_MPU_VIO_4	M-DMA0 MPU/SMPU violation. See CPUSS_MPU_VIO_0 description.
15	CPUSS_MPU_VIO_15	Test Controller MPU/SMPU violation. See CPUSS_MPU_VIO_0 description.
16	CPUSS_MPU_VIO_16	CM4 system bus AHB-Lite interface MPU violation. See CPUSS_MPU_VIO_0 description.
17	CPUSS_MPU_VIO_17	CM4 code bus AHB-Lite interface MPU violation for non flash controller accesses. See CPUSS_MPU_VIO_0 description.
18	CPUSS_MPU_VIO_18	CM4 code bus AHB-Lite interface MPU violation for flash controller accesses. See CPUSS_MPU_VIO_0 description.
26	PERI_PERI_C_ECC	Peripheral protection SRAM correctable ECC violation DATA0[10:0]: Violating address. DATA1[7:0]: Syndrome of SRAM word.
27	PERI_PERI_NC_ECC	Peripheral protection SRAM non-correctable ECC violation
28	PERI_MS_VIO_0	CM0+ Peripheral Master Interface PPU violation DATA0[31:0]: Violating address. DATA1[0]: User read. DATA1[1]: User write. DATA1[2]: User execute. DATA1[3]: Privileged read. DATA1[4]: Privileged write. DATA1[5]: Privileged execute. DATA1[5]: Non-secure. DATA1[1:8]: Master identifier. DATA1[1:8]: Protection context identifier. DATA1[31:28]: "0": master interface, PPU violation, "1': timeout detected, "2": bus error, other: undefined.
29	PERI_MS_VIO_1	CM4 Peripheral Master Interface PPU violation. See PERI_MS_VIO_0 description.
30	PERI_MS_VIO_2	P-DMA0 Peripheral Master Interface PPU violation. See PERI_MS_VIO_0 description.
31	PERI_MS_VIO_3	P-DMA1 Peripheral Master Interface PPU violation. See PERI_MS_VIO_0 description.
32	PERI_GROUP_VIO_0	Peripheral Group #0 violation. DATA0[31:0]: Violating address. DATA1[0]: User read. DATA1[1]: User write. DATA1[2]: User execute. DATA1[3]: Privileged read. DATA1[4]: Privileged write. DATA1[5]: Privileged execute. DATA1[6]: Non-secure. DATA1[11:8]: Master identifier. DATA1[11:2]: Protection context identifier. DATA1[31:28]: "0": decoder or peripheral bus error, other: undefined.
33	PERI_GROUP_VIO_1	Peripheral Group #1 violation. See PERI_GROUP_VIO_0 description.
34	PERI_GROUP_VIO_2	Peripheral Group #2 violation. See PERI_GROUP_VIO_0 description.
35	PERI_GROUP_VIO_3	Peripheral Group #3 violation. See PERI_GROUP_VIO_0 description.
37	PERI_GROUP_VIO_5	Peripheral Group #5 violation. See PERI_GROUP_VIO_0 description.
37 38	PERI_GROUP_VIO_5 PERI_GROUP_VIO_6	Peripheral Group #5 violation. See PERI_GROUP_VIO_0 description. Peripheral Group #6 violation. See PERI_GROUP_VIO_0 description.

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Faults



Table 21-1 Fault Assignments (continued)

Fault	Source	Description
48	CPUSS_FLASHC_MAIN_BUS_ERROR	Flash controller main flash bus error FAULT_DATA0[26:0]: Violating address. Append 5'b00010 as most significant bits to derive 32-bit system address. FAULT_DATA1[11:8]: Master identifier.
	CPUSS_FLASHC_MAIN_C_ECC	Flash controller main flash correctable ECC violation DATA[26:0]: Violating address. Append 5'b00010 as most significant bits to derive 32-bit system address.
49		DATA1[7:0]: Syndrome of 64-bit word (at address offset 0x00). DATA1[15:8]: Syndrome of 64-bit word (at address offset 0x08). DATA1[23:16]: Syndrome of 64-bit word (at address offset 0x10). DATA1[31:24]: Syndrome of 64-bit word (at address offset 0x18).
50	CPUSS_FLASHC_MAIN_NC_ECC	Flash controller main flash non-correctable ECC violation. See CPUSS_FLASHC_MAIN_C_ECC description.
51	CPUSS_FLASHC_WORK_BUS_ERROR	Flash controller work-flash bus error. See CPUSS_FLASHC_MAIN_BUS_ERR description.
52	CPUSS_FLASHC_WORK_C_ECC	Flash controller work flash correctable ECC violation. DATA0[26:0]: Violating address. Append 5'b00010 as most significant bits to derive 32-bit system address. DATA1[6:0]: Syndrome of 32-bit word.
53	CPUSS_FLASHC_WORK_NC_ECC	Flash controller work-flash non-correctable ECC violation. See CPUSS_FLASHC_WORK_C_ECC description.
54	CPUSS_FLASHC_CM0_CA_C_ECC	Flash controller CM0+ cache correctable ECC violation. DATA0[26:0]: Violating address. DATA1[6:0]: Syndrome of 32-bit SRAM word (at address offset 0x0). DATA1[14:8]: Syndrome of 32-bit SRAM word (at address offset 0x4). DATA1[22:16]: Syndrome of 32-bit SRAM word (at address offset 0x8). DATA1[30:24]: Syndrome of 32-bit SRAM word (at address offset 0xc).
55	CPUSS_FLASHC_CM0_CA_NC_ECC	Flash controller CM0+ cache non-correctable ECC violation. See CPUSS_FLASHC_CM0_CA_C_ECC description.
56	CPUSS_FLASHC_CM4_CA_C_ECC	Flash controller CM4 cache correctable ECC violation. See CPUSS_FLASHC_CM0_CA_C_ECC description.
57	CPUSS_FLASHC_CM4_CA_NC_ECC	Flash controller CM4 cache non-correctable ECC violation. See CPUSS_FLASHC_CM0_CA_C_ECC description.
58	CPUSS_RAMC0_C_ECC	System memory controller 0 correctable ECC violation: DATA0[31:0]: Violating address. DATA1[6:0]: Syndrome of 32-bit SRAM code word.
59	CPUSS_RAMCO_NC_ECC	System memory controller 0 non-correctable ECC violation. See CPUSS_RAMCO_C_ECC description.
60	CPUSS_RAMC1_C_ECC	System memory controller 1 correctable ECC violation. See CPUSS_RAMCO_C_ECC description.
61	CPUSS_RAMC1_NC_ECC	System memory controller 1 non-correctable ECC violation. See CPUSS_RAMCO_C_ECC description.
64	CPUSS_CRYPTO_C_ECC	Crypto memory correctable ECC violation. DATA0[31:0]: Violating address. DATA1[6:0]: Syndrome of Least Significant 32-bit SRAM. DATA1[14:8]: Syndrome of Most Significant 32-bit SRAM.
65	CPUSS_CRYPTO_NC_ECC	Crypto memory non-correctable ECC violation. See CPUSS_CRYPTO_C_ECC description.
70	CPUSS_DW0_C_ECC	P-DMA0 memory correctable ECC violation: DATA0[11:0]: Violating DW SRAM address (word address, assuming byte addressable). DATA1[6:0]: Syndrome of 32-bit SRAM code word.
71	CPUSS_DW0_NC_ECC	P-DMA0 memory non-correctable ECC violation. See CPUSS_DW0_C_ECC description.
72	CPUSS_DW1_C_ECC	P-DMA1 memory correctable ECC violation. See CPUSS_DW0_C_ECC description.
73	CPUSS_DW1_NC_ECC	P-DMA1 memory non-correctable ECC violation. See CPUSS_DW0_C_ECC description.
74	CPUSS_FM_SRAM_C_ECC	Flash code storage SRAM memory correctable ECC violation: DATA0[15:0]: Address location in the eCT Flash SRAM. DATA1[6:0]: Syndrome of 32-bit SRAM word.
75	CPUSS_FM_SRAM_NC_ECC	Flash code storage SRAM memory non-correctable ECC violation: See CPUSS_FM_SRAMC_C_ECC description.
80	CANFD_0_CAN_C_ECC	CANO message buffer correctable ECC violation: DATAO[15:0]: Violating address. DATAO[22:16]: ECC violating data[38:32] from MRAM. DATAO[27:24]: Master ID: 0-7 = CAN channel ID within mxttcanfd cluster, 8 = AHB I/F DATA1[31:0]: ECC violating data[31:0] from MRAM.

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Faults



Table 21-1 **Fault Assignments** (continued)

Fault	Source	Description
81	CANFD_0_CAN_NC_ECC	CANO message buffer non-correctable ECC violation: DATA0[15:0]: Violating address. DATA0[22:16]: ECC violating data[38:32] from MRAM (not for Address Error). DATA0[27:24]: Master ID: 0-7 = CAN channel ID within mxttcanfd cluster, 8 = AHB I/F DATA0[30]: Write access, only possible for Address Error DATA0[31]: Address Error: a CAN channel did an MRAM access above MRAM_SIZE DATA1[31:0]: ECC violating data[31:0] from MRAM (not for Address Error).
82	CANFD_1_CAN_C_ECC	CAN1 message buffer correctable ECC violation. See CANFD_0_CAN_C_ECC description.
83	CANFD_1_CAN_NC_ECC	CAN1 message buffer non-correctable ECC violation. See CANFD_0_CAN_NC_ECC description.
90	SRSS_FAULT_CSV	Consolidated fault output for clock supervisors. Multiple CSV can detect a violation at the same time. DATA0[15:0]: CLK_HF* root CSV violation flags. DATA0[24]: CLK_REF CSV violation flag (reference clock for CLK_HF CSVs) DATA0[25]: CLK_LF CSV violation flag DATA0[26]: CLK_HVILO CSV violation flag
91	SRSS_FAULT_SSV	Consolidated fault output for supply supervisors. Multiple CSV can detect a violation at the same time. DATA0[0]: BOD on VDDA DATA[1]: OVD on VDDA DATA[16]: LVD/HVD #1 DATA0[17]: LVD/HVD #2
92	SRSS_FAULT_MCWDT0	Fault output for MCWDT0 (all sub-counters) Multiple counters can detect a violation at the same time. DATA0[0]: MCWDT sub counter 0 LOWER_LIMIT DATA0[1]: MCWDT sub counter 0 UPPER_LIMIT DATA0[2]: MCWDT sub counter 1 LOWER_LIMIT DATA0[3]: MCWDT sub counter 1 UPPER_LIMIT
93	SRSS_FAULT_MCWDT1	Fault output for MCWDT1 (all sub-counters). See SRSS_FAULT_MCWDT0 description.

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Peripheral Protection Unit Fixed Structure Pairs

22 Peripheral Protection Unit Fixed Structure Pairs

Protection pair is a pair PPU structures, a master and a slave structure. The master structure protects the slave structure, and the slave structure protects resources such as peripheral registers, or the peripheral itself.

Table 22-1 PPU Fixed Structure Pairs

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
0	PERI_MS_PPU_FX_PERI_MAIN	0x40000000	0x00002000	Peripheral Interconnect main
1	PERI_MS_PPU_FX_PERI_SECURE	0x40002000	0x00000004	Peripheral interconnect secure
2	PERI_MS_PPU_FX_PERI_GR0_GROUP	0x40004010	0x00000004	Peripheral Group #0 main
3	PERI_MS_PPU_FX_PERI_GR1_GROUP	0x40004030	0x00000004	Peripheral Group #1 main
4	PERI_MS_PPU_FX_PERI_GR2_GROUP	0x40004050	0x00000004	Peripheral Group #2 main
5	PERI_MS_PPU_FX_PERI_GR3_GROUP	0x40004060	0x00000020	Peripheral Group #3 main
6	PERI_MS_PPU_FX_PERI_GR5_GROUP	0x400040A0	0x00000020	Peripheral Group #5 main
7	PERI_MS_PPU_FX_PERI_GR6_GROUP	0x400040C0	0x00000020	Peripheral Group #6 main
8	PERI_MS_PPU_FX_PERI_GR9_GROUP	0x40004120	0x00000020	Peripheral Group #9 main
9	PERI_MS_PPU_FX_PERI_TR	0x40008000	0x00008000	Peripheral trigger multiplexer
10	PERI_MS_PPU_FX_CRYPTO_MAIN	0x40100000	0x00000400	Crypto main
11	PERI_MS_PPU_FX_CRYPTO_CRYPTO	0x40101000	0x00000800	Crypto MMIO (Memory Mapped I/O)
12	PERI_MS_PPU_FX_CRYPTO_BOOT	0x40102000	0x00000100	Crypto boot
13	PERI_MS_PPU_FX_CRYPTO_KEY0	0x40102100	0x00000004	Crypto Key #0
14	PERI_MS_PPU_FX_CRYPTO_KEY1	0x40102120	0x00000004	Crypto Key #1
15	PERI_MS_PPU_FX_CRYPTO_BUF	0x40108000	0x00002000	Crypto buffer
16	PERI_MS_PPU_FX_CPUSS_CM4	0x40200000	0x00000400	CM4 CPU core
17	PERI_MS_PPU_FX_CPUSS_CM0	0x40201000	0x00001000	CM0+ CPU core
18	PERI_MS_PPU_FX_CPUSS_BOOT ^[34]	0x40202000	0x00000200	CPUSS boot
19	PERI_MS_PPU_FX_CPUSS_CM0_INT	0x40208000	0x00000800	CPUSS CM0+ interrupts
20	PERI_MS_PPU_FX_CPUSS_CM4_INT	0x4020A000	0x00000800	CPUSS CM4 interrupts
21	PERI_MS_PPU_FX_FAULT_STRUCT0_MAIN	0x40210000	0x00000100	CPUSS Fault Structure #0 main
22	PERI_MS_PPU_FX_FAULT_STRUCT1_MAIN	0x40210100	0x00000100	CPUSS Fault Structure #1 main
23	PERI_MS_PPU_FX_FAULT_STRUCT2_MAIN	0x40210200	0x00000100	CPUSS Fault Structure #2 main
24	PERI_MS_PPU_FX_FAULT_STRUCT3_MAIN	0x40210300	0x00000100	CPUSS Fault Structure #3 main
25	PERI_MS_PPU_FX_IPC_STRUCT0_IPC	0x40220000	0x00000020	CPUSS IPC Structure #0
26	PERI_MS_PPU_FX_IPC_STRUCT1_IPC	0x40220020	0x00000020	CPUSS IPC Structure #1
27	PERI_MS_PPU_FX_IPC_STRUCT2_IPC	0x40220040	0x00000020	CPUSS IPC Structure #2
28	PERI_MS_PPU_FX_IPC_STRUCT3_IPC	0x40220060	0x00000020	CPUSS IPC Structure #3
29	PERI_MS_PPU_FX_IPC_STRUCT4_IPC	0x40220080	0x00000020	CPUSS IPC Structure #4
30	PERI_MS_PPU_FX_IPC_STRUCT5_IPC	0x402200A0	0x00000020	CPUSS IPC Structure #5
31	PERI_MS_PPU_FX_IPC_STRUCT6_IPC	0x402200C0	0x00000020	CPUSS IPC Structure #6
32	PERI_MS_PPU_FX_IPC_STRUCT7_IPC	0x402200E0	0x00000020	CPUSS IPC Structure #7
33	PERI_MS_PPU_FX_IPC_INTR_STRUCT0_INTR	0x40221000	0x00000010	CPUSS IPC Interrupt Structure #0
34	PERI_MS_PPU_FX_IPC_INTR_STRUCT1_INTR	0x40221020	0x00000010	CPUSS IPC Interrupt Structure #1
35	PERI_MS_PPU_FX_IPC_INTR_STRUCT2_INTR	0x40221040	0x00000010	CPUSS IPC Interrupt Structure #2
36	PERI_MS_PPU_FX_IPC_INTR_STRUCT3_INTR	0x40221060	0x00000010	CPUSS IPC Interrupt Structure #3
37	PERI_MS_PPU_FX_IPC_INTR_STRUCT4_INTR	0x40221080	0x00000010	CPUSS IPC Interrupt Structure #4
38	PERI_MS_PPU_FX_IPC_INTR_STRUCT5_INTR	0x402210A0	0x00000010	CPUSS IPC Interrupt Structure #5

Note

34. Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

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Table 22-1 PPU Fixed Structure Pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
39	PERI_MS_PPU_FX_IPC_INTR_STRUCT6_INTR	0x402210C0	0x00000010	CPUSS IPC Interrupt Structure #6
40	PERI_MS_PPU_FX_IPC_INTR_STRUCT7_INTR	0x402210E0	0x00000010	CPUSS IPC Interrupt Structure #7
41	PERI_MS_PPU_FX_PROT_SMPU_MAIN	0x40230000	0x00000040	Peripheral protection SMPU main
42	PERI_MS_PPU_FX_PROT_MPU0_MAIN	0x40234000	0x00000004	Peripheral protection MPU #0 main
43	PERI_MS_PPU_FX_PROT_MPU14_MAIN	0x40237800	0x00000004	Peripheral protection MPU #14 main
44	PERI_MS_PPU_FX_PROT_MPU15_MAIN	0x40237C00	0x00000400	Peripheral protection MPU #15 main
45	PERI_MS_PPU_FX_FLASHC_MAIN	0x40240000	0x00000008	Flash controller main
46	PERI_MS_PPU_FX_FLASHC_CMD	0x40240008	0x00000004	Flash controller command
47	PERI_MS_PPU_FX_FLASHC_DFT	0x40240200	0x00000100	Flash controller tests
48	PERI_MS_PPU_FX_FLASHC_CM0	0x40240400	0x00000080	Flash controller CM0+
49	PERI_MS_PPU_FX_FLASHC_CM4	0x40240480	0x00000080	Flash controller CM4
50	PERI_MS_PPU_FX_FLASHC_CRYPTO	0x40240500	0x00000004	Flash controller Crypto
51	PERI_MS_PPU_FX_FLASHC_DW0	0x40240580	0x00000004	Flash controller P-DMA0
52	PERI_MS_PPU_FX_FLASHC_DW1	0x40240600	0x00000004	Flash controller P-DMA1
53	PERI_MS_PPU_FX_FLASHC_DMAC	0x40240680	0x00000004	Flash controller M-DMA0
54	PERI_MS_PPU_FX_FLASHC_FlashMgmt ^[34]	0x4024F000	0x00000080	Flash management
55	PERI_MS_PPU_FX_FLASHC_MainSafety	0x4024F400	0x00000008	Flash controller code-flash safety
56	PERI_MS_PPU_FX_FLASHC_WorkSafety	0x4024F500	0x00000004	Flash controller work-flash safety
57	PERI_MS_PPU_FX_SRSS_GENERAL	0x40260000	0x00000400	SRSS General
58	PERI_MS_PPU_FX_SRSS_MAIN	0x40261000	0x00001000	SRSS main
59	PERI_MS_PPU_FX_SRSS_SECURE	0x40262000	0x00002000	SRSS secure
60	PERI_MS_PPU_FX_MCWDT0_CONFIG	0x40268000	0x00000080	MCWDT #0 configuration
61	PERI_MS_PPU_FX_MCWDT1_CONFIG	0x40268100	0x00000080	MCWDT #1 configuration
62	PERI_MS_PPU_FX_MCWDT0_MAIN	0x40268080	0x00000040	MCWDT #0 main
63	PERI_MS_PPU_FX_MCWDT1_MAIN	0x40268180	0x00000040	MCWDT #1 main
64	PERI_MS_PPU_FX_WDT_CONFIG	0x4026C000	0x00000020	System WDT configuration
65	PERI_MS_PPU_FX_WDT_MAIN	0x4026C040	0x00000020	System WDT main
66	PERI_MS_PPU_FX_BACKUP_BACKUP	0x40270000	0x00010000	SRSS backup
67	PERI_MS_PPU_FX_DW0_DW	0x40280000	0x00000100	P-DMA0 main
68	PERI_MS_PPU_FX_DW1_DW	0x40290000	0x00000100	P-DMA1 main
69	PERI_MS_PPU_FX_DW0_DW_CRC	0x40280100	0x00000080	P-DMA0 CRC
70	PERI_MS_PPU_FX_DW1_DW_CRC	0x40290100	0x00000080	P-DMA1 CRC
71	PERI_MS_PPU_FX_DW0_CH_STRUCT0_CH	0x40288000	0x00000040	P-DMA0 Channel #0
72	PERI_MS_PPU_FX_DW0_CH_STRUCT1_CH	0x40288040	0x00000040	P-DMA0 Channel #1
73	PERI_MS_PPU_FX_DW0_CH_STRUCT2_CH	0x40288080	0x00000040	P-DMA0 Channel #2
74	PERI_MS_PPU_FX_DW0_CH_STRUCT3_CH	0x402880C0	0x00000040	P-DMA0 Channel #3
75	PERI_MS_PPU_FX_DW0_CH_STRUCT4_CH	0x40288100	0x00000040	P-DMA0 Channel #4
76	PERI_MS_PPU_FX_DW0_CH_STRUCT5_CH	0x40288140	0x00000040	P-DMA0 Channel #5
77	PERI_MS_PPU_FX_DW0_CH_STRUCT6_CH	0x40288180	0x00000040	P-DMA0 Channel #6
78	PERI_MS_PPU_FX_DW0_CH_STRUCT7_CH	0x402881C0	0x00000040	P-DMA0 Channel #7
79	PERI_MS_PPU_FX_DW0_CH_STRUCT8_CH	0x40288200	0x00000040	P-DMA0 Channel #8
80	PERI_MS_PPU_FX_DW0_CH_STRUCT9_CH	0x40288240	0x00000040	P-DMA0 Channel #9
81	PERI_MS_PPU_FX_DW0_CH_STRUCT10_CH	0x40288280	0x00000040	P-DMA0 Channel #10
82	PERI_MS_PPU_FX_DW0_CH_STRUCT11_CH	0x402882C0	0x00000040	P-DMA0 Channel #11
83	PERI_MS_PPU_FX_DW0_CH_STRUCT12_CH	0x40288300	0x00000040	P-DMA0 Channel #12

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Table 22-1 PPU Fixed Structure Pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
84	PERI_MS_PPU_FX_DW0_CH_STRUCT13_CH	0x40288340	0x00000040	P-DMA0 Channel #13
85	PERI_MS_PPU_FX_DW0_CH_STRUCT14_CH	0x40288380	0x00000040	P-DMA0 Channel #14
86	PERI_MS_PPU_FX_DW0_CH_STRUCT15_CH	0x402883C0	0x00000040	P-DMA0 Channel #15
87	PERI_MS_PPU_FX_DW0_CH_STRUCT16_CH	0x40288400	0x00000040	P-DMA0 Channel #16
88	PERI_MS_PPU_FX_DW0_CH_STRUCT17_CH	0x40288440	0x00000040	P-DMA0 Channel #17
89	PERI_MS_PPU_FX_DW0_CH_STRUCT18_CH	0x40288480	0x00000040	P-DMA0 Channel #18
90	PERI_MS_PPU_FX_DW0_CH_STRUCT19_CH	0x402884C0	0x00000040	P-DMA0 Channel #19
91	PERI_MS_PPU_FX_DW0_CH_STRUCT20_CH	0x40288500	0x00000040	P-DMA0 Channel #20
92	PERI_MS_PPU_FX_DW0_CH_STRUCT21_CH	0x40288540	0x00000040	P-DMA0 Channel #21
93	PERI_MS_PPU_FX_DW0_CH_STRUCT22_CH	0x40288580	0x00000040	P-DMA0 Channel #22
94	PERI_MS_PPU_FX_DW0_CH_STRUCT23_CH	0x402885C0	0x00000040	P-DMA0 Channel #23
95	PERI_MS_PPU_FX_DW0_CH_STRUCT24_CH	0x40288600	0x00000040	P-DMA0 Channel #24
96	PERI_MS_PPU_FX_DW0_CH_STRUCT25_CH	0x40288640	0x00000040	P-DMA0 Channel #25
97	PERI_MS_PPU_FX_DW0_CH_STRUCT26_CH	0x40288680	0x00000040	P-DMA0 Channel #26
98	PERI_MS_PPU_FX_DW0_CH_STRUCT27_CH	0x402886C0	0x00000040	P-DMA0 Channel #27
99	PERI_MS_PPU_FX_DW0_CH_STRUCT28_CH	0x40288700	0x00000040	P-DMA0 Channel #28
100	PERI_MS_PPU_FX_DW0_CH_STRUCT29_CH	0x40288740	0x00000040	P-DMA0 Channel #29
101	PERI_MS_PPU_FX_DW0_CH_STRUCT30_CH	0x40288780	0x00000040	P-DMA0 Channel #30
102	PERI_MS_PPU_FX_DW0_CH_STRUCT31_CH	0x402887C0	0x00000040	P-DMA0 Channel #31
103	PERI_MS_PPU_FX_DW0_CH_STRUCT32_CH	0x40288800	0x00000040	P-DMA0 Channel #32
104	PERI_MS_PPU_FX_DW0_CH_STRUCT33_CH	0x40288840	0x00000040	P-DMA0 Channel #33
105	PERI_MS_PPU_FX_DW0_CH_STRUCT34_CH	0x40288880	0x00000040	P-DMA0 Channel #34
106	PERI_MS_PPU_FX_DW0_CH_STRUCT35_CH	0x402888C0	0x00000040	P-DMA0 Channel #35
107	PERI_MS_PPU_FX_DW0_CH_STRUCT36_CH	0x40288900	0x00000040	P-DMA0 Channel #36
108	PERI_MS_PPU_FX_DW0_CH_STRUCT37_CH	0x40288940	0x00000040	P-DMA0 Channel #37
109	PERI_MS_PPU_FX_DW0_CH_STRUCT38_CH	0x40288980	0x00000040	P-DMA0 Channel #38
110	PERI_MS_PPU_FX_DW0_CH_STRUCT39_CH	0x402889C0	0x00000040	P-DMA0 Channel #39
111	PERI_MS_PPU_FX_DW0_CH_STRUCT40_CH	0x40288A00	0x00000040	P-DMA0 Channel #40
112	PERI MS PPU FX DW0 CH STRUCT41 CH	0x40288A40	0x00000040	P-DMA0 Channel #41
113	PERI_MS_PPU_FX_DW0_CH_STRUCT42_CH	0x40288A80	0x00000040	P-DMA0 Channel #42
114	PERI_MS_PPU_FX_DW0_CH_STRUCT43_CH	0x40288AC0	0x00000040	P-DMA0 Channel #43
115	PERI_MS_PPU_FX_DW0_CH_STRUCT44_CH	0x40288B00	0x00000040	P-DMA0 Channel #44
116	PERI_MS_PPU_FX_DW0_CH_STRUCT45_CH	0x40288B40	0x00000040	P-DMA0 Channel #45
117	PERI_MS_PPU_FX_DW0_CH_STRUCT46_CH	0x40288B80	0x00000040	P-DMA0 Channel #46
118	PERI_MS_PPU_FX_DW0_CH_STRUCT47_CH	0x40288BC0	0x00000040	P-DMA0 Channel #47
119	PERI_MS_PPU_FX_DW0_CH_STRUCT48_CH	0x40288C00	0x00000040	P-DMA0 Channel #48
120	PERI_MS_PPU_FX_DW0_CH_STRUCT49_CH	0x40288C40	0x00000040	P-DMA0 Channel #49
121	PERI_MS_PPU_FX_DW0_CH_STRUCT50_CH	0x40288C80	0x00000040	P-DMA0 Channel #50
122	PERI_MS_PPU_FX_DW0_CH_STRUCT51_CH	0x40288CC0	0x00000040	P-DMA0 Channel #51
123	PERI_MS_PPU_FX_DW0_CH_STRUCT52_CH	0x40288D00	0x00000040	P-DMA0 Channel #52
124	PERI_MS_PPU_FX_DW0_CH_STRUCT53_CH	0x40288D40	0x00000040	P-DMA0 Channel #53
125	PERI_MS_PPU_FX_DW0_CH_STRUCT54_CH	0x40288D80	0x00000040	P-DMA0 Channel #54
126	PERI_MS_PPU_FX_DW0_CH_STRUCT55_CH	0x40288DC0	0x00000040	P-DMA0 Channel #55
127	PERI_MS_PPU_FX_DW0_CH_STRUCT56_CH	0x40288E00	0x00000040	P-DMA0 Channel #56
128	PERI_MS_PPU_FX_DW0_CH_STRUCT57_CH	0x40288E40	0x00000040	P-DMA0 Channel #57
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PPU Fixed Structure Pairs (continued) **Table 22-1**

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
129	PERI_MS_PPU_FX_DW0_CH_STRUCT58_CH	0x40288E80	0x00000040	P-DMA0 Channel #58
130	PERI_MS_PPU_FX_DW0_CH_STRUCT59_CH	0x40288EC0	0x00000010	P-DMA0 Channel #59
131	PERI_MS_PPU_FX_DW0_CH_STRUCT60_CH	0x40288F00	0x00000040	P-DMA0 Channel #60
-	PERI_MS_PPU_FX_DW0_CH_STRUCT61_CH	0x40288F40	0x00000040	P-DMA0 Channel #61
132	PERI_MS_PPU_FX_DW0_CH_STRUCT62_CH	0x40288F80	0x00000040	P-DMA0 Channel #62
133				
134	PERI_MS_PPU_FX_DW0_CH_STRUCT63_CH	0x40288FC0	0x00000040	P-DMA0 Channel #63
135	PERI_MS_PPU_FX_DW0_CH_STRUCT64_CH	0x40289000	0x00000040	P-DMA0 Channel #64
136	PERI_MS_PPU_FX_DW0_CH_STRUCT65_CH	0x40289040	0x00000040	P-DMA0 Channel #65
137	PERI_MS_PPU_FX_DW0_CH_STRUCT66_CH	0x40289080	0x00000040	P-DMA0 Channel #66
138	PERI_MS_PPU_FX_DW0_CH_STRUCT67_CH	0x402890C0	0x00000040	P-DMA0 Channel #67
139	PERI_MS_PPU_FX_DW0_CH_STRUCT68_CH	0x40289100	0x00000040	P-DMA0 Channel #68
140	PERI_MS_PPU_FX_DW0_CH_STRUCT69_CH	0x40289140	0x00000040	P-DMA0 Channel #69
141	PERI_MS_PPU_FX_DW0_CH_STRUCT70_CH	0x40289180	0x00000040	P-DMA0 Channel #70
142	PERI_MS_PPU_FX_DW0_CH_STRUCT71_CH	0x402891C0	0x00000040	P-DMA0 Channel #71
143	PERI_MS_PPU_FX_DW0_CH_STRUCT72_CH	0x40289200	0x00000040	P-DMA0 Channel #72
144	PERI_MS_PPU_FX_DW0_CH_STRUCT73_CH	0x40289240	0x00000040	P-DMA0 Channel #73
145	PERI_MS_PPU_FX_DW0_CH_STRUCT74_CH	0x40289280	0x00000040	P-DMA0 Channel #74
146	PERI_MS_PPU_FX_DW0_CH_STRUCT75_CH	0x402892C0	0x00000040	P-DMA0 Channel #75
147	PERI_MS_PPU_FX_DW0_CH_STRUCT76_CH	0x40289300	0x00000040	P-DMA0 Channel #76
148	PERI_MS_PPU_FX_DW0_CH_STRUCT77_CH	0x40289340	0x00000040	P-DMA0 Channel #77
149	PERI_MS_PPU_FX_DW0_CH_STRUCT78_CH	0x40289380	0x00000040	P-DMA0 Channel #78
150	PERI_MS_PPU_FX_DW0_CH_STRUCT79_CH	0x402893C0	0x00000040	P-DMA0 Channel #79
151	PERI_MS_PPU_FX_DW0_CH_STRUCT80_CH	0x40289400	0x00000040	P-DMA0 Channel #80
152	PERI_MS_PPU_FX_DW0_CH_STRUCT81_CH	0x40289440	0x00000040	P-DMA0 Channel #81
153	PERI_MS_PPU_FX_DW0_CH_STRUCT82_CH	0x40289480	0x00000040	P-DMA0 Channel #82
154	PERI_MS_PPU_FX_DW0_CH_STRUCT83_CH	0x402894C0	0x00000040	P-DMA0 Channel #83
155	PERI_MS_PPU_FX_DW0_CH_STRUCT84_CH	0x40289500	0x00000040	P-DMA0 Channel #84
156	PERI_MS_PPU_FX_DW0_CH_STRUCT85_CH	0x40289540	0x00000040	P-DMA0 Channel #85
157	PERI_MS_PPU_FX_DW0_CH_STRUCT86_CH	0x40289580	0x00000040	P-DMA0 Channel #86
158	PERI_MS_PPU_FX_DW0_CH_STRUCT87_CH	0x402895C0	0x00000040	P-DMA0 Channel #87
159	PERI_MS_PPU_FX_DW0_CH_STRUCT88_CH	0x40289600	0x00000040	P-DMA0 Channel #88
160	PERI_MS_PPU_FX_DW1_CH_STRUCT0_CH	0x40298000	0x00000040	P-DMA1 Channel #0
161	PERI_MS_PPU_FX_DW1_CH_STRUCT1_CH	0x40298040	0x00000040	P-DMA1 Channel #1
162	PERI_MS_PPU_FX_DW1_CH_STRUCT2_CH	0x40298080	0x00000040	P-DMA1 Channel #2
163	PERI_MS_PPU_FX_DW1_CH_STRUCT3_CH	0x402980C0	0x00000040	P-DMA1 Channel #3
164	PERI_MS_PPU_FX_DW1_CH_STRUCT4_CH	0x40298100	0x00000040	P-DMA1 Channel #4
165	PERI MS PPU FX DW1 CH STRUCT5 CH	0x40298140	0x00000040	P-DMA1 Channel #5
166	PERI_MS_PPU_FX_DW1_CH_STRUCT6_CH	0x40298180	0x00000010	P-DMA1 Channel #6
167	PERI_MS_PPU_FX_DW1_CH_STRUCT7_CH	0x402981C0	0x00000040	P-DMA1 Channel #7
168	PERI_MS_PPU_FX_DW1_CH_STRUCT8_CH	0x40298200	0x00000040	P-DMA1 Channel #8
169	PERI_MS_PPU_FX_DW1_CH_STRUCT9_CH	0x40298200 0x40298240	0x00000040	P-DMA1 Channel #9
	PERI_MS_PPU_FX_DW1_CH_STRUCT10_CH	0x40298240 0x40298280	0x00000040	P-DMA1 Channel #10
170				P-DMA1 Channel #10
171	PERI_MS_PPU_FX_DW1_CH_STRUCT11_CH	0x402982C0	0x00000040	
172	PERI_MS_PPU_FX_DW1_CH_STRUCT12_CH	0x40298300	0x00000040	P-DMA1 Channel #12
173	PERI_MS_PPU_FX_DW1_CH_STRUCT13_CH	0x40298340	0x00000040	P-DMA1 Channel #13

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Table 22-1 PPU Fixed Structure Pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
174	PERI_MS_PPU_FX_DW1_CH_STRUCT14_CH	0x40298380	0x00000040	P-DMA1 Channel #14
175	PERI_MS_PPU_FX_DW1_CH_STRUCT15_CH	0x402983C0	0x00000040	P-DMA1 Channel #15
176	PERI_MS_PPU_FX_DW1_CH_STRUCT16_CH	0x40298400	0x00000040	P-DMA1 Channel #16
177	PERI_MS_PPU_FX_DW1_CH_STRUCT17_CH	0x40298440	0x00000040	P-DMA1 Channel #17
178	PERI_MS_PPU_FX_DW1_CH_STRUCT18_CH	0x40298480	0x00000040	P-DMA1 Channel #18
179	PERI_MS_PPU_FX_DW1_CH_STRUCT19_CH	0x402984C0	0x00000040	P-DMA1 Channel #19
180	PERI_MS_PPU_FX_DW1_CH_STRUCT20_CH	0x40298500	0x00000040	P-DMA1 Channel #20
181	PERI_MS_PPU_FX_DW1_CH_STRUCT21_CH	0x40298540	0x00000040	P-DMA1 Channel #21
182	PERI_MS_PPU_FX_DW1_CH_STRUCT22_CH	0x40298580	0x00000040	P-DMA1 Channel #22
183	PERI_MS_PPU_FX_DW1_CH_STRUCT23_CH	0x402985C0	0x00000040	P-DMA1 Channel #23
184	PERI_MS_PPU_FX_DW1_CH_STRUCT24_CH	0x40298600	0x00000040	P-DMA1 Channel #24
185	PERI_MS_PPU_FX_DW1_CH_STRUCT25_CH	0x40298640	0x00000040	P-DMA1 Channel #25
186	PERI_MS_PPU_FX_DW1_CH_STRUCT26_CH	0x40298680	0x00000040	P-DMA1 Channel #26
187	PERI_MS_PPU_FX_DW1_CH_STRUCT27_CH	0x402986C0	0x00000040	P-DMA1 Channel #27
188	PERI_MS_PPU_FX_DW1_CH_STRUCT28_CH	0x40298700	0x00000040	P-DMA1 Channel #28
189	PERI_MS_PPU_FX_DW1_CH_STRUCT29_CH	0x40298740	0x00000040	P-DMA1 Channel #29
190	PERI_MS_PPU_FX_DW1_CH_STRUCT30_CH	0x40298780	0x00000040	P-DMA1 Channel #30
191	PERI MS PPU FX DW1 CH STRUCT31 CH	0x402987C0	0x00000040	P-DMA1 Channel #31
192	PERI_MS_PPU_FX_DW1_CH_STRUCT32_CH	0x40298800	0x00000040	P-DMA1 Channel #32
193	PERI_MS_PPU_FX_DMAC_TOP	0x402A0000	0x00000010	M-DMA0 main
194	PERI_MS_PPU_FX_DMAC_CH0_CH	0x402A1000	0x00000100	M-DMA0 Channel #0
195	PERI_MS_PPU_FX_DMAC_CH1_CH	0x402A1100	0x00000100	M-DMA0 Channel #1
196	PERI_MS_PPU_FX_DMAC_CH2_CH	0x402A1200	0x00000100	M-DMA0 Channel #2
197	PERI_MS_PPU_FX_DMAC_CH3_CH	0x402A1300	0x00000100	M-DMA0 Channel #3
198	PERI_MS_PPU_FX_EFUSE_CTL	0x402C0000	0x00000200	EFUSE control
199	PERI_MS_PPU_FX_EFUSE_DATA	0x402C0800	0x00000200	EFUSE data
200	PERI_MS_PPU_FX_BIST	0x402F0000	0x00001000	Built-in self test
201	PERI_MS_PPU_FX_HSIOM_PRT0_PRT	0x40300000	0x00000008	HSIOm Port #0
202	PERI MS PPU FX HSIOM PRT1 PRT	0x40300010	0x00000008	HSIOm Port #1
203	PERI_MS_PPU_FX_HSIOM_PRT2_PRT	0x40300020		HSIOm Port #2
204	PERI_MS_PPU_FX_HSIOM_PRT3_PRT	0x40300030	0x00000008	HSIOm Port #3
205	PERI_MS_PPU_FX_HSIOM_PRT4_PRT	0x40300040	0x00000008	HSIOm Port #4
206	PERI MS PPU FX HSIOM PRT5 PRT	0x40300050	0x00000008	HSIOm Port #5
207	PERI_MS_PPU_FX_HSIOM_PRT6_PRT	0x40300060	0x00000008	HSIOm Port #6
208	PERI_MS_PPU_FX_HSIOM_PRT7_PRT	0x40300070	0x00000008	HSIOm Port #7
209	PERI_MS_PPU_FX_HSIOM_PRT8_PRT	0x40300080	0x00000008	HSIOm Port #8
210	PERI MS PPU FX HSIOM PRT9 PRT	0x40300090	0x00000008	HSIOm Port #9
211	PERI_MS_PPU_FX_HSIOM_PRT10_PRT	0x403000A0	0x00000008	HSIOm Port #10
212	PERI_MS_PPU_FX_HSIOM_PRT11_PRT	0x403000B0	0x00000008	HSIOm Port #11
213	PERI_MS_PPU_FX_HSIOM_PRT12_PRT	0x403000C0	0x00000008	HSIOm Port #12
214	PERI_MS_PPU_FX_HSIOM_PRT13_PRT	0x403000D0	0x00000008	HSIOm Port #13
215	PERI_MS_PPU_FX_HSIOM_PRT14_PRT	0x403000E0	0x00000008	HSIOm Port #14
216	PERI_MS_PPU_FX_HSIOM_PRT15_PRT	0x403000F0	0x00000008	HSIOm Port #15
217	PERI_MS_PPU_FX_HSIOM_PRT16_PRT	0x40300100	0x00000008	HSIOm Port #16
218	PERI_MS_PPU_FX_HSIOM_PRT17_PRT	0x40300110	0x00000008	HSIOm Port #17
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Table 22-1 PPU Fixed Structure Pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
219	PERI_MS_PPU_FX_HSIOM_PRT18_PRT	0x40300120	0x00000008	HSIOm Port #18
220	PERI_MS_PPU_FX_HSIOM_PRT19_PRT	0x40300130	0x00000008	HSIOm Port #19
221	PERI_MS_PPU_FX_HSIOM_PRT20_PRT	0x40300140	0x00000008	HSIOm Port #20
222	PERI_MS_PPU_FX_HSIOM_PRT21_PRT	0x40300150	0x00000008	HSIOm Port #21
223	PERI_MS_PPU_FX_HSIOM_PRT22_PRT	0x40300160	0x00000008	HSIOm Port #22
224	PERI_MS_PPU_FX_HSIOM_PRT23_PRT	0x40300170	0x00000008	HSIOm Port #23
225	PERI_MS_PPU_FX_HSIOM_AMUX	0x40302000	0x00000010	HSIOm Analog multiplexer
226	PERI_MS_PPU_FX_HSIOM_MON	0x40302200	0x00000010	HSIOm monitor
227	PERI_MS_PPU_FX_HSIOM_ALTJTAG	0x40302240	0x00000004	HSIOm Alternate JTAG
228	PERI_MS_PPU_FX_GPIO_PRT0_PRT	0x40310000	0x00000040	GPIO_ENH Port #0
229	PERI_MS_PPU_FX_GPIO_PRT1_PRT	0x40310080	0x00000040	GPIO_STD Port #1
230	PERI_MS_PPU_FX_GPIO_PRT2_PRT	0x40310100	0x00000040	GPIO_STD Port #2
231	PERI_MS_PPU_FX_GPIO_PRT3_PRT	0x40310180	0x00000040	GPIO_STD Port #3
232	PERI_MS_PPU_FX_GPIO_PRT4_PRT	0x40310200	0x00000040	GPIO_STD Port #4
233	PERI_MS_PPU_FX_GPIO_PRT5_PRT	0x40310280	0x00000040	GPIO_STD Port #5
234	PERI_MS_PPU_FX_GPIO_PRT6_PRT	0x40310300	0x00000040	GPIO_STD Port #6
235	PERI_MS_PPU_FX_GPIO_PRT7_PRT	0x40310380	0x00000040	GPIO_STD Port #7
236	PERI_MS_PPU_FX_GPIO_PRT8_PRT	0x40310400	0x00000040	GPIO_STD Port #8
237	PERI_MS_PPU_FX_GPIO_PRT9_PRT	0x40310480	0x00000040	GPIO_STD Port #9
238	PERI_MS_PPU_FX_GPIO_PRT10_PRT	0x40310500	0x00000040	GPIO_STD Port #10
239	PERI_MS_PPU_FX_GPIO_PRT11_PRT	0x40310580	0x00000040	GPIO_STD Port #11
240	PERI_MS_PPU_FX_GPIO_PRT12_PRT	0x40310600	0x00000040	GPIO_STD Port #12
241	PERI_MS_PPU_FX_GPIO_PRT13_PRT	0x40310680	0x00000040	GPIO_STD Port #13
242	PERI_MS_PPU_FX_GPIO_PRT14_PRT	0x40310700	0x00000040	GPIO_STD Port #14
243	PERI_MS_PPU_FX_GPIO_PRT15_PRT	0x40310780	0x00000040	GPIO_STD Port #15
244	PERI_MS_PPU_FX_GPIO_PRT16_PRT	0x40310800	0x00000040	GPIO_STD Port #16
245	PERI_MS_PPU_FX_GPIO_PRT17_PRT	0x40310880	0x00000040	GPIO_STD Port #17
246	PERI_MS_PPU_FX_GPIO_PRT18_PRT	0x40310900	0x00000040	GPIO_STD Port #18
247	PERI_MS_PPU_FX_GPIO_PRT19_PRT	0x40310980	0x00000040	GPIO_STD Port #19
248	PERI_MS_PPU_FX_GPIO_PRT20_PRT	0x40310A00	0x00000040	GPIO_STD Port #20
249	PERI_MS_PPU_FX_GPIO_PRT21_PRT	0x40310A80	0x00000040	GPIO_STD Port #21
250	PERI_MS_PPU_FX_GPIO_PRT22_PRT	0x40310B00	0x00000040	GPIO_STD Port #22
251	PERI_MS_PPU_FX_GPIO_PRT23_PRT	0x40310B80	0x00000040	GPIO_STD Port #23
252	PERI_MS_PPU_FX_GPIO_PRT0_CFG	0x40310040	0x00000020	GPIO_ENH Port #0 configuration
253	PERI_MS_PPU_FX_GPIO_PRT1_CFG	0x403100C0	0x00000020	GPIO_STD Port #1 configuration
254	PERI_MS_PPU_FX_GPIO_PRT2_CFG	0x40310140	0x00000020	GPIO_STD Port #2 configuration
255	PERI_MS_PPU_FX_GPIO_PRT3_CFG	0x403101C0	0x00000020	GPIO_STD Port #3 configuration
256	PERI_MS_PPU_FX_GPIO_PRT4_CFG	0x40310240	0x00000020	GPIO_STD Port #4 configuration
257	PERI_MS_PPU_FX_GPIO_PRT5_CFG	0x403102C0	0x00000020	GPIO_STD Port #5 configuration
258	PERI_MS_PPU_FX_GPIO_PRT6_CFG	0x40310340	0x00000020	GPIO_STD Port #6 configuration
259	PERI_MS_PPU_FX_GPIO_PRT7_CFG	0x403103C0	0x00000020	GPIO_STD Port #7 configuration
260	PERI_MS_PPU_FX_GPIO_PRT8_CFG	0x40310440	0x00000020	GPIO_STD Port #8 configuration
261	PERI_MS_PPU_FX_GPIO_PRT9_CFG	0x403104C0	0x00000020	GPIO_STD Port #9 configuration
262	PERI_MS_PPU_FX_GPIO_PRT10_CFG	0x40310540	0x00000020	GPIO_STD Port #10 configuration
263	PERI_MS_PPU_FX_GPIO_PRT11_CFG	0x403105C0	0x00000020	GPIO_STD Port #11 configuration

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Table 22-1 PPU Fixed Structure Pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
264	PERI_MS_PPU_FX_GPIO_PRT12_CFG	0x40310640	0x00000020	GPIO_STD Port #12 configuration
265	PERI_MS_PPU_FX_GPIO_PRT13_CFG	0x403106C0	0x00000020	GPIO_STD Port #13 configuration
266	PERI_MS_PPU_FX_GPIO_PRT14_CFG	0x40310740	0x00000020	GPIO_STD Port #14 configuration
267	PERI_MS_PPU_FX_GPIO_PRT15_CFG	0x403107C0	0x00000020	GPIO_STD Port #15 configuration
268	PERI_MS_PPU_FX_GPIO_PRT16_CFG	0x40310840	0x00000020	GPIO_STD Port #16 configuration
269	PERI_MS_PPU_FX_GPIO_PRT17_CFG	0x403108C0	0x00000020	GPIO_STD Port #17 configuration
270	PERI_MS_PPU_FX_GPIO_PRT18_CFG	0x40310940	0x00000020	GPIO_STD Port #18 configuration
271	PERI_MS_PPU_FX_GPIO_PRT19_CFG	0x403109C0	0x00000020	GPIO_STD Port #19 configuration
272	PERI_MS_PPU_FX_GPIO_PRT20_CFG	0x40310A40	0x00000020	GPIO_STD Port #20 configuration
273	PERI_MS_PPU_FX_GPIO_PRT21_CFG	0x40310AC0	0x00000020	GPIO_STD Port #21 configuration
274	PERI_MS_PPU_FX_GPIO_PRT22_CFG	0x40310B40	0x00000020	GPIO_STD Port #22 configuration
275	PERI_MS_PPU_FX_GPIO_PRT23_CFG	0x40310BC0	0x00000020	GPIO_STD Port #23 configuration
276	PERI_MS_PPU_FX_GPIO_GPIO	0x40314000	0x00000040	GPIO main
277	PERI_MS_PPU_FX_GPIO_TEST	0x40315000	0x00000008	GPIO test
278	PERI_MS_PPU_FX_SMARTIO_PRT12_PRT	0x40320C00	0x00000100	SMART I/O #12
279	PERI_MS_PPU_FX_SMARTIO_PRT13_PRT	0x40320D00	0x00000100	SMART I/O #13
280	PERI_MS_PPU_FX_SMARTIO_PRT14_PRT	0x40320E00	0x00000100	SMART I/O #14
281	PERI_MS_PPU_FX_SMARTIO_PRT15_PRT	0x40320F00	0x00000100	SMART I/O #15
282	PERI_MS_PPU_FX_SMARTIO_PRT17_PRT	0x40321100	0x00000100	SMART I/O #17
283	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT0_CNT	0x40380000	0x00000080	TCPWM0 Group #0, Counter #0
284	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT1_CNT	0x40380080	0x00000080	TCPWM0 Group #0, Counter #1
285	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT2_CNT	0x40380100	0x00000080	TCPWM0 Group #0, Counter #2
286	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT3_CNT	0x40380180	0x00000080	TCPWM0 Group #0, Counter #3
287	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT4_CNT	0x40380200	0x00000080	TCPWM0 Group #0, Counter #4
288	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT5_CNT	0x40380280	0x00000080	TCPWM0 Group #0, Counter #5
289	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT6_CNT	0x40380300	0x00000080	TCPWM0 Group #0, Counter #6
290	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT7_CNT	0x40380380	0x00000080	TCPWM0 Group #0, Counter #7
291	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT8_CNT	0x40380400	0x00000080	TCPWM0 Group #0, Counter #8
292	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT9_CNT	0x40380480	0x00000080	TCPWM0 Group #0, Counter #9
293	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT10_CNT	0x40380500	0x00000080	TCPWM0 Group #0, Counter #10
294	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT11_CNT	0x40380580	0x00000080	TCPWM0 Group #0, Counter #11
295	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT12_CNT	0x40380600	0x00000080	TCPWM0 Group #0, Counter #12
296	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT13_CNT	0x40380680	0x00000080	TCPWM0 Group #0, Counter #13
297	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT14_CNT	0x40380700	0x00000080	TCPWM0 Group #0, Counter #14
298	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT15_CNT	0x40380780	0x00000080	TCPWM0 Group #0, Counter #15
299	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT16_CNT	0x40380800	0x00000080	TCPWM0 Group #0, Counter #16
300	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT17_CNT	0x40380880	0x00000080	TCPWM0 Group #0, Counter #17
301	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT18_CNT	0x40380900	0x00000080	TCPWM0 Group #0, Counter #18
302	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT19_CNT	0x40380980	0x00000080	TCPWM0 Group #0, Counter #19
303	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT20_CNT	0x40380A00	0x00000080	TCPWM0 Group #0, Counter #20
304	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT21_CNT	0x40380A80	0x00000080	TCPWM0 Group #0, Counter #21
305	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT22_CNT	0x40380B00	0x00000080	TCPWM0 Group #0, Counter #22
306	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT23_CNT	0x40380B80	0x00000080	TCPWM0 Group #0, Counter #23
307	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT24_CNT	0x40380C00	0x00000080	TCPWM0 Group #0, Counter #24
308	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT25_CNT	0x40380C80	0x00000080	TCPWM0 Group #0, Counter #25

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Table 22-1 PPU Fixed Structure Pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
309	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT26_CNT	0x40380D00	0x00000080	TCPWM0 Group #0, Counter #26
310	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT27_CNT	0x40380D80	0x00000080	TCPWM0 Group #0, Counter #27
311	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT28_CNT	0x40380E00	0x00000080	TCPWM0 Group #0, Counter #28
312	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT29_CNT	0x40380E80	0x00000080	TCPWM0 Group #0, Counter #29
313	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT30_CNT	0x40380F00	0x00000080	TCPWM0 Group #0, Counter #30
314	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT31_CNT	0x40380F80	0x00000080	TCPWM0 Group #0, Counter #31
315	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT32_CNT	0x40381000	0x00000080	TCPWM0 Group #0, Counter #32
316	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT33_CNT	0x40381080	0x00000080	TCPWM0 Group #0, Counter #33
317	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT34_CNT	0x40381100	0x00000080	TCPWM0 Group #0, Counter #34
318	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT35_CNT	0x40381180	0x00000080	TCPWM0 Group #0, Counter #35
319	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT36_CNT	0x40381200	0x00000080	TCPWM0 Group #0, Counter #36
320	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT37_CNT	0x40381280	0x00000080	TCPWM0 Group #0, Counter #37
321	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT38_CNT	0x40381300	0x00000080	TCPWM0 Group #0, Counter #38
322	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT39_CNT	0x40381380	0x00000080	TCPWM0 Group #0, Counter #39
323	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT40_CNT	0x40381400	0x00000080	TCPWM0 Group #0, Counter #40
324	PERI MS PPU FX TCPWM0 GRP0 CNT41 CNT	0x40381480	0x00000000	TCPWM0 Group #0, Counter #41
325	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT42_CNT	0x40381500	0x00000000	TCPWM0 Group #0, Counter #42
326	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT43_CNT	0x40381580	0x00000000	TCPWM0 Group #0, Counter #43
327	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT44_CNT	0x40381600	0x00000080	TCPWM0 Group #0, Counter #44
328	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT45_CNT	0x40381680	0x00000080	TCPWM0 Group #0, Counter #45
329	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT46_CNT	0x40381700	0x00000080	TCPWM0 Group #0, Counter #46
330	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT47_CNT	0x40381780	0x00000000	TCPWM0 Group #0, Counter #47
331	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT48_CNT	0x40381800	0x00000000	TCPWM0 Group #0, Counter #48
332	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT49_CNT	0x40381880	0x00000000	TCPWM0 Group #0, Counter #49
333	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT50_CNT	0x40381900	0x00000080	TCPWM0 Group #0, Counter #50
	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT51_CNT	0x40381980	0x00000080	TCPWM0 Group #0, Counter #51
334	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT52_CNT	0x40381900 0x40381A00	0x00000080	TCPWM0 Group #0, Counter #52
335	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT53_CNT	0x40381A00	0x00000080	TCPWM0 Group #0, Counter #53
336	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT54_CNT	0x40381A80	0x00000080	TCPWM0 Group #0, Counter #54
337				• •
338	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT55_CNT PERI_MS_PPU_FX_TCPWM0_GRP0_CNT56_CNT	0x40381B80 0x40381C00	0x00000080 0x00000080	TCPWM0 Group #0, Counter #55 TCPWM0 Group #0, Counter #56
339				TCPWM0 Group #0, Counter #56
340	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT57_CNT PERI_MS_PPU_FX_TCPWM0_GRP0_CNT58_CNT	0x40381C80 0x40381D00	0x00000080 0x00000080	TCPWM0 Group #0, Counter #57
341	PERI MS PPU FX TCPWM0 GRP0 CNT59 CNT	0x40381D00	0x00000080	TCPWM0 Group #0, Counter #59
342			0x00000080	' '
343	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT60_CNT	0x40381E00	0x00000080	TCPWM0 Group #0, Counter #60 TCPWM0 Group #0, Counter #61
344	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT61_CNT	0x40381E80		' '
345	PERI_MS_PPU_FX_TCPWM0_GRP0_CNT62_CNT	0x40381F00	0x00000080	TCPWM0 Group #1, Counter #62
346	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT0_CNT	0x40388000	0x00000080	TCPWM0 Group #1, Counter #0
347	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT1_CNT	0x40388080	0x00000080	TCPWM0 Group #1, Counter #1
348	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT2_CNT	0x40388100	0x00000080	TCPWM0 Group #1, Counter #2
349	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT3_CNT	0x40388180	0x00000080	TCPWM0 Group #1, Counter #3
350	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT4_CNT	0x40388200	0x00000080	TCPWM0 Group #1, Counter #4
351	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT5_CNT	0x40388280	0x00000080	TCPWM0 Group #1, Counter #5
352	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT6_CNT	0x40388300	0x00000080	TCPWM0 Group #1, Counter #6
353	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT7_CNT	0x40388380	0x00000080	TCPWM0 Group #1, Counter #7

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Table 22-1 PPU Fixed Structure Pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
354	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT8_CNT	0x40388400	0x00000080	TCPWM0 Group #1, Counter #8
355	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT9_CNT	0x40388480	0x00000080	TCPWM0 Group #1, Counter #9
356	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT10_CNT	0x40388500	0x00000080	TCPWM0 Group #1, Counter #10
357	PERI_MS_PPU_FX_TCPWM0_GRP1_CNT11_CNT	0x40388580	0x00000080	TCPWM0 Group #1, Counter #11
358	PERI_MS_PPU_FX_TCPWM0_GRP2_CNT0_CNT	0x40390000	0x00000080	TCPWM0 Group #2, Counter #0
359	PERI_MS_PPU_FX_TCPWM0_GRP2_CNT1_CNT	0x40390080	0x00000080	TCPWM0 Group #2, Counter #1
360	PERI_MS_PPU_FX_TCPWM0_GRP2_CNT2_CNT	0x40390100	0x00000080	TCPWM0 Group #2, Counter #2
361	PERI_MS_PPU_FX_TCPWM0_GRP2_CNT3_CNT	0x40390180	0x00000080	TCPWM0 Group #2, Counter #3
362	PERI_MS_PPU_FX_EVTGEN0	0x403F0000	0x00001000	Event generator #0
363	PERI_MS_PPU_FX_LIN0_MAIN	0x40500000	0x00000008	LINO, main
364	PERI_MS_PPU_FX_LIN0_CH0_CH	0x40508000	0x00000100	LINO, Channel #0
365	PERI_MS_PPU_FX_LIN0_CH1_CH	0x40508100	0x00000100	LINO, Channel #1
366	PERI_MS_PPU_FX_LIN0_CH2_CH	0x40508200	0x00000100	LIN0, Channel #2
367	PERI_MS_PPU_FX_LIN0_CH3_CH	0x40508300	0x00000100	LINO, Channel #3
368	PERI_MS_PPU_FX_LIN0_CH4_CH	0x40508400	0x00000100	LINO, Channel #4
369	PERI_MS_PPU_FX_LIN0_CH5_CH	0x40508500	0x00000100	LINO, Channel #5
370	PERI_MS_PPU_FX_LIN0_CH6_CH	0x40508600	0x00000100	LINO, Channel #6
371	PERI_MS_PPU_FX_LIN0_CH7_CH	0x40508700	0x00000100	LINO, Channel #7
372	PERI_MS_PPU_FX_CANFD0_CH0_CH	0x40520000	0x00000200	CAN0, Channel #0
373	PERI_MS_PPU_FX_CANFD0_CH1_CH	0x40520200	0x00000200	CAN0, Channel #1
374	PERI_MS_PPU_FX_CANFD0_CH2_CH	0x40520400	0x00000200	CAN0, Channel #2
375	PERI_MS_PPU_FX_CANFD1_CH0_CH	0x40540000	0x00000200	CAN1, Channel #0
376	PERI_MS_PPU_FX_CANFD1_CH1_CH	0x40540200	0x00000200	CAN1, Channel #1
377	PERI_MS_PPU_FX_CANFD1_CH2_CH	0x40540400	0x00000200	CAN1, Channel #2
378	PERI_MS_PPU_FX_CANFD0_MAIN	0x40521000	0x00000100	CAN0 main
379	PERI_MS_PPU_FX_CANFD1_MAIN	0x40541000	0x00000100	CAN1 main
380	PERI_MS_PPU_FX_CANFD0_BUF	0x40530000	0x00010000	CAN0 buffer
381	PERI_MS_PPU_FX_CANFD1_BUF	0x40550000	0x00010000	CAN1 buffer
382	PERI_MS_PPU_FX_SCB0	0x40600000	0x00010000	SCB0
383	PERI_MS_PPU_FX_SCB1	0x40610000	0x00010000	SCB1
384	PERI_MS_PPU_FX_SCB2	0x40620000	0x00010000	SCB2
385	PERI_MS_PPU_FX_SCB3	0x40630000	0x00010000	SCB3
386	PERI_MS_PPU_FX_SCB4	0x40640000	0x00010000	SCB4
387	PERI_MS_PPU_FX_SCB5	0x40650000	0x00010000	SCB5
388	PERI_MS_PPU_FX_SCB6	0x40660000	0x00010000	SCB6
389	PERI_MS_PPU_FX_SCB7	0x40670000	0x00010000	SCB7
390	PERI_MS_PPU_FX_PASS0_SAR0_SAR	0x40900000	0x00000400	PASS SAR0
391	PERI_MS_PPU_FX_PASS0_SAR1_SAR	0x40901000	0x00000400	PASS SAR1
392	PERI_MS_PPU_FX_PASS0_SAR2_SAR	0x40902000	0x00000400	PASS SAR2
393	PERI_MS_PPU_FX_PASS0_SAR0_CH0_CH	0x40900800	0x00000040	SAR0, Channel #0
394	PERI_MS_PPU_FX_PASS0_SAR0_CH1_CH	0x40900840	0x00000040	SAR0, Channel #1
395	PERI_MS_PPU_FX_PASS0_SAR0_CH2_CH	0x40900880	0x00000040	SAR0, Channel #2
396	PERI_MS_PPU_FX_PASS0_SAR0_CH3_CH	0x409008C0	0x00000040	SAR0, Channel #3
397	PERI_MS_PPU_FX_PASS0_SAR0_CH4_CH	0x40900900	0x00000040	SAR0, Channel #4
398	PERI_MS_PPU_FX_PASS0_SAR0_CH5_CH	0x40900940	0x00000040	SAR0, Channel #5

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Table 22-1 PPU Fixed Structure Pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
399	PERI_MS_PPU_FX_PASS0_SAR0_CH6_CH	0x40900980	0x00000040	SAR0, Channel #6
400	PERI_MS_PPU_FX_PASS0_SAR0_CH7_CH	0x409009C0	0x00000040	SAR0, Channel #7
401	PERI_MS_PPU_FX_PASS0_SAR0_CH8_CH	0x40900A00	0x00000040	SAR0, Channel #8
402	PERI_MS_PPU_FX_PASS0_SAR0_CH9_CH	0x40900A40	0x00000040	SAR0, Channel #9
403	PERI_MS_PPU_FX_PASS0_SAR0_CH10_CH	0x40900A80	0x00000040	SAR0, Channel #10
404	PERI_MS_PPU_FX_PASS0_SAR0_CH11_CH	0x40900AC0	0x00000040	SAR0, Channel #11
405	PERI_MS_PPU_FX_PASS0_SAR0_CH12_CH	0x40900B00	0x00000040	SAR0, Channel #12
406	PERI_MS_PPU_FX_PASS0_SAR0_CH13_CH	0x40900B40	0x00000040	SAR0, Channel #13
407	PERI_MS_PPU_FX_PASS0_SAR0_CH14_CH	0x40900B80	0x00000040	SAR0, Channel #14
408	PERI_MS_PPU_FX_PASS0_SAR0_CH15_CH	0x40900BC0	0x00000040	SAR0, Channel #15
409	PERI_MS_PPU_FX_PASS0_SAR0_CH16_CH	0x40900C00	0x00000040	SAR0, Channel #16
410	PERI_MS_PPU_FX_PASS0_SAR0_CH17_CH	0x40900C40	0x00000040	SAR0, Channel #17
411	PERI_MS_PPU_FX_PASS0_SAR0_CH18_CH	0x40900C80	0x00000040	SAR0, Channel #18
412	PERI_MS_PPU_FX_PASS0_SAR0_CH19_CH	0x40900CC0	0x00000040	SAR0, Channel #19
413	PERI_MS_PPU_FX_PASS0_SAR0_CH20_CH	0x40900D00	0x00000040	SAR0, Channel #20
414	PERI_MS_PPU_FX_PASS0_SAR0_CH21_CH	0x40900D40	0x00000040	SAR0, Channel #21
415	PERI_MS_PPU_FX_PASS0_SAR0_CH22_CH	0x40900D80	0x00000040	SAR0, Channel #22
416	PERI_MS_PPU_FX_PASS0_SAR0_CH23_CH	0x40900DC0	0x00000040	SAR0, Channel #23
417	PERI_MS_PPU_FX_PASS0_SAR1_CH0_CH	0x40901800	0x00000040	SAR1, Channel #0
418	PERI_MS_PPU_FX_PASS0_SAR1_CH1_CH	0x40901840	0x00000040	SAR1, Channel #1
419	PERI_MS_PPU_FX_PASS0_SAR1_CH2_CH	0x40901880	0x00000040	SAR1, Channel #2
420	PERI_MS_PPU_FX_PASS0_SAR1_CH3_CH	0x409018C0	0x00000040	SAR1, Channel #3
421	PERI_MS_PPU_FX_PASS0_SAR1_CH4_CH	0x40901900	0x00000040	SAR1, Channel #4
422	PERI_MS_PPU_FX_PASS0_SAR1_CH5_CH	0x40901940	0x00000040	SAR1, Channel #5
423	PERI_MS_PPU_FX_PASS0_SAR1_CH6_CH	0x40901980	0x00000040	SAR1, Channel #6
424	PERI_MS_PPU_FX_PASS0_SAR1_CH7_CH	0x409019C0	0x00000040	SAR1, Channel #7
425	PERI_MS_PPU_FX_PASS0_SAR1_CH8_CH	0x40901A00	0x00000040	SAR1, Channel #8
426	PERI_MS_PPU_FX_PASS0_SAR1_CH9_CH	0x40901A40	0x00000040	SAR1, Channel #9
427	PERI_MS_PPU_FX_PASS0_SAR1_CH10_CH	0x40901A80	0x00000040	SAR1, Channel #10
428	PERI_MS_PPU_FX_PASS0_SAR1_CH11_CH	0x40901AC0	0x00000040	SAR1, Channel #11
429	PERI_MS_PPU_FX_PASS0_SAR1_CH12_CH	0x40901B00	0x00000040	SAR1, Channel #12
430	PERI_MS_PPU_FX_PASS0_SAR1_CH13_CH	0x40901B40	0x00000040	SAR1, Channel #13
431	PERI_MS_PPU_FX_PASS0_SAR1_CH14_CH	0x40901B80	0x00000040	SAR1, Channel #14
432	PERI_MS_PPU_FX_PASS0_SAR1_CH15_CH	0x40901BC0	0x00000040	SAR1, Channel #15
433	PERI_MS_PPU_FX_PASS0_SAR1_CH16_CH	0x40901C00	0x00000040	SAR1, Channel #16
434	PERI_MS_PPU_FX_PASS0_SAR1_CH17_CH	0x40901C40	0x00000040	SAR1, Channel #17
435	PERI_MS_PPU_FX_PASS0_SAR1_CH18_CH	0x40901C80	0x00000040	SAR1, Channel #18
436	PERI_MS_PPU_FX_PASS0_SAR1_CH19_CH	0x40901CC0	0x00000040	SAR1, Channel #19
437	PERI_MS_PPU_FX_PASS0_SAR1_CH20_CH	0x40901D00	0x00000040	SAR1, Channel #20
438	PERI_MS_PPU_FX_PASSO_SAR1_CH21_CH	0x40901D40	0x00000040	SAR1, Channel #21
439	PERI_MS_PPU_FX_PASS0_SAR1_CH22_CH	0x40901D80	0x00000040	SAR1, Channel #22
440	PERI_MS_PPU_FX_PASSO_SAR1_CH23_CH	0x40901DC0	0x00000040	SAR1, Channel #23
441	PERI_MS_PPU_FX_PASSO_SAR1_CH24_CH	0x40901E00	0x00000040	SAR1, Channel #24
442	PERI_MS_PPU_FX_PASS0_SAR1_CH25_CH	0x40901E40	0x00000040	SAR1, Channel #25
443	PERI_MS_PPU_FX_PASS0_SAR1_CH26_CH	0x40901E80	0x00000040	SAR1, Channel #26

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Table 22-1 PPU Fixed Structure Pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
444	PERI_MS_PPU_FX_PASS0_SAR1_CH27_CH	0x40901EC0	0x00000040	SAR1, Channel #27
445	PERI_MS_PPU_FX_PASS0_SAR1_CH28_CH	0x40901F00	0x00000040	SAR1, Channel #28
446	PERI_MS_PPU_FX_PASS0_SAR1_CH29_CH	0x40901F40	0x00000040	SAR1, Channel #29
447	PERI_MS_PPU_FX_PASS0_SAR1_CH30_CH	0x40901F80	0x00000040	SAR1, Channel #30
448	PERI_MS_PPU_FX_PASS0_SAR1_CH31_CH	0x40901FC0	0x00000040	SAR1, Channel #31
449	PERI_MS_PPU_FX_PASS0_SAR2_CH0_CH	0x40902800	0x00000040	SAR2, Channel #0
450	PERI_MS_PPU_FX_PASS0_SAR2_CH1_CH	0x40902840	0x00000040	SAR2, Channel #1
451	PERI_MS_PPU_FX_PASS0_SAR2_CH2_CH	0x40902880	0x00000040	SAR2, Channel #2
452	PERI_MS_PPU_FX_PASS0_SAR2_CH3_CH	0x409028C0	0x00000040	SAR2, Channel #3
453	PERI_MS_PPU_FX_PASS0_SAR2_CH4_CH	0x40902900	0x00000040	SAR2, Channel #4
454	PERI_MS_PPU_FX_PASS0_SAR2_CH5_CH	0x40902940	0x00000040	SAR2, Channel #5
455	PERI_MS_PPU_FX_PASS0_SAR2_CH6_CH	0x40902980	0x00000040	SAR2, Channel #6
456	PERI_MS_PPU_FX_PASS0_SAR2_CH7_CH	0x409029C0	0x00000040	SAR2, Channel #7
457	PERI_MS_PPU_FX_PASS0_TOP	0x409F0000	0x00001000	PASS0 SAR main

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Bus masters



23 Bus masters

The Arbiter (part of flash controller) performs priority-based arbitration based on the master identifier. Each bus master has a dedicated 4-bit master identifier. This master identifier is used for bus arbitration and IPC functionality.

Table 23-1 Bus masters for access and protection control

ID No.	Master ID	Description
0	CPUSS_MS_ID_CM0	Master ID for CM0+
1	CPUSS_MS_ID_CRYPTO	Master ID for Crypto
2	CPUSS_MS_ID_DW0	Master ID for P-DMA 0
3	CPUSS_MS_ID_DW1	Master ID for P-DMA 1
4	CPUSS_MS_ID_DMAC	Master ID for M-DMA0
14	CPUSS_MS_ID_CM4	Master ID for CM4
15	CPUSS_MS_ID_TC	Master ID for DAP Tap Controller

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Miscellaneous configuration



24 Miscellaneous configuration

Table 24-1 Miscellaneous configuration for CYT2B7 devices

Sl. No.	Configuration	Number/ Instances	Description
0	SRSS_NUM_CLKPATH	4	Number of clock paths. One for each of FLL, PLL, Direct and CSV
1	SRSS_NUM_HFROOT	3	Number of CLK_HFs present
2	PERI_PC_NR	8	Number of protection contexts
3	PERI_CLOCK_NR	110	Number of programmable clocks (outputs)
4	PERI_DIV_8_NR	32	Number of divide-by-8 clock dividers
5	PERI_DIV_16_NR	16	Number of divide-by-16 clock dividers
6	PERI_DIV_24_5_NR	8	Number of divide-by-24.5 clock dividers
7	CPUSS_CM0P_MPU_NR	8	Number of MPU regions in CM0+
8	CPUSS_CM4_MPU_NR	8	Number of MPU regions in CM4
9	CPUSS_CRYPTO_BUFF_SIZE	2048	Number of 32-bit words in the IP internal memory buffer (to allow for a 256-B, 512-B, 1-KB, 2-KB, 4-KB, 8-KB, 16-KB, and 32-KB memory buffer)
10	CPUSS_FAULT_FAULT_NR	4	Number of fault structures
11	CPUSS_IPC_IPC_NR	8	Number of IPC structures 0 - Reserved for CM0+ access 1 - Reserved for CM4 access 2 - Reserved for DAP access Remaining for user purposes
12	SCBx_EZ_DATA_NR	256	Number of EZ memory bytes. This memory is used in EZ mode, CMD_RESP mode and FIFO mode. Note: Only SCB0 supports CMD_RESP mode
13	CPUSS_PROT_SMPU_STRUCT_NR	16	Number of SMPU protection structures
14	TCPWM_TR_ONE_CNT_NR	3	Number of input triggers per counter, routed to one counter
15	TCPWM_TR_ALL_CNT_NR	27	Number of input triggers routed to all counters, based on the pin package
16	TCPWM_GRP_NR	3	Number of TCPWM0 counter groups
17	TCPWM_GRP_NR0_GRP_GRP_CNT_NR	63	Number of counters per TCPWM0 Group #0
18	TCPWM_GRP_NR0_CNT_GRP_CNT_WIDTH	16	Counter width in number of bits per TCPWM0 Group #0
19	TCPWM_GRP_NR1_GRP_GRP_CNT_NR	12	Number of counters per TCPWM0 Group #1
20	TCPWM_GRP_NR1_CNT_GRP_CNT_WIDTH	16	Counter width in number of bits per TCPWM0 Group #1
21	TCPWM_GRP_NR2_GRP_GRP_CNT_NR	4	Number of counters per TCPWM0 Group #2
22	TCPWM_GRP_NR2_CNT_GRP_CNT_WIDTH	32	Counter width in number of bits per TCPWM0 Group #2
23	CANFD0_MRAM_SIZE / CANFD1_MRAM_SIZE	24	Message RAM size in KB shared by all the channels
24	EVTGEN_COMP_STRUCT_NR	11	Number of Event Generator comparator structures

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Development support



25 Development support

CYT2B7 has a rich set of documentation, programming tools, and online resources to assist during the development process. Visit **www.infineon.com** to find out more.

25.1 Documentation

A suite of documentation supports CYT2B7 to ensure that you can find answers to your questions quickly. This section contains a list of some of the key documents.

25.1.1 Software user guide

A step-by-step guide for using the sample driver library along with third-party IDEs such as IAR EWARM and GHS Multi.

25.1.2 Technical reference manual

The Technical Reference Manual (TRM) contains all the technical detail needed to use a CYT2B7 device, including a complete description of all registers. The TRM is available in the documentation section at **www.infineon.com**.

25.2 Tools

CYT2B7 is supported on third-party development tool ecosystems such as IAR and GHS. CYT2B7 is also supported by Infineon programming utilities for programming, erasing, or reading using Infineon's MiniProg4 or Segger J-link. More details are available in the documentation section at www.infineon.com.

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26.1 Absolute maximum ratings

Use of this device under conditions outside the min and max limits listed in Table 26-1 may cause permanent damage to the device. Exposure to conditions within the limits of Table 26-1 but beyond those of normal operation for extended periods of time may affect device reliability. The maximum storage temperature is 150 °C in compliance with JEDEC Standard JESD22-A103, High Temperature Storage Life. When operated under conditions within the limits of **Table 26-1** but beyond those of normal operation, the device may not operate to specification.

Power considerations

The average chip-junction temperature, T_J, in °C, may be calculated using Equation 1:

$$T_J = T_A + (P_D \times \theta_{JA})$$
 Equation. 1

Where:

 T_A is the ambient temperature in °C.

 θ_{JA} is the package junction-to-ambient thermal resistance, in °C/W.

 P_D is the sum of P_{INT} and P_{IO} ($P_D = P_{INT} + P_{IO}$).

 P_{INT} is the chip internal power. $(P_{INT} = V_{DDD} \times I_{DD} + V_{DDA} \times I_{A})$

P_{IO} represents the power dissipation on input and output pins; user determined.

For most applications, $P_{IO} < P_{INT}$ and may be neglected.

On the other hand, P_{IO} may be significant if the device is configured to continuously drive external modules and/or memories.

Table 26-1 Absolute maximum ratings

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID10	V _{DDD_ABS}	V _{DDD} power supply voltage ^[35]	V _{SSD} - 0.3	-	V _{SSD} + 6.0	V	For ports 0, 1, 2, 3, 4, 5, 16, 17, 18, 19, 20, 21, 22, 23
SID10B	V _{DDIO_1_ABS}	V _{DDIO_1} power supply voltage ^[35]	V _{SSD} - 0.3	-	V _{SSD} + 6.0	V	V _{DDIO_1} ≥ V _{DDD} For ports 6, 7, 8, 9 ^[36]
SID10C1	V _{DDIO_2_ABS}	V _{DDIO_2} power supply voltage ^[35]	V _{SSD} - 0.3	-	V _{SSD} + 6.0	V	For ports 10, 11, 12, 13, 14, 15
SID11	V _{DDA_ABS}	V _{DDA} analog power supply voltage ^[35]	V _{SSA} - 0.3	-	V _{SSA} + 6.0	V	$V_{DDIO_2} = V_{DDA}$
SID12	V _{REFH_ABS}	Analog reference voltage, HIGH [35]	V _{SSA} - 0.3	-	V _{SSA} + 6.0	V	$V_{REFH} \le V_{DDA} + 0.3 V$
SID12A	V _{REFL_ABS}	Analog reference voltage, LOW ^[35]	V _{SSA} - 0.3	-	V _{SSA} + 0.3	V	
SID15A	V _{I0_ABS0}	Input voltage ^[35]	V _{SSD} - 0.5	-	V _{DDD} + 0.5	V	For ports 0, 1, 2, 3, 4, 5, 16, 17, 18, 19, 20, 21, 22, 23
SID15B	V _{I1_ABS1}	Input voltage ^[35]	V _{SSD} - 0.5	-	V _{DDIO_1} + 0.5	V	For ports 6, 7, 8, 9 ^[36]
SID15C	V _{I2_ABS2}	Input voltage ^[35]	V _{SSD} - 0.5	-	V _{DDIO_2} + 0.5	V	For ports 10, 11, 12, 13, 14, 15
SID16	V _{IA_ABS}	Analog input voltage ^[35]	V _{SSA} - 0.3	-	V _{DDA} + 0.3	V	
SID17A	V _{O0_ABS0}	Output voltage ^[35]	V _{SSD} - 0.3	-	V _{DDD} + 0.3	V	For ports 0, 1, 2, 3, 4, 5, 16, 17, 18, 19, 20, 21, 22, 23
SID17B	V _{O1_ABS1}	Output voltage ^[35]	V _{SSD} - 0.3	-	V _{DDIO_1} + 0.3	V	For ports 6, 7, 8, 9 ^[36]
SID17C	V _{O2_ABS2}	Output voltage ^[35]	V _{SSD} - 0.3	-	V _{DDIO_2} + 0.3	V	For ports 10, 11, 12, 13, 14, 15

Notes

^{35.}These parameters are based on the condition that V_{SSD} = V_{SSA} = 0.0 V.

36.The I/Os in V_{DDIO 1} domain are referred to the V_{DDD} domain in 64-LQFP package.

37.A current-limiting resistor must be provided such that the current at the I/O pin does not exceed rated values at any time, including

during power transients. Refer to **Figure 26-1** for more information on the recommended circuit.

38.V_{DDIO} and V_{DDD} must be sufficiently loaded or protected to prevent them from being pulled out of the recommended operating range by the clamp current.

^{39.} When the conditions of [37], [38], and SID18A/B/C/D are met, |I_{CLAMP_ABS}| supersedes V_{IA_ABS} and V_{I_ABS}.
40. The definition of "closer" depends on the package. In LQFP packaging, "closest" is determined by counting pins. For example, in a 176-LQFP package, P17.4 (pin 120) is closer to the V_{DDD} on pin 110 than on pin 132. Ports 11 and 21 should not be used for injection currents. The impact of injection currents is only defined for GPIO_STD/GPIO_ENH type I/Os.

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Table 26-1 Absolute maximum ratings (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID18	I _{CLAMP_ABS}	Maximum clamp current [37, 38, 39]	-5	-	5	mA	
SID18A	I _{CLAMP_SUP} - PLY_POS_ABS	Maximum positive clamp current per I/O supply pin. Limit applies to I/O supply pin closest to the B+ injected current [40]	-	-	10	mA	+B injected DC currents are not allowed for Ports 11 and 21.
SID18B	I _{CLAMP_SUP} - PLY_NEG_ABS	Maximum negative clamp current per I/O ground pin. Limit applies to I/O supply pin closest to the B+ injected current [40]	-	-	10	mA	+B injected DC currents are not allowed for Ports 11 and 21.
SID18C	I _{CLAMP_TO-} TAL_POS_ABS	Maximum positive clamp current per I/O supply, if not limited by the per supply pin (based on SID18A).	-	-	50	mA	
SID18D	I _{CLAMP_TO} - TAL_NEG_ABS	Maximum negative clamp current per I/O ground, if not limited by the per supply pin (based on SID18B).	-	-	50	mA	
SID20A	I _{OL1A_ABS}	LOW-level maximum output current [41]	-	-	6	mA	For GPIO_STD, configured for drive_sel<1:0>= 0b0X
SID20B	I _{OL1B_ABS}	LOW-level maximum output current [41]	=	-	2	mA	For GPIO_STD, configured for drive_sel<1:0>= 0b10
SID20C	I _{OL1C_ABS}	LOW-level maximum output current [41]	-	-	1	mA	For GPIO_STD, configured for drive_sel<1:0>= 0b11
SID21A	I _{OL2A_ABS}	LOW-level maximum output current [41]	-	-	6	mA	For GPIO_ENH, configured for drive_sel<1:0>= 0b0X
SID21B	I _{OL2B_ABS}	LOW-level maximum output current [41]	-	-	2	mA	For GPIO_ENH, configured for drive_sel<1:0>= 0b10
SID21C	I _{OL2C_ABS}	LOW-level maximum output current [41]	=	-	1	mA	For GPIO_ENH, configured for drive_sel<1:0>= 0b11
SID26A	ΣI _{OL_ABS_GPIO}	LOW-level total output current [42]	-	_	50	mA	
SID27A	I _{OH1A_ABS}	HIGH-level maximum output current [41]	=	-	-5	mA	For GPIO_STD, configured for drive_sel<1:0>= 0b0X
SID27B	I _{OH1B_ABS}	HIGH-level maximum output current [41]	-	-	-2	mA	For GPIO_STD, configured for drive_sel<1:0>= 0b10
SID27C	I _{OH1C_ABS}	HIGH-level maximum output current [41]	-	-	-1	mA	For GPIO_STD, configured for drive_sel<1:0>= 0b11
SID28A	I _{OH2A_ABS}	HIGH-level maximum output current [41]	-	-	-5	mA	For GPIO_ENH, configured for drive_sel<1:0>= 0b0X
SID28B	I _{OH2B_ABS}	HIGH-level maximum output current [41]	-	-	-2	mA	For GPIO_ENH, configured for drive_sel<1:0>= 0b10
SID28C	I _{OH2C_ABS}	HIGH-level maximum output current [41]	-	-	-1	mA	For GPIO_ENH, configured for drive_sel<1:0 ≥ 0b11
SID33A	ΣI _{OH_ABS_GPIO}	HIGH-level total output current [42]	-	-	-50	mA	
SID34	P_D	Power dissipation	-	_	1000	mW	T _J should not exceed 150 °C
SID35	T _A	Ambient temperature	-40	-	105	°C	For S-grade devices
SID36	T _A	Ambient temperature	-40	_	125	°C	For E-grade devices
SID37	T _{STG}	Storage temperature	-55	-	150	°C	
SID38	TJ	Operating Junction temperature	-40	_	150	°C	
SID39A	V _{ESD_HBM}	Electrostatic discharge human body model	2000	-	-	٧	
SID39B1	V _{ESD_CDM1}	Electrostatic discharge charged device model for corner pins	750	-	-	V	
SID39B2	V _{ESD_CDM2}	Electrostatic discharge charged device model for all other pins	500	-		V	
SID39C	I _{LU}	The maximum pin current the device can tolerate before triggering a latch-up	-100	-	100	mA	

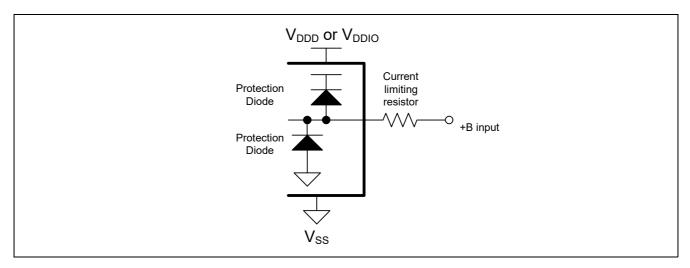
^{41.} The maximum output current is the peak current flowing through any one I/O. 42. The total output current is the maximum current flowing through all I/Os (GPIO_STD, and GPIO_ENH).

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Example of a recommended circuit $^{[43]}$ Figure 26-1

WARNING:

Semiconductor devices may be permanently damaged by application of stress (including, without limitation, voltage, current, or temperature) in excess of absolute maximum ratings. Do not exceed any of these ratings.

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26.2 Device-level specifications

Table 26-2 Recommended operating conditions

Spec ID	Parameter	Description	Min	Тур	Max	Unit s	Details/Conditions
SID40	V _{DDD} , V _{DDA} , V _{DDIO_1} , V _{DDIO_2} ,	Power supply voltage ^[44]	2.7 ^[45]	-	5.5 ^[46]	V	
SID40A		Power supply voltage for eFuse programming ^[47]	3	-	5.5	V	
SID41	C _{S1}	Smoothing capacitor ^[48, 49]	3.76	_	11	μF	

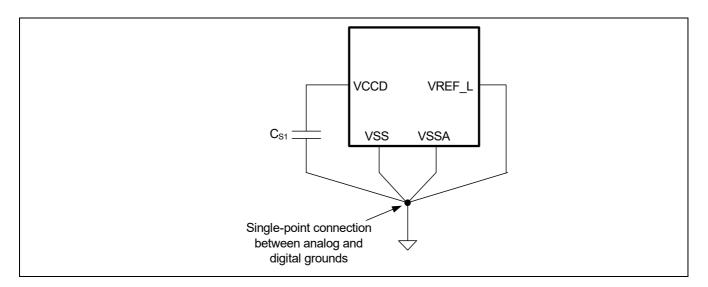


Figure 26-2 Smoothing capacitor

Smoothing capacitor should be placed as close as possible to the V_{CCD} pin.

Notes

43.+B is the positive battery voltage around 45 V.

44.V_{DDD}, V_{DDIO_2}, and V_{DDA} do not have any sequencing limitation and can establish in any order. These supplies (except for V_{DDA} and V_{DDIO_2}) are independent in voltage level. See 12-Bit SAR ADC DC Specifications when using ADC units.

45.3.0 V ±10% is supported with a lower BOD setting option for V_{DDD} and V_{DDA}. This setting provides robust protection for internal timing but BOD reset occurs at a voltage below the specified operating conditions. A higher BOD setting option is available (consistent with down to 3.0 V) and guarantees that all operating conditions are met.

46.5.0 V ±10% is supported with a higher OVD setting option for V_{DDD} and V_{DDA}. This setting provides robust protection for internal and interface timing, but OVD reset occurs at a voltage above the specified operating conditions. A lower OVD setting option is available (consistent with up to 5.0 V) and guarantees that all operating conditions are met. Voltage overshoot to a higher OVD setting range for V_{DDD} and V_{DDA} is permissible, provided the duration is less than 2 hours cumulated. Note that during overshoot voltage condition electrical parameters are not guaranteed.

47.eFuse programming must be executed with the part in a "quiet" state, with minimal activity (preferably only JTAG or a single LIN/CAN channel on V_{DDD} domain, no activity on V_{DDIO 1}).

48. Smoothing capacitor, C_{S1} is required per chip (not per V_{CCD} pin). The V_{CCD} pins must be connected together to ensure a low-impedance connection (see the requirement in **Figure 26-2**).

49. Capacitors used for power supply decoupling or filtering are operated under a continuous DC-bias. Many capacitors used with DC power across them provide less than their target capacitance, and their capacitance is not constant across their working voltage range. When selecting capacitors for use with this device, ensure that the selected components provide the required capacitance under the specific operating conditions of temperature and voltage used in your design. While the temperature coefficient is normally found within a parts catalog (such as, X7R, C0G, Y5V), the matching voltage coefficient may only be available on the component datasheet or direct from the manufacturer. Use of components that do not provide the required capacitance under the actual operating conditions may cause the device to operate to less than datasheet specifications.

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26.3 DC specifications

Table 26-3 DC specifications, CPU current and transition time specifications

All specifications are valid for –40 °C \leq T $_{A}$ \leq 125 °C and for 2.7 V to 5.5 V except where noted.

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID49C1A	IDD1_CM04_8_1A	LP Active mode (CM4 and CM0+ at 8 MHz, all peripherals are disabled)	-	4	9	mA	CM0+ and CM4 clocked at 8 MHz with IMO. All peripherals are disabled. No I/O toggling. TYP: $T_A = 25$ °C, $V_{DDD} = 5.0$ V, process typ (TT), CM0+ and CM4 executing Dhrystone from flash with cache enabled MAX: $T_A = 25$ °C, $V_{DDD} = 5.5$ V, process worst (FF), CM0+ and CM4 executing Dhrystone from flash with cache enabled.
SID49CA	IDD1_CM04_8A	LP Active mode (CM4 and CM0+ at 8 MHz, all peripherals are enabled)	_	5	51	mA	CM0+ and CM4 clocked at 8 MHz with IMO. All peripherals are enabled. No I/O toggling. M-DMA transferring data from code + work flash, P-DMA chains with maximum trigger activity. TYP: T _A = 25 °C, V _{DDD} = 5.0 V, process typ (TT), CM0+ and CM4 executing Dhrystone from flash with cache enabled MAX: T _A = 125 °C, V _{DDD} = 5.5 V, process worst (FF), CM0+ and CM4 executing max_power.c from flash with cache enabled.
SID49E1	IDD1_F160_1M	Active mode (CM4 at 160 MHz, CM0+ at 80 MHz, all peripherals are enabled)	-	39	102	mA	PLL enabled at 160 MHz with ECO reference. All peripherals are enabled. No I/O toggling. M-DMA transferring data from code + work flash, P-DMA chains with maximum trigger activity. TYP: T _A = 25 °C, V _{DDD} = 5.0 V, process typ (TT), CM4 and CM0+ executing Dhrystone from flash with cache enabled. MAX: T _A = 125 °C, V _{DDD} = 5.5 V, process worst (FF), CM4 and CM0+ executing max_power.c from flash with cache enabled
SID53A1	I _{DD2_8_1}	All CPUs in Sleep mode	-	3	46	mA	PLL disabled, CM4 and CM0+ are sleeping at 8 MHz with IMO. All peripherals, peripheral clocks, interrupts, CSV, DMA, FLL, ECO are disabled. No I/O toggling. Typ: $T_A = 25$ °C, $V_{DDD} = 5.0$ V, process typ (TT) Max: $T_A = 125$ °C, $V_{DDD} = 5.5$ V, process worst (FF)

Note

50.At cold temperature -5 °C to -40 °C, the DeepSleep to Active transition time can be higher than the max time indicated by as much as 20 μ s.

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Table 26-3 DC specifications, CPU current and transition time specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID56A	I _{DD_CWU2}	Average current for cyclic wake-up operation This is the average current for the specified LP Active mode and DeepSleep mode (RTC, WDT, and Event generator operating).	_	46	136	μΑ	V _{DDD} = 5.5 V, T _A = 25 °C, 64-KB SRAM, ILO0 operation in DeepSleep, Smart I/O operations with ILO0, CM0+, CM4: Retained TYP: process typ (TT) MAX: process worst (FF) This average current is achieved under the following conditions. 1. MCU repetitively goes from DeepSleep to LP Active with a period of 32 ms. 2. One of the I/Os is toggled using Smart I/O to activate an external sensor connected to an analog input of A/D in DeepSleep 3. After 200 μs delay, the CM4 wakes up by event generator trigger to LP Active mode with IMO and A/D conversion is triggered by software. 4. Group A/D conversion is performed on 5 channels with the sampling time of 1 μs each. 5. Once the group A/D conversion is finished, and the results fit in the window of the range comparator, the I/O is toggled back by software to de-activate the sensor and the CM4 goes back to DeepSleep.
SID59A	I _{DD_DS64B}	64-KB SRAM retention, ILO0 operation in DeepSleep mode	-	35	130	μА	DeepSleep Mode (RTC, WDT, and event generator operating, all other peripherals are off except for retention registers), T _A = 25 °C, CM0+, CM4: Retained Typ: V _{DDD} = 5.0 V, process typ (TT) Max: V _{DDD} = 5.5 V, process worst (FF)
SID61A	I _{DD_DS64D}	64-KB SRAM retention, ILO0 operation in DeepSleep mode	-	0.9	3.5	mA	DeepSleep Mode steady state at T _A = 125 °C (RTC, WDT, and event generator operating, all other peripherals are off except for retention registers), CMO+, CM4: Retained Typ: V _{DDD} = 5.0 V, process typ (TT) Max: V _{DDD} = 5.5 V, process worst (FF)
Hibernate	Mode						
SID62	I _{DD_HIB1}	Hibernate Mode	_	5	-	μА	ILOO/WDT operating. All other peripherals, and all CPUs are off. T _A = 25 °C, V _{DDD} = 5.5 V, process typ (TT)
SID62A	I _{DD_HIB2}	Hibernate Mode	-	-	130	μА	ILOO/WDT operating. All other peripherals, and all CPUs are off. T _A = 125 °C, V _{DDD} = 5.5 V, process worst (FF)
Power mod	de transition tim	ies					
SID65	t _{ACT_DS}	Power down time from Active to DeepSleep	_	_	2.5	μs	When the IMO is already running and all HFCLK roots are at least 8 MHz. HFCLK roots that are slower than this will require additional time to turn off.

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Table 26-3 DC specifications, CPU current and transition time specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID63	t _{DS_ACT}	DeepSleep to Active transition time (IMO clock, SRAM execution)	-	-	10 ^[50]	μs	When using the 8-MHz IMO. Measured from wakeup interrupt during DeepSleep until wakeup.
SID63C	t _{DS_ACT}	DeepSleep to Active transition time (IMO clock, flash execution)	_	_	20 ^[50]	μs	When using the 8-MHz IMO. Measured from wakeup interrupt during DeepSleep until flash execution.
SID63A	t _{DS_ACT_FLL}	DeepSleep to Active transition time (FLL clock, SRAM execution)	-	_	15 ^[50]	μs	When using the FLL to generate 96 MHz from the 8-MHz IMO. Measured from wakeup interrupt during DeepSleep until the FLL locks.
SID63D	t _{DS_ACT_FLL1}	DeepSleep to Active transition time (FLL clock, flash execution)	-	-	21.5 ^[50]	μs	When using the FLL to generate 96 MHz from the 8-MHz IMO. Measured from wakeup interrupt during DeepSleep until flash execution.
SID63B	t _{DS_ACT_PLL}	DeepSleep to Active transition time (PLL clock, SRAM or flash execution)	-	-	60 ^[50]	μs	When using the PLL to generate 96 MHz from the 8-MHz IMO. Measured from wakeup interrupt during DeepSleep until the PLL locks.
SID68	t _{HVR_ACT}	Release time from HV reset (POR, BOD, OVD, OCD, WDT, Hibernate wakeup, or XRES_L) release until CM0+ begins executing ROM boot	_	-	265	μs	Without boot runtime. Guaranteed by design
SID68A	t _{LVR_ACT}	Release time from LV reset (Fault, Internal system reset, MCWDT, or CSV) during Active/Sleep until CM0+ begins executing ROM boot	_	-	10	μs	Without boot runtime. Guaranteed by design
SID68B	t _{LVR_DS}	Release time from LV reset (Fault, or MCWDT) during DeepSleep until CM0+ begins executing ROM boot	_	_	15	μs	Without boot runtime. Guaranteed by design
SID80A	t _{RB_N}	ROM boot startup time or wakeup time from hibernate in NORMAL protection state	-	-	1800	μs	Guaranteed by Design, CM0+ clocked at 100 MHz (Flash boot version 3.1.0.556 and later)
SID80B	t _{RB_S}	ROM boot startup time or wakeup time from hibernate in SECURE protection state	-	-	2740	μs	Guaranteed by Design, CM0+ clocked at 100 MHz (Flash boot version 3.1.0.556 and later)
SID81A	t _{FB}	Flash boot startup time or wakeup time from hibernate in NORMAL/SECURE protection state	_	_	80	μs	Guaranteed by Design, TOC2_FLAGS=0x2CF, CM0+ clocked at 100 MHz (Flash boot version 3.1.0.556 and later), Listen window = 0 ms

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Table 26-3 DC specifications, CPU current and transition time specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID81B	t _{FB_A}	Flash boot with app authentication time in NORMAL/SECURE protection state	_	-	5000	μs	Guaranteed by Design, TOC2_FLAGS=0x24F, CM0+ clocked at 100 MHz (Flash boot version 3.1.0.556 and later), Listen window = 0 ms, Public key exponent e = 0x010001, App size is 64 KB with the last 256 bytes being a digital signature in RSASSA-PKCS1-v1.5 Valid for RSA-2048.
SID80A_2	t _{RB_N_2}	ROM boot startup time or wakeup time from hibernate in NORMAL protection state	_	-	2930	μs	Guaranteed by Design, CM0+ clocked at 50 MHz (Flash boot version earlier than 3.1.0.556)
SID80B_2	t _{RB_S_2}	ROM boot startup time or wakeup time from hibernate in SECURE protection state	_	-	4680	μs	Guaranteed by Design, CM0+ clocked at 50 MHz (Flash boot version earlier than 3.1.0.556)
SID81A_2	t _{FB_2}	Flash boot startup time or wakeup time from hibernate in NORMAL/SECURE protection state	_	-	200	μs	Guaranteed by Design, TOC2_FLAGS=0x2CF, CM0+ clocked at 50 MHz (Flash boot version earlier than 3.1.0.556), Listen window = 0 ms
SID81B_2	t _{FB_A_2}	Flash boot with app authentication time in NORMAL/SECURE protection state	_	_	10000	μs	Guaranteed by Design, TOC2_FLAGS=0x24F, CM0+ clocked at 50 MHz (Flash boot version earlier than 3.1.0.556), Listen window=0 ms, Public key exponent e=0x010001, App size is 64 KB with the last 256 bytes being a digital signature in RSASSA-PKCS1-v1.5 Valid for RSA-2048.
Regulator	specifications						
SID600	V _{CCD}	Core supply voltage	1.05	1.1	1.15	V	
SID601	I _{DD_ACT}	Regulator operating current in Active/Sleep mode	_	80	150	μΑ	Guaranteed by design
SID602	I _{DD_DPSLP}	Regulator operating current in DeepSleep mode	_	1.5	20	μА	Guaranteed by design
SID604	I _{OUT}	Available regulator output current for operation	_	-	150	mA	Without triggering OVD
SID603	I _{RUSH}	In-rush current	_	-	375	mA	Average V _{DDD} current until C _{s1} (connected to V _{CCD} pin) is charged after Active regulator is turned on

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26.4 Reset specifications

Table 26-4 XRES_L reset

Spec ID	Paramete r	Description	Min	Тур	Max	Units	Details/Conditions
XRES_L D	C specificat	tions					
SID73	I _{DD_XRES}	I _{DD} when XRES_L asserted	-	-	0.9	mA	T _A = 125 °C, V _{DDD} = 5.5 V, process worst (FF)
SID74	V _{IH}	Input voltage HIGH threshold	$0.7 \times V_{DDD}$	-	-	V	CMOS input
SID75	V_{IL}	Input voltage LOW threshold	-	-	$0.3 \times V_{DDD}$	V	CMOS input
SID76	R _{PULLUP}	Pull-up resistor	7	-	20	kΩ	
SID77	C _{IN}	Input capacitance	_	-	5	pF	
SID78	V _{HYSXRES}	Input voltage hysteresis	$0.05 \times V_{DDD}$	-	-	V	
XRES_L A	C specificat	ions					
SID70	t _{XRES_ACT}	XRES_L release to Active transition time	-	-	265	μs	Without boot runtime. Guaranteed by design
SID71	t _{XRES_PW}	XRES_L pulse width	5	-	-	μs	
SID72	t _{XRES_FT}	Pulse suppression width	100	-	-	ns	

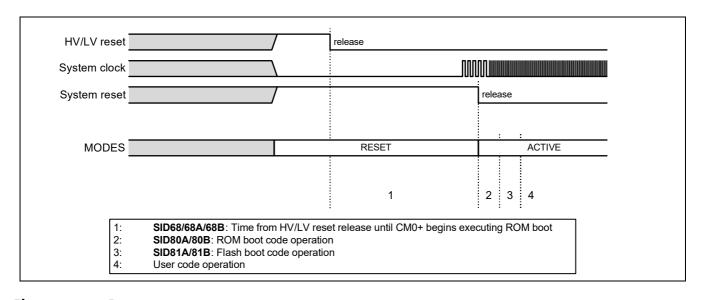


Figure 26-3 Reset sequence

Based on Arm® Cortex®-M4F single

Electrical specifications



26.5 I/O

I/O specifications **Table 26-5**

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
GPIO_STI	Specifications f	or ports P1 through	P23				
SID650	V _{OL1_GPIO_STD}	Output voltage LOW level	-	-	0.6	V	I_{OL} = 6 mA drive_sel<1:0> = 0b0X, 4.5 V \leq V _{DDD} or V _{DDIO_1} or V _{DDIO_2} \leq 5.5 V
SID650C	V _{OL1C_GPIO_STD}	Output voltage LOW level	-	1	0.4	V	I_{OL} = 5 mA drive_sel<1:0> = 0b0X, 4.5 V \leq V _{DDD} or V _{DDIO_1} or V _{DDIO_2} \leq 5.5 V
SID651	V _{OL2_GPIO_STD}	Output voltage LOW level	-	-	0.4	V	I_{OL} = 2 mA drive_sel<1:0> = 0b0X, 2.7 V \leq V _{DDD} or V _{DDIO_1} or V _{DDIO_2} < 4.5 V
SID652	V _{OL3_GPIO_STD}	Output voltage LOW level	-	-	0.4	V	I_{OL} = 1 mA drive_sel<1:0> = 0b10, 2.7 V \leq V _{DDD} or V _{DDIO_1} or V _{DDIO_2} < 4.5 V
SID652C	V _{OL3C_GPIO_STD}	Output voltage LOW level	-	1	0.4	V	I_{OL} = 2 mA drive_sel<1:0> = 0b10, 4.5 V \leq V _{DDD} or V _{DDIO_1} or V _{DDIO_2} \leq 5.5 V
SID653	V _{OL4_GPIO_STD}	Output voltage LOW level	-	1	0.4	V	$I_{OL} = 0.5 \text{ mA}$ drive_sel<1:0> = 0b11, $2.7 \text{ V} \le \text{V}_{DDD} \text{ or V}_{DDIO_1} \text{ or V}_{DDIO_2} < 4.5 \text{ V}$
SID653C	V _{OL4C_GPIO_STD}	Output voltage LOW level	-	1	0.4	V	$I_{OL} = 1 \text{ mA}$ $drive_sel < 1:0 > = 0b11,$ $4.5 \text{ V} \le \text{V}_{DDD} \text{ or V}_{DDIO_1} \text{ or V}_{DDIO_2} \le 5.5 \text{ V}$
SID654	V _{OH1_GPIO_STD}	Output voltage HIGH level	$(V_{DDD} \text{ or } V_{DDIO_1} \text{ or } V_{DDIO_2)} - 0.5$	-	-	V	I_{OH} = -2 mA drive_sel<1:0> = 0b0X, 2.7 V \leq V _{DDD} or V _{DDIO_1} or V _{DDIO_2} < 4.5 V
SID655	V _{OH2_GPIO_STD}	Output voltage HIGH level	$(V_{DDD} \text{ or } V_{DDIO_1} \text{ or } V_{DDIO_2)} - 0.5$	-	-	V	I_{OH} = -5 mA drive_sel<1:0> = 0b0X, 4.5 V \le V_{DDD} or V_{DDIO_1} or $V_{DDIO_2} \le 5.5 V$
SID656	V _{OH3_GPIO_STD}	Output voltage HIGH level	(V _{DDD} or V _{DDIO_1} or V _{DDIO_2}) - 0.5	-	-	V	$I_{OH} = -1 \text{ mA}$ drive_sel<1:0> = 0b10, $2.7 \text{ V} \le \text{V}_{DDD} \text{ or V}_{DDIO_1} \text{ or V}_{DDIO_2} < 4.5 \text{ V}$
SID656C	V _{OH3C_GPIO_STD}	Output voltage HIGH level	(V _{DDD} or V _{DDIO_1} or V _{DDIO_2}) - 0.5	-	-	V	$I_{OH} = -2 \text{ mA}$ drive_sel<1:0> = 0b10, $4.5 \text{ V} \le \text{V}_{DDD} \text{ or V}_{DDIO_1} \text{ or V}_{DDIO_2} \le 5.5 \text{ V}$
SID657	V _{OH4_GPIO_STD}	Output voltage HIGH level	$(V_{DDD} \text{ or } V_{DDIO_1} \text{ or } V_{DDIO_2)} - 0.5$	_	_	V	$I_{OH} = -0.5 \text{ mA}$ drive_sel<1:0> = 0b11, 2.7 V \le V_{DDD} \text{ or V}_{DDIO_1} \text{ or V}_{DDIO_2} < 4.5 \text{ V}

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Table 26-5 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID657C	V _{OH4C_GPIO_STD}	Output voltage HIGH level	$(V_{DDD} \text{ or } V_{DDIO_1} \text{ or } V_{DDIO_2}) - 0.5$	I	-	V	$I_{OH} = -1 \text{ mA}$ drive_sel<1:0> = 0b11, $4.5 \text{ V} \le \text{V}_{DDD} \text{ or V}_{DDIO_1} \text{ or V}_{DDIO_2} \le 5.5 \text{ V}$
SID658	R _{PD_GPIO_STD}	Pull-down resis- tance	25	50	100	kΩ	
SID659	R _{PU_GPIO_STD}	Pull-up resistance	25	50	100	kΩ	
SID660	V _{IH_CMOS_GPI} - O_STD	Input voltage HIGH threshold in CMOS mode	$0.7 \times (V_{DDD} \\ or V_{DDIO_1} or \\ V_{DDIO_2)}$	-	_	V	
SID661	V _{IH_TTL_GPIO_STD}	Input voltage HIGH threshold in TTL mode	2.0	I	_	V	
SID662	V _{IH_AUTO_GPI} - O_STD	Input voltage HIGH threshold in AUTO mode	$\begin{array}{c} 0.8 \times (V_{DDD} \text{ or } \\ V_{DDIO_1} \text{ or } \\ V_{DDIO_2)} \end{array}$	-	_	V	
SID663	V _{IL_CMOS_GPI} - o_std	Input voltage LOW threshold in CMOS mode	-	ı	$0.3 \times (V_{DDD} \text{ or } V_{DDIO_1} \text{ or } V_{DDIO_2)}$	٧	
SID664	V _{IL_TTL_GPIO_STD}	Input voltage LOW threshold in TTL mode	_	-	0.8	V	
SID665	V _{IL_AUTO_GPIO_STD}	Input voltage LOW threshold in AUTO mode	-	-	$0.5 \times (V_{DDD} \text{ or } V_{DDIO_1} \text{ or } V_{DDIO_2})$	V	
SID666	V _{HYST_CMOS_GPI-} O_STD	Hysteresis in CMOS mode	$0.05 \times (V_{DDD} \\ or V_{DDIO_1} or \\ V_{DDIO_2)}$	-	_	V	
SID668	V _{HYST_AUTO_GPI-} O_STD	Hysteresis in AUTO mode	$0.05 \times (V_{DDD} \\ or V_{DDIO_1} or \\ V_{DDIO_2)}$	ı	_	V	
SID669	C _{in_GPIO_STD}	Input pin capaci- tance	-	-	5	pF	For 10 MHz and 100 MHz
SID670	I _{IL_GPIO_STD}	Input leakage current	-250	0.02	250	nA	For GPIO_STD except P21.0, P21.1, P21.2, P21.3, P21.4, P23.3, P23.4. $V_{DDIO_1} = V_{DDIO_2} = V_{DDD} = V_{DDA} = 5.5 \text{ V, V}_{SSD} < V_{I} < V_{DDD}, V_{DDIO_1}, V_{DDIO_2} - 40 \text{ °C} \le TA \le 125 \text{ °C} $ $TYP: T_A = 25 \text{ °C}, V_{DDIO_1} = V_{DDIO_2} = V_{DDD} = V_{DDA} = 5.0 \text{ V}$

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Table 26-5 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID670C	I _{IL_GPIO_STD_B}	Input leakage current	-700	0.02	700	nA	Only for P21.0, P21.1, P21.2, P21.3, P21.4, P23.3, P23.4.
							$\begin{vmatrix} V_{DDIO_1} = V_{DDIO_2} = V_{DDD} \\ = V_{DDA} = 5.5 \text{ V}, V_{SSD} < V_{I} < 0.5 \text{ M} $
							$V_{DDD}, V_{DDIO_1}, V_{DDIO_2}$ -40 °C \le TA \le 125 °C
							TYP: $T_A = 25 ^{\circ}\text{C}$, $V_{DDIO_1} = V_{DDIO_2} = V_{DDD}$ $= V_{DDA} = 5.0 ^{\circ}\text{V}$
SID671	t _R or t _F (fast) _{20_0_GPI} - 0_STD	Rise time or fall time (10% to 90% of V _{DDIO})	1	-	10	ns	20-pF load, drive_sel<1:0> = 0b00
SID672	t _R or t _F (fast)_ _{50_0_GPI} - o_std	Rise time or fall time (10% to 90% of V _{DDIO})	1	-	20	ns	50-pF load, drive_sel<1:0> = 0b00
SID673	t_R or t_F $(fast)_{20_1}$ GPI-	Rise time or fall time (10% to 90% of V _{DDIO})	1	-	20	ns	20-pF load, drive_sel<1:0> = 0b01, guaranteed by design
SID674	t _R or t _F (fast) _{_10_2_GPI-} o_STD	Rise time or fall time (10% to 90% of V _{DDIO})	1	-	20	ns	10-pF load, drive_sel<1:0> = 0b10, guaranteed by design
SID675	t _R or t _F (fast)_6_3_GPI- O_STD	Rise time or fall time (10% to 90% of V _{DDIO})	1	-	20	ns	6-pF load, drive_sel<1:0> = 0b11, guaranteed by design
SID676	t _F (fast) _{_100_GPl} - O_STD	Fall time (30% to 70% of V _{DDIO})	0.35	-	250	ns	10-pF to 400-pF load, RPU = 767 Ω, drive_sel<1:0>= 0b00, Freq = 100 kHz
SID677	t _F (fast) _{_400_GPI} o_STD	Fall time (30% to 70% of V _{DDIO})	0.35	-	250	ns	10-pF to 400-pF load, RPU = 350 Ω, drive_sel<1:0>= 0b00, Freq = 400 kHz
SID678	f _{IN_GPIO_STD}	Input frequency	-	-	100	MHz	
SID679	fout_gpio_stdoh	Output frequency	-	_	50	MHz	20-pF load, drive_sel<1:0>= 00, $4.5 \text{ V} \leq \text{V}_{DDD} \text{ or V}_{DDIO_1} \text{ or V}_{DDIO_2} \leq 5.5 \text{ V}$
SID680	f _{OUT_GPIO_STD0L}	Output frequency	-	-	32	MHz	20-pF load, drive_sel<1:0>= 00, $2.7 \text{ V} \leq \text{V}_{DDD} \text{ or V}_{DDIO_1} \text{ or V}_{DDIO_2} < 4.5 \text{ V}$
SID681	fout_gpio_std1H	Output frequency	-	-	25	MHz	20-pF load, drive_sel<1:0>= 01, $4.5 \text{ V} \leq \text{V}_{\text{DDD}} \text{ or V}_{\text{DDIO}_1} \text{ or V}_{\text{DDIO}_2} \leq 5.5 \text{ V}$

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 Table 26-5
 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID682	fout_gpio_std1L	Output frequency	-	ı	15	MHz	20-pF load, drive_sel<1:0>= 01, $2.7 \text{ V} \leq \text{V}_{\text{DDD}} \text{ or V}_{\text{DDIO}_1} \text{ or V}_{\text{DDIO}_2} < 4.5 \text{ V}$
SID683	fout_gpio_std2h	Output frequency	-	1	25	MHz	10-pF load, drive_sel<1:0>= 10, $4.5 \text{ V} \leq \text{V}_{DDD} \text{ or V}_{DDIO_1} \text{ or V}_{DDIO_2} \leq 5.5 \text{ V}$
SID684	fout_gpio_std2L	Output frequency	-	1	15	MHz	10-pF load, drive_sel<1:0>= 10, 2.7 V ≤ V _{DDD} or V _{DDIO_1} or V _{DDIO_2} < 4.5 V
SID685	fout_gpio_std3H	Output frequency	-	-	15	MHz	6-pF load, drive_sel<1:0>= 11, 4.5 V ≤ V _{DDD} or V _{DDIO_1} or V _{DDIO_2} ≤ 5.5 V
SID686	fout_gpio_std3L	Output frequency	-	1	10	MHz	6-pF load, drive_sel<1:0>= 11, 2.7 V ≤ V _{DDD} or V _{DDIO_1} or V _{DDIO_2} < 4.5 V
GPIO_EN	H specifications o	nly for P0					
SID650A	V _{OL1_GPIO_ENH}	Output voltage LOW level	_	-	0.6	V	I _{OL} = 6 mA drive_sel<1:0> = 0b0X, 2.7 V ≤ V _{DDD} ≤ 5.5 V
SID650D	V _{OL1D_GPIO_ENH}	Output voltage LOW level	_	1	0.4	V	$I_{OL} = 5 \text{ mA}$ drive_sel<1:0> = 0b0X, 4.5 V \le V_DDD \le 5.5 V
SID651A	V _{OL2_GPIO_ENH}	Output voltage LOW level	-	1	0.4	V	I _{OL} = 2 mA, 3 mA drive_sel<1:0> = 0b0X, 2.7 V ≤ V _{DDD} < 4.5 V
SID652A	V _{OL3_GPIO_ENH}	Output voltage LOW level	_	-	0.4	V	I _{OL} = 1 mA drive_sel<1:0> = 0b10, 2.7 V ≤ V _{DDD} < 4.5 V
SID652D	V _{OL3D_GPIO_ENH}	Output voltage LOW level	-	-	0.4	V	$I_{OL} = 2 \text{ mA}$ drive_sel<1:0> = 0b10, $4.5 \text{ V} \le V_{DDD} \le 5.5 \text{ V}$
SID653A	V _{OL4_GPIO_ENH}	Output voltage LOW level	-	-	0.4	V	I _{OL} = 0.5 mA drive_sel<1:0> = 0b11, 2.7 V ≤ V _{DDD} < 4.5 V
SID653D	V _{OL4D_GPIO_ENH}	Output voltage LOW level	_	-	0.4	V	$I_{OL} = 1 \text{ mA}$ drive_sel<1:0> = 0b11, 4.5 V \le V_DDD \le 5.5 V
SID654A	V _{OH1_GPIO_ENH}	Output voltage HIGH level	V _{DDD} - 0.5	-	-	V	I _{OL} = -2 mA drive_sel<1:0> = 0b0X, 2.7 V ≤ V _{DDD} < 4.5 V
SID655A	V _{OH2_GPIO_ENH}	Output voltage HIGH level	V _{DDD} - 0.5	-	-	V	I _{OL} = -5 mA drive_sel<1:0> = 0b0X, 4.5 V ≤ V _{DDD} ≤ 5.5 V

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 Table 26-5
 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID656A	V _{OH3_GPIO_ENH}	Output voltage HIGH level	V _{DDD} - 0.5	-	-	V	$I_{OL} = -1 \text{ mA}$ drive_sel<1:0> = 0b10, 2.7 V \le V_DDD < 4.5 V
SID656D	V _{OH3D_GPIO_ENH}	Output voltage HIGH level	V _{DDD} - 0.5			V	$I_{OL} = -2 \text{ mA}$ drive_sel<1:0> = 0b10, 4.5 V \le V_DDD \le 5.5 V
SID657A	V _{OH4_GPIO_ENH}	Output voltage HIGH level	V _{DDD} - 0.5	-	_	V	l _{OL} = -0.5 mA drive_sel<1:0> = 0b11, 2.7 V ≤ V _{DDD} < 4.5 V
SID657D	V _{OH4D_GPIO_ENH}	Output voltage HIGH level	V _{DDD} - 0.5	_	-	V	$I_{OL} = -1 \text{ mA}$ drive_sel<1:0> = 0b11, 4.5 V \le V_DDD \le 5.5 V
SID658A	R _{PD_GPIO_ENH}	Pull-down resis- tance	25	50	100	kΩ	
SID659A	R _{PU_GPIO_ENH}	Pull-up resistance	25	50	100	kΩ	
SID660A	V _{IH_CMOS_GPI} - O_ENH	Input voltage HIGH threshold in CMOS mode	0.7 × V _{DDD}	-	-	V	
SID661A	V _{IH_TTL_GPIO_ENH}	Input voltage HIGH threshold in TTL mode	2	-	-	V	
SID662A	V _{IH_AUTO_GPI} - O_ENH	Input voltage HIGH threshold in AUTO mode	0.8 × V _{DDD}	1	_	V	
SID663A	V _{IL_CMOS_GPI} - O_ENH	Input voltage LOW threshold in CMOS mode	_	1	0.3 × V _{DDD}	V	
SID664A	V _{IL_TTL_GPIO_ENH}	Input voltage LOW threshold in TTL mode	_	-	0.8	V	
SID665A	V _{IL_AUTO_GPI} - O_ENH	Input voltage LOW threshold in AUTO mode	_	-	0.5 × V _{DDD}	V	
SID666A	V _{HYST_CMOS_GPI} - O_ENH	Hysteresis in CMOS mode	$0.05 \times V_{DDD}$	ı	-	V	
SID668A	V _{HYST_AUTO_GPI-} O_ENH	Hysteresis in AUTO mode	$0.05 \times V_{DDD}$	1	_	V	
SID669A	C _{in_GPIO_ENH}	Input pin capaci- tance	-	1	5	pF	For 10 MHz and 100 MHz
SID670A	I _{IL_GPIO_ENH}	Input leakage current	-350	0.055	350	nA	$V_{DDD} = V_{DDA} = 5.5 \text{ V},$ $V_{SSD} < V_{I} < V_{DDD},$ $-40 \text{ °C} \le T_{A} \le 125 \text{ °C}$ $TYP: T_{A} = 25 \text{ °C},$ $V_{DDD} = V_{DDA} = 5.0 \text{ V}$
SID671A	t _R or t _F (fast)_ _{20_0_GPI-} _{0_ENH}	Rise time or fall time (10% to 90% of V _{DDIO})	1	_	10	ns	20-pF load, drive_sel<1:0> = 0b00, slow = 0
SID672A	t _R or t _F (fast)_ _{50_0_GPI-} O_ENH	Rise time or fall time (10% to 90% of V _{DDIO})	1	_	20	ns	50-pF load, drive_sel<1:0> = 0b00, slow = 0

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 Table 26-5
 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID673A	t _R or t _F (fast) _{_20_1_GPI} - O_ENH	Rise time or fall time (10% to 90% of V _{DDIO})	1	-	20	ns	20-pF load, drive_sel<1:0> = 0b01, slow = 0, guaranteed by design
SID674A	t _R or t _F (fast)_10_2_GPI- O_ENH	Rise time or fall time (10% to 90% of V _{DDIO})	1	-	20	ns	10-pF load, drive_sel<1:0> = 0b10, slow = 0, guaranteed by design
SID675A	t _R or t _F (fast) _{_6_3_GPI} . O_ENH	Rise time or fall time (10% to 90% of V _{DDIO})	1	1	20	ns	6-pF load, drive_sel<1:0> = 0b11, slow = 0, guaranteed by design
SID676A	t _{F_I2C} (slow)_ _{GPIO_ENH}	Fall time (30% to 70% of V _{DDIO})	20 × (V _{DDD} / 5.5)	1	250	ns	10-pF to 400-pF load, drive_sel<1:0> = 0b00, slow = 1, minimum R_{PU} = 400 Ω
SID677A	t _R or t _F (slow) _{_20_GPI-} O_ENH	Rise time or fall time (10% to 90% of V _{DDIO})	20 × (V _{DDD} / 5.5)	1	160	ns	20-pF load, drive_sel<1:0> = 0b00, slow = 1, output frequency = 1 MHz
SID678A	t _R or t _F (slow) _{_400_GPI-}	Rise time or fall time (10% to 90% of V _{DDIO})	20 × (V _{DDD} / 5.5)	1	250	ns	400-pF load, drive_sel<1:0> = 0b00, slow = 1, output frequency = 400 kHz
SID679A	f _{IN_GPIO_ENH}	Input frequency	-	-	100	MHz	
SID680A	f _{OUT_GPIO_ENH0H}	Output frequency	-	-	50	MHz	20-pF load, drive_sel<1:0>= 0b00, 4.5 V ≤ V _{DDD} ≤ 5.5 V
SID681A	f _{OUT_GPIO_ENHOL}	Output frequency	-	-	32	MHz	20-pF load, drive_sel<1:0>= 0b00, 2.7 V ≤ V _{DDD} < 4.5 V
SID682A	f _{OUT_GPIO_ENH1} H	Output frequency	-	1	25	MHz	20-pF load, drive_sel<1:0>= 0b01, 4.5 V ≤ V _{DDD} ≤ 5.5 V
SID683A	f _{OUT_GPIO_ENH1L}	Output frequency	_	-	15	MHz	20-pF load, drive_sel<1:0>= 0b01, 2.7 V ≤ V _{DDD} < 4.5 V
SID684A	f _{OUT_GPIO_ENH2H}	Output frequency	-	-	25	MHz	10-pF load, drive_sel<1:0>= 0b10, 4.5 V ≤ V _{DDD} ≤ 5.5 V
SID685A	f _{OUT_GPIO_ENH2L}	Output frequency	-	_	15	MHz	10-pF load, drive_sel<1:0>= 0b10, 2.7 V ≤ V _{DDD} < 4.5 V



Electrical specifications



I/O specifications (continued) **Table 26-5**

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID686A	f _{OUT_GPIO_ENH3H}	Output frequency	-	-	15	MHz	6-pF load, drive_sel<1:0>= 0b11, 4.5 V ≤ V _{DDD} ≤ 5.5 V
SID687A	f _{OUT_GPIO_ENH3L}	Output frequency	1	_	10	MHz	6-pF load, drive_sel<1:0>= 0b11, 2.7 V ≤ V _{DDD} < 4.5 V
GPIO inp	ut specifications						
SID98	t _{FT}	Analog glitch filter (pulse suppression width)	_	_	50 ^[51]	ns	One filter per port group
SID99	t _{INT}	Minimum pulse width for GPIO interrupt	160	-	I	ns	

51.If longer pulse suppression width is required, use Smart I/O.

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Analog peripherals 26.6

All specifications are valid for –40 °C \leq T_A \leq 125 °C and for 2.7 V to 5.5 V except where noted.

SAR ADC 26.6.1

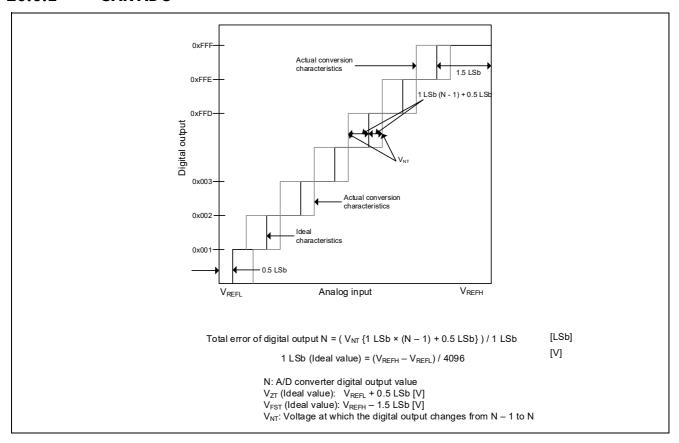


Figure 26-4 **ADC characteristics and error definitions**

Table 26-6 12-Bit SAR ADC DC specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID100	A_RES	SAR ADC resolution	-	-	12	bits	
SID101	A_V _{INS}	Input voltage range	V _{REFL}	-	V _{REFH}	V	
SID102	A_V _{REFH}	V _{REFH} voltage range	2.7	-	V _{DDA}	V	ADC performance degrades when high reference is higher than supply
SID102A	A_V _{DDA} ^[52]	V _{DDA} voltage range	2.7	-	5.5	V	
SID103	A_V _{REFL}	V _{REFL} voltage range	V _{SSA}	-	V _{SSA}	V	ADC performance degrades when low reference is lower than ground
SID103A	V _{band_gap}	Internal band gap reference voltage	0.882	0.9	0.918	V	
SID19A	CLAMP_COU- PLING_RA- TIO_POS	Ratio of current collected on a pin to the positive current injected into a neighboring pin	-	-	0.25	%	
SID19B	CLAMP_COU- PLING_RA- TIO_NEG	Ratio of current collected on a pin to the negative current injected into a neighboring pin	_	_	1.2	%	
SID19C	R _{CLAMP_INTERNAL}	Internal pin resistance to current collection point		_	50	Ω	

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26.6.2 Calculating the impact of neighboring pins

The three ADC specifications based on SID19A, SID19B, and SID19C, can be used to calculate the pin leakage and resulting ADC offset caused by injection current using the below formula:

I_{LEAK} = I_{INJECTED} × CLAMP_COUPLING_RATIO

 $V_{ERROR} = I_{LEAK} \times (R_{CLAMP_INTERNAL} + R_{SOURCE})$

Code Error = $V_{ERROR} \times 2^{12} / V_{REF}$

Where:

I_{INJECTED} is the injected current in mA.

I_{LEAK} is the calculated leakage current in mA.

V_{ERROR} is the voltage error calculated due to leakage currents in V.

V_{RFF} is the ADC reference voltage in V.

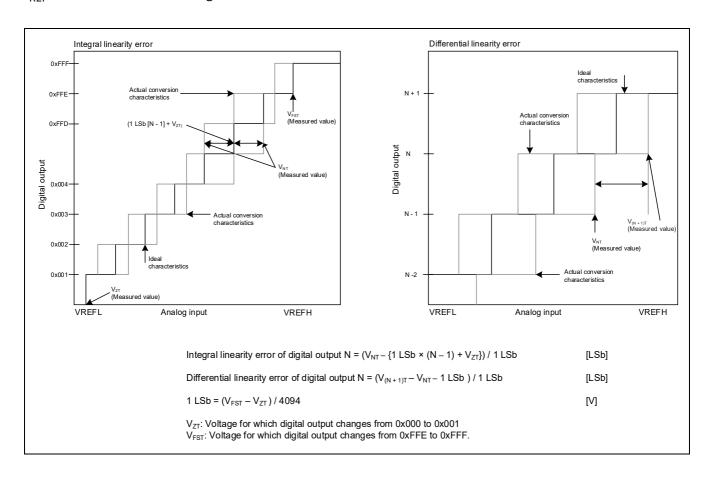


Figure 26-5 Integral and differential linearity errors

Note

 $52.V_{DDD}$ must be greater than $0.8 \times V_{DDA}$ when ADC[2] is enabled. V_{DDIO_1} must be greater than $0.8 \times V_{DDA}$ when ADC[0] is enabled.

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Electrical specifications



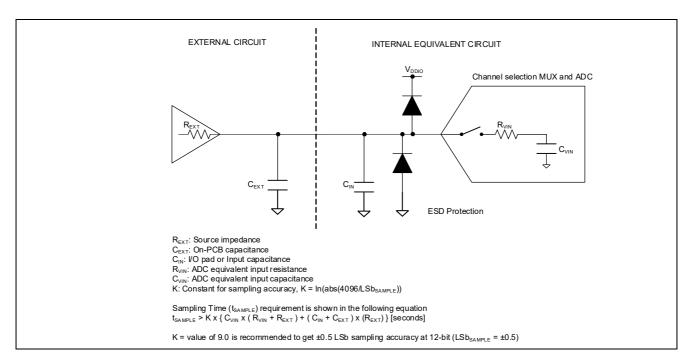


Figure 26-6 ADC equivalent circuit for analog input

Table 26-7 SAR ADC AC specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID104	V _{ZT}	Zero transition voltage	-20	-	20	mV	$V_{DDA} = 2.7 \text{ V to } 5.5 \text{ V},$ -40 °C \leq T _A \leq 125 °C before offset adjustment
SID105	V _{FST}	Full-scale transition voltage	-20	-	20	mV	$V_{DDA} = 2.7 \text{ V to } 5.5 \text{ V},$ -40 °C \leq T _A \leq 125 °C before offset adjustment
SID114	f _{ADC_4P5}	ADC operating frequency	2	-	26.67	MHz	$4.5 \text{ V} \leq \text{V}_{\text{DDA}} \leq 5.5 \text{ V}$
SID114A	f _{ADC_2P7}	ADC operating frequency	2	-	13.34	MHz	$2.7 \text{ V} \le \text{V}_{DDA} < 4.5 \text{ V}$
SID113	t _{S_4P5}	Analog input sample time for channels of own SARMUX	412	-	_	ns	4.5 V ≤ V _{DDA} ≤ 5.5 V Guaranteed by design
SID113A	t _{S_2P7}	Analog input sample time for channels of own SARMUX	600	-	_	ns	2.7 V ≤ V _{DDA} < 4.5 V Guaranteed by design
SID113B	t _{S_DR_4P5}	Analog input sample time when input is from diagnostic reference	2	-	_	μs	4.5 V ≤ V _{DDA} ≤ 5.5 V Guaranteed by design
SID113C	t _{S_DR_2P7}	Analog input sample time when input is from diagnostic reference	2.5	-	_	μs	2.7 V ≤ V _{DDA} < 4.5 V Guaranteed by design
SID113D	t _{S_TS}	Analog input sample time for temperature sensor	3	-	-	μs	2.7 V ≤ V _{DDA} ≤ 5.5 V Guaranteed by design

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Electrical specifications



Table 26-7 SAR ADC AC specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID113E	t _{S_4P5_A}	Analog input sample time for channels of another SARMUXn (n=1,2)	824	-	-	ns	4.5 V ≤ V _{DDA} ≤ 5.5 V When ADC0 borrows the SARMUX of another ADC, guaranteed by design
SID113F	t _{S_2P7_A}	Analog input sample time for channels of another SARMUXn (n=1,2)	1648	_	I	ns	2.7V ≤ V _{DDA} ≤ 4.5 V When ADC0 borrows the SARMUX of another ADC, guaranteed by design
SID106	t _{ST_4P5}	ADC max throughput (samples per second) when using the SARMUX of own ADC	ı	_	1	Msps	4.5 V ≤ V _{DDA} ≤ 5.5 V, 80 MHz / 3 = 26.67 MHz, 11 sampling cycles, 15 conversion cycles
SID106A	t _{ST_2P7}	ADC max throughput (samples per second) when using the SARMUX of own ADC	-	-	0.5	Msps	2.7 V ≤ V _{DDA} < 4.5 V 80 MHz / 6 = 13.3 MHz, 11 sampling cycles, 15 conversion cycles
SID106B	t _{ST_4P5_A}	ADC0 max throughput (samples per second) when borrowing the SARMUXn of another ADC (n=1,2)	-	-	0.5	Msps	4.5 V ≤ V _{DDA} ≤ 5.5 V, 80 MHz/6 = 13.3 MHz, 11 sampling cycles, 15 conversion cycles
SID106C	t _{ST_2P7_A}	ADC0 max throughput (samples per second) when borrowing the SARMUXn of another ADC (n=1,2)	-	-	0.25	Msps	2.7V \le VDDA < 4.5 V, 80 MHz / 12 = 6.67 MHz, 11 sampling cycles, 15 conversion cycles
SID107	C _{VIN}	ADC input sampling capacitance	-	_	4.8	pF	Guaranteed by design
SID108	R _{VIN1}	Input path ON resistance (4.5 V to 5.5 V)	-	-	9.4	kΩ	Guaranteed by design
SID108A	R _{VIN2}	Input path ON resistance (2.7 V to 4.5 V)	-	_	13.9	kΩ	Guaranteed by design
SID108B	R _{DREF1}	Diagnostic path ON resistance (4.5 V to 5.5 V)	-	_	40	kΩ	Guaranteed by design
SID108C	R _{DREF2}	Diagnostic path ON resistance (2.7 V to 4.5 V)	-	_	50	kΩ	Guaranteed by design
SID119	ACC_RLAD	Diagnostic reference resistor ladder accuracy	-4	-	4	%	
SID109	A_TE	Total error	-5	_	5	LSb	V _{DDA} = V _{REFH} = 2.7 V to 5.5 V, V _{REFL} = V _{SSA} -40 °C ≤ T _A ≤ 125 °C Total error after offset and gain adjustment at 12 bit resolution mode
SID109A	A_TEB	Total error	-12	-	12	LSb	$V_{DDA} = V_{REFH} = 2.7 \text{ V to}$ 5.5 V, $V_{REFL} = V_{SSA}$ $-40 \text{ °C} \le T_A \le 125 \text{ °C}$ Total error before offset and gain adjustment at 12 bit resolution mode
SID110	A_INL	Integral nonlinearity	-2.5	_	2.5	LSb	$V_{DDA} = 2.7 \text{ V to } 5.5 \text{ V},$ -40 °C \le T _A \le 125 °C

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Electrical specifications



Table 26-7 SAR ADC AC specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID111	A_DNL	Differential nonlinearity	-0.99	_	1.9	LSb	$V_{DDA} = 2.7 \text{ V to } 5.5 \text{ V},$ -40 °C \le T_A \le 125 °C
SID112	A_CE	Channel-to-channel variation (for channels connected to same ADC)	-1	-	1	LSb	$V_{DDA} = 2.7 \text{ V to } 5.5 \text{ V},$ -40 °C \leq T _A \leq 125 °C
SID115	I _{AIC}	Analog input leakage current	-350	70	350	nA	When input pad is selected for conversion
SID116	I _{DIAGREF}	Diagnostic reference current	-	-	70	μΑ	
SID117	I _{VDDA}	Analog power supply current while ADC is operating	-	360	550	μΑ	Per enabled ADC
SID117A	I _{VDDA_DS}	Analog power supply current while ADC is not operating	-	-	21	μА	Per enabled ADC
SID118	I _{VREF}	Analog reference voltage current while ADC is operating	-	360	550	μА	Per enabled ADC
SID118A	I _{VREF_LEAK}	Analog reference voltage current while ADC is not operating	-	1.8	5	μΑ	Per enabled ADC

26.6.3 Temperature sensor

Table 26-8 Temperature sensor specifications

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID201	T _{SENSACC2}	Temperature sensor accuracy 2	-5	-	5	°C	$ \begin{array}{l} -40 \text{ °C} \leq T_{\text{J}} \leq 150 \text{ °C} \\ \text{This spec is valid when using ADC[0]} \\ (V_{\text{DDIO}_1}), \text{ADC[1]} \\ (V_{\text{DDD}}) \text{ with the following} \\ \text{conditions:} \\ \text{a. } 3.0 \text{ V} \leq \text{V}_{\text{DDD}}, \text{V}_{\text{DDIO}_1} \text{ or V}_{\text{DDIO}_2} = \\ \text{V}_{\text{DDA}} = \text{V}_{\text{REFH}} \leq 3.6 \text{ V} \\ \text{or} \\ \text{b. } 4.5 \text{ V} \leq \text{V}_{\text{DDD}}, \text{V}_{\text{DDIO}_1} \text{ or V}_{\text{DDIO}_2} = \\ \text{V}_{\text{DDA}} = \text{V}_{\text{REFH}} \leq 5.5 \text{ V} \end{array} $
SID201A	T _{SENSACC3}	Temperature sensor accuracy 3	-10	-	10	°C	-40 °C ≤ T_J ≤ 150 °C This spec is valid when using ADC[0] (V_{DDIO_1}) or ADC[2] (V_{DDD}) with the following condition: 2.7 V ≤ V_{DDD} or V_{DDIO_1} ≤ 5.5 V and 2.7 V ≤ V_{DDA} = V_{REFH} ≤ 5.5 V and 0.8 × V_{DDA} < V_{DDD} or V_{DDIO_1}

26.6.4 Voltage divider accuracy

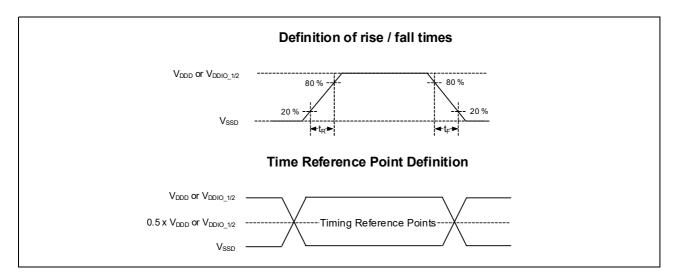
Table 26-9 Voltage divider accuracy

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID202	V _{MONDIV}	Uncorrected monitor voltage divider accuracy (measured by ADC), compared to ideal supply/2	-20	2	20	%	Any HV supply pad within 2.7-V–5.5-V operating range

Electrical specifications

AC specifications 26.7

Unless otherwise noted, the timings are defined with the guidelines mentioned in the Figure 26-7.



AC timings specifications Figure 26-7



26.8 Digital peripherals

All specifications are valid for –40 °C \leq T $_{A}$ \leq 125 °C and for 2.7 V to 5.5 V except where noted.

Table 26-10 Timer/counter/PWM (TCPWM) specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID120	f _C	TCPWM operating frequency	_	_	100	MHz	f _C = peripheral clock
SID121	t _{PWMENEXT}	Input trigger pulse width for all trigger events	2 / f _C	-	-	ns	Trigger Events can be Stop, Start, Reload, Count, Capture, or Kill depending on which mode of operation is selected.
SID122	t _{PWMEXT}	Output trigger pulse widths	2 / f _C	_	-	ns	Minimum possible width of Overflow, Underflow, and Counter = Compare (CC) value trigger outputs
SID123	t _{CRES}	Resolution of counter	1 / f _C	_	_	ns	Minimum time between successive counts
SID124	t _{PWMRES}	PWM resolution	1 / f _C	-	-	ns	Minimum pulse width of PWM output
SID125	t _{QRES}	Quadrature inputs resolution	2 / f _C	_	-	ns	Minimum pulse width between Quadrature phase inputs.

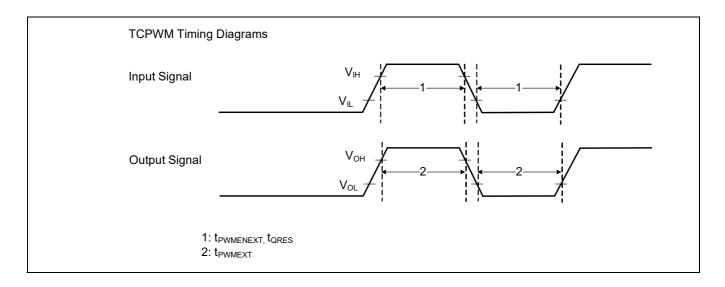
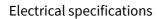


Figure 26-8 TCPWM timing diagrams

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Serial communication block (SCB) specifications **Table 26-11**

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID129	f_{SCB}	SCB operating frequency	-	-	100	MHz	
I ² C Interf	ace-Standard-	mode	1		.1		
SID130	f_{SCL}	SCL clock frequency	_	_	100	kHz	
SID131	t _{HD;STA}	Hold time, START condition	4000	-	-	ns	
SID132	t_{LOW}	Low period of SCL	4700	_	-	ns	
SID133	t _{HIGH}	High period of SCL	4000	-	-	ns	
SID134	t _{SU;STA}	Setup time for a repeated START	4700	_	_	ns	
SID135	t _{HD;DAT}	Data hold time, for receiver	0	_	_	ns	
SID136	t _{SU;DAT}	Data setup time	250	_	_	ns	
SID138	t _F	Fall time of SCL and SDA	-	_	300	ns	Input and output
SID139	t _{SU;STO}	Setup time for STOP	4000	-	-	ns	
SID140	t _{BUF}	Bus-free time between START and STOP	4700	_	_	ns	
SID141	C _B	Capacitive load for each bus line	-	_	400	pF	
SID142	t _{VD;DAT}	Time for data signal from SCL LOW to SDA output	-	_	3450	ns	
SID143	t _{VD;ACK}	Data valid acknowledge time	-	_	3450	ns	
SID144	V _{OL}	LOW level output voltage	0	_	0.4	V	Open-drain at 3 mA sink current
SID145	I _{OL}	LOW level output current	3	-	_	mA	V _{OL} = 0.4 V
I ² C Interf	ace-Fast-mod	9					
SID150	f _{SCL_F}	SCL clock frequency	-	-	400	kHz	
SID151	t _{HD;STA_F}	Hold time, START condition	600	_	_	ns	
SID152	t _{LOW_F}	Low period of SCL	1300	_	_	ns	
SID153	t _{HIGH_F}	High period of SCL	600	_	_	ns	
SID154	t _{SU;STA_F}	Setup time for a repeated START	600	_	_	ns	
SID155	t _{HD;DAT_F}	Data hold time, for receiver	0	-	_	ns	
SID156	t _{SU;DAT_F}	Data setup time	100	-	-	ns	
SID158	t _{F_F}	Fall time of SCL and SDA	20 × (V _{DDD} / 5.5)	-	300	ns	Input and output, GPIO_ENH: slow mode, 400 pF load

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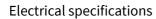
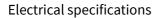




 Table 26-11
 Serial communication block (SCB) specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID158A	t _{FA_F}	Fall time of SCL and SDA	0.35	-	300	ns	Input and output GPIO_STD: drive_sel<1:0>= 0b00 MIN: 10 pF load, RPU = 35.41 k Ω MAX: 400 pF load, RPU = 350 Ω
SID159	t _{SU;STO_F}	Setup time for STOP	600	-	_	ns	Input and output
SID160	t _{BUF_F}	Bus free time between START and STOP	1300	-	_	ns	
SID161	C _{B_F}	Capacitive load for each bus line	-	-	400	pF	
SID162	t _{VD;DAT_F}	Time for data signal from SCL LOW to SDA output	-	-	900	ns	
SID163	t _{VD;ACK_F}	Data valid acknowledge time	-	-	900	ns	
SID164	t _{SP_F}	Pulse width of spikes that must be suppressed by the input filter	-	-	50	ns	
SID165	V _{OL_F}	LOW level output voltage	0	-	0.4	V	Open-drain at 3 mA sink current
SID165	I _{OL_F}	LOW level output current	3	-	-	mA	V _{OL} = 0.4 V
SID167	I _{OL2_F}	LOW level output current	6	-	_	mA	$V_{OL} = 0.6 V^{[53]}$
I ² C Interf	ace-Fast-Plus	mode					
SID170	f _{SCL_FP}	SCL clock frequency	_	-	1	MHz	
SID171	t _{HD;STA_FP}	Hold time, START condition	260	-	_	ns	
SID172	t _{LOW_FP}	Low period of SCL	500	-	_	ns	
SID173	t _{HIGH_FP}	High period of SCL	260	-	_	ns	
SID174	t _{SU;STA_FP}	Setup time for a repeated START	260	-	-	ns	
SID175	t _{HD;DAT_FP}	Data hold time, for receiver	0	-	_	ns	
SID176	t _{SU;DAT_FP}	Data setup time	50	-	_	ns	
SID178	t _{F_FP}	Fall time of SCL and SDA	20 × (V _{DDD} /5.5)	-	160	ns	Input and output 20-pF load GPIO_ENH: slow mode
SID179	t _{SU;STO_FP}	Setup time for STOP	260	-	-	ns	Input and output
SID180	t _{BUF_FP}	Bus free time between START and STOP	500	-	-	ns	
SID181	C _{B_FP}	Capacitive load for each bus line	-	-	20	pF	
SID182	t _{VD;DAT_FP}	Time for data signal from SCL LOW to SDA output	-	-	450	ns	

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Serial communication block (SCB) specifications (continued) **Table 26-11**

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID183	t _{VD;ACK_FP}	Data valid acknowledge time	_	_	450	ns	
SID184	t _{SP_FP}	Pulse width of spikes that must be suppressed by the input filter	-	-	50	ns	
SID186	V _{OL_FP}	LOW level output voltage	0	_	0.4	V	Open-drain at 3 mA sink current
SID187	I _{OL_FP}	LOW level output current	3	_	-	mA	$V_{OL} = 0.4 V^{[54]}$
SPI Inter	face Master (Fu	ıll-clock mode: LATE_MIS	O_SAMPLE	= 1) [Cond	litions: d	rive_s	el<1:0>= 0x]
SID190	f _{SPI}	SPI operating frequency	-	-	12.5	MHz	Do not use half-clock mode: LATE_MISO_SAMPLE = 0
SID191	t _{DMO}	SPI Master: MOSI valid after SCLK driving edge	_	_	15	ns	
SID192	t _{DSI}	SPI Master: MISO valid before SCLK capturing edge	40	_	-	ns	
SID193	t _{HMO}	SPI Master: Previous MOSI data hold time	0	_	-	ns	
SID194	t _{W_SCLK_H_L}	SPI SCLK pulse width HIGH or LOW	_	0.4 × (1 / f _{SPI})	-	ns	
SID196	t _{DHI}	SPI Master: MISO hold time after SCLK capturing edge	0	_	-	ns	
SID198	t _{EN_SETUP}	SSEL valid, before the first SCK capturing edge	0.5 × (1/f _{SPI})	_	-	ns	Min is half clock period
SID199	t _{EN_SHOLD}	SSEL hold, after the last SCK capturing edge	0.5 × (1/f _{SPI})	_	-	ns	Min is half clock period
SID195	C _{SPIM_MS}	SPI capacitive load	-	-	10	pF	
SPI Inter	face Slave (inte	ernally clocked) [Conditio	ns: drive_s	sel<1:0>=	Dx]		
SID205	f _{SPI_INT}	SPI operating frequency	ı	_	10	MHz	
SID206	t _{DMI_INT}	SPI Slave: MOSI Valid before Sclock capturing edge	5	_	-	ns	
SID207	t _{DSO_INT}	SPI Slave: MISO Valid after Sclock driving edge, in the internal-clocked mode	-	-	62	ns	
SID208	t _{HSP}	SPI Slave: Previous MISO data hold time	3	_	_	ns	
SID209	t _{EN_SETUP_INT}	SPI Slave: SSEL valid to first SCK valid edge	33	_	_	ns	

Notes

^{53.}In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL}.
54.In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL}. However, this device does not support it.

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 Table 26-11
 Serial communication block (SCB) specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID210	t _{EN_HOLD_INT}	SPI Slave Select active (LOW) from last SCLK hold	33	-	_	ns	
SID211	t _{EN_SETUP_PRE}	SPI Slave: from SSEL valid, to SCK falling edge before the first data bit	20	_	_	ns	
SID212	t _{EN_HOLD_PRE}	SPI Slave: from SCK falling edge before the first data bit, to SSEL invalid	20	_	_	ns	
SID213	t _{EN_SETUP_CO}	SPI Slave: from SSEL valid, to SCK falling edge in the first data bit	20	_	_	ns	
SID214	t _{EN_HOLD_CO}	SPI Slave: from SCK falling edge in the first data bit, to SSEL invalid	20	_	_	ns	
SID215	t _{W_DIS_INT}	SPI Slave Select inactive time	40	_	_	ns	
SID216	t _{W_SCLKH_INT}	SPI SCLK pulse width HIGH	20	-	_	ns	
SID217	t _{W_SCLKL_INT}	SPI SCLK pulse width LOW	20	-	_	ns	
SID218	t _{SIH_INT}	SPI MOSI hold from SCLK	12	-	_	ns	
SID219	C _{SPIS_INT}	SPI capacitive load	_	-	10	pF	
SPI Interf		ernally clocked) [Condition	ns: drive_s	sel<1:0>=	0x]	ı	
SID220	f _{SPI_EXT}	SPI operating frequency	-	_	12.5	MHz	
SID221	t _{DMI_EXT}	SPI Slave: MOSI Valid before Sclock capturing edge	5	-	-	ns	
SID222	t _{DSO_EXT}	SPI Slave: MISO Valid after Sclock driving edge, in the external-clocked mode	-	-	32	ns	
SID223	t _{HSO_EXT}	SPI Slave: Previous MISO data hold time	3	_	_	ns	
SID224	t _{EN_SETUP_EXT}	SPI Slave: SSEL valid to first SCK valid edge	40	-	_	ns	
SID225	t _{EN_HOLD_EXT}	SPI Slave Select active (LOW) from last SCLK hold	40	_	-	ns	
SID226	t _{W_DIS_EXT}	SPI Slave Select inactive time	80	-	_	ns	
SID227	t _{W_SCLKH_EXT}	SPI SCLK pulse width HIGH	34	_	_	ns	
SID228	t _{W_SCLKL_EXT}	SPI SCLK pulse width LOW	34	_	_	ns	
SID229	t _{SIH_EXT}	SPI MOSI hold from SCLK	20	_	_	ns	

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Table 26-11 Serial communication block (SCB) specifications (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID230	C _{SPIS_EXT}	SPI capacitive load	-	-	10	pF	
SID231	t _{VSS_EXT}	SPI Slave: MISO valid after SSEL falling edge (CPHA = 0)	_	-	33	ns	
UART Inte	erface						
SID240	f _{BPS}	Data rate	-	_	10	Mbps	

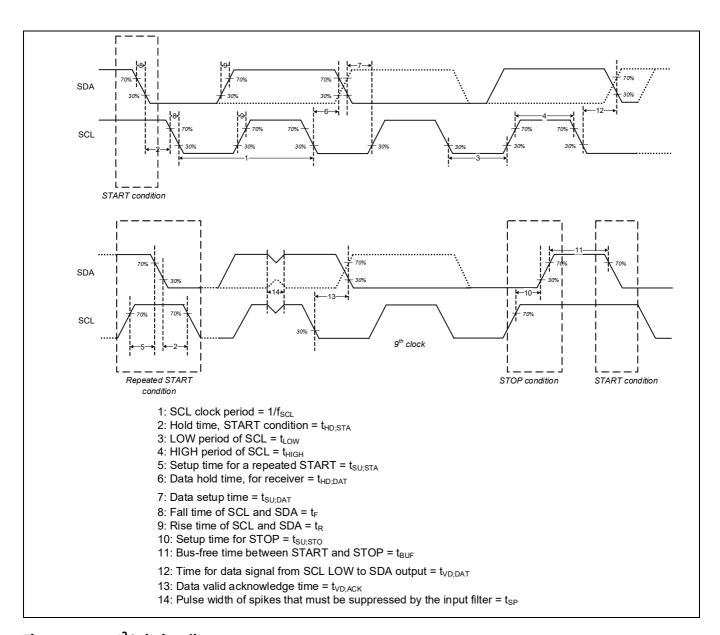


Figure 26-9 I²C timing diagrams

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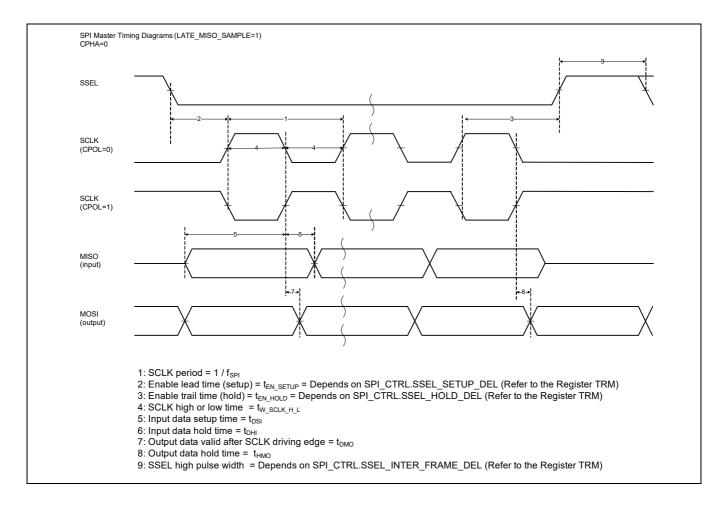


Figure 26-10 SPI master timing diagrams with LOW clock phase

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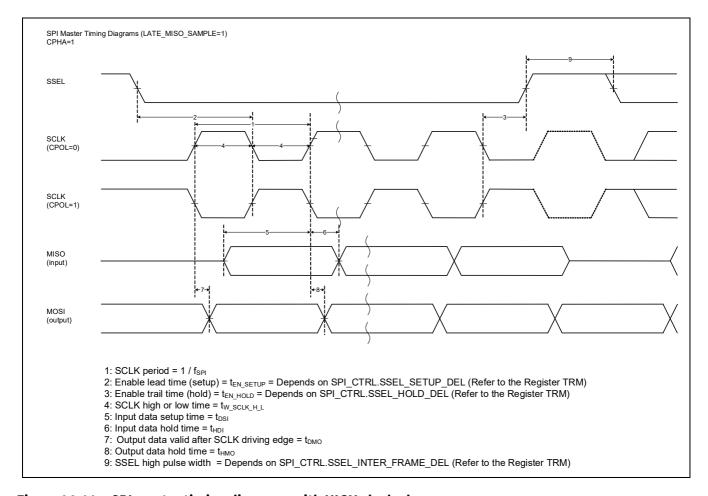


Figure 26-11 SPI master timing diagrams with HIGH clock phase

Based on Arm® Cortex®-M4F single



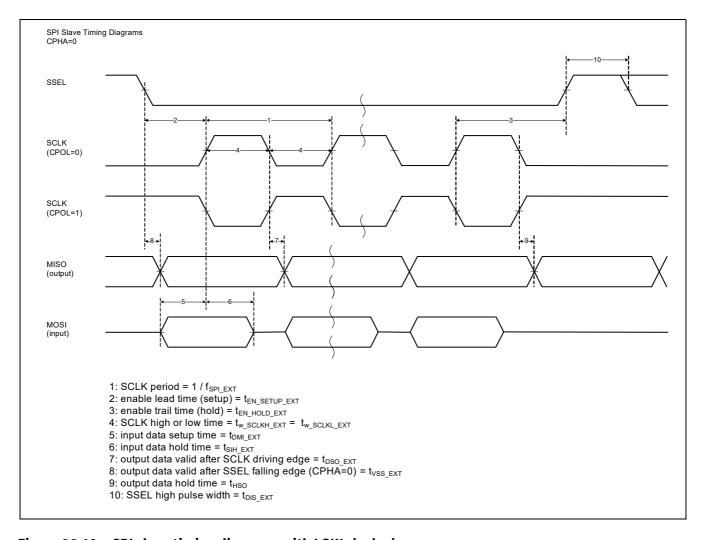


Figure 26-12 SPI slave timing diagrams with LOW clock phase

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Electrical specifications



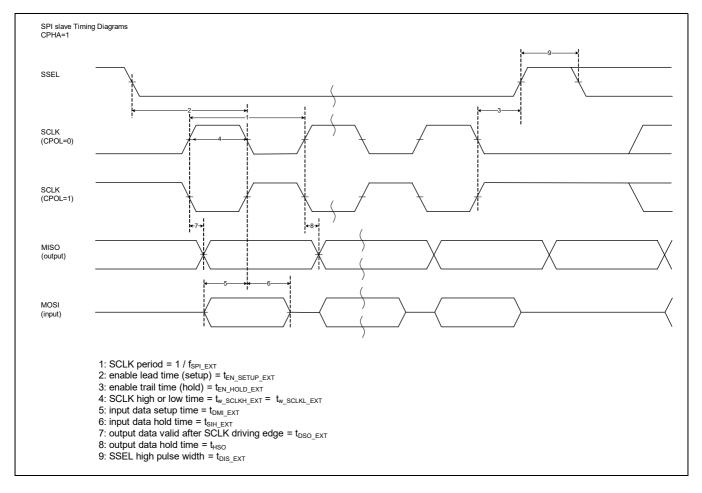


Figure 26-13 SPI slave timing diagrams with HIGH clock phase

26.8.1 LIN specifications

Table 26-12 LIN specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID249	f _{LIN}	Internal clock frequency to the LIN block	-	_	100	MHz	
SID250	BR_NOM	Bit rate on the LIN bus	1	-	20	kbps	Guaranteed by design
SID250A	BR_REF	Bit rate on the LIN bus (not in standard LIN specification) for re-flashing in LIN slave mode	1	_	115.2	kbps	Guaranteed by design

26.8.2 CAN FD specifications

Table 26-13 CAN FD specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID630	f _{HCLK}	System clock frequency	_	_	100	MHz	f _{cclk} ≤ f _{hclk} , Guaranteed by design
SID631	f _{CCLK}	CAN clock frequency	_	_	100	MHz	f _{cclk} ≤ f _{hclk} , Guaranteed by design

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Electrical specifications



26.9 Memory

All specifications are valid for –40 °C \leq T_A \leq 125 °C and for 2.7 V to 5.5 V except where noted.

Table 26-14 Flash DC specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID260	V_{PE}	Erase and program voltage	2.7	-	5.5	V	

Table 26-15 Flash AC specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID257	f _{FO}	Maximum flash memory operation frequency	-	-	100	MHz	Zero wait access to code-flash memory up to 100 MHz Zero wait access with cache hit up to 160 MHz
SID254	t _{ERS_SUS}	Maximum time from erase suspend command till erase is indeed suspend	-	-	37.5	μs	
SID255	t _{ERS_RES_SUS}	Minimum time allowed from erase resume to erase suspend	250	_	_	μs	Guaranteed by design
SID258	t _{BC_WF}	Blank check time for N-bytes of work-flash	-	-	10 + 0.3 × N	μs	At 100 MHz, N≥4 and multiple of 4, excludes system overhead time
SID259	t _{SECTORERASE1}	Sector erase time (Code-flash: 32 KB)	-	45	90	ms	Includes internal preprogramming time
SID259A	t _{SECTORERASE2}	Sector erase time (Code-flash: 8 KB)	-	15	30	ms	Includes internal preprogramming time
SID261	t _{SECTORERASE3}	Sector erase time (Work-flash, 2 KB)	-	80	160	ms	Includes internal preprogramming time
SID262	t _{SECTORERASE4}	Sector erase time (Work-flash, 128 bytes)	-	5	15	ms	Includes internal preprogramming time
SID263	t _{WRITE1}	64-bit write time (Code-flash)	-	30	60	μs	Excludes system overhead time
SID264	t _{WRITE2}	256-bit write time (Code-flash)	-	40	70	μs	Excludes system overhead time
SID265	t _{WRITE3}	4096-bit write time (Code-flash) ^[55]	-	320	1200	μs	Excludes system overhead time
SID266	t _{WRITE4}	32-bit write time (Work-flash)	_	30	60	μs	Excludes system overhead time
SID267	t _{FRET1}	Code-flash retention. 1000 program/erase cycles	20	_	_	years	T _A (power on and off) ≤ 85 °C average
SID268	t _{FRET3}	Work-flash retention. 125,000 program/erase cycles	20	-	_	years	T _A (power on and off) ≤ 85 °C average
SID269	t _{FRET4}	Work-flash retention. 250,000 program/erase cycles	10	_	_	years	T _A (power on and off) ≤ 85 °C average
SID612	I _{CC_ACT2}	Program operating current (Code or Work-flash)	-	15	48	mA	V _{DDD} = 5 V Guaranteed by design
SID613	I _{CC_ACT3}	Erase operating current (Code or Work-flash)	-	15	48	mA	V _{DDD} = 5 V Guaranteed by design

Note

^{55.} The code-flash includes a 'Write Buffer' of 4096-bit. If the application software writes this buffer multiple times, to get the overall write time multiply one sector write time with the corresponding factor (say for factor 64, example, 64 x 512 B = 32 KB [one sector]).

Based on Arm® Cortex®-M4F single

Electrical specifications



26.10 System resources

All specifications are valid for –40 °C \leq T $_{A}$ \leq 125 °C and for 2.7 V to 5.5 V except where noted.

Table 26-16 System resources

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
Power-o	n-reset specifica	ations		1		1	1
SID270	V _{POR_R}	V _{DDD} rising voltage to deassert POR	1.5	-	2.35	V	Guaranteed by design
SID276	V _{POR_F}	V _{DDD} falling voltage to assert POR	1.45	-	2.1	V	
SID271	V _{POR_H}	Level detection hysteresis	20	-	300	mV	Guaranteed by design
SID272	t _{DLY_POR}	Delay between V _{DDD} rising through 2.3 V and an internal deassertion of POR	_	_	3	μs	Guaranteed by design
SID273	t _{POFF}	V _{DDD} Power off time	100	-	-	μs	V _{DDD} < 1.45 V
SID274	POR_RR1	V _{DDD} power ramp rate with robust BOD (BOD operation is guaranteed)	-	-	100	mV/μs	This ramp supports robust BOD
SID275	POR_RR2	V _{DDD} power ramp rate without robust BOD	-	-	1000	mV/μs	This ramp does not support robust BOD t _{POFF} must be satisfied
High-vo	ltage BOD (HV Bo	OD) specifications					
SID500	V _{TR_2P7_R}	HV BOD 2.7 V rising detection point for V _{DDD} and V _{DDA} (default)	2.474	2.55	2.627	V	
SID501	V _{TR_2P7_F}	HV BOD 2.7 V falling detection point for V _{DDD} and V _{DDA} (default)	2.449	2.525	2.601	V	
SID502	V _{TR_3P0_R}	HV BOD 3.0 V rising detection point for V _{DDD} and V _{DDA}	2.765	2.85	2.936	V	
SID503	V _{TR_3P0_F}	HV BOD 3.0 V falling detection point for V _{DDD} and V _{DDA}	2.74	2.825	2.91	V	
SID505	HVBOD_RR_A	Power ramp rate: V _{DDD} and V _{DDA} (Active)	-	-	100	mV/μs	
SID506	HVBOD_RR_DS	Power ramp rate: V _{DDD} and V _{DDA} (DeepSleep)	-	-	10	mV/μs	
SID507	t _{DLY_ACT_HVBOD}	Active mode delay between V _{DDD} falling/rising through V _{TR_2P7_F/R} or V _{TR_3P0_F/R} and an internal HV BOD signal transitioning	_	_	0.5	μs	Guaranteed by design
SID507A	t _{DLY_ACT_HVBOD}	Active mode delay between V _{DDA} falling/rising through V _{TR_2P7_F/R} or V _{TR_3P0_F/R} and internal HV BOD signal transitioning	-	-	1	μs	Guaranteed by design

Based on Arm® Cortex®-M4F single



 Table 26-16
 System resources (continued)

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
SID507 B	t _{DLY_DS_HVBOD}	DeepSleep mode delay between V _{DDD} /V _{DDA} falling/rising through V _{TR_2P7_F/R} or V _{TR_3P0_F/R} and an internal HV BOD signal transitioning	-	-	4	μs	Guaranteed by design
SID508	t _{RES_HVBOD}	Response time of HV BOD, V _{DDD} /V _{DDA} supply. (For falling-then-rising supply at max ramp rate; threshold is V _{TR_2P7_F} or V _{TR_3P0_F} .)	100	-	-	ns	Guaranteed by design
Low-vol	tage BOD (LV BO	D) specifications					
SID510	V _{TR_R_LVBOD}	LV BOD rising detection point for V _{CCD}	0.917	0.945	0.973	V	
SID511	V _{TR_F_LVBOD}	LV BOD falling detection point for V _{CCD}	0.892	0.92	0.948	V	
SID515	t _{DLY_ACT_LVBOD}	Active delay between V _{CCD} falling/rising through V _{TR_R/F_LVBOD} and an internal LV BOD signal transitioning	-	-	1	μs	Guaranteed by design
SID515A	t _{DLY_DS_LVBOD}	DeepSleep mode delay between V _{CCD} falling/rising through V _{TR_R/F_LVBOD} and an internal LV BOD signal transi- tioning	-	-	12	μs	Guaranteed by design
SID516	t _{RES_LVBOD}	Response time of LV BOD. (For falling-then-rising supply at max ramp rate; threshold is $V_{TR_F_LVBOD}$.)	100	-	-	ns	Guaranteed by design
Low-vol	tage detector (L'	VD) DC specifications					
SID520	V _{TR_2P8_F}	LVD 2.8 V falling detection point for V _{DDD}	Typ – 4%	2800	Typ + 4%	mV	
SID521	V _{TR_2P9_F}	LVD 2.9 V falling detection point for V _{DDD}	Typ – 4%	2900	Typ + 4%	mV	
SID522	V _{TR_3P0_F}	LVD 3.0 V falling detection point for V _{DDD}	Typ – 4%	3000	Typ + 4%	mV	
SID523	V _{TR_3P1_F}	LVD 3.1 V falling detection point for V _{DDD}	Typ – 4%	3100	Typ + 4%	mV	
SID524	V _{TR_3P2_F}	LVD 3.2 V falling detection point for V _{DDD}	Typ – 4%	3200	Typ + 4%	mV	
SID525	V _{TR_3P3_F}	LVD 3.3 V falling detection point for V _{DDD}	Typ – 4%	3300	Typ + 4%	mV	
SID526	V _{TR_3P4_F}	LVD 3.4 V falling detection point for V _{DDD}	Typ – 4%	3400	Typ + 4%	mV	
SID527	V _{TR_3P5_F}	LVD 3.5 V falling detection point for V _{DDD}	Typ – 4%	3500	Typ + 4%	mV	
SID528	V _{TR_3P6_F}	LVD 3.6 V falling detection point for V _{DDD}	Typ – 4%	3600	Typ + 4%	mV	
SID529	V _{TR_3P7_F}	LVD 3.7 V falling detection point for V _{DDD}	Typ – 4%	3700	Typ + 4%	mV	

Based on Arm® Cortex®-M4F single

Electrical specifications



 Table 26-16
 System resources (continued)

Table 26	<u> </u>						Details/
Spec ID	Parameter	Description	Min	Тур	Max	Units	Conditions
SID530	V _{TR_3P8_F}	LVD 3.8 V falling detection point for V _{DDD}	Typ - 4%	3800	Typ + 4%	mV	
SID531	V _{TR_3P9_F}	LVD 3.9 V falling detection point for V _{DDD}	Typ – 4%	3900	Typ + 4%	mV	
SID532	V _{TR_4P0_F}	LVD 4.0 V falling detection point for V _{DDD}	Typ – 4%	4000	Typ + 4%	mV	
SID533	V _{TR_4P1_F}	LVD 4.1 V falling detection point for V _{DDD}	Typ – 4%	4100	Typ + 4%	mV	
SID534	V _{TR_4P2_F}	LVD 4.2 V falling detection point for V _{DDD}	Typ – 4%	4200	Typ + 4%	mV	
SID535	V _{TR_4P3_F}	LVD 4.3 V falling detection point for V _{DDD}	Typ – 4%	4300	Typ + 4%	mV	
SID536	V _{TR_4P4_F}	LVD 4.4 V falling detection point for V _{DDD}	Typ – 4%	4400	Typ + 4%	mV	
SID537	V _{TR_4P5_F}	LVD 4.5 V falling detection point for V _{DDD}	Typ – 4%	4500	Typ + 4%	mV	
SID538	V _{TR_4P6_F}	LVD 4.6 V falling detection point for V _{DDD}	Typ – 4%	4600	Typ + 4%	mV	
SID539	V _{TR_4P7_F}	LVD 4.7 V falling detection point for V _{DDD}	Typ – 4%	4700	Typ + 4%	mV	
SID540	V _{TR_4P8_F}	LVD 4.8 V falling detection point for V _{DDD}	Typ – 4%	4800	Typ + 4%	mV	
SID541	V _{TR_4P9_F}	LVD 4.9 V falling detection point for V _{DDD}	Typ – 4%	4900	Typ + 4%	mV	
SID542	V _{TR_5P0_F}	LVD 5.0 V falling detection point for V _{DDD}	Typ – 4%	5000	Typ + 4%	mV	
SID543	V _{TR_5P1_F}	LVD 5.1 V falling detection point for V _{DDD}	Typ – 4%	5100	Typ + 4%	mV	
SID544	V _{TR_5P2_F}	LVD 5.2 V falling detection point for V _{DDD}	Typ – 4%	5200	Typ + 4%	mV	
SID545	V _{TR_5P3_F}	LVD 5.3 V falling detection point for V _{DDD}	Typ - 4%	5300	Typ + 4%	mV	
SID546	V _{TR_2P8_R}	LVD 2.8 V rising detection point for V _{DDD}	Typ - 4%	2825	Typ + 4%	mV	Same as V _{TR_2P8_F} + 25 mV
SID547	V _{TR_2P9_R}	LVD 2.9 V rising detection point for V _{DDD}	Typ – 4%	2925	Typ + 4%	mV	Same as V _{TR_2P9_F} + 25 mV
SID548	V _{TR_3P0_R}	LVD 3.0 V rising detection point for V _{DDD}	Typ – 4%	3025	Typ + 4%	mV	Same as V _{TR_3P0_F} + 25 mV
SID549	V _{TR_3P1_R}	LVD 3.1 V rising detection point for V _{DDD}	Typ – 4%	3125	Typ + 4%	mV	Same as V _{TR_3P1_F} + 25 mV
SID550	V _{TR_3P2_R}	LVD 3.2 V rising detection point for V _{DDD}	Typ - 4%	3225	Typ + 4%	mV	Same as V _{TR_3P2_F} + 25 mV
SID551	V _{TR_3P3_R}	LVD 3.3 V rising detection point for V _{DDD}	Typ – 4%	3325	Typ + 4%	mV	Same as V _{TR_3P3_F} + 25 mV
SID552	V _{TR_3P4_R}	LVD 3.4 V rising detection point for V _{DDD}	Typ - 4%	3425	Typ + 4%	mV	Same as V _{TR_3P4_F} + 25 mV
SID553	V _{TR_3P5_R}	LVD 3.5 V rising detection point for V _{DDD}	Typ – 4%	3525	Typ + 4%	mV	Same as V _{TR_3P5_F} + 25 mV

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 Table 26-16
 System resources (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID554	V _{TR_3P6_R}	LVD 3.6 V rising detection point for V _{DDD}	Typ – 4%	3625	Typ + 4%	mV	Same as V _{TR_3P6_F} + 25 mV
SID555	V _{TR_3P7_R}	LVD 3.7 V rising detection point for V _{DDD}	Typ – 4%	3725	Typ + 4%	mV	Same as V _{TR_3P7_F} + 25 mV
SID556	V _{TR_3P8_R}	LVD 3.8 V rising detection point for V _{DDD}	Typ – 4%	3825	Typ + 4%	mV	Same as V _{TR_3P8_F} + 25 mV
SID557	V _{TR_3P9_R}	LVD 3.9 V rising detection point for V _{DDD}	Typ – 4%	3925	Typ + 4%	mV	Same as V _{TR_3P9_F} + 25 mV
SID558	V _{TR_4P0_R}	LVD 4.0 V rising detection point for V _{DDD}	Typ – 4%	4025	Typ + 4%	mV	Same as V _{TR_4P0_F} + 25 mV
SID559	V _{TR_4P1_R}	LVD 4.1 V rising detection point for V _{DDD}	Typ – 4%	4125	Typ + 4%	mV	Same as V _{TR_4P1_F} + 25 mV
SID560	V _{TR_4P2_R}	LVD 4.2 V rising detection point for V _{DDD}	Typ – 4%	4225	Typ + 4%	mV	Same as $V_{TR_4P2_F}$ + 25 mV
SID561	V _{TR_4P3_R}	LVD 4.3 V rising detection point for V _{DDD}	Typ – 4%	4325	Typ + 4%	mV	Same as $V_{TR_4P3_F}$ + 25 mV
SID562	V _{TR_4P4_R}	LVD 4.4 V rising detection point for V _{DDD}	Typ – 4%	4425	Typ + 4%	mV	Same as V _{TR_4P4_F} + 25 mV
SID563	V _{TR_4P5_R}	LVD 4.5 V rising detection point for V _{DDD}	Typ – 4%	4525	Typ + 4%	mV	Same as V _{TR_4P5_F} + 25 mV
SID564	V _{TR_4P6_R}	LVD 4.6 V rising detection point for V _{DDD}	Typ – 4%	4625	Typ + 4%	mV	Same as $V_{TR_4P6_F}$ + 25 mV
SID565	V _{TR_4P7_R}	LVD 4.7 V rising detection point for V _{DDD}	Typ – 4%	4725	Typ + 4%	mV	Same as V _{TR_4P7_F} + 25 mV
SID566	V _{TR_4P8_R}	LVD 4.8 V rising detection point for V _{DDD}	Typ – 4%	4825	Typ + 4%	mV	Same as V _{TR_4P8_F} + 25 mV
SID567	V _{TR_4P9_R}	LVD 4.9 V rising detection point for V _{DDD}	Typ – 4%	4925	Typ + 4%	mV	Same as V _{TR_4P9_F} + 25 mV
SID568	V _{TR_5P0_R}	LVD 5.0 V rising detection point for V _{DDD}	Typ – 4%	5025	Typ + 4%	mV	Same as V _{TR_5P0_F} + 25 mV
SID569	V _{TR_5P1_R}	LVD 5.1 V rising detection point for V _{DDD}	Typ – 4%	5125	Typ + 4%	mV	Same as V _{TR_5P1_F} + 25 mV
SID570	V _{TR_5P2_R}	LVD 5.2 V rising detection point for V _{DDD}	Typ – 4%	5225	Typ + 4%	mV	Same as V _{TR_5P2_F} + 25 mV
SID571	V _{TR_5P3_R}	LVD 5.3 V rising detection point for V _{DDD}	Typ – 4%	5325	Typ + 4%	mV	Same as V _{TR_5P3_F} + 25 mV
SID573	LVD_RR_A	Power ramp rate: V _{DDD} (Active)	-	-	100	mV/μs	
SID574	LVD_RR_DS	Power ramp rate: V _{DDD} (DeepSleep)	-	-	10	mV/μs	
SID575	t _{DLY_ACT_LVD}	Active mode delay between V _{DDD} falling/rising through LVD rising/falling point and an internal LVD signal transitioning	-	-	1	μs	Guaranteed by design

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 Table 26-16
 System resources (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID575A	t _{DLY_DS_LVD}	DeepSleep mode delay between V _{DDD} falling/rising through LVD rising/falling point and an internal LVD signal rising	-	-	4	μs	Guaranteed by design
SID576	t _{RES_LVD}	Response time of LVD, V _{DDD} supply. LVD guaranteed to generate pulse for V _{DDD} pulse width greater than this. (For falling-then-rising supply at max ramp rate; pulse width is time below LVD falling point)	100	-	-	ns	Guaranteed by design
High-vo	ltage OVD (HV O	/D) specifications					
SID580	V _{TR_5P0_R}	HV OVD 5.0-V rising detection point for V _{DDD} and V _{DDA}	5.049	5.205	5.361	V	
SID581	V _{TR_5P0_F}	HV OVD 5.0-V falling detection point for V _{DDD} and V _{DDA}	5.025	5.18	5.335	V	
SID582	V _{TR_5P5_R}	HV OVD 5.5-V rising detection point for V _{DDD} and V _{DDA} (default)	5.548	5.72	5.892	V	
SID583	V _{TR_5P5_F}	HV OVD 5.5-V falling detection point for V _{DDD} and V _{DDA} (default)	5.524	5.695	5.866	V	
SID585	HVOVD_RR_A	Power ramp rate: V _{DDD} and V _{DDA} (Active)	-	-	100	mV/μs	
SID586	HVOVD_RR_DS	Power ramp rate: V _{DDD} and V _{DDA} (DeepSleep)	-	-	10	mV/μs	
SID587	t _{DLY_ACT_HVOVD}	Active mode delay between V _{DDD} falling/rising through V _{TR_5P0_F/R} or V _{TR_5P5_F/R} and an internal HV OVD signal transitioning	-	_	1	μs	Guaranteed by design
SID587A	t _{DLY_ACT_H} - VOVD_A	Active mode delay between V _{DDA} falling/rising through V _{TR_5P0_F/R} or V _{TR_5P5_F/R} and an internal HV OVD signal transitioning	-	-	1.5	μs	Guaranteed by design
SID587 B	t _{DLY_DS_HVOVD}	DeepSleep mode delay between V _{DDD} /V _{DDA} falling/rising through V _{TR_5P0_F/R} or V _{TR_5P5_F/R} and an internal HV OVD signal transitioning	-	-	4	μs	Guaranteed by design
SID588	t _{RES_HVOVD}	Response time of HV OVD. (For rising-then-falling supply at max ramp rate; threshold is $V_{TR_5P0_R}$ or $V_{TR_5P5_R}$.)	100	_	-	ns	Guaranteed by design
Low-vol	tage OVD (LV OV	D) specifications				•	
SID590	V _{TR_R_LVOVD}	LV OVD rising detection point for V _{CCD}	1.261	1.3	1.339	V	

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 Table 26-16
 System resources (continued)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID591	V _{TR_F_LVOVD}	LV OVD falling detection point for V _{CCD}	1.237	1.275	1.313	V	
SID595	t _{DLY_ACT_LVOVD}	Active mode delay between V _{CCD} falling/rising through V _{TR F/R LVOVD} and an internal LV OVD signal transitioning	-	-	1	μs	Guaranteed by design
SID595A	t _{DLY_DS_LVOVD}	DeepSleep mode delay between V _{CCD} falling/rising through V _{TR F/R LVOVD} and an internal LV OVD signal transi- tioning	-	-	12	μs	Guaranteed by design
SID596	t _{RES_LVOVD}	Response time of LV OVD. (For rising-then-falling supply at max ramp rate; threshold is V_{TR_RLVOVD} .)	100	_	-	ns	Guaranteed by design
Overcur	rent detection (OCD) specifications					
SID598	I _{OCD}	OCD range for V _{CCD}	156	-	315	mA	Guaranteed by design
SID599	I _{OCD_DPSLP}	OCD range in DeepSleep mode	18	-	72	mA	Guaranteed by design

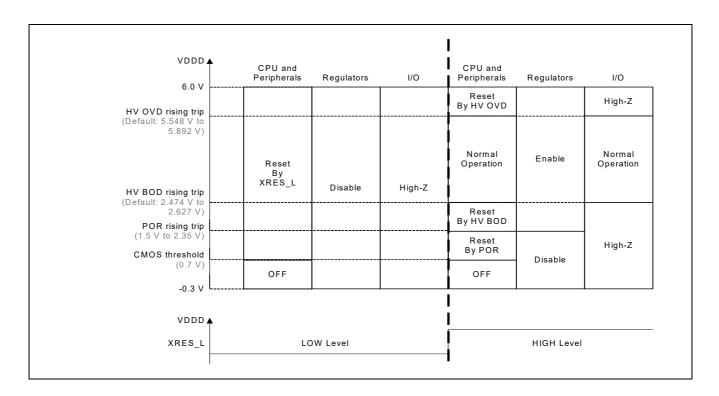


Figure 26-14 Device operations supply range



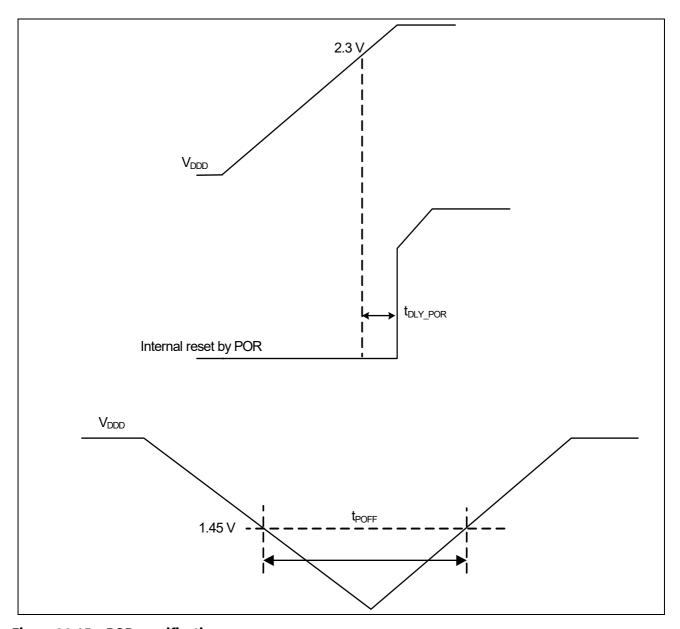


Figure 26-15 POR specifications



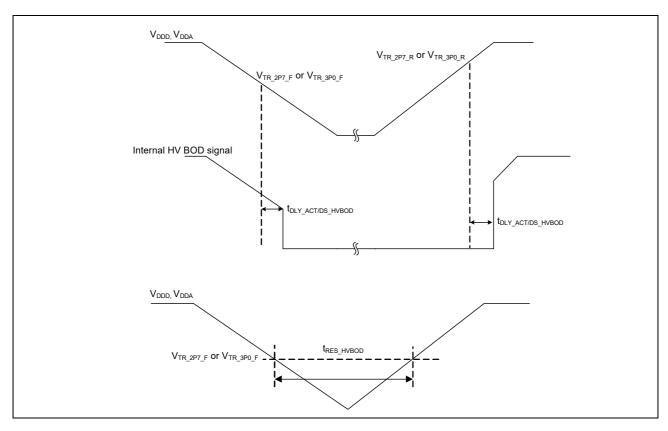


Figure 26-16 High-voltage BOD specifications

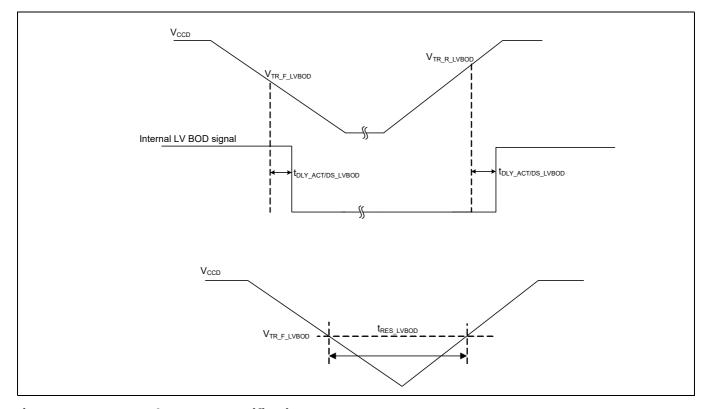


Figure 26-17 Low-voltage BOD specifications



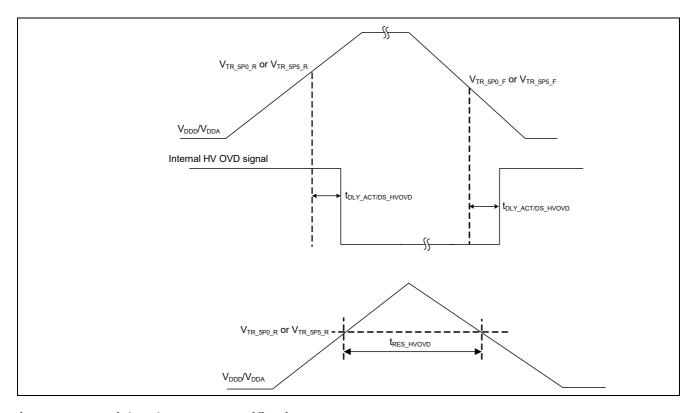


Figure 26-18 High-voltage OVD specifications

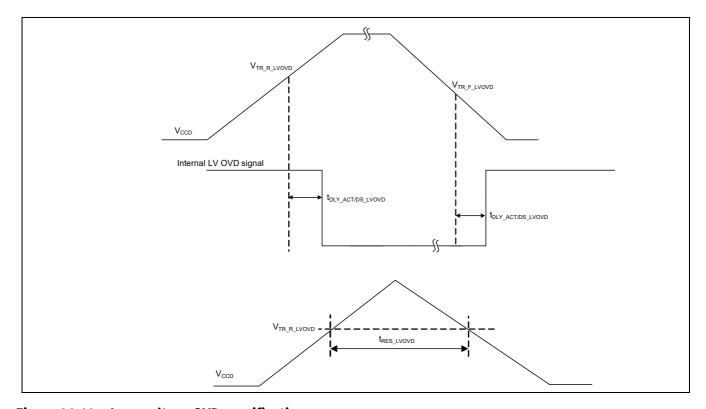


Figure 26-19 Low-voltage OVD specifications

Based on Arm® Cortex®-M4F single

Electrical specifications



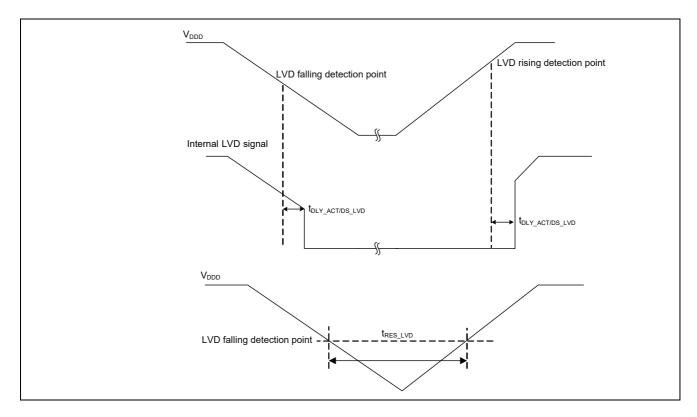


Figure 26-20 LVD specifications

26.11 Debug

All specifications are valid for –40 °C \leq T $_{A}$ \leq 125 °C and for 2.7 V to 5.5 V except where noted.

26.11.1 SWD

Table 26-17 SWD interface specifications [Conditions: drive_sel<1:0>= 00]

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID300	f _{SWDCLK}	SWD clock input frequency	-	-	10	MHz	$2.7 \text{ V} \le \text{V}_{\text{DDD}} \le 5.5 \text{ V}$
SID301	t _{SWDI_SETUP}	SWDI setup time	0.25×T	-	_	ns	T = 1 / f _{SWDCLK}
SID302	t _{SWDI_HOLD}	SWDI hold time	0.25×T	-	-	ns	$T = 1 / f_{SWDCLK}$
SID303	t _{SWDO_VALID}	SWDO valid time	-	-	0.5 × T	ns	T = 1 / f _{SWDCLK}
SID304	t _{SWDO_HOLD}	SWDO hold time	1	_	_	ns	T = 1 / f _{SWDCLK}

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26.11.2 JTAG

Table 26-18 JTAG AC specifications [Conditions: drive_sel<1:0>=00]

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID620	t _{JCKH}	TCK HIGH time	30	_	_	ns	30-pF load
SID621	t _{JCKL}	TCK LOW time	30	_	_	ns	30-pF load
SID622	t _{JCP}	TCK clock period	66.7	_	_	ns	30-pF load
SID623	t _{JSU}	TDI/TMS setup time	12	_	_	ns	30-pF load
SID624	t _{JH}	TDI/TMS hold time	12	_	_	ns	30-pF load
SID625	t _{JZX}	TDO High-Z to active	_	_	30	ns	30-pF load
SID626	t _{JXZ}	TDO active to High-Z	_	_	30	ns	30-pF load
SID627	t _{JCO}	TDO clock to output	_	_	30	ns	30-pF load

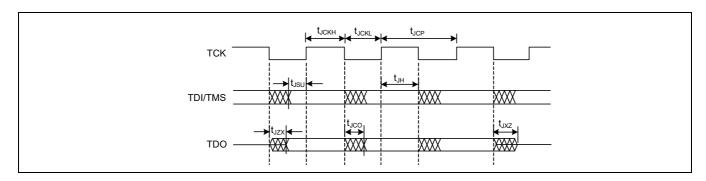


Figure 26-21 JTAG timing diagram

26.11.3 Trace

Table 26-19 Trace specifications [Conditions: drive_sel<1:0>= 00]

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID1412A	C _{TRACE}	Trace capacitive load	-	_	30	pF	
SID1412	t _{TRACE_CYC}	Trace clock period	40	-	-	ns	Trace clock cycle time for 25 MHz
SID1413	t _{TRACE_CLKL}	Trace clock LOW pulse width	2	-	-	ns	Clock low pulse width
SID1414	t _{TRACE_CLKH}	Trace clock HIGH pulse width	2	-	-	ns	Clock high pulse width
SID1415A	t _{TRACE_SETUP}	Trace data setup time	3	_	_	ns	Trace data setup time
SID1416A	t _{TRACE_HOLD}	Trace data hold time	2	-	-	ns	Trace data hold time

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26.12 Clock specifications

All specifications are valid for –40 °C \leq T $_{A}$ \leq 125 °C and for 2.7 V to 5.5 V except where noted.

The following is a basic requirement on the clock frequency dependency of the cores: Cortex-M0+ core should run at an integer divider from the Cortex-M4F core clock.

Example combinations are listed in the Table 26-20.

Table 26-20 Clock requirements

Core Cortex-M4F Clock (MHz)	Core Cortex-CM0+ Clock (MHz)
160	80
120	60
100	100
80	80

Table 26-21 Root and intermediate clocks^[56]

Clock	Max Frequency (MHz)	Description
CLK_HF0	160	Root clock for CPUSS, PERI
CLK_HF1	100	Event generator (CLK_REF), Clock output on EXT_CLK pins (when used as output)
CLK_HF2	2	CSV
CLK_FAST	160	Generated by dividing CLK_HF0, intermediate clock for CM4
CLK_SLOW	100	Generated by clock gating CLK_PERI, intermediate clock for CM0+, Crypto, P-DMA, M-DMA
CLK_PERI	100	Generated by clock gating CLK_HF0, intermediate clock for LIN, SCB, PASS, CAN, TCPWM, IOSS, CPU trace

Table 26-22 IMO AC specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID310	f _{IMOTOL}	IMO operating frequency	7.92	8	8.08	MHz	
SID311	t _{STARTIMO}	IMO startup time	-	-	7.5		Startup time to 90% of final frequency
SID312	I _{IMO_ACT}	IMO current	_	13.5	22	μΑ	Guaranteed by design

Table 26-23 ILO AC specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID320	f _{ILOTRIM}	ILO operating frequency	31.1296	32.768	34.4064	kHz	
SID321	t _{STARTILO}	ILO startup time	-	8	12	μs	Startup time to 90% of final frequency
SID323	I _{ILO}	ILO current	_	500	2800	nA	Guaranteed by design

Note

56.Intermediate clocks that are not listed have the same limitations as that of their parent clock.



ECO specifications **Table 26-24**

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID330	f _{ECO}	Crystal frequency range	3.988	_	33.34	MHz	
SID332	R _{FDBK}	Feedback resistor value. Min: RTRIM = 3; Max: RTRIM = 0 with 100-kΩ step size on RTRIM	100	_	400	kΩ	Guaranteed by design
SID333	I _{ECO3}	ECO current at T _J = 150 °C	-	_	2000	μА	Maximum operation current with a 33-MHz crystal, max 18-pF load
SID334	t _{START_4M}	4-MHz ECO startup time ^[57]	_	_	10	ms	Time from set CLK_ECO CONFIG.ECO_EN to 1 until CLK_ECO_STATUS.ECO_READ Y is set to 1 (See Clock Timing Diagrams)
SID335	t _{START_33M}	33-MHz ECO startup time ^[57]	-	-	1	ms	Time from set CLK_ECO CONFIG.ECO_EN to 1 until CLK_ECO_STATUS.ECO_READ Y is set to 1 (See Clock Timing Diagrams)

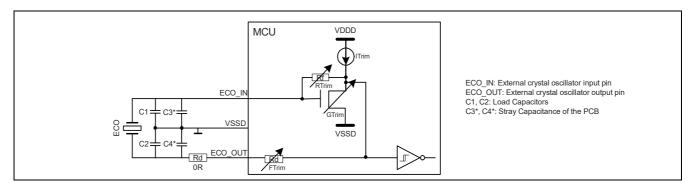


Figure 26-22 ECO connection scheme^[58]

Table 26-25 PLL specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID340	PLL_LOCK	Time to achieve PLL lock	_	-	35	μs	
SID341	f _{PLL_OUT}	Output frequency from PLL block	11	-	160	MHz	
SID342	PLL_LJIT1	Long term jitter	-0.25	1	0.25	ns	For 125 ns f _{PLL_VCO} : 320 MHz f _{PLL_OUT} : 40 MHz to 160 MHz f _{PLL_PFD} : 8 MHz f _{PLL_IN} : ECO
SID343	PLL_LJIT2	Long term jitter	-0.5	-	0.5	ns	For 500 ns f _{PLL_VCO} : 320 MHz f _{PLL_OUT} : 40 MHz to 160 MHz f _{PLL_PFD} : 8 MHz f _{PLL_IN} : ECO

^{57.}Mainly depends on the external crystal.
58.Please refer to the family-specific Architecture TRM for more information on crystal requirements (002-19314, TRAVEO™ T2G Automotive MCU body controller entry architecture technical reference manual).

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PLL specifications (continued) **Table 26-25**

SID345A PLL_LJIT5 Long term jitter -0.75 - 0.75 ns FpL_NFD F	tails/Conditions	Details/	Units	Max	Тур	Min	Description	Parameter	Spec ID
SID346 f_{PLL_IN} PLL input frequency 3.988 - 33.34 MHz	o: 320 MHz n: 40 MHz to 160 MHz o: 8 MHz ECO	f _{PLL_PFD} : 8 MI f _{PLL_IN} : ECO	ns	0.5	-				SID344
SID347 I_{PLL_160M1}	o: 320 MHz T: 40 MHz to 160 MHz o: 8 MHz	For 10000 ns f _{PLL_VCO} : 320 f _{PLL_OUT} : 40 N f _{PLL_PFD} : 8 MI f _{PLL_IN} : ECO	ns	0.75	-	-0.75	Long term jitter	PLL_LJIT5	SID345A
SID347A			MHz	33.34	-	3.988	PLL input frequency	f _{PLL_IN}	SID346
SID347B	MHz, 20 MHz,	$f_{IN} = 4 \text{ MHz},$ $f_{PFD} = 4 \text{ MHz},$ $f_{VCO} = 320 \text{ MH},$ $f_{OUT} = 160 \text{ MH},$	μА	1110	740	-	PLL operating current (f _{OUT} = 160 MHz)	I _{PLL_160M1}	SID347
SID339 I _{PLL_100M1} PLL operating current (f _{OUT} = 100 MHz) F _{PC} = 8 M f _{VCO} = 32l f _{OUT} = 160 MHz) F _{IN} = 4 MH f _{IN} = 4 MH f _{IN} = 4 MH f _{IN} = 100 MHz) F _{IN} = 100 MHz F	MHz, 20 MHz,	$f_{IN} = 8 \text{ MHz},$ $f_{PFD} = 8 \text{ MHz},$ $f_{VCO} = 320 \text{ MH},$ $f_{OUT} = 160 \text{ MH},$	μА	1125	750	-	PLL operating current (f _{OUT} = 160 MHz)	I _{PLL_160M2}	SID347A
SID339A I _{PLL_100M2} PLL operating current (f _{OUT} = 100 MHz) F _{PED} = 4 M f _{VCO} = 20 MHz SID339A I _{PLL_100M2} PLL operating current (f _{OUT} = 100 MHz) F _{PED} = 8 M f _{VCO} = 20 MHz SID339B I _{PLL_100M3} PLL operating current (f _{OUT} = 100 MHz) F _{PED} = 8 M f _{VCO} = 20 MHz SID348 I _{PLL_80M1} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348A I _{PLL_80M2} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} F _{OUT} = 80 MHz SID348B I _{PLL_80M3} PLL operating current (f _{OUT} = 80 MHz) F _{OUT} = 80 MHz SID348B I _{PLL_80M3} F _{OUT} = 80 MHz SID348B I	MHz, 20 MHz,	$f_{IN} = 16 \text{ MHz},$ $f_{PFD} = 8 \text{ MHz},$ $f_{VCO} = 320 \text{ MH},$ $f_{OUT} = 160 \text{ MHz},$	μА	1125	750	-		I _{PLL_160M3}	SID347B
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	MHz, 00 MHz,	$\begin{aligned} f_{\text{IN}} &= 4 \text{ MHz}, \\ f_{\text{PFD}} &= 4 \text{ MHz}, \\ f_{\text{VCO}} &= 200 \text{ MHz}, \\ f_{\text{OUT}} &= 100 \text{ MHz}, \end{aligned}$	μА	780	520	-		I _{PLL_100M1}	SID339
	MHz, 00 MHz,	$\begin{aligned} f_{\text{IN}} &= 8 \text{ MHz,} \\ f_{\text{PFD}} &= 8 \text{ MHz,} \\ f_{\text{VCO}} &= 200 \text{ MHz,} \\ f_{\text{OUT}} &= 100 \text{ MHz,} \end{aligned}$	μΑ	795	530	1		I _{PLL_100M2}	SID339A
	MHz, 00 MHz,	$f_{IN} = 16 \text{ MHz},$ $f_{PFD} = 8 \text{ MHz},$ $f_{VCO} = 200 \text{ MH},$ $f_{OUT} = 100 \text{ MH},$	μΑ	795	530	1		I _{PLL_100M3}	SID339B
	MHz, 40 MHz,	f_{IN} = 4 MHz, f_{PFD} = 4 MHz, f_{VCO} = 240 MH f_{OUT} = 80 MH	μΑ	780	520	-	PLL operating current (f _{OUT} = 80 MHz)	I _{PLL_80M1}	SID348
$(f_{OUT} = 80 \text{ MHz})$ $f_{PFD} = 8 \text{ M}$ $f_{VCO} = 24 \text{ M}$ $f_{OUT} = 80 \text{ MHz}$	MHz, 40 MHz,	$f_{IN} = 8 \text{ MHz},$ $f_{PFD} = 8 \text{ MHz},$ $f_{VCO} = 240 \text{ MH},$ $f_{OUT} = 80 \text{ MH}.$	μА	795	530	-	PLL operating current (f _{OUT} = 80 MHz)	I _{PLL_80M2}	SID348A
SID348C for year VCO frequency 170 - 400 MHz	MHz, 40 MHz,	$f_{IN} = 16 \text{ MHz},$ $f_{PFD} = 8 \text{ MHz},$ $f_{VCO} = 240 \text{ MH},$ $f_{OUT} = 80 \text{ MH}.$	μА	795	530	-	PLL operating current (f _{OUT} = 80 MHz)	I _{PLL_80M3}	SID348B
- I TO TOO MITZ			MHz	400	ı	170	VCO frequency	f _{PLL_VCO}	SID348C
SID349C f _{PLL_PFD} PFD frequency 3.988 - 8 MHz			MHz	8	-	3.988	PFD frequency		SID349C



Table 26-26 FLL specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID350	t _{FLL_WAKE}	FLL wake up time	-	-	5	μs	Wakeup with < 10 °C temperature change while in DeepSleep. f _{FLL_IN} = 8 MHz, f _{FLL_OUT} = 100 MHz, Time from stable reference clock until FLL frequency is within 5% of final value
SID351	f _{FLL_OUT}	Output frequency from FLL block	24	ı	100	MHz	Output range of FLL divided-by-2 output
SID352	FLL_CJIT	FLL frequency accuracy	-1	-	1	%	This is added to the error of the source
SID353	f _{FLL_IN}	Input frequency	0.25	_	80	MHz	
SID354	I _{FLL}	FLL operating current	_	250	360	μА	Reference clock: IMO, CCO frequency: 200 MHz, FLL frequency: 100 MHz, guaranteed by design

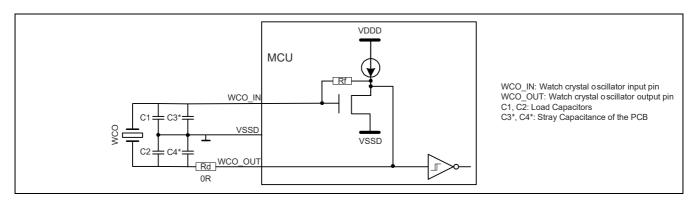


Figure 26-23 WCO connection scheme^[59]

Table 26-27 WCO specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID360	f_{WCO}	Watch Crystal frequency	-	32.768	-	kHz	Maximum drive level: 0.5 μW
SID361	WCO_DC	WCO duty cycle	10	_	90	%	
SID362	t _{START_WCO}	WCO start-up time ^[60]	-	_	1000	ms	For Grade-S devices Time from set CTL.WCO_EN to 1 until STATUS.WCO_OK is set to 1. (See Clock Timing Diagrams)
SID362E	t _{START_WCOE}	WCO start-up time ^[60]	-	-	1400	ms	For Grade-E devices Time from set CTL.WCO_EN to 1 until STATUS.WCO_OK is set to 1. (See Clock Timing Diagrams)
SID363	I _{wco}	WCO current	-	1.4	-	μΑ	

Notes

^{59.}Please refer to family-specific Architecture TRM for more information on crystal requirements (002-19314, TRAVEO™ T2G Automotive MCU body controller entry architecture technical reference manual).
60.Mainly depends on the external crystal.

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Electrical specifications



Table 26-28 External clock input specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID366	f _{EXT}	External clock input frequency	0.25	_	80	MHz	For EXT_CLK pin (all input level settings: CMOS, TTL, Automotive)
SID367	EXT_DC	External clock duty cycle	45	-	55	%	

26.12.1 Clock timing diagrams

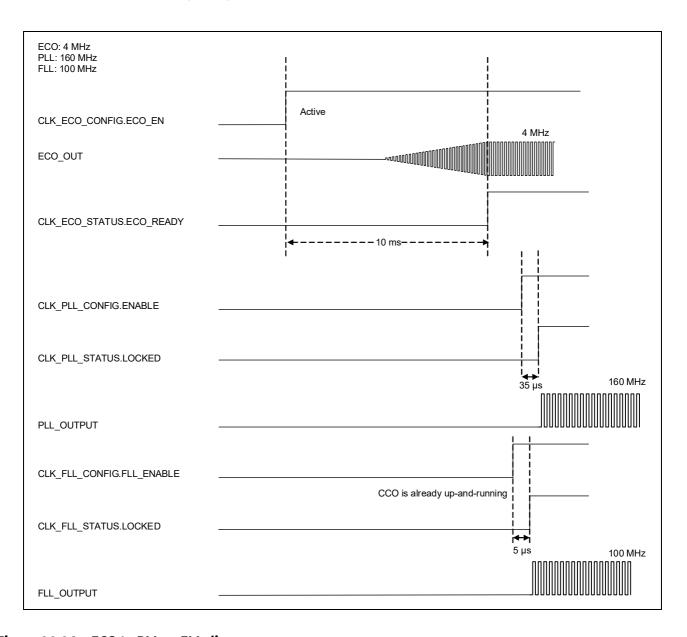


Figure 26-24 ECO to PLL or FLL diagram

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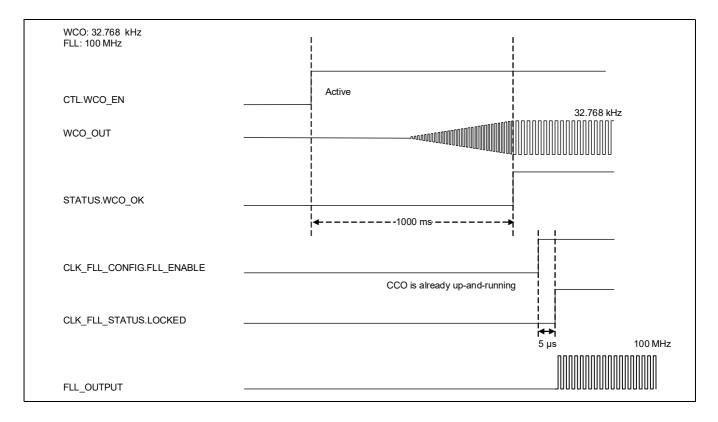


Figure 26-25 WCO to FLL Diagram

Table 26-29 MCWDT timeout specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID410	t _{MCWDT1}	Minimum MCWDT timeout	58.12	-	-	μs	When using the ILO (32.768 kHz + 5%) and 16-bit MCWDT counter Guaranteed by design
SID411	t _{MCWDT2}	Maximum MCWDT timeout	-	-	2.11	S	When using the ILO (32.768 kHz – 5%) and 16-bit MCWDT counter Guaranteed by design

WDT timeout specifications Table 26-30

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID412	t _{WDT1}	Minimum WDT timeout	58.12	-	-	μs	When using the ILO (32.768 kHz + 5%) and 32-bit WDT counter Guaranteed by design
SID413	t _{WDT2}	Maximum WDT timeout	-	-	38.33	h	When using the ILO (32.768 kHz – 5%) and 32-bit WDT counter Guaranteed by design
SID414	t _{WDT3}	Default WDT timeout	-	1000	-	ms	When using the ILO and 32-bit WDT counter at 0x8000 (default value), guaranteed by design

Ordering information

Ordering information 27

The CYT2B7 microcontroller part numbers and features are listed in **Table 27-1**. The Arm® TAP JTAG ID is 0x6BA0 0477.

CYT2B7 ordering information Table 27-1

Device Code	Ordering Code ^[61]	Package	Code-flash (KB)	Work-flash (KB)	RAM (KB)	ADC Channels	SCB Channels	LIN Channels	CANFD Channels	eSHE/HSM	Temperature Grade	JTAG ID CODE
CYT2B73BAS ^[62]	CYT2B73BADQ0AZSGS	64-LQFP	1088 ^[63]	96 ^[64]	128	27	7	6	5	eSHE	S ^[65]	0x2E3C9069 ^[67]
CYT2B73BAE ^[62]	CYT2B73BADQ0AZEGS	64-LQFP	1088	96	128	27	7	6	5	eSHE	E ^[66]	0x2E3C9069
CYT2B73CAS	CYT2B73CADQ0AZSGS	64-LQFP	1088	96	128	27	7	6	5	HSM	S	0x2E3CA069
CYT2B73CAE	CYT2B73CADQ0AZEGS	64-LQFP	1088	96	128	27	7	6	5	HSM	E	0x2E3CA069
CYT2B74BAS ^[62]	CYT2B74BADQ0AZSGS	80-LQFP	1088	96	128	34	8	7	6	eSHE	S	0x2E3D1069
CYT2B74BAE ^[62]	CYT2B74BADQ0AZEGS	80-LQFP	1088	96	128	34	8	7	6	eSHE	Е	0x2E3D1069
CYT2B74CAS	CYT2B74CADQ0AZSGS	80-LQFP	1088	96	128	34	8	7	6	HSM	S	0x2E3D2069
CYT2B74CAE	CYT2B74CADQ0AZEGS	80-LQFP	1088	96	128	34	8	7	6	HSM	E	0x2E3D2069
CYT2B75BAS ^[62]	CYT2B75BADQ0AZSGS	100-LQFP	1088	96	128	39	8	7	6	eSHE	S	0x2E3D9069
CYT2B75BAE ^[62]	CYT2B75BADQ0AZEGS	100-LQFP	1088	96	128	39	8	7	6	eSHE	E	0x2E3D9069
CYT2B75CAS	CYT2B75CADQ0AZSGS	100-LQFP	1088	96	128	39	8	7	6	HSM	S	0x2E3DA069
CYT2B75CAE	CYT2B75CADQ0AZEGS	100-LQFP	1088	96	128	39	8	7	6	HSM	E	0x2E3DA069
CYT2B77BAS ^[62]	CYT2B77BADQ0AZSGS	144-LQFP	1088	96	128	54	8	8	6	eSHE	S	0x2E3E1069
CYT2B77BAE ^[62]	CYT2B77BADQ0AZEGS	144-LQFP	1088	96	128	54	8	8	6	eSHE	E	0x2E3E1069
CYT2B77CAS	CYT2B77CADQ0AZSGS	144-LQFP	1088	96	128	54	8	8	6	HSM	S	0x2E3E2069
CYT2B77CAE	CYT2B77CADQ0AZEGS	144-LQFP	1088	96	128	54	8	8	6	HSM	E	0x2E3E2069
CYT2B78BAS ^[62]	CYT2B78BADQ0AZSGS	176-LQFP	1088	96	128	64	8	8	6	eSHE	S	0x2E3E9069
CYT2B78BAE ^[62]	CYT2B78BADQ0AZEGS	176-LQFP	1088	96	128	64	8	8	6	eSHE	E	0x2E3E9069
CYT2B78CAS	CYT2B78CADQ0AZSGS	176-LQFP	1088	96	128	64	8	8	6	HSM	S	0x2E3EA069
CYT2B78CAE	CYT2B78CADQ0AZEGS	176-LQFP	1088	96	128	64	8	8	6	HSM	E	0x2E3EA069

Notes

61.Supported shipment types are "Tray" (default) and "Tape and Reel". Add the character 'T' at the end to get the ordering code for "Tape and Reel" shipment type. 62.3DES/SHA-1/SHA-2/SHA-3/CRC/Vector unit for asymmetric cryptography features are not supported.
63.Code-flash size 1088 KB = 32 KB × 30 (Large Sectors) + 8 KB × 16 (Small Sectors)
64.Work-flash size 96 KB = 2 KB × 36 (Large Sectors) + 128 B × 192 (Small Sectors).
65.S-grade Temperature (-40 °C to 105 °C).
66.E-grade Temperature (-40 °C to 125 °C).

67. JTAG ID CODE bits 12 through 27, represents the Silicon ID of the device.



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Ordering information



27.1 Part number nomenclature

Table 27-2 Device code nomenclature

Field	Description	Value	Meaning
CY	Cypress Prefix	CY	
T	Category	Т	TRAVEO™
2	Family Name	2	TRAVEO™ T2G (Core M4)
В	Application	В	Body
D	Code-flash/Work-flash/SRAM quantity	7	1088 KB / 96 KB / 128 KB
		3	64-LQFP
		4	80-LQFP
Р	Packages	5	100-LQFP
		7	144-LQFP
		8	176-LQFP
Н	Hardwara Ontion	В	eSHE – on, HSM – off, RSA-2048
П	Hardware Option —	С	eSHE – on, HSM – on, RSA-2048
I	Marketing Option	А	No options
С	Tomporature Crade	S	S-grade (–40 °C to 105 °C)
C	Temperature Grade —	E	E-grade (–40 °C to 125 °C)

Table 27-3 Ordering code nomenclature

Field	Description	Value	Meaning
CY	Cypress Prefix	CY	
Т	Category	Т	TRAVEO™
2	Family Name	2	TRAVEO™ T2G (Core M4)
В	Application	В	Body
D	Code-flash/Work-flash/SRAM quantity	7	1088 KB / 96 KB / 128 KB
		3	64 LQFP
		4	80 LQFP
Р	Packages	5	100 LQFP
		7	144 LQFP
		8	176 LQFP
Н	Hardware Ontion	В	eSHE – on, HSM – off, RSA-2048
П	Hardware Option —	С	eSHE – on, HSM – on, RSA-2048
I	Marketing Option	A	No options
		А	First revision
R	Revision	В	Second revision
K	Revision	С	Third revision
		D	Fourth revision
F	Fab Location	Q	UMC (Fab 12i) Singapore
Х	Reserved	0	Reserved
K	Package Code	AZ	LQFP
С	Temperature Grade	S	S-grade (-40 °C to 105 °C)
C	Temperature Grade	E	E-grade (–40 °C to 125 °C)
0	Quality Crade	ES	Engineering samples
Q	Quality Grade	GS	Standard grade of automotive
	Chinment Type	Blank	Tray shipment
S	Shipment Type	Т	Tape and Reel shipment



Packaging 28

CYT2B7 is offered in the packages listed in the Table 28-1.

Table 28-1 Package Information

Package	Dimensions	Contact/Lead pitch	Coefficient of thermal expansion ^[72]	I/O Pins
176-LQFP	24 × 24 × 1.7 mm (max)	0.5 mm	a1 ^[70] = 8.5 ppm/°C, a2 ^[71] = 33.8 ppm/°C	152
144-LQFP	20 × 20 × 1.7 mm (max)	0.5 mm	a1 ^[70] = 8.5 ppm/°C, a2 ^[71] = 33.7 ppm/°C	122
100-LQFP	14 × 14 × 1.7 mm (max)	0.5 mm	a1 ^[70] = 8.5 ppm/°C, a2 ^[71] = 33.6 ppm/°C	78
80-LQFP	12 × 12 × 1.7 mm (max)	0.5 mm	a1 ^[70] = 8.5 ppm/°C, a2 ^[71] = 33.5 ppm/°C	63
64-LQFP	10 × 10 × 1.7 mm (max)	0.5 mm	a1 ^[70] = 8.5 ppm/°C, a2 ^[71] = 33.2 ppm/°C	49

Table 28-2 Package Characteristics

Parameter	Description	Conditions	Min	Тур	Мах	Units
T _A	Operating ambient temperature	S-grade	-40	-	105	°C
T _A	Operating ambient temperature	E-grade	-40	-	125	°C
Т	Operating junction temperature	-	_	-	150	°C
		64 LQFP	_	-	37.6	°C/Watt
	Package thermal resistance,	80 LQFP	_	-	32.7	°C/Watt
$R_{ heta JA}$	junction to ambient $\theta_{JA}^{[68]}$	100 LQFP	_	-	29.8	°C/Watt
	03]	144 LQFP	_	-	26.2	°C/Watt
		176 LQFP	_	-	25.9	°C/Watt
	Package thermal resistance, junction to board θ _{JB}	64 LQFP	-	_	32.0	°C/Watt
		80 LQFP	-	-	26.7	°C/Watt
$R_{ heta JB}$		100 LQFP	_	-	21.3	°C/Watt
	James of a care of DB	144 LQFP	_	-	20.9	°C/Watt
		176 LQFP	_	-	20.8	°C/Watt
		64 LQFP	_	_	7.8	°C/Watt
		80 LQFP	-	-	6.6	°C/Watt
$R_{ heta JC}$	Package thermal resistance, junction to case θ _{JC}	100 LQFP	_	_	5.6	°C/Watt
		144 LQFP	_	-	4.2	°C/Watt
		176 LQFP	_	-	3.8	°C/Watt

Table 28-3 Solder Reflow Peak Temperature, Package Moisture Sensitivity Level (MSL), IPC/JEDEC J-STD-2

Package	Maximum Peak Temperature (°C)	Maximum Time at Peak Temperature (seconds)	MSL
176 LQFP	260	30 seconds	3

Datasheet

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002-18043 Rev. *L

^{68.} Board condition complies to JESD51-7(4 Layers)

^{69.}Maximum value °C/Watt shown is for $T_A = 125$ °C. 70.a1 = CTE (Coefficient of Thermal Expansion) value below T_g (ppm/°C) (T_g is glass transition temperature which is 131 °C). 71.a2 = CTE value above T_g (ppm/°C). 72.The numbers are estimated values based simulation only and are based on a single bill of material combination per package type.

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Solder Reflow Peak Temperature, Package Moisture Sensitivity Level (MSL), IPC/JEDEC **Table 28-3** J-STD-2

Package	Maximum Peak Temperature (°C)	Maximum Time at Peak Temperature (seconds)	MSL
144 LQFP	260	30 seconds	3
100 LQFP	260	30 seconds	3
80 LQFP	260	30 seconds	3
64 LQFP	260	30 seconds	3



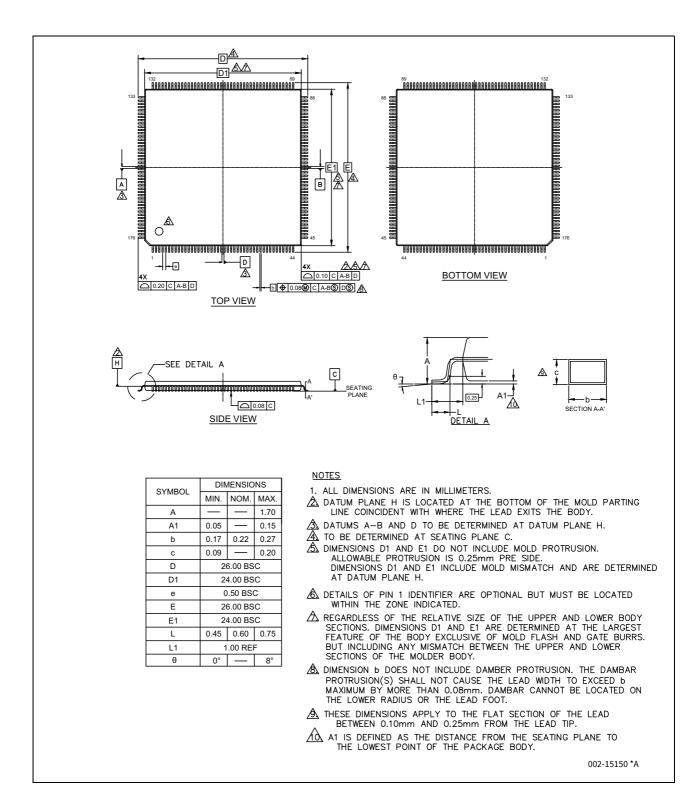


Figure 28-1 176-LQFP package outline



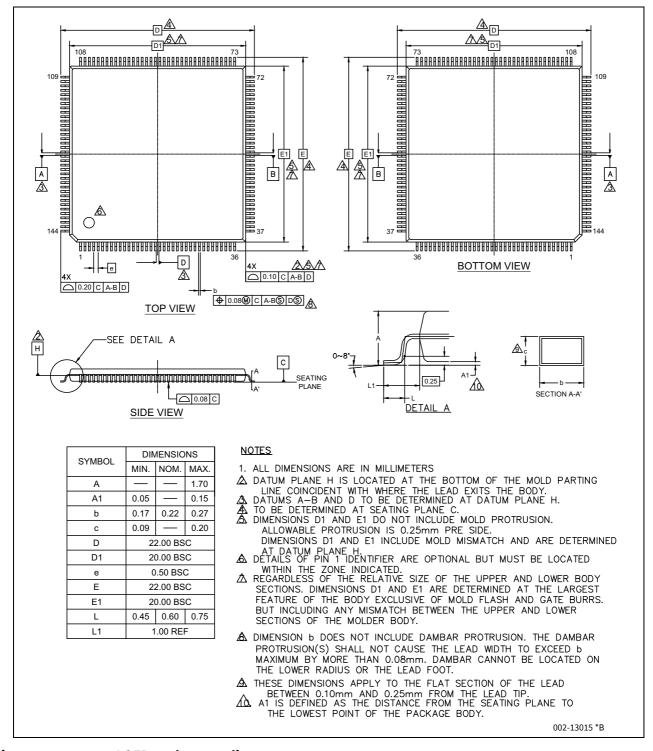


Figure 28-2 144-LQFP package outline



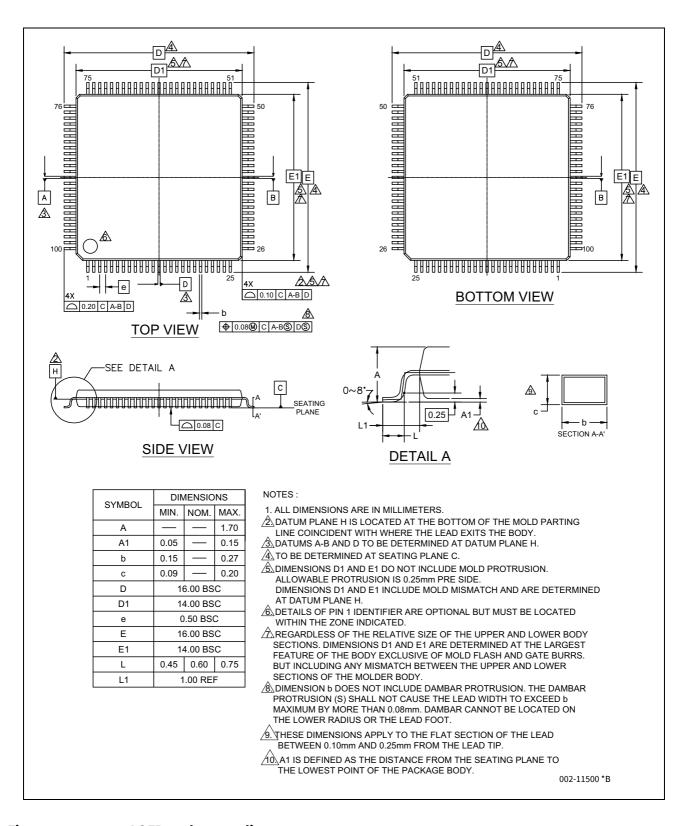


Figure 28-3 100-LQFP package outline



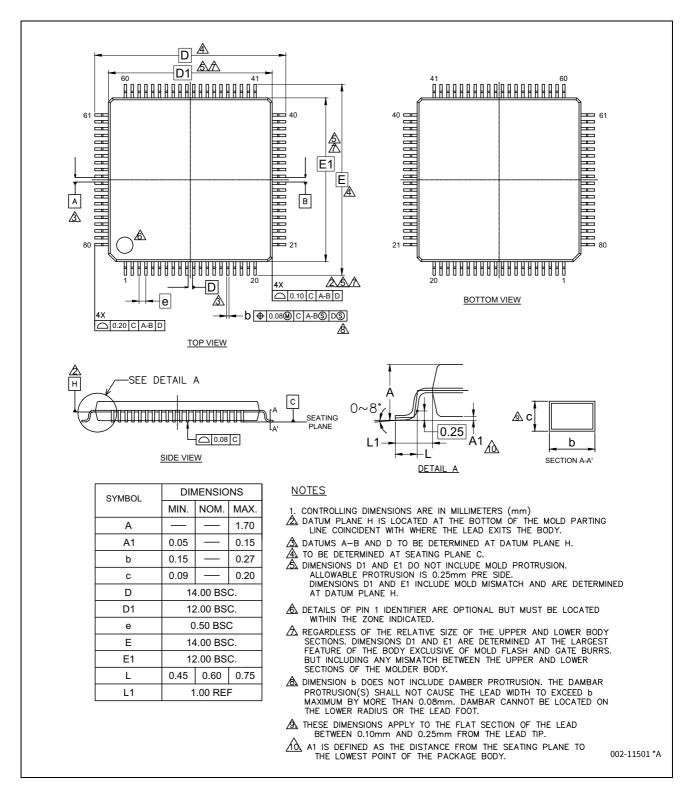


Figure 28-4 80-LQFP package outline

Packaging



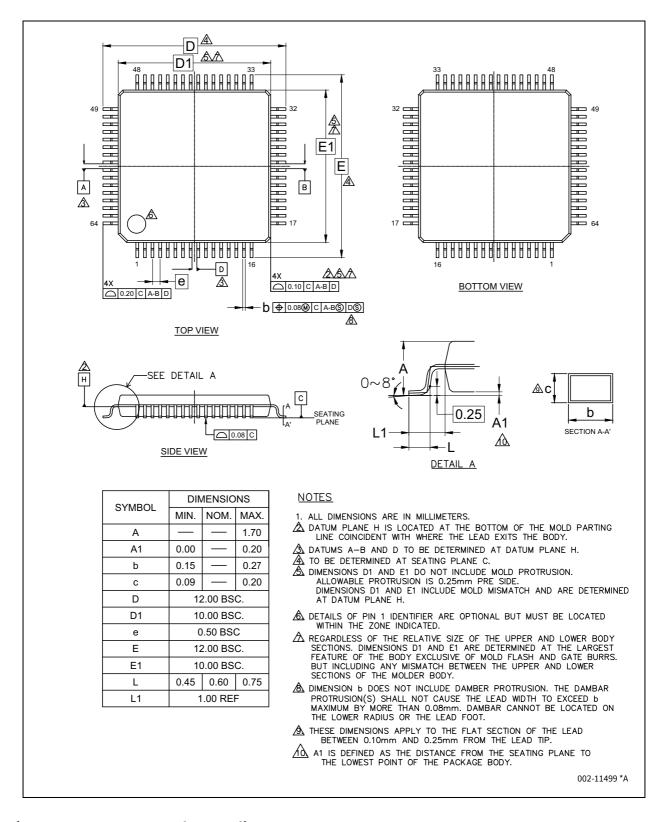


Figure 28-5 64-LQFP package outline

Appendix



29 Appendix

29.1 Bootloading or end-of-line programming

- Triggered at device startup, if a trigger condition is applied
- Either CAN or LIN communication may be used
- Bootloader polls for the communication on CAN or LIN at separate time frames, until the overall 300-second timeout is reached
- If a bootloader command is received on either communication interface, the polling stops and bootloader starts using this interface

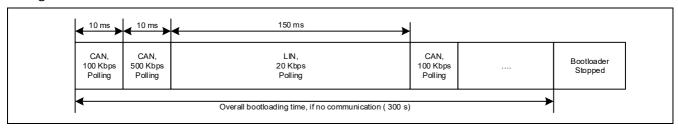


Figure 29-1 Bootloading sequence

Table 29-1 CAN interface details

Sl. No.	CAN interface	Configuration
1	CAN Mode	Classic CAN
2	CAN Instance	CAN0, Channel#1
3	CAN TX	P0.2 / CAN0_1_TX
4	CAN RX	P0.3 / CAN0_1_RX
5	CAN Transceiver NSTB / EN (Low)	P23.3 (optional)
6	CAN Transceiver EN / EN (High)	P2.1 (optional)
7	CAN RX Message ID	0x1A1
8	CAN TX Message ID	0x1B1
9	Baud	100 or 500 kbps alternating

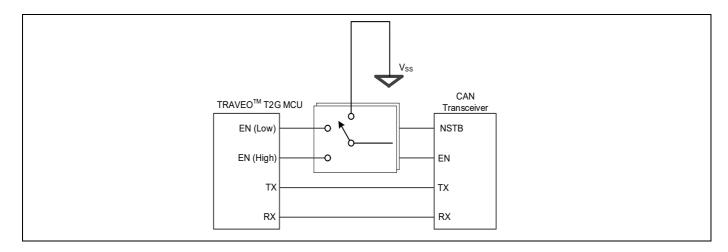


Figure 29-2 MCU to CAN transceiver connections

Appendix



Table 29-2 LIN interface details

Sl. No.	LIN interface	Configuration
1	LIN Type	LIN0, Channel#1
2	LIN Mode	Slave
3	LIN Checksum Type	Classic
4	LIN TX	P0.1 / LIN1_TX
5	LIN RX	P0.0 / LIN1_RX
6	LIN EN / EN (High)	P2.1 (optional)
7	LIN EN (Low)	P23.3 (optional)
8	LIN TX PID	0x46
9	LIN RX PID	0x45
10	Baud	20 or 115.2 kbps
11	Break Field Length	11
12	Break Delimiter Length	1 bit

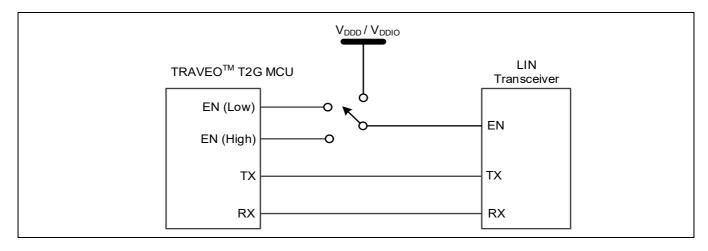


Figure 29-3 MCU to LIN transceiver connections

29.2 External IP revisions

Table 29-3 IP revisions

Module	IP	Revision	Vendor
CANFD	mxttcanfd	M_TTCAN IP revision: Rev.3.2.3	Bosch
Arm® Cortex®-M0+	armcm0p	Cortex®-M0+-r0p1	Arm®
Arm® Cortex®-M4F	armcm4	Cortex®-M4-r0p1	Arm [®]
Arm® Coresight	armcoresighttk	CoreSight-SoC-TM100-r3p2	Arm®

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Acronyms



Acronyms 30

Acronyms used in the Document **Table 30-1**

Acronym	Description	Acronym	Description
A/D	Analog to Digital	JTAG	Joint test action group
ABS	Absolute	LDO	Low drop out regulators
ADC	Analog to Digital converter	LIN	Local Interconnect Network, a communications protocol
AES	Advanced encryption standard	LVD	Low voltage detection
АНВ	AMBA (advanced microcontroller bus architecture) high-performance bus, Arm® data transfer bus	ОТА	Over-the-air programming
Arm®	Advanced RISC machine, a CPU architecture	ОТР	One-time programmable
ASIL	Automotive safety integrity level	OVD	Over voltage detection
BOD	Brown-out detection	P-DMA	Peripheral-Direct Memory Access same as DW
CAN FD	Controller Area Network with Flexible Data rate	PLL	Phase-locked loop
CMOS	Complementary metal-oxide-semiconductor	POR	Power-on reset
CPU	Central Processing Unit	PPU	Peripheral protection unit
CRC	Cyclic redundancy check, an error-checking protocol	PRNG	Pseudorandom number generator
CSV	Clock supervisor	PWM	Pulse-width modulation
CTI	Cross trigger interface	мси	Microcontroller Unit
DES	Data encryption standard	MCWDT	Multi-counter watchdog timer
DFT	Design-For-Test	M-DMA	Memory-Direct Memory Access
DW	Datawire same as P-DMA	MISO	SPI Master-in slave-out
ECC	Error correcting code/Elliptical curve cryptography	MMIO	Memory mapped I/O
ECO	External crystal oscillator	MOSI	SPI Master-out slave-in
ETM	Embedded Trace Macrocell	MPU	Memory protection unit
EVTGEN	Event Generator	МТВ	Micro trace buffer
FLL	Frequency-locked loop	MUL	Multiplier
FPU	Floating point unit	MUX	Multiplexer
GHS	Green Hills tool chain with Multi IDE	NVIC	Nested vectored interrupt controller
GPIO	General purpose input/output	RAM	Random access memory
HSM	Hardware security module	RISC	Reduced-instruction-set computing
I/O	Input/output	ROM	Read only memory
I ² C	Inter-Integrated Circuit, a communications protocol	RSA	Rivest-Shamir-Adleman Public Key Encryption Algorithm
ILO	Internal low-speed oscillator	RTC	Real-time clock
IMO	Internal main oscillator	SAR	Successive approximation register

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Acronyms



 Table 30-1
 Acronyms used in the Document (continued)

Acronym	Description	Acronym	Description
IOSS	Input/output sub-system	SCB	Serial communication block
IPC	Inter-processor communication	SCL	I ² C serial clock
IrDA	Infrared interface	SDA	I ² C serial data
IRQ	Interrupt request	SECDED	Single error correction, double error detection
SHA	Secure hash algorithm	TCPWM	Timer/Counter Pulse-width modulator
SHE	Secure hardware extension	TTL	Transistor-transistor logic
SMPU	Shared memory protection unit	TRNG	True random number generator
SPI	Serial peripheral interface, a communications protocol	UART	Universal Asynchronous Transmitter Receiver
SRAM	Static random access memory	WCO	Watch crystal oscillator
SWD	Serial wire debug	WDT	Watchdog timer reset
SWJ	Serial wire JTAG		-

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Errata



31 **Errata**

This section describes the errata for the CYT2B7 product family. Details include errata trigger conditions, scope of impact, available workaround, and silicon revision applicability. Contact your local Infineon Sales Representative if you have questions.

Part Numbers Affected

Part Number	
All CYT2B7 parts	

CYT2B7 Qualification Status

Production samples

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Errata

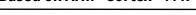


CYT2B7 Errata Summary

The following table defines the errata applicability to available CYT2B7 family devices.

Items	Errata ID	СҮТ2В7	Silicon Rev.	Fix Status
[1.] Crypto LSL1, LSR1, LSL1_WITH_CARRY, & LSR1_WITH_CARRY instructions may work incorrectly in certain scenarios	53			No silicon fix planned. Use workaround.
[2] Crypto MEM_BUF may be corrupted	42			No silicon fix planned. Use workaround.
[3] ConfigureFmInterrupt API assumes a parameter with 8 bytes boundary, but actual boundary is 4 bytes	67			No silicon fix planned. Use workaround.
[4] SMPU/MPU/PPU protection region size is limited to 2 GB	68			No silicon fix planned. Use workaround.
[5] DirectExecute API may return error if called with arguments placed in SRAM memory	69			No silicon fix planned. Use workaround.
[6] CAN FD RX FIFO top pointer feature does not function as expected	96			No silicon fix planned. Use workaround.
[7] CAN FD debug message handling state machine does not reset to Idle state when CANFD_CH_CCCR.INIT is set	97			No silicon fix planned. Use workaround.
[8] TPIU Peripheral ID mismatch	98			No fix planned
[9] Limitation of the memory hole in SCB register space	124	CYT2B73BADQ0AZSGS		No silicon fix planned. Use workaround
[10] WDT service can be missed	129	CYT2B73BADQ0AZEGS CYT2B73CADQ0AZSGS CYT2B73CADQ0AZEGS		No silicon fix planned. Use workaround
[11] CAN FD controller message order inversion when transmitting from dedicated Tx Buffers configured with same Message ID	147	CYT2B74BADQ0AZSGS CYT2B74BADQ0AZEGS CYT2B74CADQ0AZSGS		No silicon fix planned. Use workaround
[12] CAN FD incomplete description of Dedicated Tx Buffers and Tx Queue related to transmission from multiple buffers configured with the same Message ID	167	CYT2B74CADQ0AZEGS CYT2B75BADQ0AZSGS CYT2B75BADQ0AZEGS CYT2B75CADQ0AZSGS	D	No silicon fix planned. Use workaround. TRM was updated.
[13]Misleading status is returned for Flash and eFuse system calls, if there are pending NC ECC faults in SRAM controller #0	175	CYT2B75CADQ0AZEGS CYT2B77BADQ0AZSGS CYT2B77BADQ0AZEGS CYT2B77CADQ0AZSGS		No silicon fix planned. TRM was updated.
[14]WDT reset causes loss of SRAM retention	176	CYT2B77CADQ0AZEGS CYT2B78BADQ0AZSGS		No silicon fix planned. TRM was updated.
[15] Crypto ECC errors may be set after boot with application authentication	185	CYT2B78BADQ0AZEGS CYT2B78CADQ0AZSGS CYT2B78CADQ0AZEGS		No silicon fix planned. TRM was updated.
[16]Incomplete erase of Code Flash cells could happen Erase Suspend / Erase Resume is used along with Erase Sector operation in Non-Blocking mode	198			Fixed to update the Flash settings from date code 304xxxxx.
[17]Limitation for keeping the port state from peripheral IP after wakeup from DeepSleep	199			No silicon fix planned. TRM was updated.
[18]Limitation of clock configuration before entering DeepSleep mode.	202			No silicon fix planned. TRM was updated.
[19]Several data retention information in the Register TRM are incorrect.	203			No silicon fix planned. TRM was updated.
[20] SCBx JNTR TX.UNDERFLOW bit may be set unintentionally.	204			No silicon fix planned. TRM was updated.
[21]Hardfault may occur when calling the SROM APIs listed below while executing EraseSector or ProgramRow in non-blocking mode	206			No silicon fix planned. TRM will be updated.
[22] CAN FD sporadic data corruption (payload) in case acceptance filtering does not finish before reception of data R3 (DB7DB4) is complete	209			No silicon fix planned. Use workaround.

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Errata

Items	Errata ID	CYT2B7	Silicon Rev.	Fix Status
[23] Description for PASS SARx to TCPWMx direct connect triggers one-to-one is incorrect in datasheet	212			No silicon fix planned. Datasheet was updated.

1. Crypto LSL1, LSR1, L	SL1_WITH_CARRY, & LSR1_WITH_CARRY instructions may work incorrectly in certain scenarios
Problem Definition	LSL1, LSR1, LSL1_WITH_CARRY, & LSR1_WITH_CARRY instructions should ignore the value in IW[3:0] (shift by 1 instruction does not use these fields). But because of a HW issue, shift does not work if the register data field, pointed by IW[3:0], is '0' (destination data is same as source data).
Parameters Affected	NA NA
Trigger Condition(s)	Using LSL1, LSR1, LSL1_WITH_CARRY, & LSR1_WITH_CARRY instructions
Scope of Impact	The shift does not happen (destination data is same as source data).
Workaround	IW[3:0] should be pointed to a dummy register where the data field of the register is non-zero value (rsrc0->data[12:0]). Since stack pointer(r15) points to a non-zero value (to use the LSL1 instruction you must have allocated at least one register, so that SP will not be zero), it is safe to use r15 as rsrc0. staticforceinline void LSL1 (int rdst, int rsrc1) { AHB_WRITE_W (MMIO_CRYPTO_INSTR_FF_WR, (CRYPTO_VU_LSL_OPC << 24)
Fix Status	No silicon fix planned. Use workaround.

2. Crypto MEM_BUF ma	y be corrupted
Problem Definition	The SRAM in the Crypto block is 8 KB but the address decode is wired to create four 8-KB images of the SRAM within a 32-KB address space. Writes to memory space above the initial 8-KB image will corrupt SRAM contents.
Parameters Affected	NA
Trigger Condition(s)	Any write to address between 0x40108000 and 0x4010FFFF
Scope of Impact	CRYPTO MEM_BUF may be corrupted
Workaround	The software should ensure that there is no access beyond 8 KB MEM_BUF address range from either MMIO writes or address overflows while executing Crypto operations
Fix Status	No silicon fix planned. Use workaround.

3. ConfigureFmInterrupt	API assumes a parameter with 8 bytes boundary, but actual boundary is 4 bytes
Problem Definition	STATUS_ADDR_PROTECTED will be returned if the ConfigureFmInterrupt API is called with arguments stored in SRAM with 4-byte boundary (available SRAM or protected boundary SRAM).
Parameters Affected	NA NA
Trigger Condition(s)	Call ConfigureFmInterrupt API with arguments stored in SRAM at 4 bytes boundary of available SRAM or protected boundary of SRAM.

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Errata

Scope of Impact	ConfigureFmInterrupt API will fail by returning STATUS_ADDR_PROTECTED error status when called with argument having 4 bytes boundary of available SRAM or protected boundary of SRAM.
Workaround	Allow 4 bytes margin (that is, assume that the API parameter size is 8 and store the arguments) for ConfigureFmInterrupt API parameter.
Fix Status	No silicon fix planned. Use workaround.
4 SMPH/MPH/PPH prof	tection region size is limited to 2 GB
Problem Definition	
Problem Definition	If SMPU/MPU/PPU protection block size is configured for 4 GB (PROT_SMPU_SMPUSTRUCT_ATTO.REGION.SIZE = 31), then during protection check in SROM, the value of the internal uint32 variable will overflow (4G = 0x1 0000 0000). Therefore, SROM assumes the protection size equals zero, and no protection will be applied.
Parameters Affected	NA NA
Trigger Condition(s)	Configure SMPU/MPU/PPU to protect with region size equal to 4 GB or the region size with value 31u.
Scope of Impact	If SMPU/MPU/PPU is configured to protect region size of 4 GB, then SROM software does not apply any protection as per the request.
Workaround	Use two protection blocks of region size equal to 2 GB if 4-GB region size protection is required.
Fix Status	No silicon fix planned. Use workaround.
Problem Definition	ay return error if called with arguments placed in SRAM memory If DirectExecute API is called in the master PC (other than PC0 or PC1) with arguments in SRAM_SCRATCH_ADDR, then the API will return STATUS_ADDR_PROTECTED.
Parameters Affected	NA NA
Trigger Condition(s)	Call DirectExecute API with arguments in SRAM_SCRATCH_ADDR and master PC configured > 1.
Scope of Impact	DirectExecute API, if called with master PC configured > 1 and arguments in SRAM_SCRATCH_ADDR, the API will return STATUS_ADDR_PROTECTED.
Workaround	Call DirectExecute API with master PC0 or PC1, if arguments are stored in SRAM memory.
Workaround Fix Status	Call DirectExecute API with master PC0 or PC1, if arguments are stored in SRAM memory. No silicon fix planned. Use workaround.
Fix Status	No silicon fix planned. Use workaround.
6. CAN FD RX FIFO top p	No silicon fix planned. Use workaround. pointer feature does not function as expected
Fix Status	No silicon fix planned. Use workaround.
Fix Status 6. CAN FD RX FIFO top p Problem Definition	No silicon fix planned. Use workaround. pointer feature does not function as expected The RX FIFO top pointer function calculates the address for received messages in Message RAM by hardware. This address should restart back from the start address after reading all messages of RX FIFO n size (n: 0 or 1). However, the address does not restart from the start address when the RX FIFO n size is set to 1 (CANFD_CH_RXFnC.FnS = 0x01). This results in CPU/DMA reading messages from the wrong address
Fix Status 6. CAN FD RX FIFO top p Problem Definition Parameters Affected	No silicon fix planned. Use workaround. pointer feature does not function as expected The RX FIFO top pointer function calculates the address for received messages in Message RAM by hardware. This address should restart back from the start address after reading all messages of RX FIFO n size (n: 0 or 1). However, the address does not restart from the start address when the RX FIFO n size is set to 1 (CANFD_CH_RXFnC.FnS = 0x01). This results in CPU/DMA reading messages from the wrong address in Message RAM. NA
Fix Status 6. CAN FD RX FIFO top p Problem Definition Parameters Affected Trigger Condition(s)	No silicon fix planned. Use workaround. pointer feature does not function as expected The RX FIFO top pointer function calculates the address for received messages in Message RAM by hardware. This address should restart back from the start address after reading all messages of RX FIFO n size (n: 0 or 1). However, the address does not restart from the start address when the RX FIFO n size is set to 1 (CANFD_CH_RXFnC.FnS = 0x01). This results in CPU/DMA reading messages from the wrong address in Message RAM. NA
Fix Status 6. CAN FD RX FIFO top p	No silicon fix planned. Use workaround. pointer feature does not function as expected The RX FIFO top pointer function calculates the address for received messages in Message RAM by hardware. This address should restart back from the start address after reading all messages of RX FIFO n size (n: 0 or 1). However, the address does not restart from the start address when the RX FIFO n size is set to 1 (CANFD_CH_RXFnC.FnS = 0x01). This results in CPU/DMA reading messages from the wrong address in Message RAM. NA RX FIFO top pointer function is used when RX FIFO n size is set to 1 element (CANFD_CH_RXFnC.FnS = 0x01) Received message cannot be correctly read by using the RX FIFO top pointer function, when the RX FIFO





7. CAN FD debug messa	ge handling state machine does not reset to Idle state when CANFD_CH_CCCR.INIT is set
Problem Definition	If either of the CANFD_CH_CCCR.INIT bits is set by the Host or when the M_TTCAN module enters BusOff state, the debug message handling state machine stays in its current state instead of being reset to Idle state. Configuring the CANFD_CH_CCCR.CCE bit does not change CANFD_CH_RXF1S.DMS.
Parameters Affected	NA NA
Trigger Condition(s)	$Either of the {\tt CANFD_CH_CCCR.INIT}\ bits is set by the {\tt Host}\ or\ when the\ {\tt M_TTCAN}\ module\ enters\ BusOff state.$
Scope of Impact	The errata is limited to the use case when the Debug on CAN functionality is active. Normal operation of the CAN module is not affected, in which case the debug message handling state machine always remains in Idle state. In the described use case, the debug message handling state machine is stopped and remains in the current state signaled by the CANFD_CH_RXF1S.DMS bit. If CANFD_CH_RXF1S.DMS is set to 0b11, the DMA request remains active.
Workaround	In case the debug message handling state machine stops while CANFD_CH_RXF1S.DMS is 0b01 or 0b10, it can be reset to Idle state by hardware reset or by reception of debug messages after CANFD_CH_CCCR.INIT is reset to zero.
Fix Status	No silicon fix planned. Use workaround.

8. TPIU Peripheral ID mismatch	
Problem Definition	TPIU peripheral ID indicates that it is M3-TPIU instead of M4-TPIU.
Parameters Affected	NA NA
Trigger Condition(s)	When the debugger reads PID registers for component identification.
Scope of Impact	The only impact is that the debuggers read the TPIU as M3-TPIU.
Workaround	No specific workaround required. Debuggers can use trace features.
Fix Status	No fix planned

Problem Definition	The memory hole [offset address: 0x1000 to 0xFFFF] inside the SCB register space is not aligned to the below defined spec. Since the offset address bits [15:12] are ignored and treated as 4'b0000, write/read access to the offset address [0x1000 to 0xFFFF] will actually happen to [0x0000 to 0x0FFF]. - Access to address gaps in mapped memory space: writes are ignored and any read returns a zero.
Parameters Affected	NA
Trigger Condition(s)	Access to the memory hole [offset address: 0x1000 to 0xFFFF] in SCB register space
Scope of Impact	The memory hole [offset address: 0x1000 to 0xFFFF] in the SCB register space is not aligned to other IP registers.
Workaround	Do not access to the memory hole [offset address: 0x1000 to 0xFFFF] in SCB register space.
Fix Status	No fix planned





fully complete an internal handshake. A service after DeepSleep wakeup may then be missed if it occ less than 2 ILO clock cycles after the processor resumes clocking. After this time, the internal handshake complete and servicing works normally. Parameters Affected NA Service WDT within 4 ILO clock cycles before DeepSleep entry and within 2 ILO clock cycles of process clock resuming Scope of Impact WDT service after DeepSleep wakeup may be ignored and WDT continues counting. This can cause unintended WARN_ACTION or UPPER_ACTION, including interrupt, fault, and/or reset	Problem Definition	If WDT service happens within 4 ILO clock cycles before DeepSleep entry, it clears the counter but does not
Trigger Condition(s) Service WDT within 4 ILO clock cycles before DeepSleep entry and within 2 ILO clock cycles of process clock resuming WDT service after DeepSleep wakeup may be ignored and WDT continues counting. This can cause unintended WARN_ACTION or UPPER_ACTION, including interrupt, fault, and/or reset Workaround Wait 130 μs or more after DeepSleep wakeup. (For example, to measure 130 μs, software can read WDT_register at wake up and make sure that WDT_CNT was incremented of 4 units before servicing WDT). Afterwards, write '1' to WDT service (WDT_SERVICE.SERVICE) after waiting until WDT service (WDT_SERVICE.SERVICE) reads '0'.	Problem Demillion	fully complete an internal handshake. A service after DeepSleep wakeup may then be missed if it occurs less than 2 ILO clock cycles after the processor resumes clocking. After this time, the internal handshake is
Clock resuming WDT service after DeepSleep wakeup may be ignored and WDT continues counting. This can cause unintended WARN_ACTION or UPPER_ACTION, including interrupt, fault, and/or reset Workaround Wait 130 μs or more after DeepSleep wakeup. (For example, to measure 130 μs, software can read WDT_register at wake up and make sure that WDT_CNT was incremented of 4 units before servicing WDT). Afterwards, write '1' to WDT service (WDT_SERVICE.SERVICE) after waiting until WDT service (WDT_SERVICE.SERVICE) reads '0'.	Parameters Affected	NA
This can cause unintended WARN_ACTION or UPPER_ACTION, including interrupt, fault, and/or reset Workaround Wait 130 µs or more after DeepSleep wakeup. (For example, to measure 130 µs, software can read WDT_ register at wake up and make sure that WDT_CNT was incremented of 4 units before servicing WDT). Afterwards, write '1' to WDT service (WDT_SERVICE.SERVICE) after waiting until WDT service (WDT_SERVICE.SERVICE) reads '0'.	Trigger Condition(s)	Service WDT within 4 ILO clock cycles before DeepSleep entry and within 2 ILO clock cycles of processor clock resuming
register at wake up and make sure that WDT_CNT was incremented of 4 units before servicing WDT). Afterwards, write '1' to WDT service (WDT_SERVICE.SERVICE) after waiting until WDT service (WDT_SERVICE.SERVICE) reads '0'.	Scope of Impact	WDT service after DeepSleep wakeup may be ignored and WDT continues counting. This can cause unintended WARN_ACTION or UPPER_ACTION, including interrupt, fault, and/or reset.
Fix Status No silicon fix planned. Use workaround.	Workaround	Afterwards, write '1' to WDT service (WDT_SERVICE.SERVICE) after waiting until WDT service
	Fix Status	No silicon fix planned. Use workaround.

11. CAN FD controller	nessage order inversion when transmitting from dedicated Tx Buffers configured with same Message ID
Problem Definition	Configuration: Several Tx buffers are configured with the same Message ID. Transmission of these Tx buffers is requested sequentially with a delay between the individual Tx requests. Expected behavior: When multiple Tx buffers that are configured with the same Message ID have pending Tx requests, they shall be transmitted in ascending order of their Tx buffer numbers. The Tx buffer with the lowest buffer number and pending Tx request is transmitted first. Observed behavior: It may happen, depending on the delay between the individual Tx requests, that in the case where multiple Tx buffers are configured with the same Message ID, the Tx buffers are not transmitted in order of the Tx buffer number (lowest number first).
Parameters Affected	NA
Trigger Condition(s)	When multiple Tx buffers, configured with the same Message ID, have pending Tx requests.
Scope of Impact	In the case described it is possible that Tx buffers configured with the same Message ID and pending Tx request are not transmitted with the lowest Tx buffer number first (message order inversion).
Workaround	Any of the following: 1) First write the group of Tx message with the same Message ID to the Message RAM and later request transmission of all these messages concurrently by a single write access to CANFDx_CHy_TXBAR. Before requesting a group of Tx messages with this Message ID, ensure that no message with this Message ID has a pending Tx request. 2) Use the Tx FIFO instead of dedicated Tx buffers for the transmission of several messages with the same Message ID in a specific order.
	Applications not able to use workaround #1 or #2 can implement a counter within the data section of their messages sent with same ID in order to allow the recipients to determine the correct sending sequence.
Fix Status	No silicon fix planned. Use workaround.

one after the other.

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Fix Status



12. CAN FD incomplete description of Dedicated Tx Buffers and Tx Queue related to transmission from multiple buffers configured with the same Message ID

Problem Definition The following are the updated description in Sections "Dedicated Tx Buffers" and "Tx Queue" of the Architecture TRM related to the transmission from multiple buffers configured with the same Message ID. **Dedicated Tx buffers** - TRM statement: If multiple Tx buffers are configured with the same Message ID, the Tx Buffer with the lowest buffer number is transmitted first. - Enhancement: These Tx buffers shall be requested in ascending order with the lowest buffer number first. Alternatively all Tx buffers configured with the same Message ID can be requested simultaneously by a single write access to CANFDx_CHy_TXBAR. Tx Queue - TRM statement: If multiple queue buffers are configured with the same Message ID, the queue buffer with the lowest buffer number is transmitted first. - Replacement: If multiple Tx Queue buffers are configured with the same Message ID, the transmission order depends on numbers of the buffers where the messages were stored for transmission. As these buffer numbers depend on the then current states of the PUT Index, a prediction of the transmission order is not possible. - TRM statement: An Add Request cyclically increments the Put Index to the next free Tx Buffer. - Replacement: The PUT Index always points to that free buffer of the Tx Queue with the lowest number. **Parameters Affected** NA Trigger Condition(s) Using multiple dedicated Tx Buffers or Tx Queue Buffers configured with the same Message ID. **Scope of Impact** In the case the dedicated Tx Buffers with the same Message ID are not requested in ascending order or at the same time or in case of multiple Tx Queue Buffers with the same Message ID, it cannot be guaranteed, that these messages are transmitted in ascending order with lowest buffer number first. Workaround In case a defined order of transmission is required the Tx FIFO shall be used for transmission of messages with the same Message ID. Alternatively dedicated Tx Buffers with the same Message ID shall be requested in ascending order with lowest buffer number first or by a single write access to CANFDx_CHy_TXBAR. Alternatively a single Tx Buffer can be used to transmit those messages

13.Misleading status is returned for Flash and eFuse system calls, if there are pending NC ECC faults in SRAM controller #0	
Problem Definition	Flash and eFuse system calls will return misleading status of 0xF0000005 ("Page is write protected") even for non-protected row, or 0xF0000002 ("Invalid eFuse address") for valid eFuse address in case of pending NC ECC faults in SRAM controller #0.
Parameters Affected	Return status of Flash and eFuse system calls.
Trigger Condition(s)	NC ECC fault(s) pending in SRAM controller #0 and SWPUs are populated in the design.
Scope of Impact	Flash and eFuse system calls will not work until the NC ECC fault(s) pending in SRAM controller #0 is/are properly handled.
Workaround	If the NC ECC fault(s) are not due to HW malfunction (i.e. if the faults are due to usage of non-initialized SRAM or improper SRAM initialization), then clearing of these pending faults will resolve the issue.
Fix Status	No silicon fix planned. TRM was updated.

No silicon fix planned. Use workaround. TRM was updated accordingly.





14.WDT reset causes loss of SRAM retention	
Problem Definition	The "Reset Cause Distribution" table in the Architecture TRM shows that the WDT reset can retain SRAM if there is an orderly shutdown of the SRAM only during a warning interrupt. However, this is wrong. WDT reset causes loss of SRAM retention.
Parameters Affected	NA NA
Trigger Condition(s)	WDT reset
Scope of Impact	WDT reset causes loss of SRAM retention.
Workaround	None
Fix Status	No silicon fix planned. TRM was updated.

15.Crypto ECC errors may be set after boot with application authentication	
Problem Definition	Due to the improper initialization of the Crypto memory buffer, Crypto ECC errors may be set after boot with application authentication. In spite of the Crypto ECC errors, the result of the authentication is reliable.
Parameters Affected	N/A
Trigger Condition(s)	Boot device with application authentication.
Scope of Impact	Crypto ECC errors may be set after boot with application authentication.
Workaround	Clear or ignore Crypto ECC errors which were generated during boot with application authentication.
Fix Status	No silicon fix planned. TRM was updated.

16.Incomplete erase of Code Flash cells could happen Erase Suspend / Erase Resume is used along with Erase Sector operation in Non-Blocking mode	
Problem Definition	Code Flash memory can be erased in "Non-Blocking" mode; a Non-Blocking mode supported option allow users to suspend an ongoing erase sector operation. When an ongoing erase operation is interrupted using "Erase Suspend" and "Erase Resume", Flash cells may not have been erased completely, even after the erase operation complete is indicated by FLASH-C_STATUS register. Only Code Flash is impacted by this issue, Work Flash and Supervisory Flash (SFlash) are not impacted.
Parameters Affected	N/A
Trigger Condition(s)	Using EraseSector System Call in Non-Blocking mode for CM0+ to erase Code Flash and the ongoing erase operation is interrupted using EraseSuspend and EraseResume System calls.
Scope of Impact	When Code Flash sectors are erased in Non-Blocking mode and the ongoing erase operation is interrupted by Erase Suspend / Erase Resume, it cannot be guaranteed that the Code Flash cells are fully erased. Any read on the Code Flash area after the erase is complete or read on the programmed data after ProgramRow is complete can trigger ECC errors.
Workaround	Use any of the following: 1) User can use Non-Blocking mode for EraseSector, but must not interrupt the erase operation using Erase Suspend / Erase Resume. 2) If a Code Flash sector erase operation is interrupted using Erase Suspend / Erase Resume, then erase the same sector again without Erase Suspend / Erase Resume before reading the sector or programming the sector.
Fix Status	Fixed to update the Flash settings from date code 304xxxxx.





17.Limitation for keep	17.Limitation for keeping the port state from peripheral IP after wakeup from DeepSleep	
Problem Definition	The port state is not retained when the port selects peripheral IP (except for LIN or CAN FD) and MCU wakes up from DeepSleep.	
Parameters Affected	N/A	
Trigger Condition(s)	The port selects peripherals (except for LIN or CAN-FD) and MCU wakes up from DeepSleep.	
Scope of Impact	Unexpected port output change might affect user system.	
Workaround	If the port selects peripherals (except for LIN or CAN FD), and the port output value needed to be maintained after wakeup from DeepSleep, set HSIOM_PRTx_PORT_SEL.IOy_SEL = 0 (GPIO) before DeepSleep and set the required output value in GPIO configuration registers. After wakeup, change HSIOM_PRTx_PORT_SEL.IOy_SEL back to the peripheral module as needed.	
Fix Status	No silicon fix planned. TRM was updated.	

18.Limitation of clock configuration before entering DeepSleep mode.	
Problem Definition	DeepSleep should not be entered while any FLL/PLL is enabled and uses ECO as its reference clock. Since the unstable ECO clock after wakeup is outside the allowed reference clock limits for FLL/PLL, it is possible for DeepSleep wakeup to fail.
Parameters Affected	N/A
Trigger Condition(s)	DeepSleep transition while any FLL/PLL is enabled and uses ECO as its reference clock.
Scope of Impact	Possibility of DeepSleep wakeup failure.
Workaround	If any FLL/PLL operates with the ECO as its reference clock, change the clock to either ECO direct or IMO direct or IMO with FLL/PLL before entering DeepSleep.
Fix Status	No silicon fix planned. TRM was updated.

19.3everal uata retenti	ion information in the Register TRM are incorrect.
Problem Definition	The following registers are described as 'Retained' in the Register TRM while it is not guaranteed that the value before entering DeepSleep mode is still readable from the register. - SARADC: PASSx_SARy_CHz_RESULT - SRSS: PWR_LVD_STATUS - SRSS: PWR_LVD_STATUS2 - SRSS: CLK_CAL_CNT1 - SRSS: CLK_CAL_CNT2 - SRSS: CLK_FLL_STATUS - SRSS: WDT_INTR - SRSS: WDT_INTR_MASKED - SRSS: CLK_PLL400Mx_STATUS
Parameters Affected	N/A
Trigger Condition(s)	Use of the related function and wakeup from DeepSleep mode.
Scope of Impact	The values before entering DeepSleep are not retained.
Workaround	For PASSx_SARy_CHz_RESULT, do any of the following: 1) Store the conversion values at another memory location before entering DeepSleep mode 2) Restart the conversion after wakeup from DeepSleep mode For the other registers: Rewrite the register value or read the status flags again after wakeup.
Fix Status	No silicon fix planned. TRM was updated.





20.SCBx_INTR_TX.UNDERFLOW bit may be set unintentionally.					
Problem Definition There is possibility of setting the SCBx_INTR_TX.UNDERFLOW bit even if the FIFO is not experience.					
Parameters Affected N/A					
Trigger Condition(s)	Using the TX FIFO for SCB when the AHB-Lite interface clock (CLK_GR6) frequency of the AHB bus is great than 3x the SCB functionality clock (PCLK_SCBx_CLOCK).				
Scope of Impact	SCBx_INTR_TX.UNDERFLOW bit may be set unintentionally.				
Workaround	Ignore the SCBx_INTR_TX.UNDERFLOW bit if the FIFO is not empty.				
Fix Status	No silicon fix planned. TRM was updated.				

21.Hardfault may occu mode	r when calling the SROM APIs listed below while executing EraseSector or ProgramRow in non-blocking					
Problem Definition	The following SROM APIs read data in SFlash from bank#0 (or bank#1 if dual bank mode with mapping B is used). While doing that, they check if active non-blocking erase or program of bank#0 (or bank#1 if dual bank mode with mapping B is used) is not performed. Therefore, reading bank#0 (or bank#1 if dual bank mode with mapping B is used) while there is an active erase/program operation triggers a bus error. This results in a hardfault based on the FLASHC_FLASH_CTL register settings.					
	Affected SROM APIs:					
	 ReadSWPU WriteSWPU GenerateHash Checksum* ComputeBasicHash* CheckFactoryHash ProgramWorkFlash** *: Do not call it to calculate on the bank where programming/erasing is in progress. **: Do not use it during non-blocking operation. 					
Parameters Affected	N/A					
Trigger Condition(s)	Calling the affected SROM APIs while executing EraseSector or ProgramRow in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used).					
Scope of Impact	The affected SROM APIs cannot be used while executing EraseSector or ProgramRow in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used).					
Workaround	Do not use the affected SROM APIs while executing EraseSector or ProgramRow in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used).					
Fix Status	No silicon fix planned. TRM will be updated.					
Impact on Infineon Software	S-LLD, HSM-Perf-Lib: While executing EraseSector or ProgramRow in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used), users must not do any of following: a) call CySldProt_GetSwpuFlashStructCfg b) call CySldProt_VerifySecureDomainFlashWriteProtection if CySldProt_SwpuFlashStructGroupConfigurations is non-empty					

Errata



22.CAN FD sporadic data corruption (payload) in case acceptance filtering does not finish before reception of data R3 (DB7..DB4) is complete

Problem Definition

During frame reception the Rx Handler accesses the external Message RAM for acceptance filtering (read accesses) and for storing of the accepted messages (write accesses).

The time needed for acceptance filtering and for storing of a received message depends on

- · The Host clock frequency
- The worst-case latency of the read and write accesses to the external Message RAM
- The number of configured filter elements
- The workload of the transmit message (Tx) handler in parallel to the receive message (Rx) handler

Received data bytes (DB0..DBm) from the CAN Core are buffered in the cache of the Rx Handler before they are written to the Message RAM (in words of 4 byte). Data words inside the Message RAM are numbered from R2 to Rn ($n \le 17$).

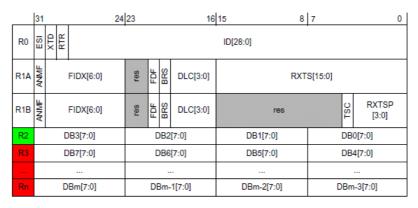


Figure 1 Rx Buffer and FIFO Element

Under the following conditions, a received message has corrupted data while the received message is signaled as valid to the host.

- 1) The data length code (DLC) of the received Message is greater than 4 (DLC > 4)
- 2) The storage of Ri of a received message into the Message RAM (after acceptance filtering is done) has not completed before R(i+1) is transferred from the CAN Core into the cache of the Rx Handler (where $2 \le i \le 5$).
- 3) While condition 1) and 2) apply, a concurrent read of data word Ri from the cache and write of data word R(i+1) into the cache of the Rx handler happens.

The data will be corrupted in a way, that in the Message RAM R(i+1) has the same content as Ri.

Despite the corrupted data, the M_TTCAN signals the storage of a valid frame in the Message RAM:

- Rx FIFO: FIFO put index RXFnS.FnPI is updated.
- Dedicated Rx Buffer: New Data flag NDATn.NDxx is set.
- Interrupt flag IR.MRAF is not set.

The issue may occur in the FD Frame Format as well as in the Classic Frame Format.

Figure 2 shows how the available time for acceptance filtering and storage is reduced.

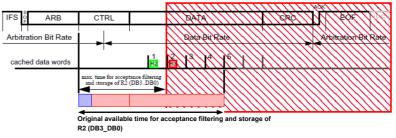


Figure 2 CAN Frame with DLC>4

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22.CAN FD sporadic data corruption (payload) in case acceptance filtering does not finish before reception of data R3 (DB7..DB4) is complete

	Number of	Number Arbitration bit rate = 0.5 Mbps					Arbitration	n bit rate = 1	Mbps	
	configured	of active	Data	Data	Data bit	Data bit	Data bit	Data bit	Data bit	Data bit
	active filter	CAN	bit	bit	rate = 2	rate = 4	rate = 1	rate = 2	rate = 4	rate = 5
	element	channel	rate =	rate =	Mbps	Mbps	Mbps	Mbps	Mbps	Mbps
	11-bit IDs /	s in an	0.5	1 Mbps						
	29-bit IDs	instance	Mbps							
	32 / 16	2	3.9	7.1	13.1 MHz	22.8 MHz	7.7 MHz	14.1 MHz	26.1 MHz	31.5 MHz
			MHz	MHz						
		3	5.4	9.9	18.3 MHz	31.8 MHz	10.7 MHz	19.7 MHz	36.5 MHz	44.0 MHz
			MHz	MHz						
	64 / 32	2	7.4	13.5	24.9 MHz	43.4 MHz	14.7 MHz	26.9 MHz	49.8 MHz	60.0 MHz
			MHz	MHz	04.0441		00 5 1 41 1	07.01411		
		3	10.3	18.8	34.9 MHz	60.7 MHz	20.5 MHz	37.6 MHz	69.7 MHz	84.0 MHz
	96 / 48	2	MHz 10. 8	MHz 19.9	36.8 MHz	64.0 MHz	21.6 MHz	39.7 MHz	73.5 MHz	
	96 / 48	2	MHz		30.6 MITZ	64.0 MHZ	21.6 МП2	39.1 MITZ	13.3 MHZ	88.6 MHz
		3	15.1	MHz 27.8	51.5 MHz	00 C MII-	30.2 MHz	55.6 MHz	102.9 MHz ³	124.0 MHz ³
		3	MHz	MHz	31.3 WH 12	89.6 MHz	30.2 MHZ	33.0 MHZ	102.9 MHZ	124.0 MITZ
	128 / 64	2	14.3	26.3	48.6 MHz	84.7 MHz	28.4 MHz	52.5 MHz	97.2 MHz	117.2 MHz ³
			MHz	MHz		04.7 10112			31.2 MHZ	117.2 141112
		3	20.0	36.8	68.0 MHz	118.5 MHz ³	40.0 MHz	73.5 MHz	136.0 MHz ³	164.0 MHz ³
			MHz	MHz		110.5 11112			130.0 11112	101.011112
	tance filterin message. The filtering proce 2.Acceptance setting shoul 11-bit filter el 3. Frequency	erefore, the ess. filtering se d be consid ement.	esequence earch for dered. Se	ce of conf 11-bit IDs earching fo	igured filter s and 29-bit or one 29-b	elements ha : IDs filter ele it filter eleme	s a significa ment runs ent requires	ant impact separately; approxima	on the perfor only one cor ately double o	mance of the nfigured filte cycles for or
rameters Affected	N/A	N/A								
rigger Condition(s)	Under the following conditions a received message has corrupted data while the received message is signaled as valid to the host: 1) The data length code (DLC) of the received message is greater than 4 (DLC > 4) 2) The storage of Ri of a received message into the Message RAM (after acceptance filtering is done) has not completed before R(i+1) is transferred from the CAN Core into the cache of the Rx Handler (where 2 ≤ i ≤ 5). 3) While condition 1) and 2) apply, a concurrent read of data word Ri from the cache and write of data word R(i+1 into the cache of the Rx handler happens.									
									e is below th	

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22.CAN FD sporadic complete	data corruption (payload) in case acceptance filtering does not finish before reception of data R3 (DB7DB4) is
Workaround	Check whether the minimum Host clock frequency (shown in Table 1) is below the Host clock frequency used in the actual device. If yes, there is no problem with the selected configuration. If no, use one of the following two workarounds. 1) Try a different configuration by changing the following parameters until the actual Host clock frequency (CLK_GR5) is above the minimum host frequency shown in Table 1 : • Increase the CLK_GR5 frequency in the actual device
	Reduce the CAN-FD data bit rate
	Reduce the number of configured filter elements
	Reduce the number of active CAN channels in an instance
	Also, use DLC ≥ 8 instead of DLCs 5, 6, and 7 in the CAN environment/system, as they place higher demands on the minimum Host clock frequency (the worst case is DLC = 5) or restrict your CAN environment/system to DLC 4.
	Note: While changing the actual host clock frequency, CLK_GR5 must always be equal to or higher than PCLKCANFD[x]_CLOCK_CAN[y] for all configurations.
	2) Due to condition 3) listed in " Trigger Conditions ", the issue occurs only sporadically. Use an end-to-end (E2E) protection (for example, checksum or CRC covering the data field) and add it to all messages in the CAN system, to detect data corruption in the received frames.
Fix Status	No silicon fix planned. Use workaround.
Impact on Infineon software	Impact: Limitation Related modules: CAN, MCU Comment: The user must evaluate the impact of the erratum for each CAN instance separately. A CAN instance is the entirety of CanControllers with the same CanControllerInstance value. 1) For the number of active CAN nodes: Use the maximum number of CanController configurations of a CAI instance that can be active (Autosar controller state STARTED or SLEEP) at a time. 2) For the host clock frequency: In McuPeriGroupSettings, locate the setting with McuPeriGroup MCU_PERI_GROUP5_MMIO5 and take the value from McuPeriGroupClockFrequency. 4) For the number of configured active filter element 11-bit IDs / 29-bit IDs: Use the corresponding values from the "Message RAM () linking table" in the generated Can_PBcfg.h file. Note that each CanController has it separate table. Take the maximum values. 5) For the arbitration bit rate: Use the maximum CanControllerBaudRate value of all the CanControllers. 6) For the data bit rate: Use the maximum CanControllerFdBaudRate value of all the CanControllers.

23.Description for PASS SARx to TCPWMx direct connect triggers one-to-one is incorrect in datasheet				
Problem Definition	The existing datasheet shows the incorrect TCPWM input trigger selection (TR_IN_SEL) value, 'trig=2', in the description for PASS SARx to TCPWMx direct connect triggers one-to-one. The correct value is '4' as shown in the architecture TRM (chapter 25 descriptions and table 25-2).			
Parameters Affected	N/A			
Trigger Condition(s)	Using the triggers one-to-one for PASS SARx to TCPWMx direct connect			
Scope of Impact	The triggers one-to-one for PASS SARx to TCPWMx direct connect cannot work if TCPWM's input trigger selection is not correct			
Workaround	Use '4' as TCPWM's input trigger selection (TR_IN_SEL) value for PASS SARx to TCPWMx direct connect			
Fix Status	No silicon fix planned. Datasheet was updated.			
Impact on Infineon Software	Impact: No Related modules: PWM Comment: The MCAL PWM module does not support one-to-one triggers.			

configured. Otherwise use CanControllerBaudRate.

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Revision history



Revision history

Document revision	Date	Description of changes			
**	2017/02/10	Advance datasheet			
*A	2017/03/31	Extensive rewrite of all sections for better clarity			
*B	2017/09/11	Updated Features. Minor corrections in Features list. Updated Blocks and functionality. Updated Functional description. Updated Memory Map to clarify single and dual bank mode functionality Updated Electrical specifications. Added the following timing diagrams in Electrical specifications: Reset, TCPWM, SCB (I ² C, SPI), Crystal Connection Scheme, SAR ADC, Syste Resources, and JTAG. Updated Ordering information. Updated Packaging to include two formats: - Without alternate functions - With alternate functions Updated Package Characteristics.			
*C	2018/02/12	Updated Ordering information . Updated title to "CYT2B5/B7 Datasheet 32-bit Arm® Cortex®-M4F Micro troller TRAVEO™ T2G Family". Updated Electrical specifications . Updated SPI Diagrams. Added ADC equivalent circuit for analog input.			
*D	2018/09/27	Updated Features list and Peripheral I/O map. Updated Pin assignment. Updated Alternate function pin assignments Updated Functional description. Updated Trigger multiplexer and Interrupts and wake-up assignments. Added General P-DMA descriptions, Clock Dividers, and GPIO power port source information. Updated Clock diagram Added HSIOM connections reference table and references to it in alternate pin assignment. Update Electrical specifications. Updated Design Review. Added Errata.			
*E	2019/07/25	Updated Features, Features list, and Functional description. Updated Peripheral I/O map. Updated Alternate function pin assignments Updated Interrupts and wake-up assignments and Core interrupt types. Updated Trigger Groups and Peripheral clocks. Updated Peripheral Protection Unit Fixed Structure Pairs. Updated Bus masters. Updated Miscellaneous configuration. Updated Reset Sequence, ADC, and SPI Diagrams. Updated Table 26-21 and Table 26-24. Updated Ordering information and Packaging. Updated Appendix.			

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Revision history

Document revision	Date	Description of changes				
*F	2019/11/26	Updated SRAM in CYT2B7 address map. Updated PLL and FLL in Functional description. Updated Programmable PPU and SCB in Peripheral I/O map. Updated Package Characteristics. Updated affected MPNs in Errata. Updated sample revision in Ordering information.				
*G	2020/04/23	Added eSHE footnote on page 1. Updated Block diagram. Updated SCB/UART content in Functional description. Added note for VCCD in Power pin assignments. Added Pin Mux descriptions. Updated Fault Assignments table with detailed descriptions. Added JTAG ID and package support footnotes in Ordering information. Removed CM7 from Part number nomenclature. Updated Packaging. Updated Errata.				
*H	2020/06/29	Updated Features list. Updated Clock system. Updated Electrical specifications. Updated Ordering information. Updated Appendix. For details, refer to Revision History Change Log.				
*	2021/10/13	Updated Features list. Updated Communication peripheral instance list. Updated High-speed I/O matrix connections. Updated Alternate function pin assignments. Updated Faults. Updated Electrical specifications. Updated Part number nomenclature. Updated Appendix. Added Errata. For details, refer to Rev *I updates in the Revision History Change Log.				
*J	2022/09/08	Updated Electrical specifications . Updated Errata . For details, refer to Rev *J updates in the Revision History Change Log .				
*K	2023/07/12	Updated General description. Updated Features list. Updated Blocks and functionality. Updated Peripheral I/O map. Updated Package pin list and alternate functions. Updated Power pin assignments. Updated Alternate function pin assignments. Updated Ordering information. Updated Packaging. Updated Errata				
*L	2024/03/04	Updated Triggers one-to-one . Updated Errata .				

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Revision History Change Log



Revision History Change Log

Rev. *L section updates

Section Change Description		Current Spec	New Spec	Reason for change	
19. Triggers one-to-one	MUX Group 3: PASS SARx to TCPWM0 direct connect Input: 0	Description: SAR0 ch#0, range violation to TCPWM0 Group #1 Counter #00 trig=2	Description: SAR0 ch#0, range violation to TCPWM0 Group #1 Counter #00 trig=4	Correction	
	Input 63	SAR2 ch#7, range violation to TCPWM0 Group #0 Counter #51 trig=2	SAR2 ch#7, range violation to TCPWM0 Group #0 Counter #51 trig=4		
31. Errata	CYT2B7 Errata Summary [21] Items: Fix Status:	Items: Hardfault may occur when calling ReadSWPU or WriteSWPU while executing EraseSector or ProgramRow in non-blocking mode	Items: Hardfault may occur when calling the SROM APIs listed below while executing EraseSector or ProgramRow in non-block- ing mode	Updated	
		Fix Status: No silicon fix planned. TRM was updated.	Fix Status: No silicon fix planned. TRM will be updated.		
31. Errata	CYT2B7 Errata Summary [23] Items: Errata ID: Fix Status:	none	Items: Description for PASS SARx to TCPWMx direct connect triggers one-to-one is incorrect in datasheet	Added errata	
			Errata ID: 212		
			Fix Status: No silicon fix planned. Datasheet was updated.		
31. Errata	21.Hardfault may occur when calling the SROM APIs listed below while executing Erase-Sector or ProgramRow in non-blocking mode Problem Definition: Trigger Condition(s): Scope of Impact: Workaround: Fix Status:	Problem Definition: ReadSWPU or WriteSWPU read data from bank#0 (or bank#1 if dual bank mode with mapping B is used) in SFlash. While doing that, the check for active non-blocking erase or program of bank#0 (or bank#1 if dual bank mode with mapping B is used) is not performed. Therefore, reading bank#0 (or bank#1 if dual bank mode with mapping B is used) while there is an active erase/program operation will trigger a bus error, which can result in a hardfault occurrence based on FLASHCFLASH_CTL register settings. Trigger Condition(s): Calling ReadSWPU or WriteSWPU while executing EraseSector or ProgramRow in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used). Scope of Impact: ReadSWPU or WriteSWPU can't be used while executing EraseSector or ProgramRow in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used).	Problem Definition: The following SROM APIs read data in SFlash from bank#0 (or bank#1 if dual bank mode with mapping B is used). While doing that, they check if active non-blocking erase or program of bank#0 (or bank#1 if dual bank mode with mapping B is used) is not performed. Therefore, reading bank#0 (or bank#1 if dual bank mode with mapping B is used) while there is an active erase/pro- gram operation triggers a bus error. This re- sults in a hardfault based on the FLASHC FLASH_CTL register settings. Affected SROM APIs: ReadSWPU WriteSWPU GenerateHash Checksum* CheckFactoryHash ProgramWorkFlash** Do not call it to calculate on the bank where programming/erasing is in progress. Do not use it during non-blocking opera- tion. Trigger Condition(s): Calling the affected SROM APIs while exe- cuting EraseSector or ProgramRow in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used). Scope of Impact: The affected SROM APIs cannot be used while executing EraseSector or Program- Row in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used).	Updated	
		Workaround: Do not use ReadSWPU or WriteSWPU while executing EraseSector or ProgramRow in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used).	Workaround: Do not use the affected SROM APIs while executing EraseSector or ProgramRow in non-blocking mode on bank#0 (or bank#1 if dual bank mode with mapping B is used).		
		Fix Status: No silicon fix planned. TRM was updated.	Fix Status: No silicon fix planned. TRM will be updated.		
31. Errata	23.Description for PASS SARx to TCPWMx direct connect trig- gers one-to-one is incorrect in datasheet	none	Added "23.Description for PASS SARx to TCPWMx direct connect triggers one-to-one is incorrect in datasheet"	Added errata	

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